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**Kim et al.**

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(54) **RED PHOSPHORESCENT COMPOSITION  
AND ORGANIC ELECTROLUMINESCENT  
DEVICE USING THE SAME**

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(30) **Foreign Application Priority Data**

Oct. 29, 2008 (KR) ..... 10-2008-0106548

(51) **Int. Cl.**

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**C09K 11/06** (2006.01)

**H01L 51/00** (2006.01)

**H01L 51/50** (2006.01)

(52) **U.S. Cl.**

CPC ..... **C09K 11/06** (2013.01); **C09K 2211/1007** (2013.01); **C09K 2211/1029** (2013.01); **C09K 2211/185** (2013.01); **H01L 51/0085** (2013.01); **H01L 51/5016** (2013.01)

(58) **Field of Classification Search**

None

See application file for complete search history.

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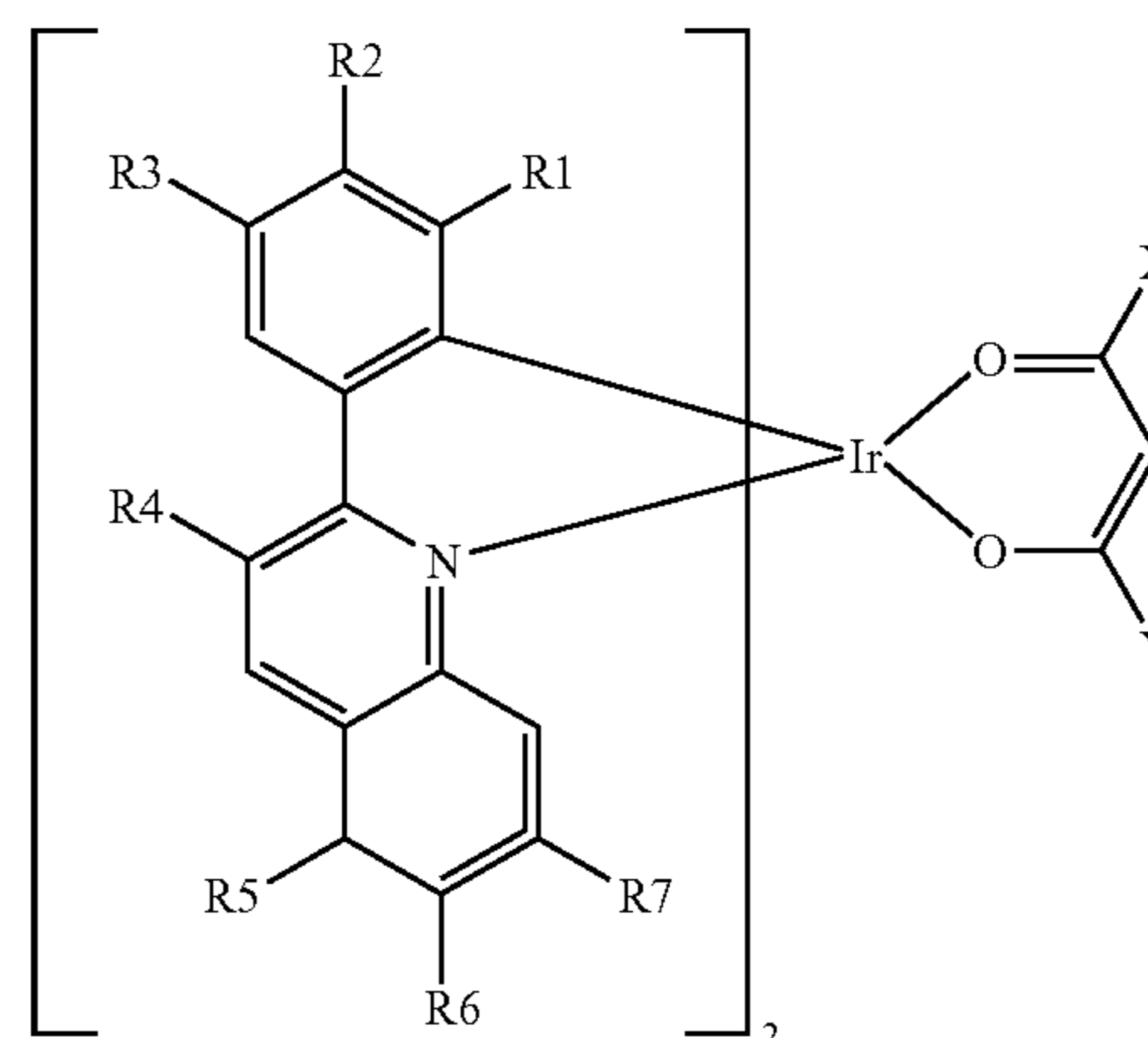
\* cited by examiner

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(57) **ABSTRACT**

A red phosphorescent composition includes a host material being capable of transporting an electron or a hole; and a dopant material represented by the following Formula 1:



[Formula 1]

wherein each of R1 to R4 is selected from the group consisting of hydrogen atom (H), C1 to C6 alkyl and C1 to C6 alkoxy, and at least one of R1 to R4 is C1 to C6 alkyl, and wherein each of R5 to R7 is selected from the group consisting of hydrogen, C1 to C6 alkyl and halogen atom, and at least one of R5 to R7 is halogen atom, and wherein each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

**17 Claims, 2 Drawing Sheets**

FIG. 1  
PRIOR ART

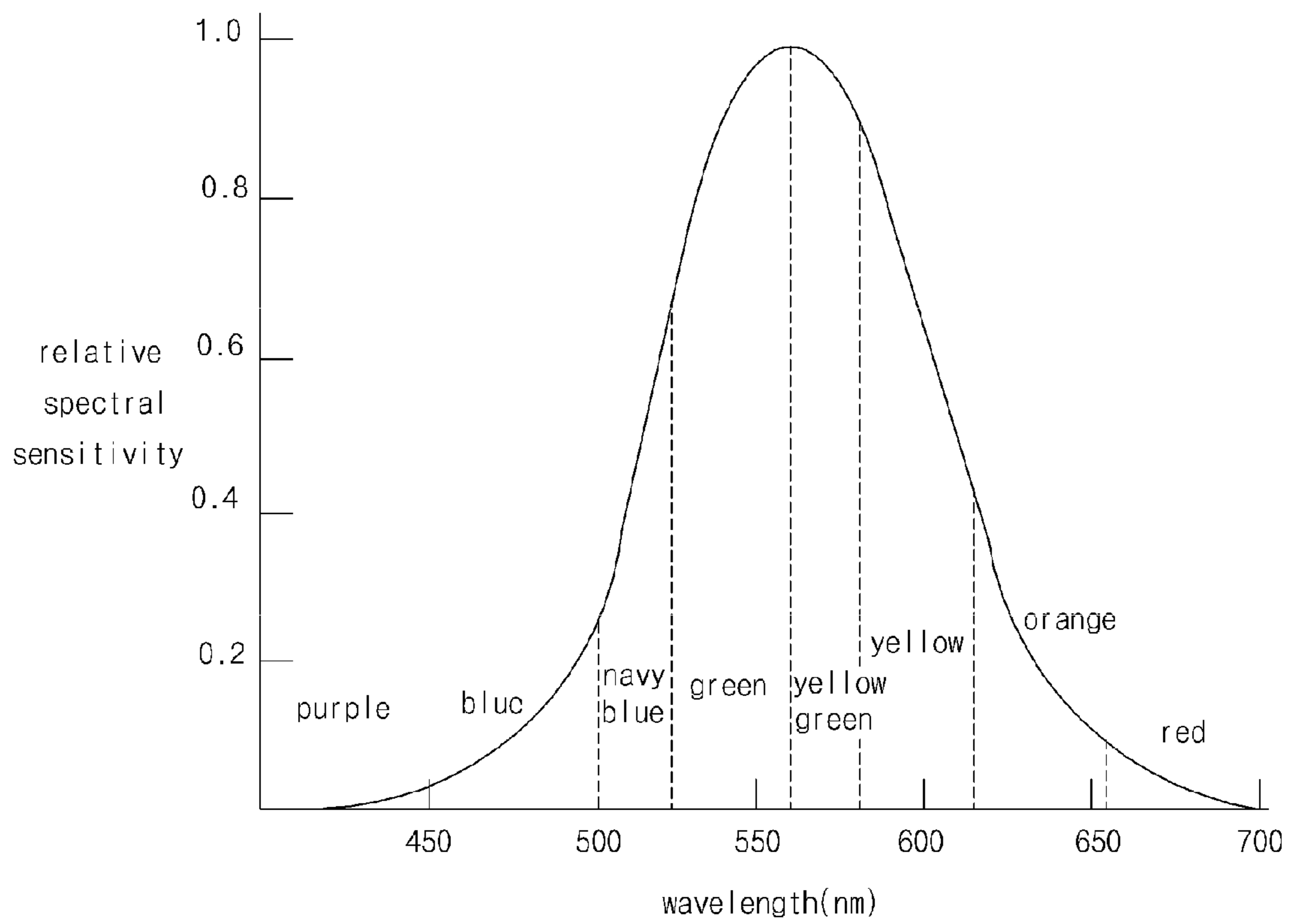
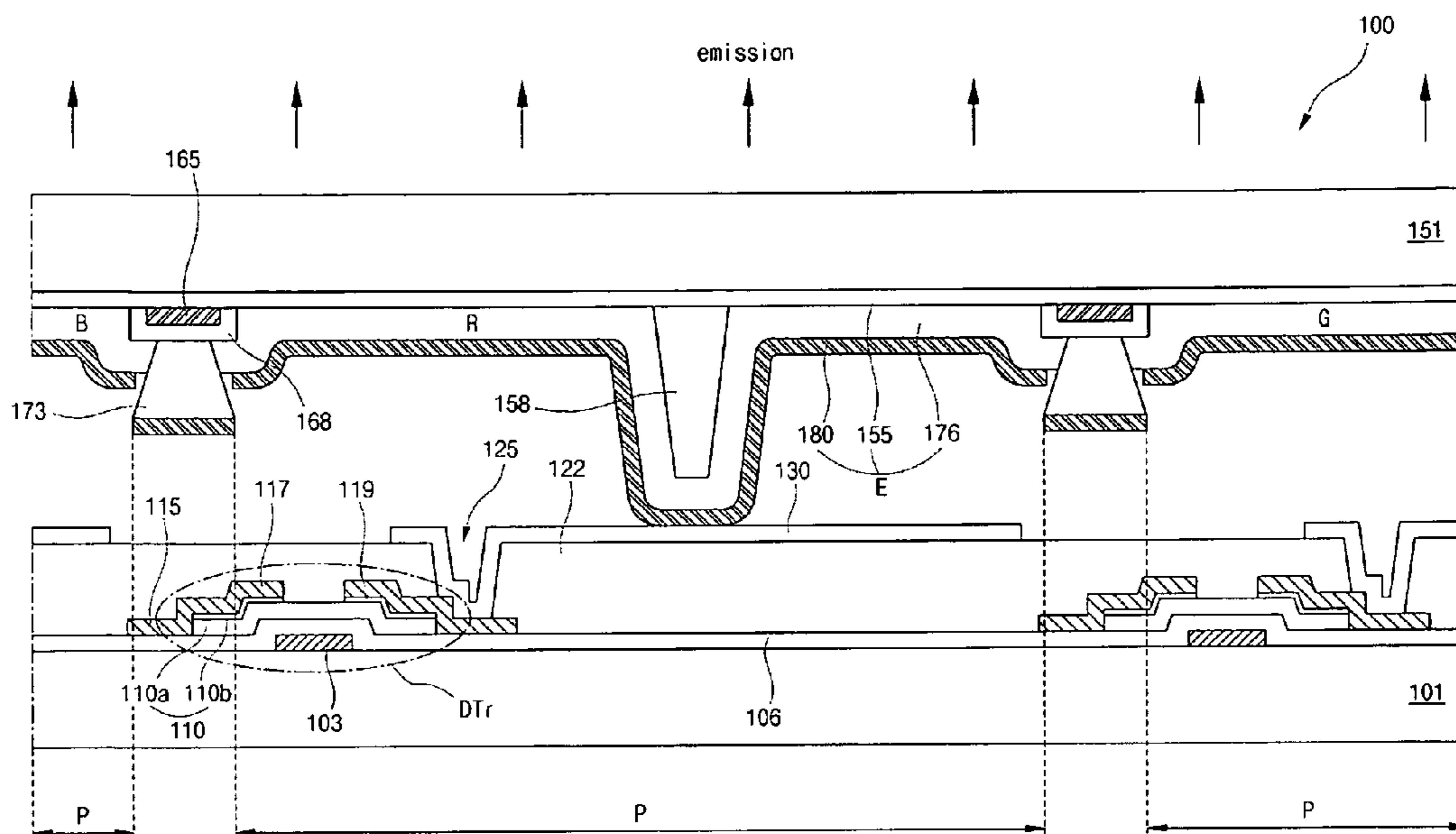


FIG. 2





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**RED PHOSPHORESCENT COMPOSITION  
AND ORGANIC ELECTROLUMINESCENT  
DEVICE USING THE SAME**

The present application claims the benefit of Korean Patent Application No. 10-2008-0106548 filed in Korea on Oct. 29, 2008, which is hereby incorporated by reference as if fully set forth herein.

**BACKGROUND OF THE INVENTION**

**1. Field of the Invention**

The present invention relates to a red phosphorescent compound and an organic electroluminescent device (OLED) and more particularly to a red phosphorescent compound having high color purity, an improved lifetime, and an OLED using the red phosphorescent compound.

**2. Discussion of the Related Art**

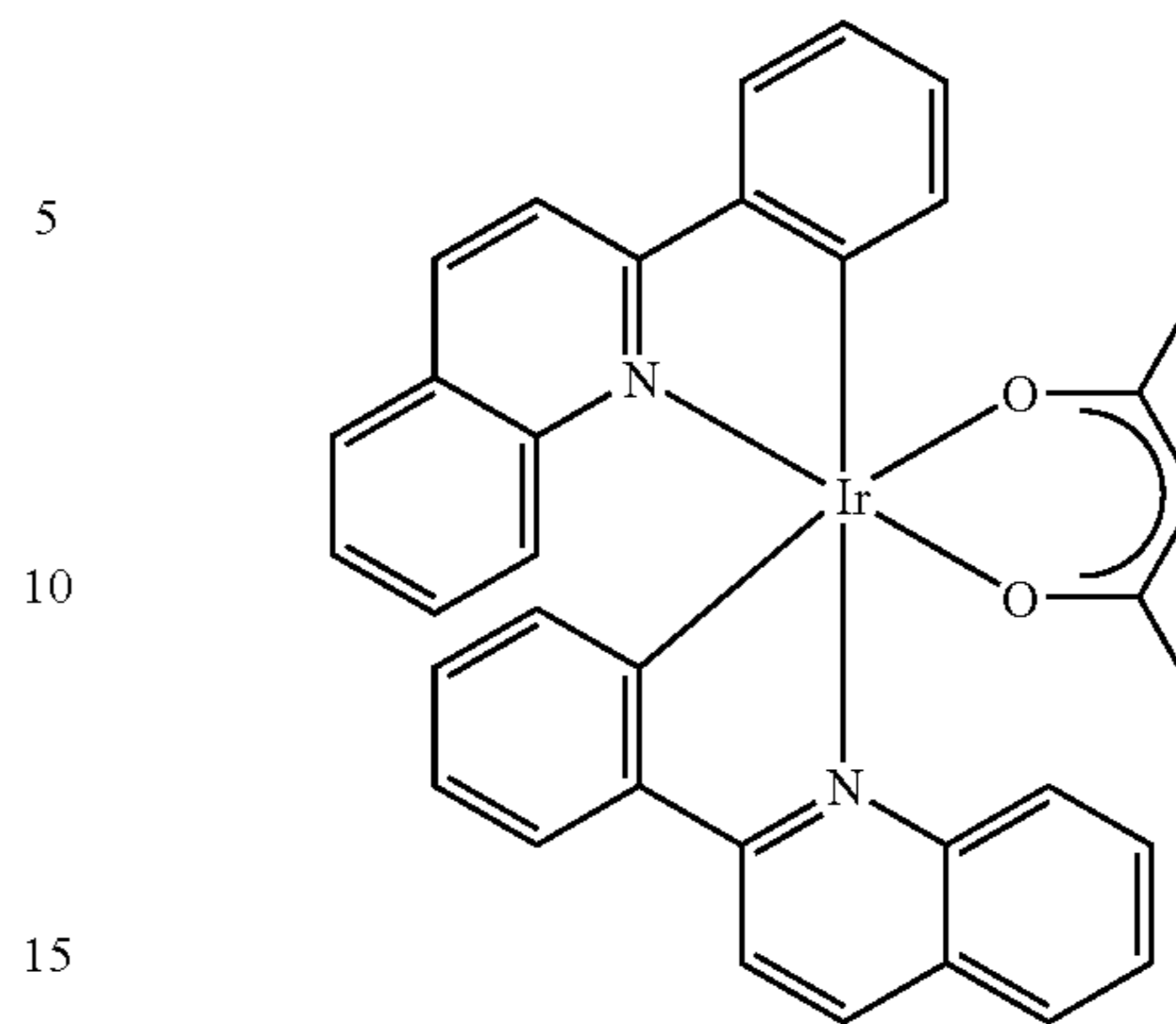
Recently, requirements for a flat panel display device having a relatively large display area and a relatively small occupancy have been increased. Among the flat panel display devices, an OLED has various advantages as compared to an inorganic electroluminescent device, a liquid crystal display device, a plasma display panel, and so on. The OLED device has excellent characteristics of viewing angle, contrast ratio, and so on. Also, since the OLED device does not require a backlight assembly, the OLED device has lower weight and lower power consumption. Moreover, the OLED device has advantages of a faster response rate, low production cost, and so on.

In general, the OLED emits light by injecting electrons from a cathode and holes from an anode into an emission compound layer, combining the electrons with the holes, generating an exciton, and transforming the exciton from an excited state to a ground state. A flexible substrate, for example, a plastic substrate, can be used as a base substrate where elements are formed. The OLED has excellent characteristics of viewing angle, contrast ratio, and so on. Also, since the OLED does not require a backlight assembly, the OLED has lower weight and lower power consumption. Moreover, the OLED has advantages of a faster response rate, low production cost, high color purity, and so on. The OLED can be operated at a voltage (e.g., 10V or below) lower than a voltage required to operate other display devices. In addition, the OLED is adequate to produce full-color images.

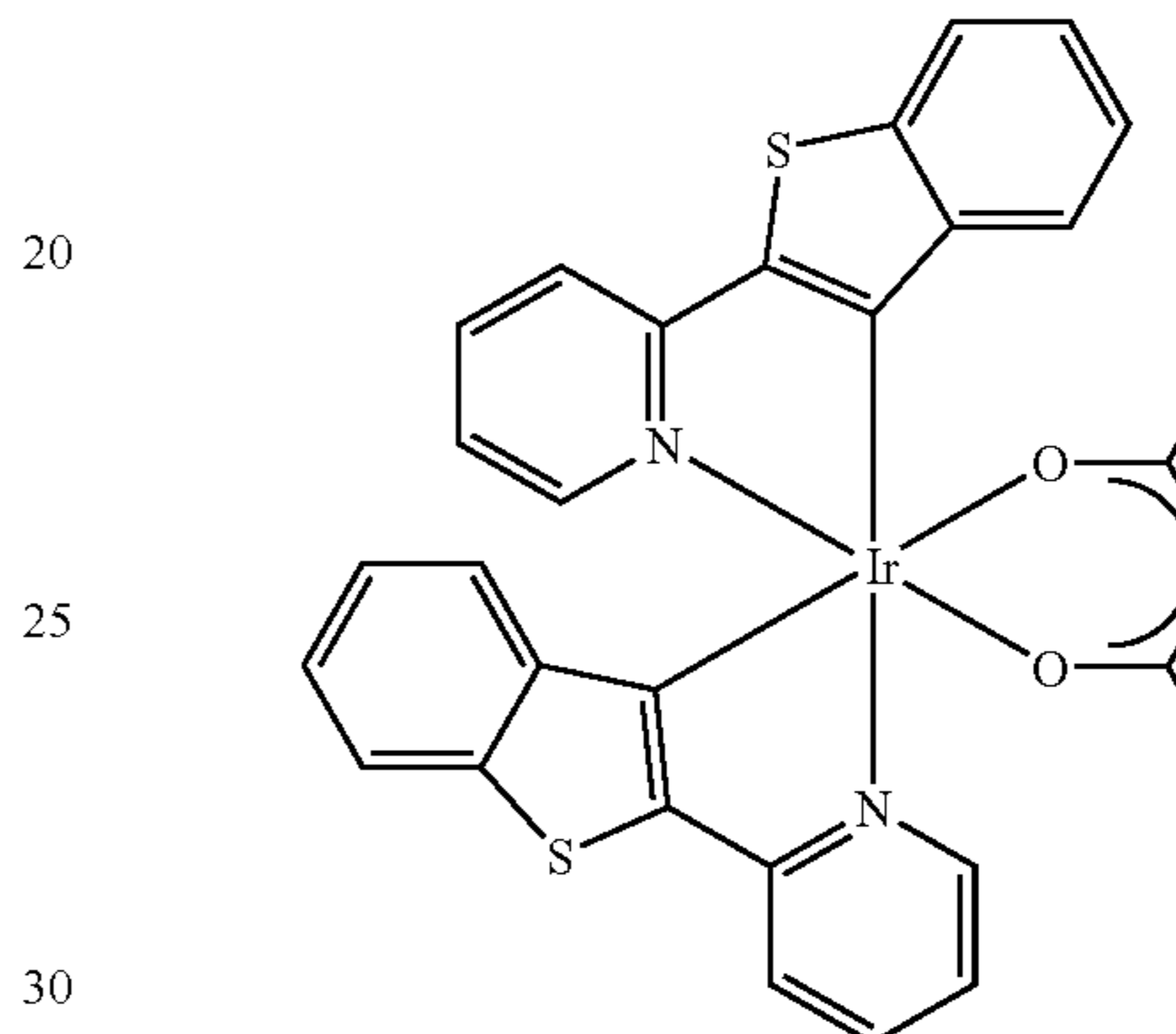
A general method for fabricating OLEDs will be briefly explained below. First, an anode is formed on a substrate by depositing a transparent conductive compound, for example, indium-tin-oxide (ITO). Next, a hole injection layer (HIL) is formed on the anode. For example, the HIL may be formed of copper phthalocyanine (CuPC) and have a thickness of about 10 nm to about 30 nm. Next, a hole transporting layer (HTL) is formed on the HIL. For example, the HTL may be formed of 4,4'-bis[N-(1-naphthyl)-N-phenylamino]-biphenyl (NPB) and have a thickness of about 30 nm to about 60 nm. Next, an emitting compound layer (EML) is formed on the HTL. A dopant may be doped onto the EML. In a phosphorescent type, the EML may be formed of 4,4'-N,N'-dicarbazole-biphenyl (CBP) and have a thickness of about 30 nm to about 60 nm, and the dopant may include one of iridium complex represented by following Formulas 1-1 to 1-3.

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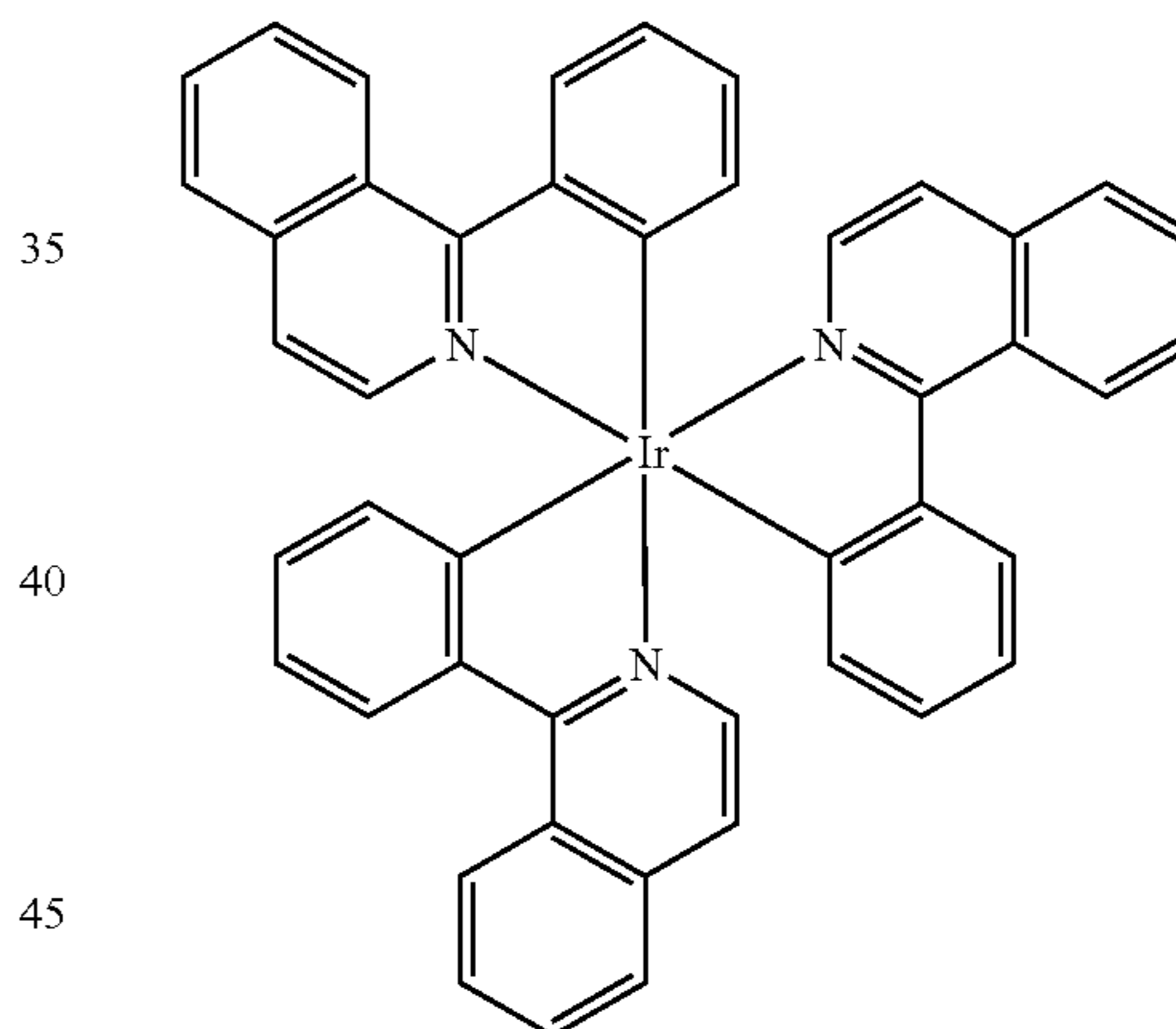
[Formula 1-1]



[Formula 1-2]



[Formula 1-3]



Next, an electron transporting layer (ETL) and an electron injection layer (EIL) are stacked on the EML. For example, the ETL may be formed of tris(8-hydroxy-quinolate)aluminum (Alq3). A cathode is formed on the EIL, and a passivation layer is formed on the cathode.

In the above structure, the EML produces red, green and blue colors such that the OLED can display full-color images. In an emitting compound, an exciton is generated by combining the electrons from a cathode and holes from an anode. The exciton includes a singlet exciton and a triplet exciton. The singlet exciton participates in a fluorescent type emission, while the triplet exciton participates in a phosphorescent type emission. The singlet exciton has a formation probability of about 25%, while the triplet exciton has a formation probability of about 75%. Accordingly, the phosphorescent type emission has luminescence efficiency greater than the fluorescent type emission.

In the phosphorescent compound, since a red phosphorescent compound has excellent luminescence efficiency as



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compared to a red fluorescent compound, the red phosphorescent compound has been widely developed and researched to improve an emission efficiency of the OLED. The phosphorescent compound is required to have high luminescence efficiency, high color purity, long life span, and so on. Particularly, as shown in FIG. 1, as the color purity of an OLED using a red phosphorescent material becomes higher (i.e. as the X index on CIE chromaticity coordinates increase), the relative spectral sensitivity of images from the OLED decreases. Accordingly, it is difficult to achieve high luminance efficiency of the OLED.

## SUMMARY OF THE INVENTION

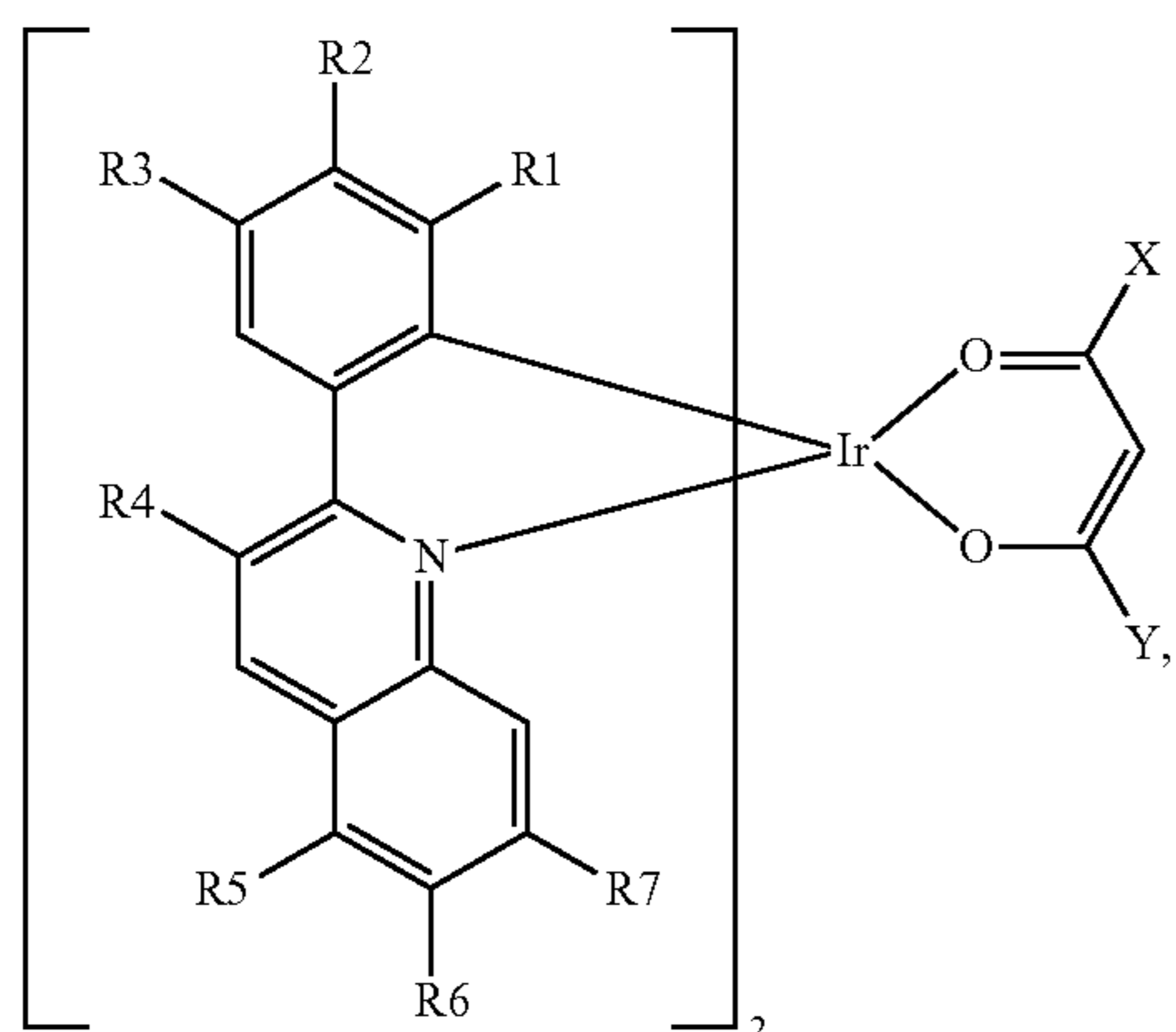
Accordingly, the present invention is directed to a red phosphorescent compound and an organic electroluminescent device (OLED) using the same that substantially obviates one or more of the problems due to limitations and disadvantages of the related art.

An object of the present invention is to provide a red phosphorescent compound having high color purity (e.g., X index of CIE chromaticity coordinates being greater than 0.65), high luminescence efficiency, and long lifetime.

Another object of the present invention is to provide an OLED device using the red phosphorescent compound.

Additional features and advantages of the invention will be set forth in the description which follows, and in part will be apparent from the description, or may be learned by practice of the invention. The objectives and other advantages of the invention will be realized and attained by the structure particularly pointed out in the written description and claims hereof as well as the appended drawings.

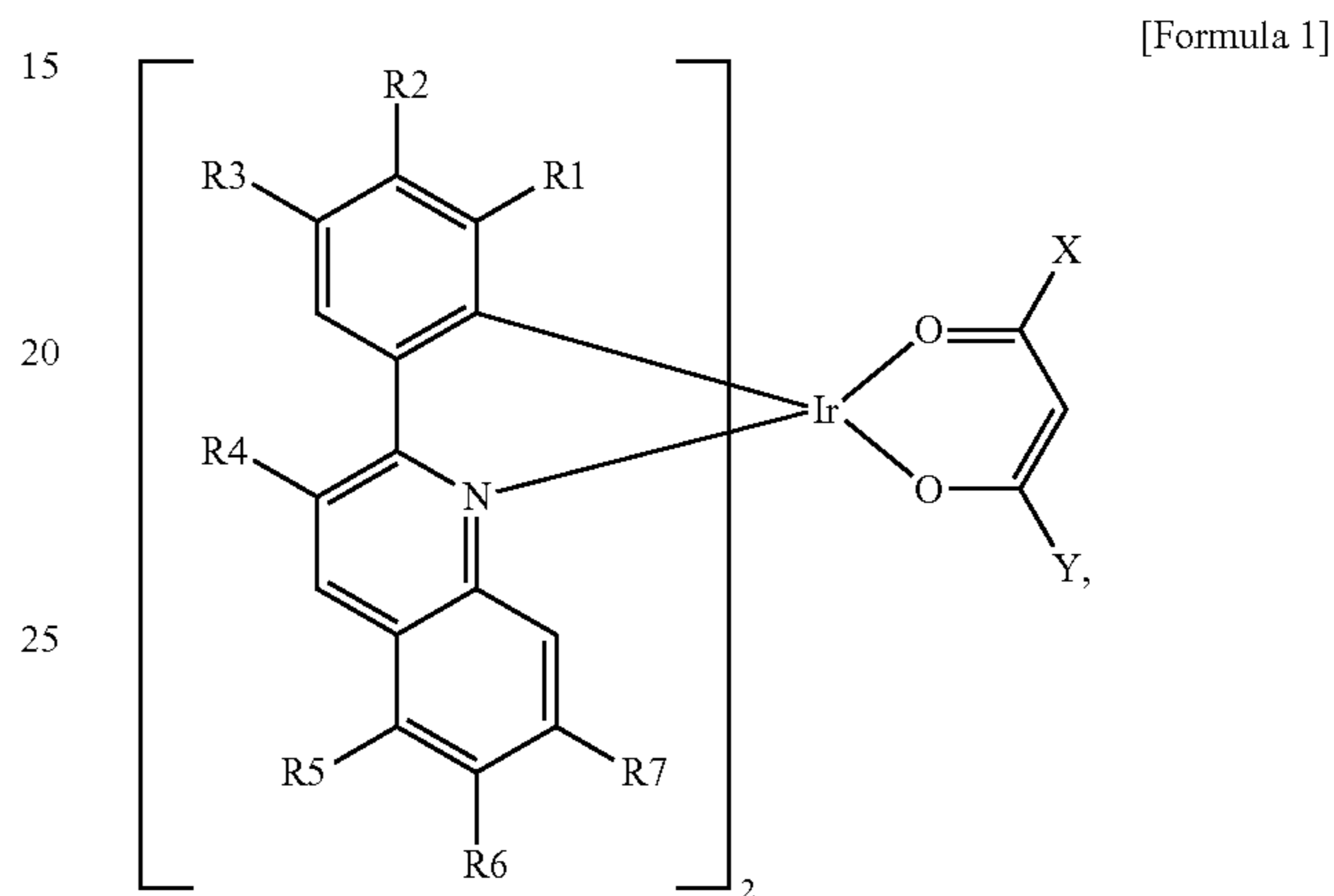
To achieve these and other advantages and in accordance with the purpose of the present invention, as embodied and broadly described herein, a red phosphorescent composition, includes a host material being capable of transporting an electron or a hole; and a dopant material represented by the following Formula 1:



wherein each of R1 to R4 is selected from the group consisting of hydrogen atom (H), C1 to C6 alkyl and C1 to C6 alkoxy, and at least one of R1 to R4 is C1 to C6 alkyl, and wherein each of R5 to R7 is selected from the group consisting of hydrogen, C1 to C6 alkyl and halogen atom, and at least one of R5 to R7 is halogen atom, and wherein each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

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In another aspect of the present invention, an organic electroluminescent device includes a first substrate; a thin film transistor on the first substrate; a second substrate facing the first substrate; and an organic luminescent diode electrically connected to the thin film transistor and including a first electrode, a second electrode facing the first electrode and an organic emission layer disposed between the first and second electrodes, a red phosphorescent composition of the organic emission layer including a host material being capable of transporting an electron or a hole; and a dopant material represented by the following Formula 1:



wherein each of R1 to R4 is selected from the group consisting of hydrogen atom (H), C1 to C6 alkyl and C1 to C6 alkoxy, and at least one of R1 to R4 is C1 to C6 alkyl, and wherein each of R5 to R7 is selected from the group consisting of hydrogen, C1 to C6 alkyl and halogen atom, and at least one of R5 to R7 is halogen atom, and wherein each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

## BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention and together with the description serve to explain the principles of the invention.

FIG. 1 is a graph showing a relation of a color purity and a visible degree; and

FIG. 2 is a schematic cross-sectional view of an OLED according to the present invention.

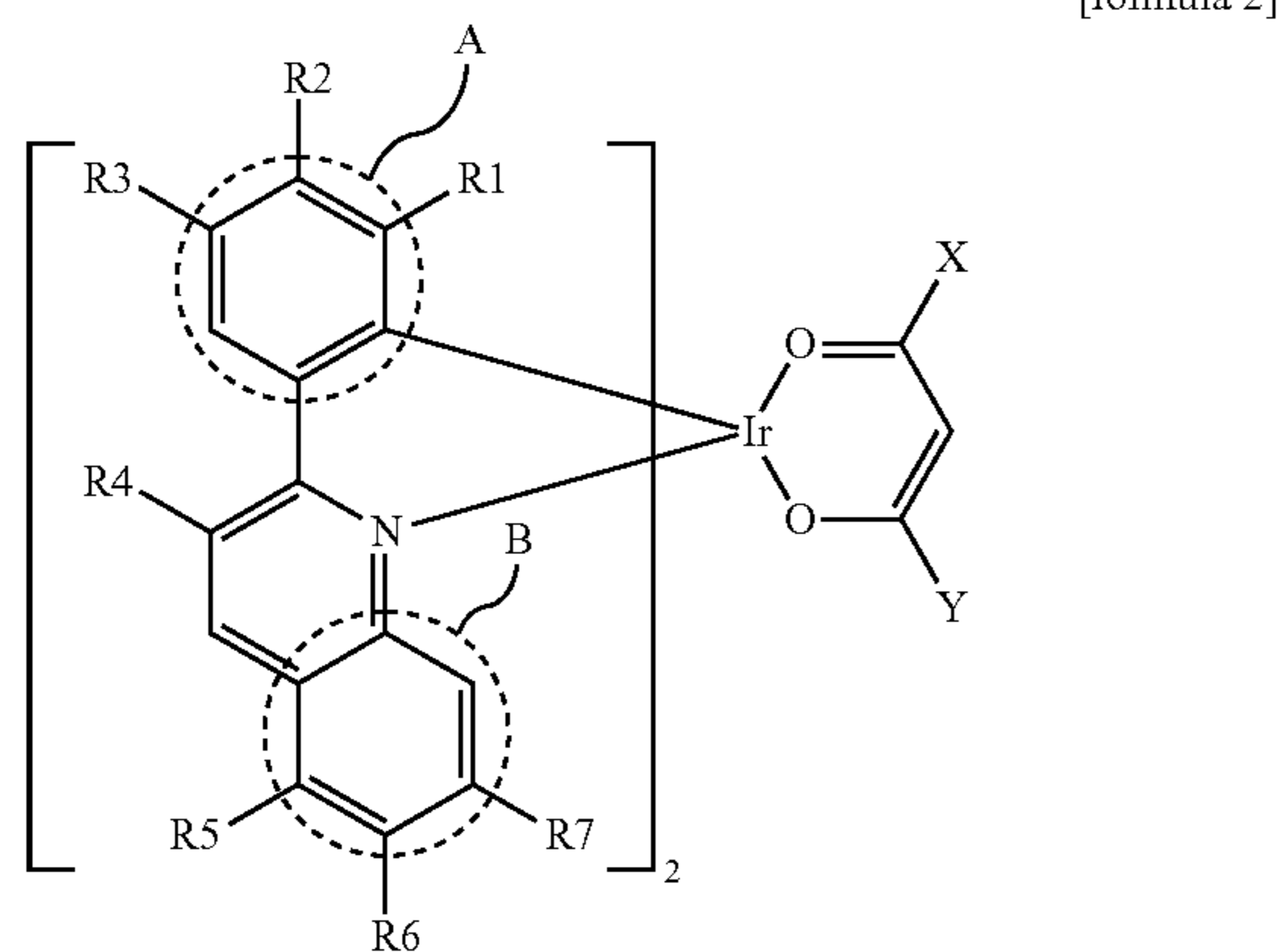
## DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

Reference will now be made in detail to the preferred embodiments, examples of which are illustrated in the accompanying drawings.

A red phosphorescent compound includes at least one alkyl, which is substituted in a phenyl part, and at least one halogen atom, which is substituted in a quinoline part, such that the red phosphorescent compound has improved color

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purity, luminescence efficiency and life time. The red phosphorescent compound is represented by the following Formula 2.



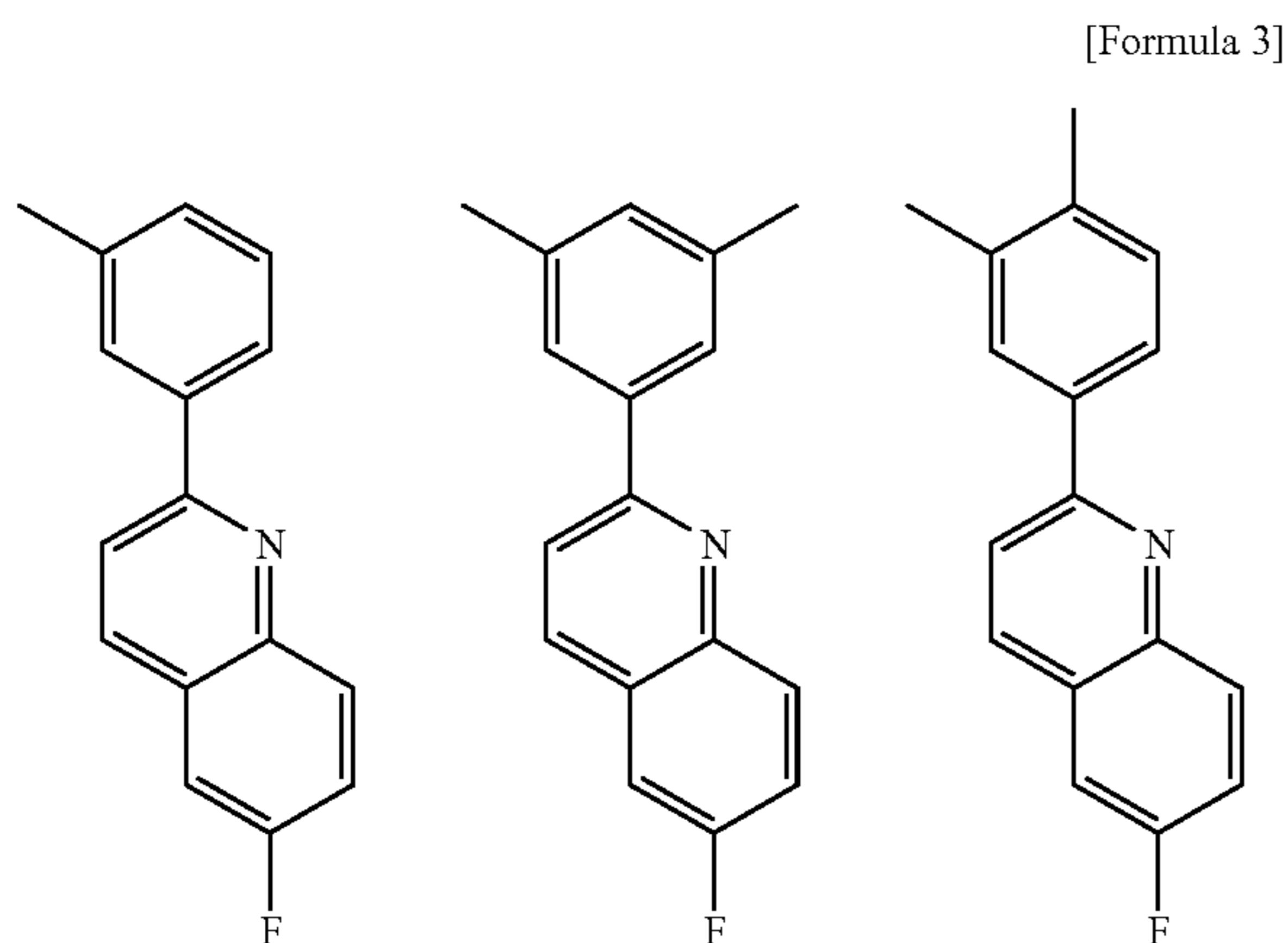
In the above formula 2, each of R1 to R4 is selected from the group consisting of hydrogen atom (H), C1 to C6 alkyl and C1 to C6 alkoxy. In addition, at least one of R1 to R4 is C1 to C6 alkyl. Each of R5 to R7 is selected from the group consisting of H, C1 to C6 alkyl and halogen atom. In addition, at least one of R5 to R7 is halogen atom.

As mentioned above, at least one alkyl is substituted in a first phenyl part "A" such that the red phosphorescent compound has improved color purity and luminescence efficiency. In addition, at least one halogen atom is substituted in a second phenyl part "B", which is not substituted by nitrogen, in a quinoline part such that the red phosphorescent compound has further improved color purity and luminescence efficiency and elongated lifetime.

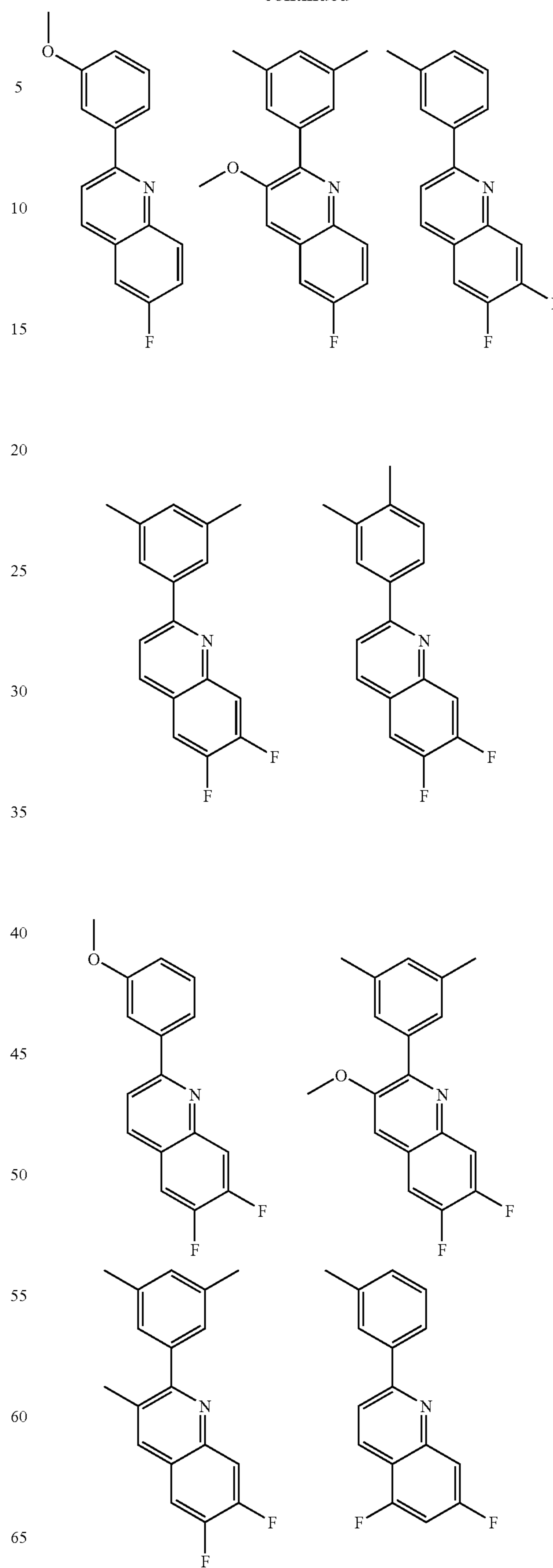
In formula 2, each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

For example, the C1 to C6 alkyl may be selected from the group consisting of methyl, ethyl, n propyl, i-propyl, n-butyl, i-butyl and t-butyl, and the C1 to C6 alkoxy may be selected from the group consisting of methoxy, ethoxy, n-propoxy, i-propoxy, n-butoxy, i-butoxy and t-butoxy.

As a result, in the above formula 2, a left side structure of central iridium (Ir) is selected from the following Formula 3.

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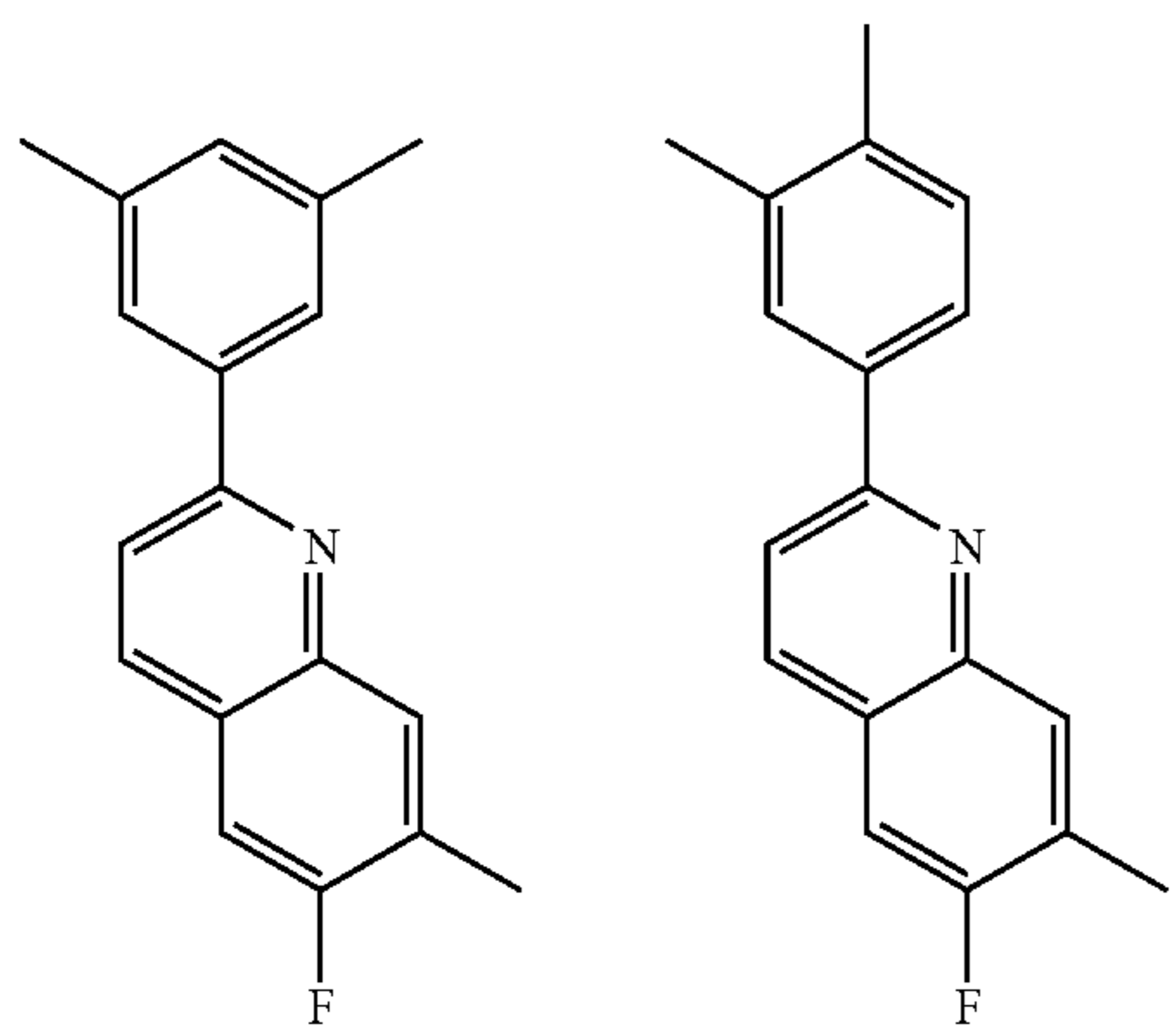
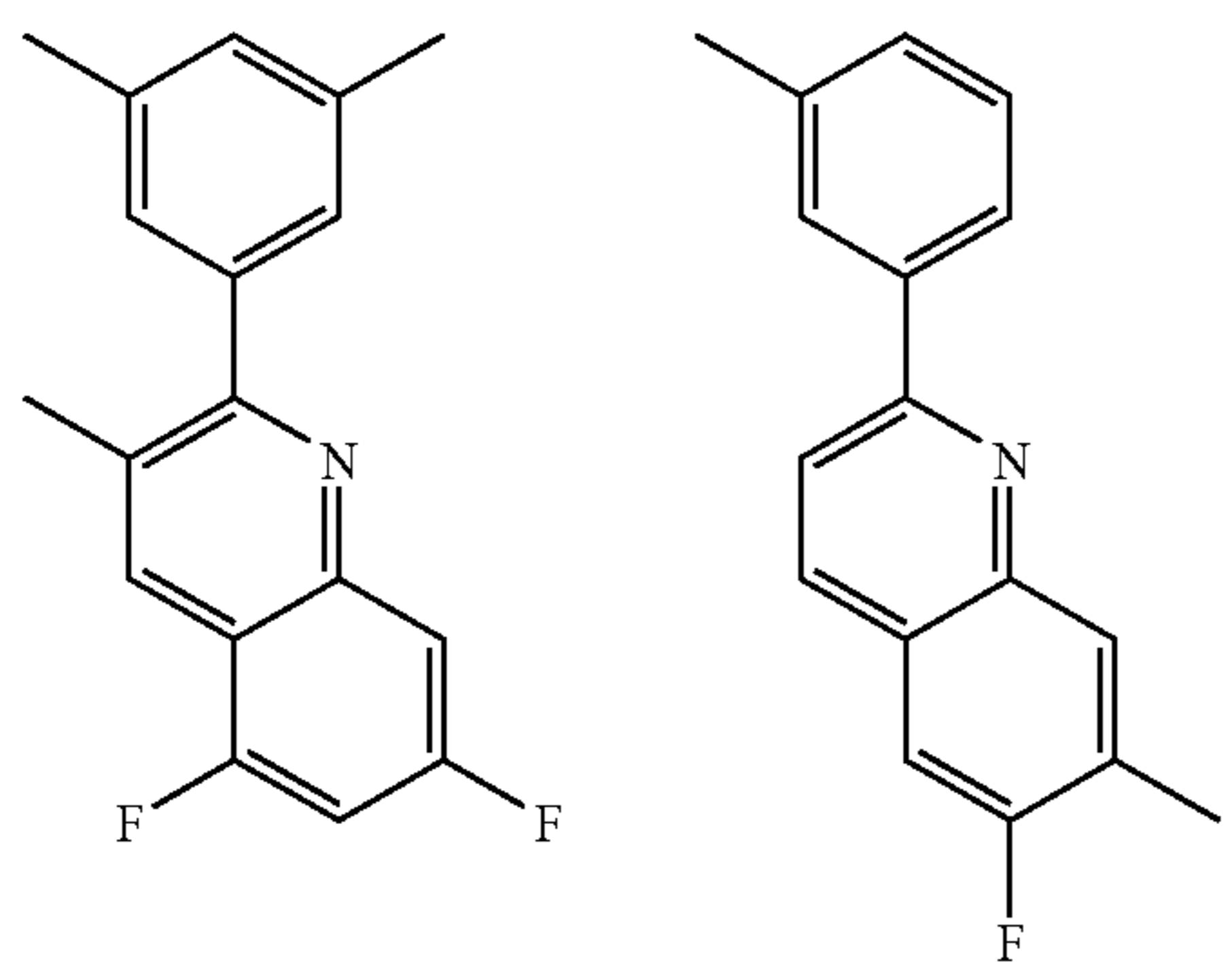
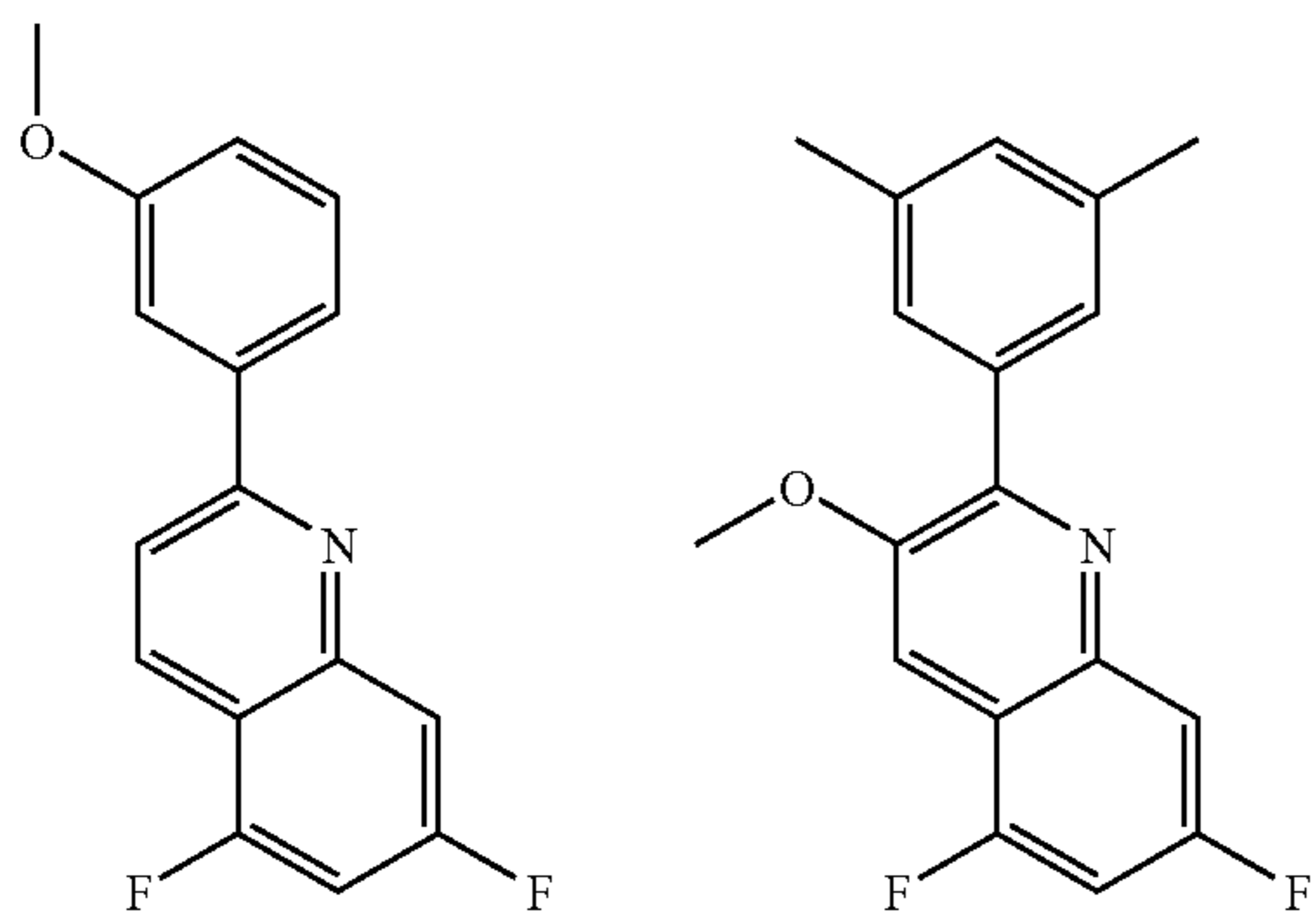
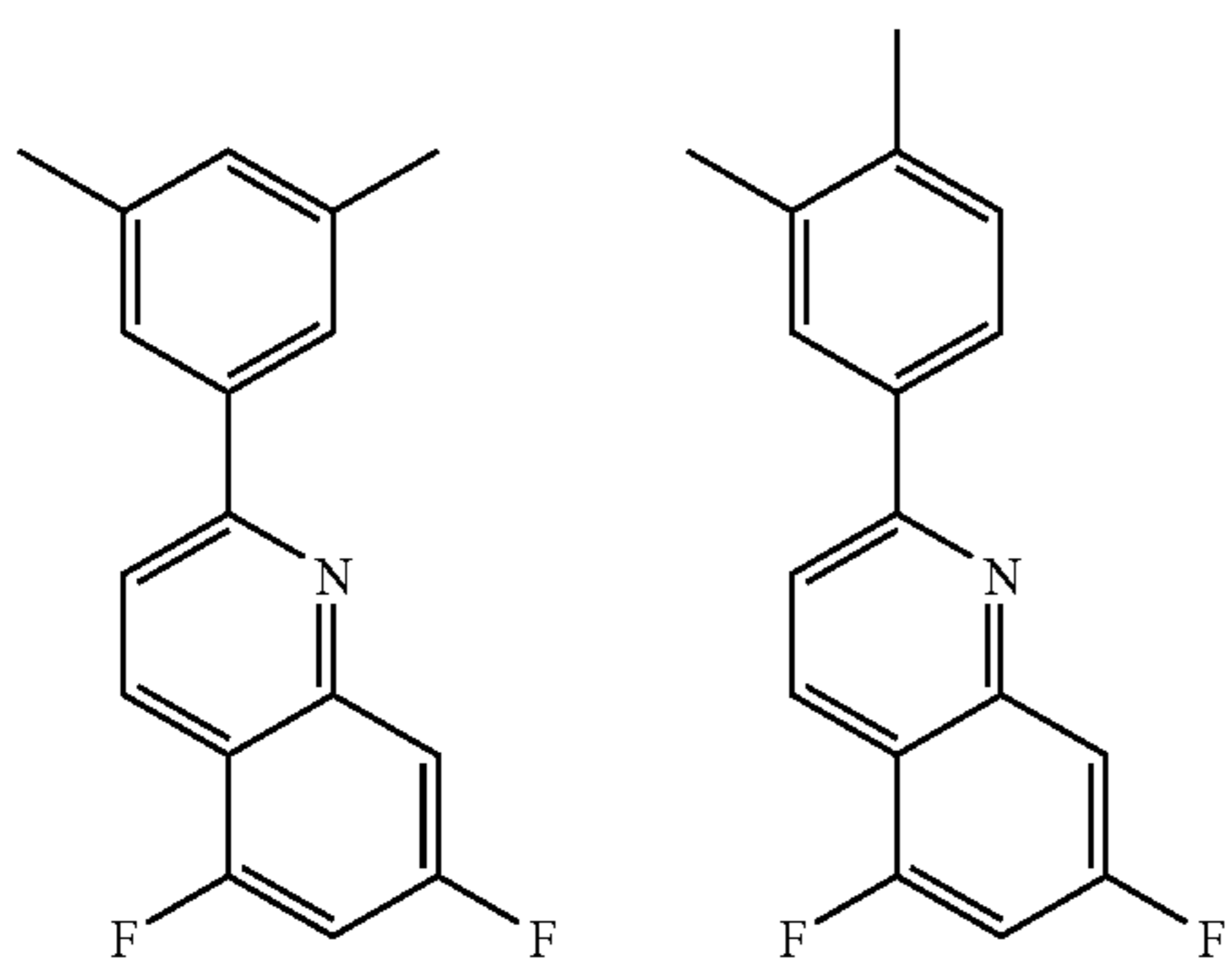
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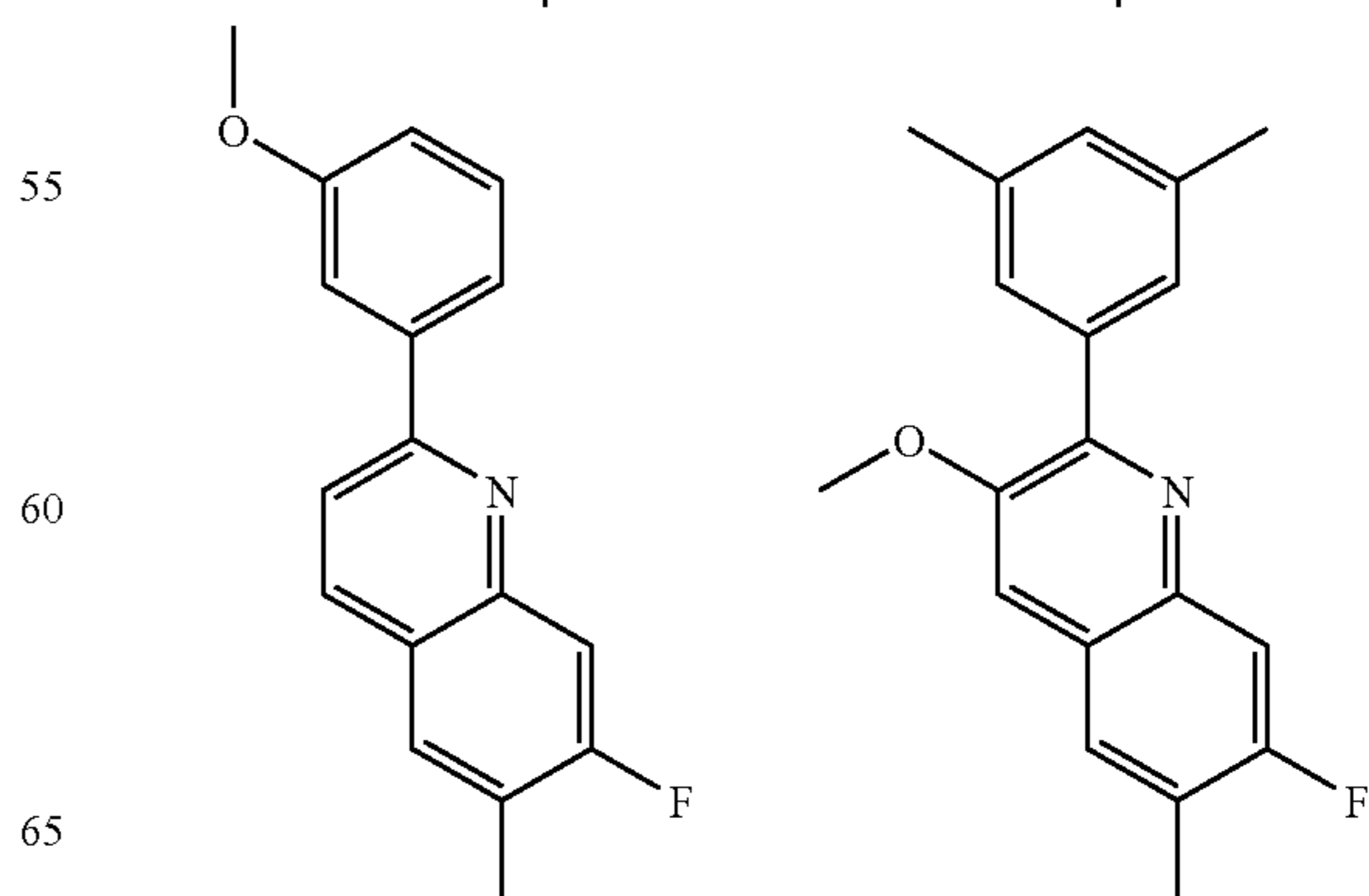
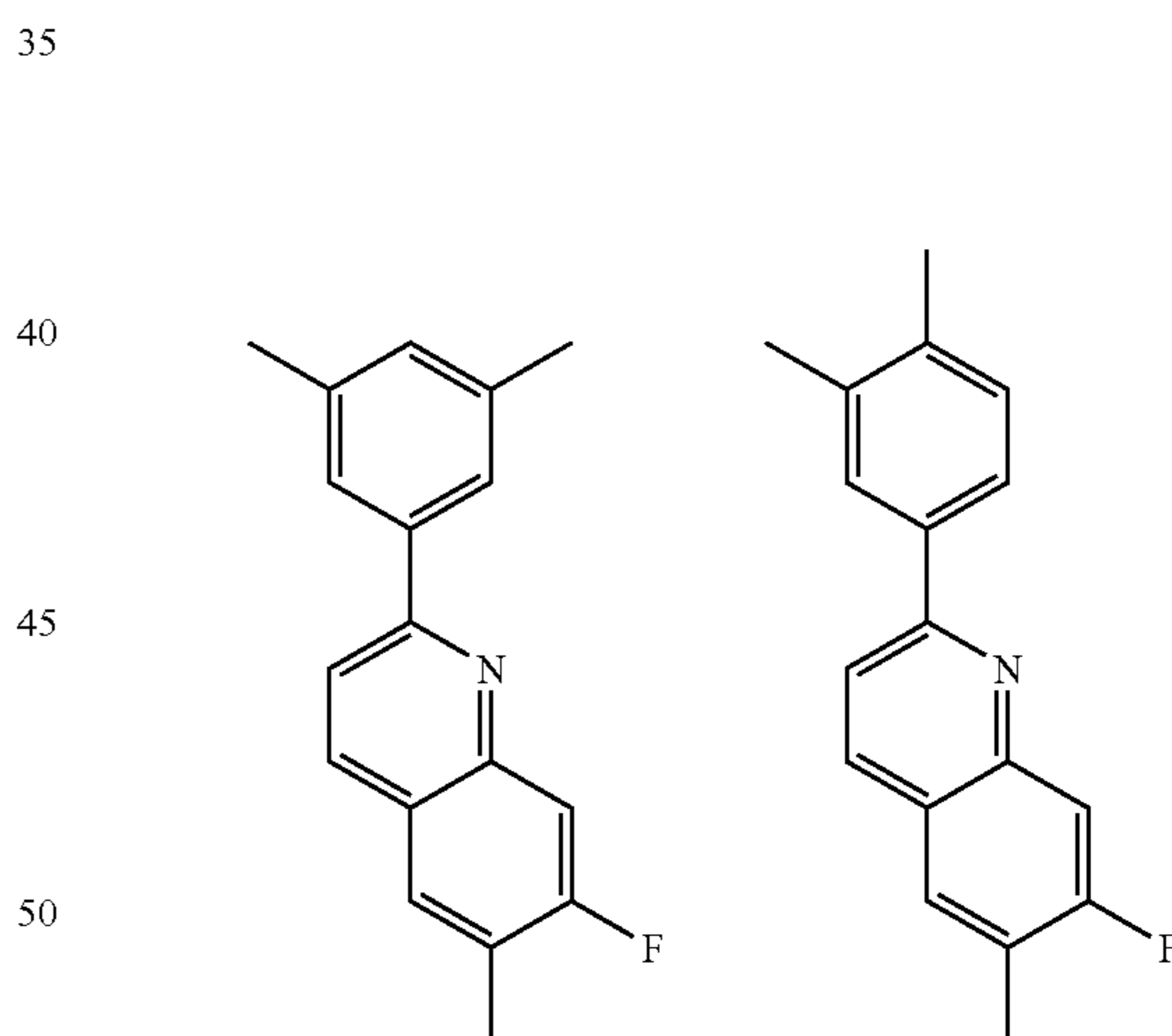
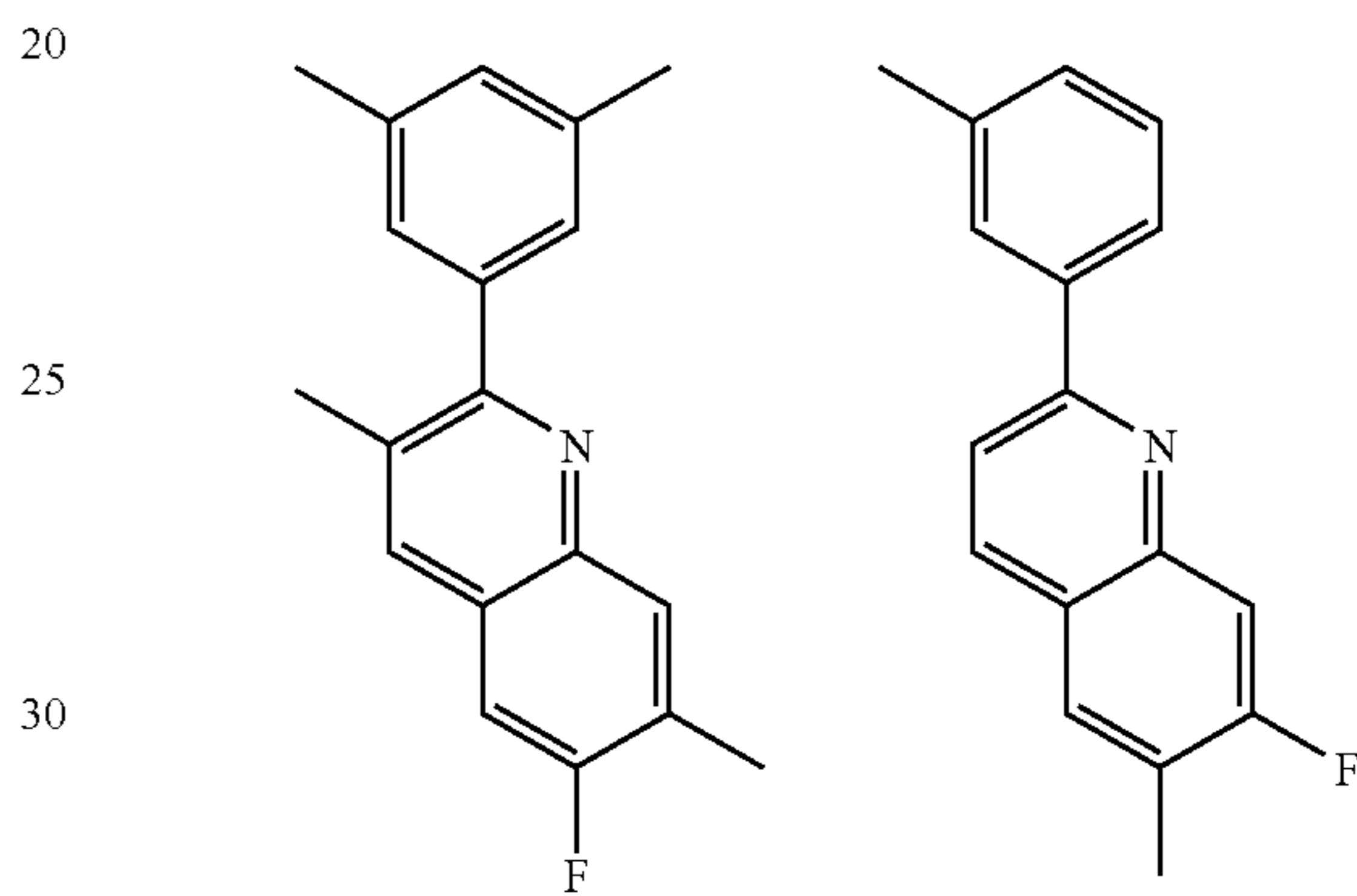
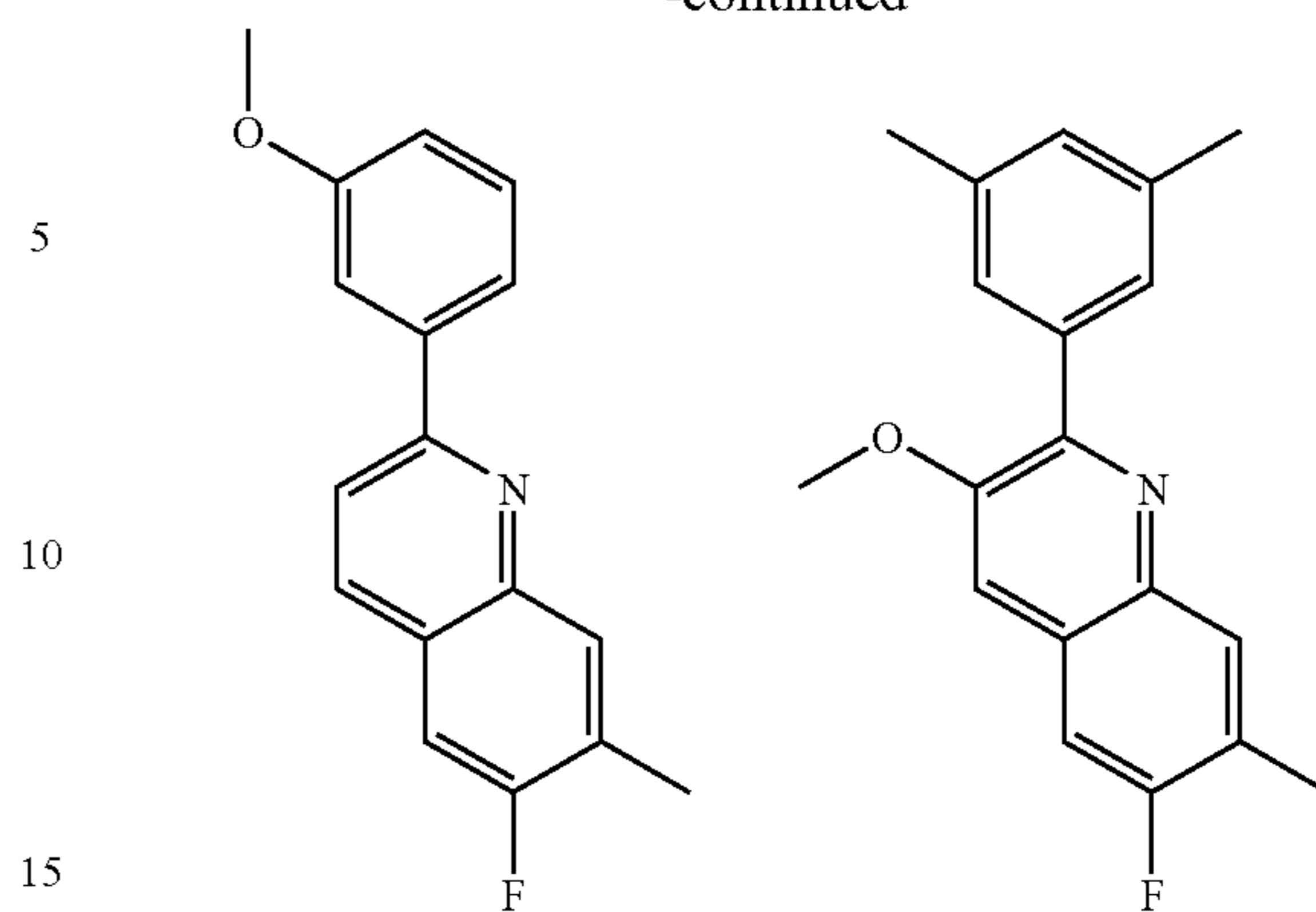
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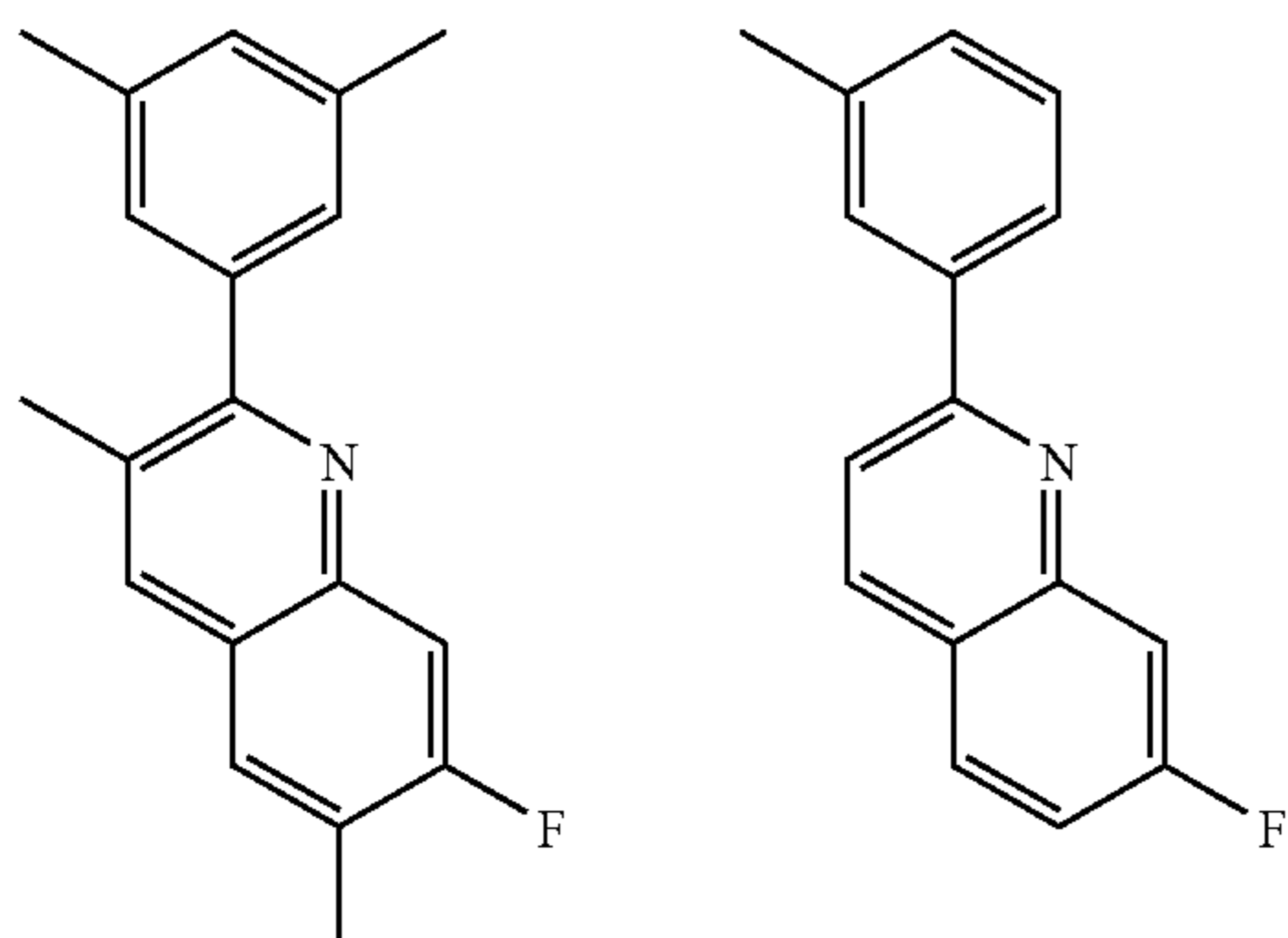
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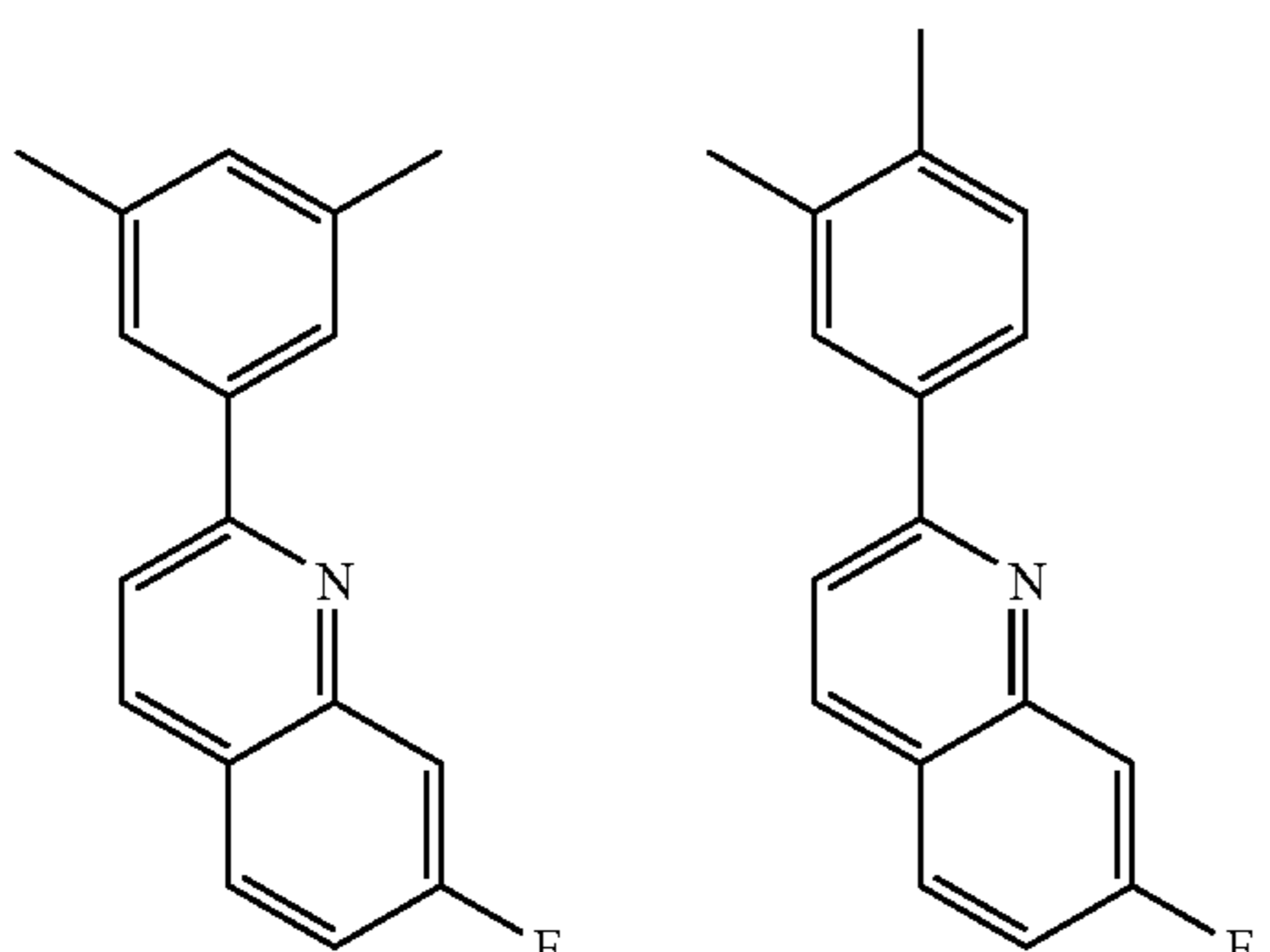
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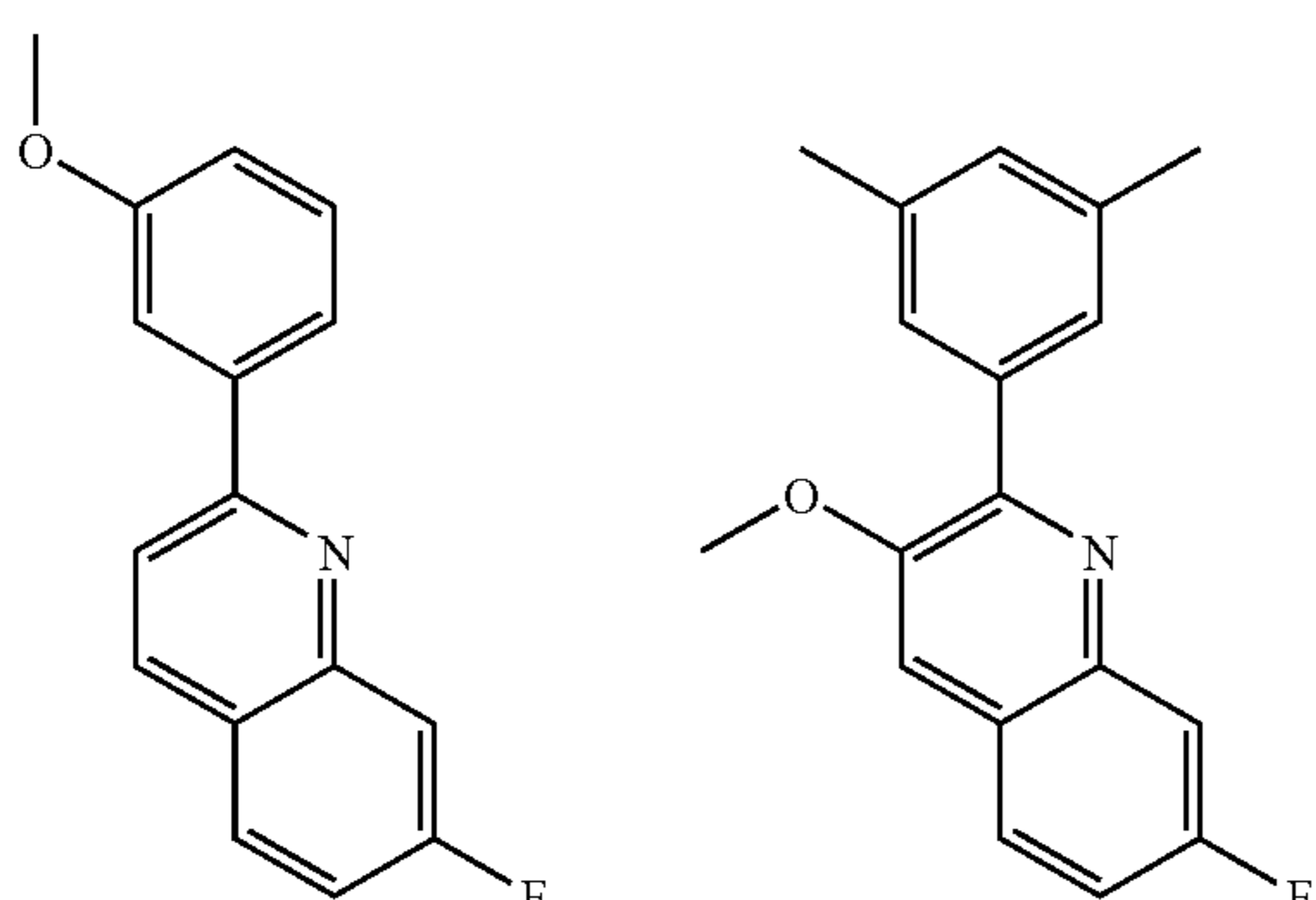
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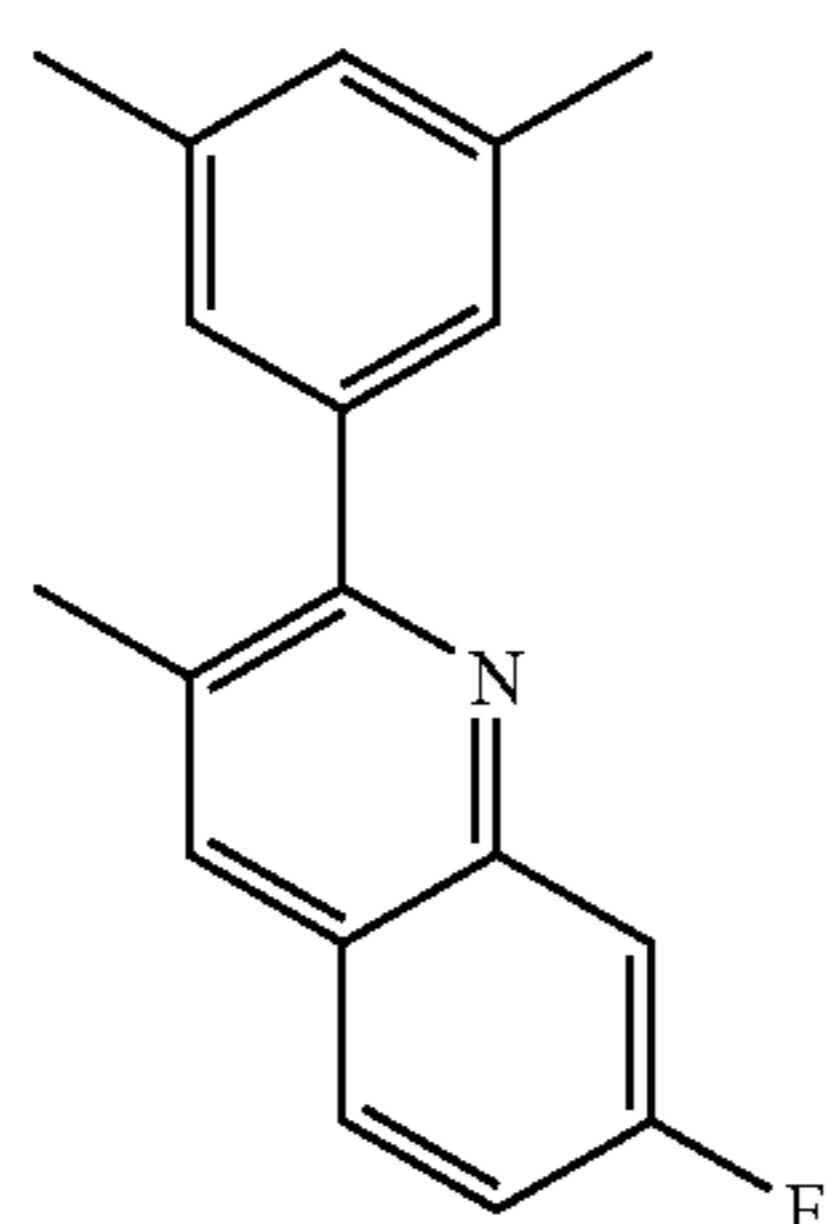
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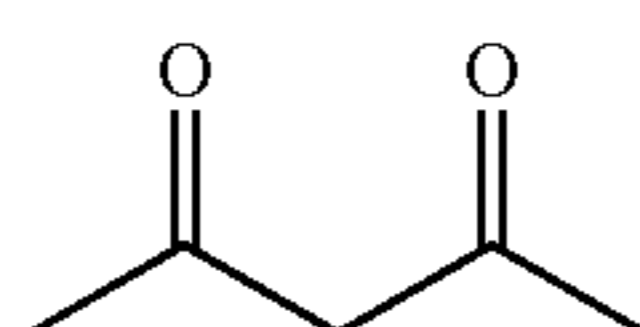
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In addition, in the above formula 2, a right side structure of central iridium (Ir) is selected from the following Formulas 4-1 to 4-8. The structures of the Formulas 4-1 to 4-8 are 2,4-pentanedione, 2,2,6,6-tetramethylheptane-3,5-dione, 1,3-propanedione, 1,3-butanedione, 3,5-heptanedione, 1,1,1-trifluoro-2,4-pentanedione, 1,1,1,5,5,5-hexafluoro-2,4-pentanedione and 2,2-dimethyl-3,5-hexanedione, respectively.

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[Formula 4-1]

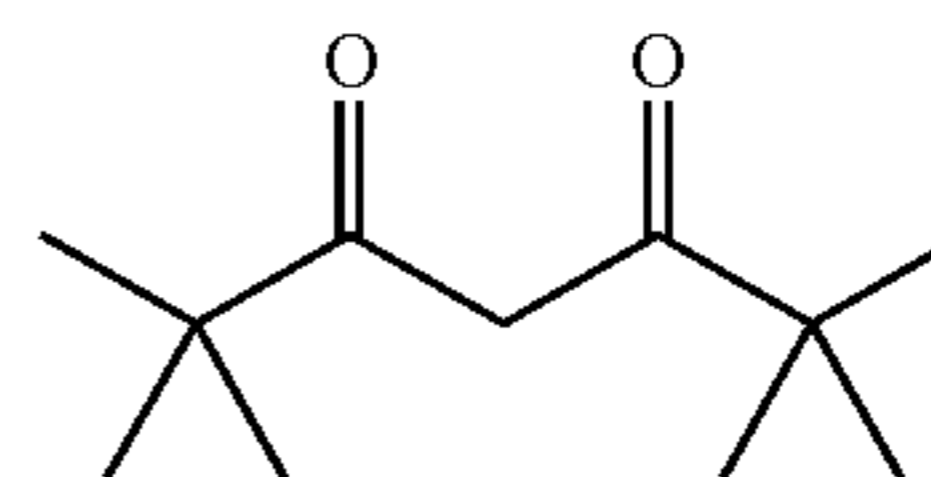


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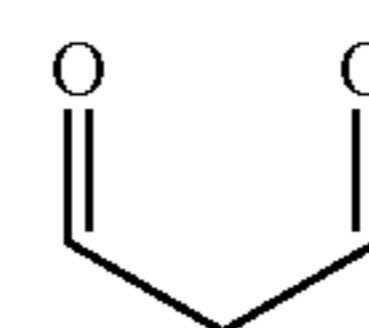
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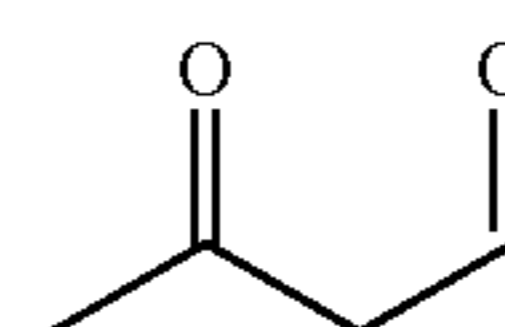
[Formula 4-2]



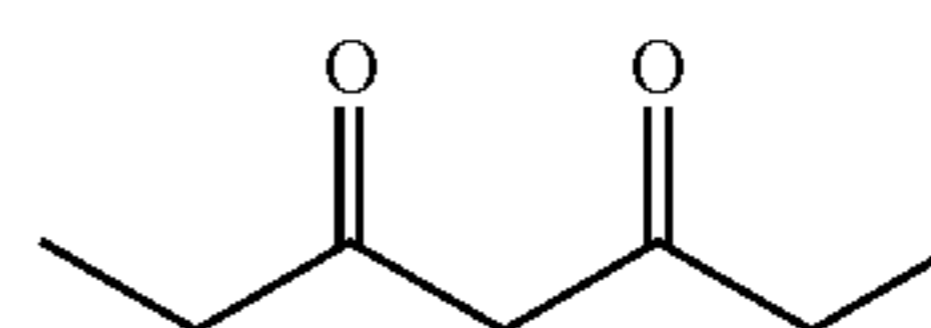
[Formula 4-3]



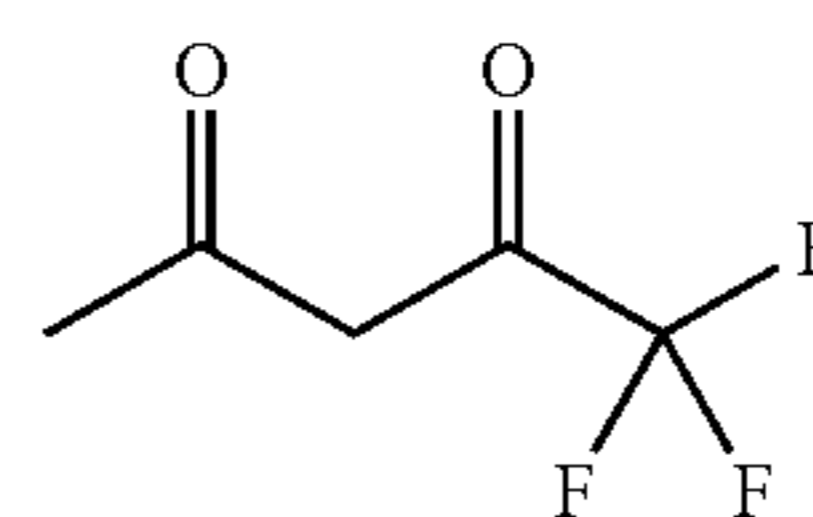
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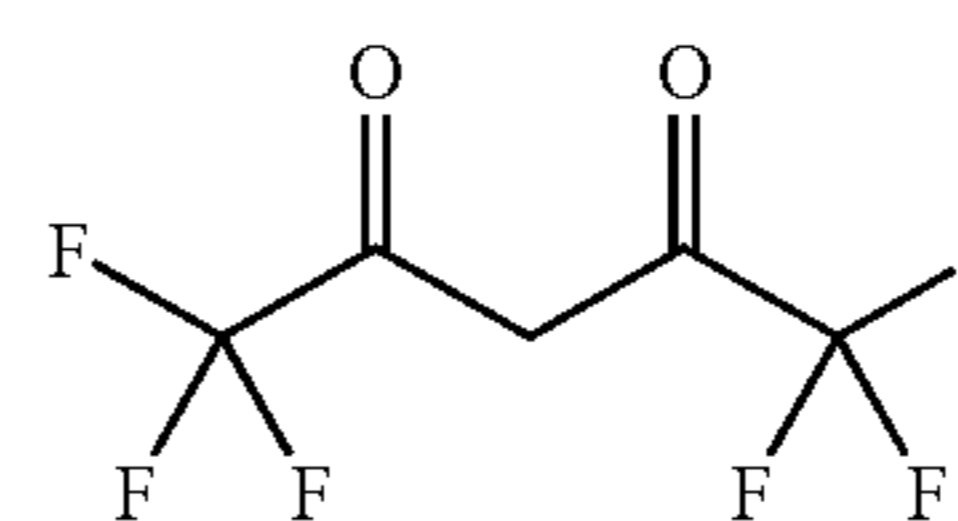
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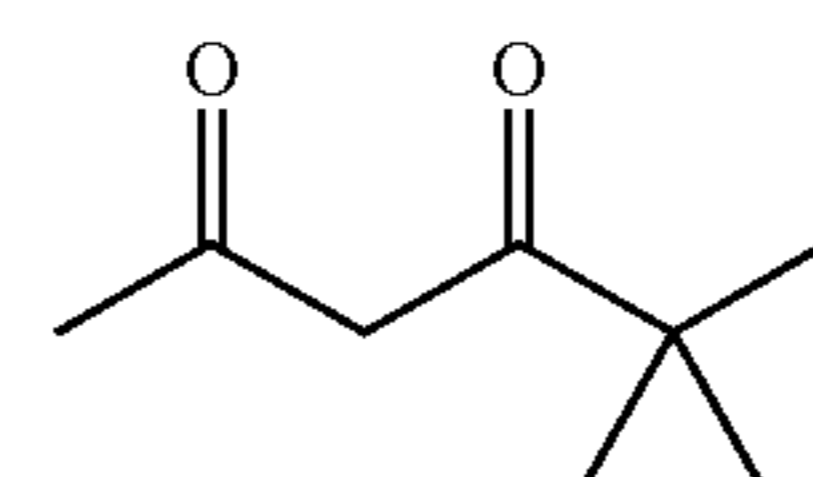
[Formula 4-6]



[Formula 4-7]



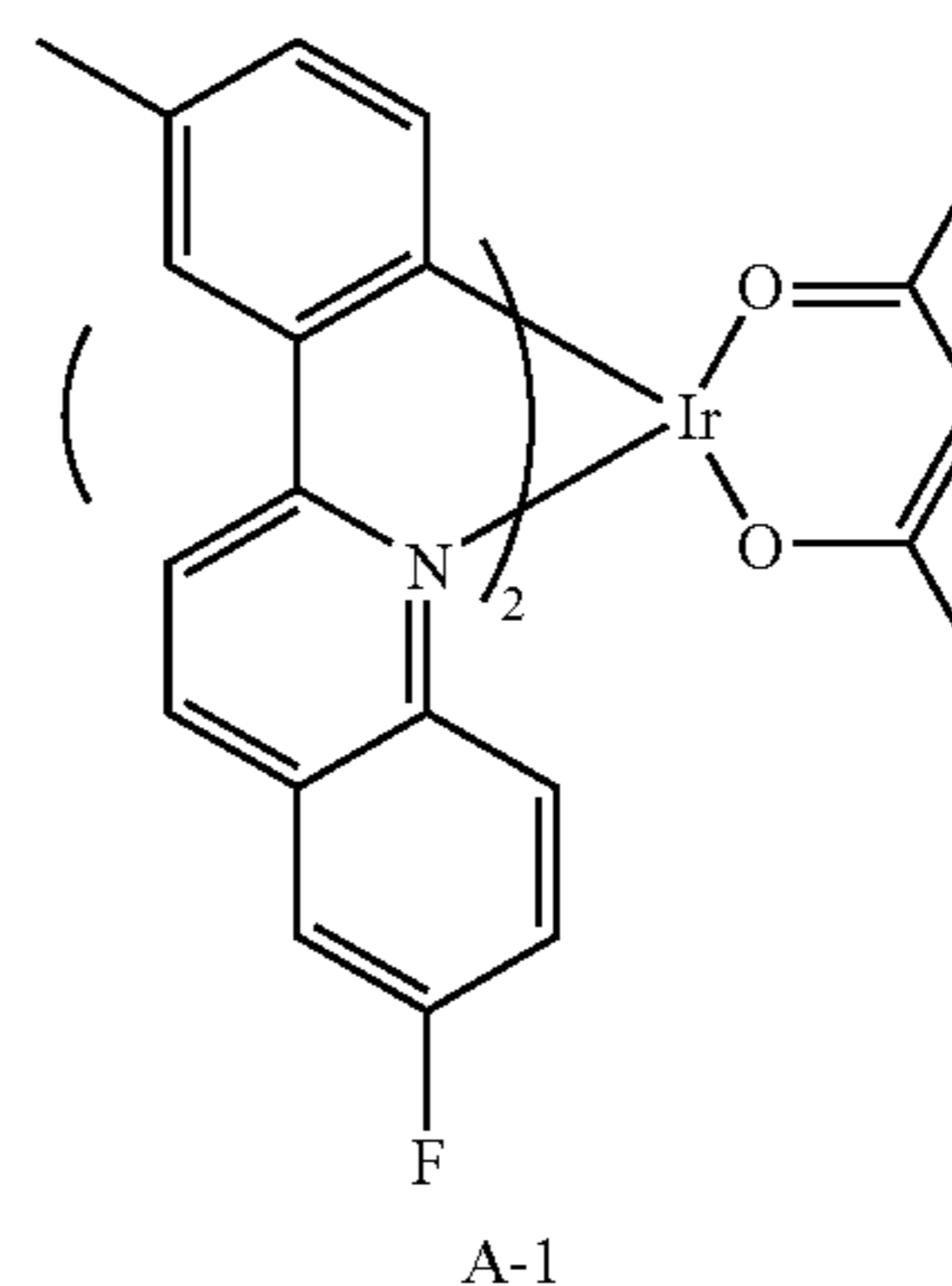
[Formula 4-8]



As a result, the red phosphorescent compound represented by Formula 2 is selected from the following Formula 5. For convenience of explanation, the references of A1 to A72 are marked on each compound.

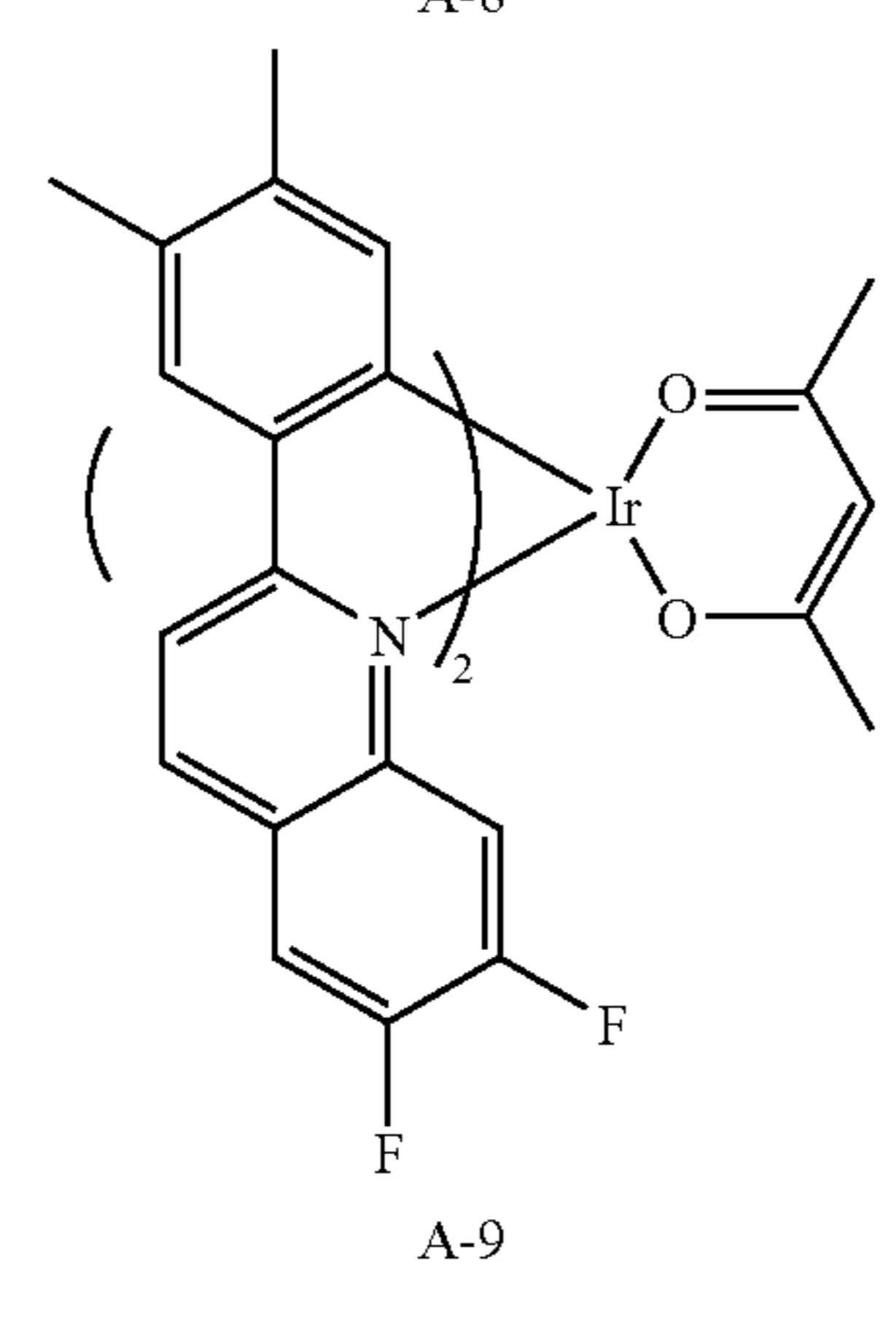
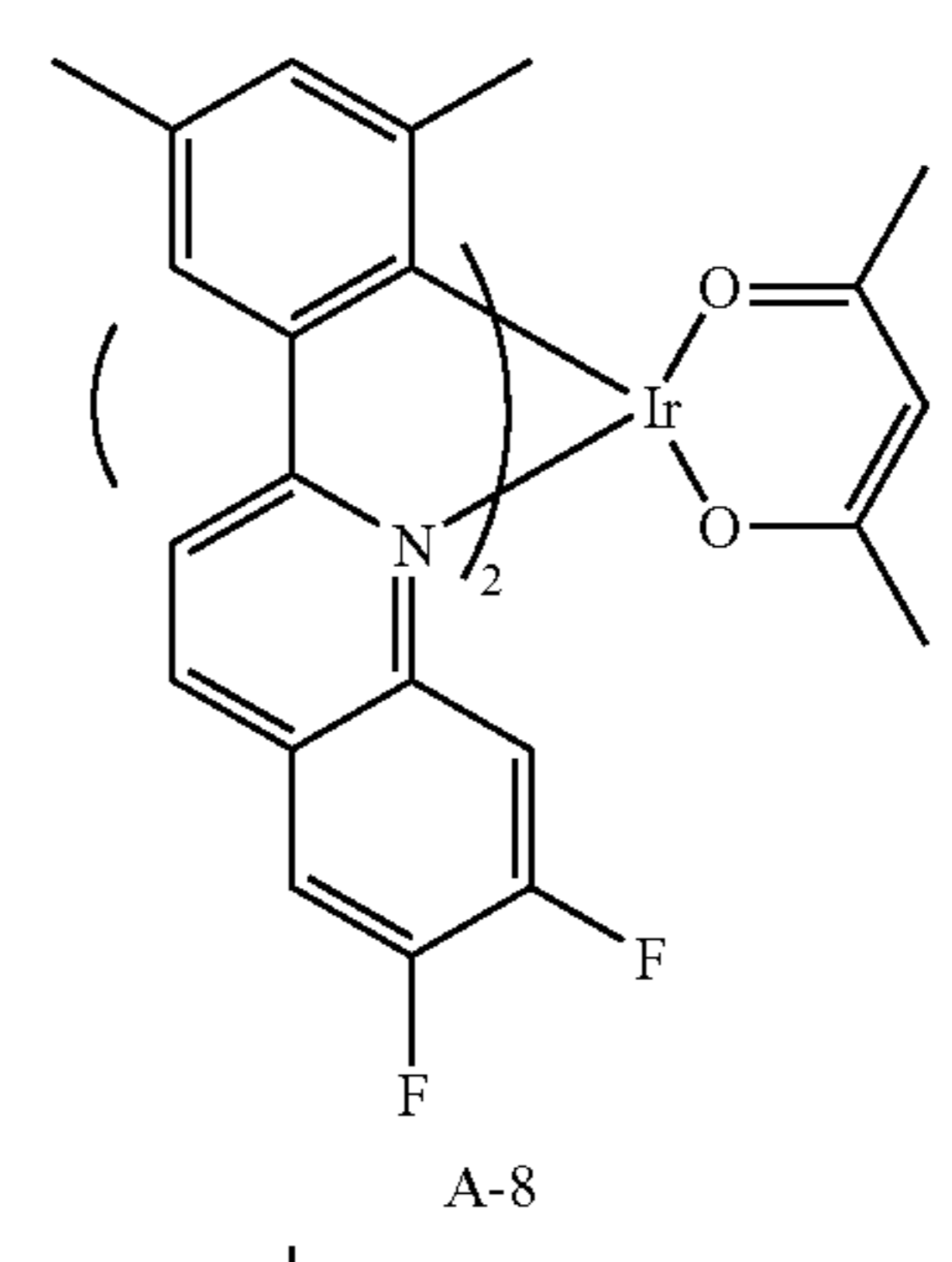
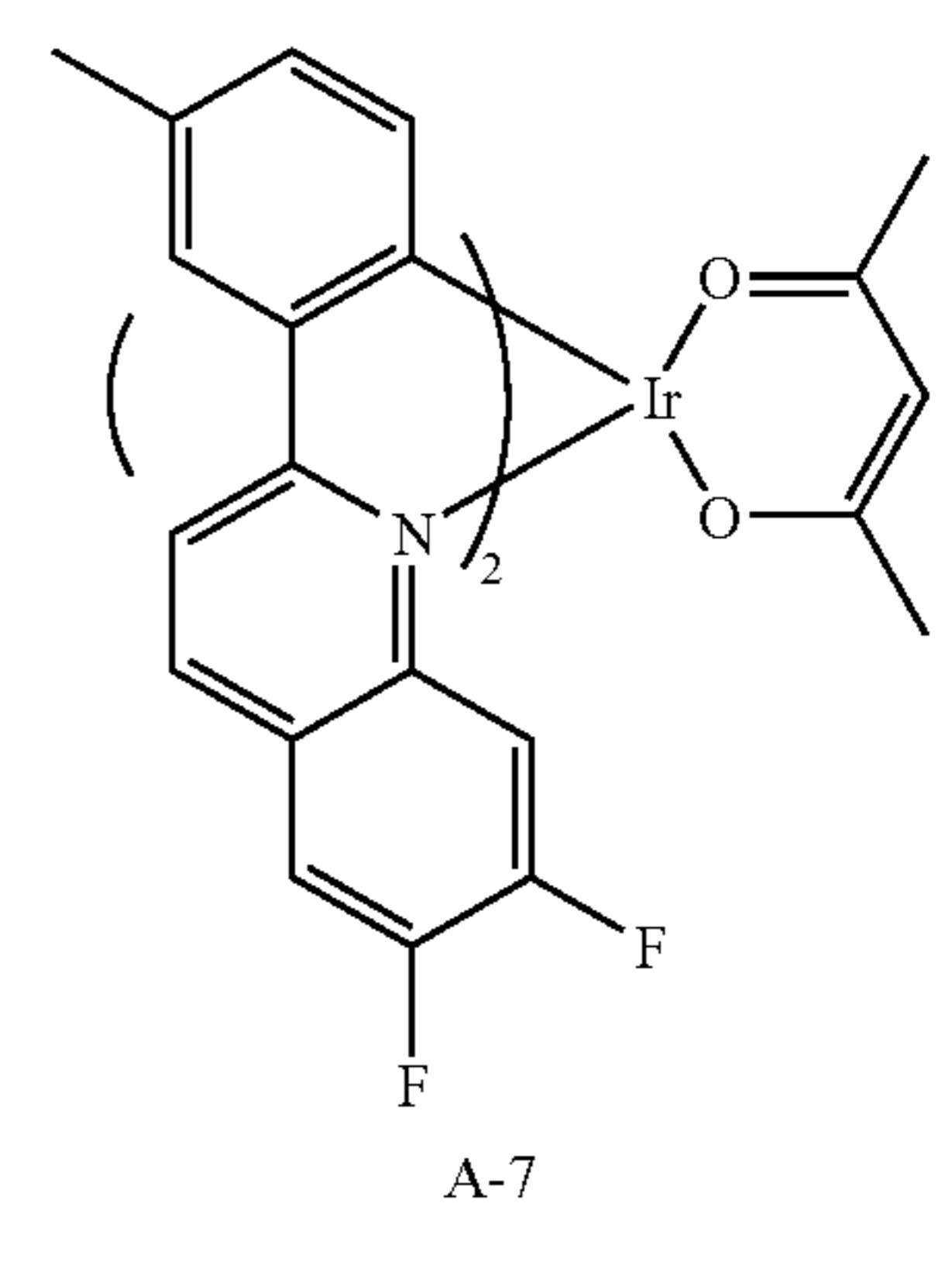
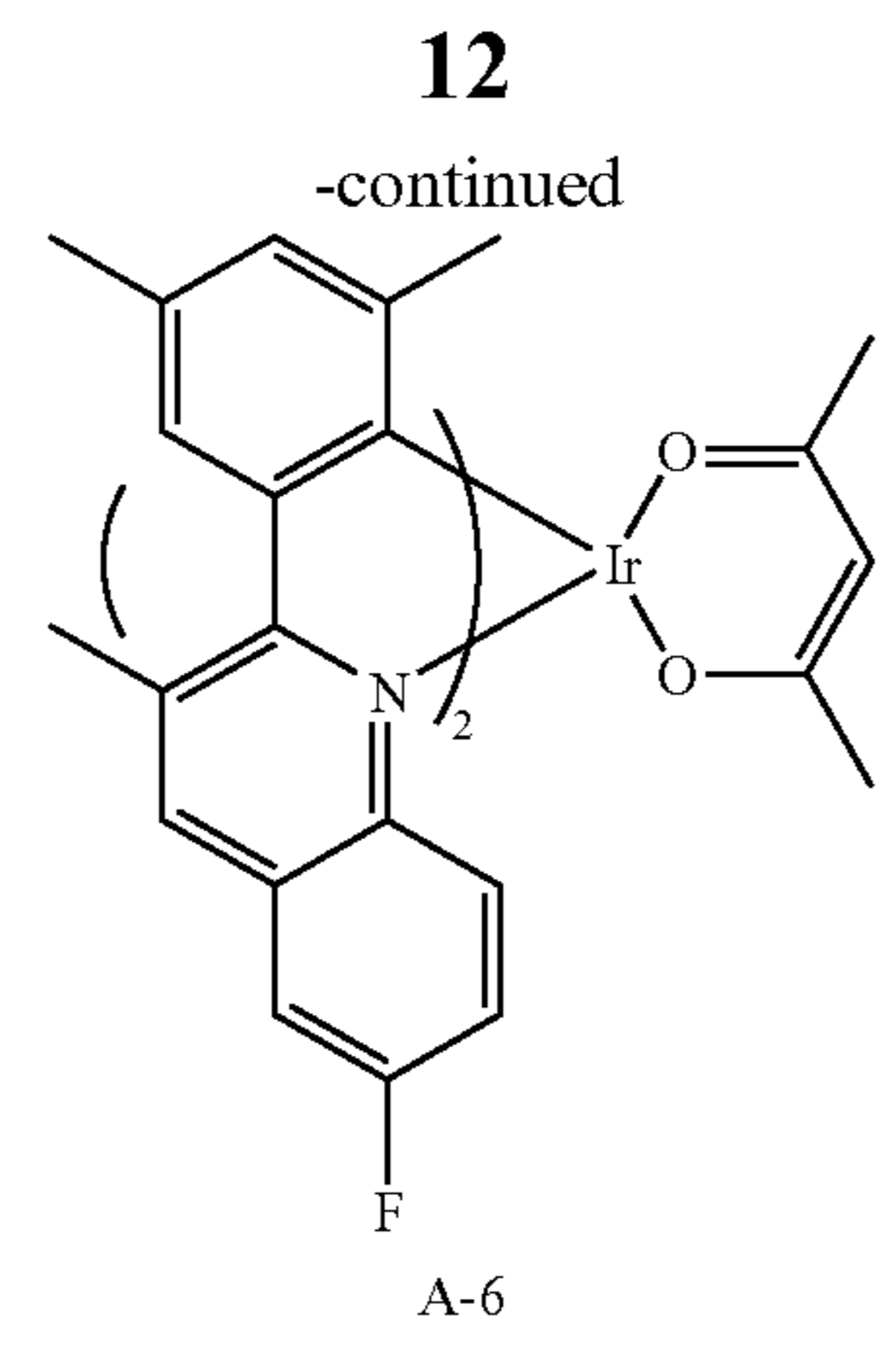
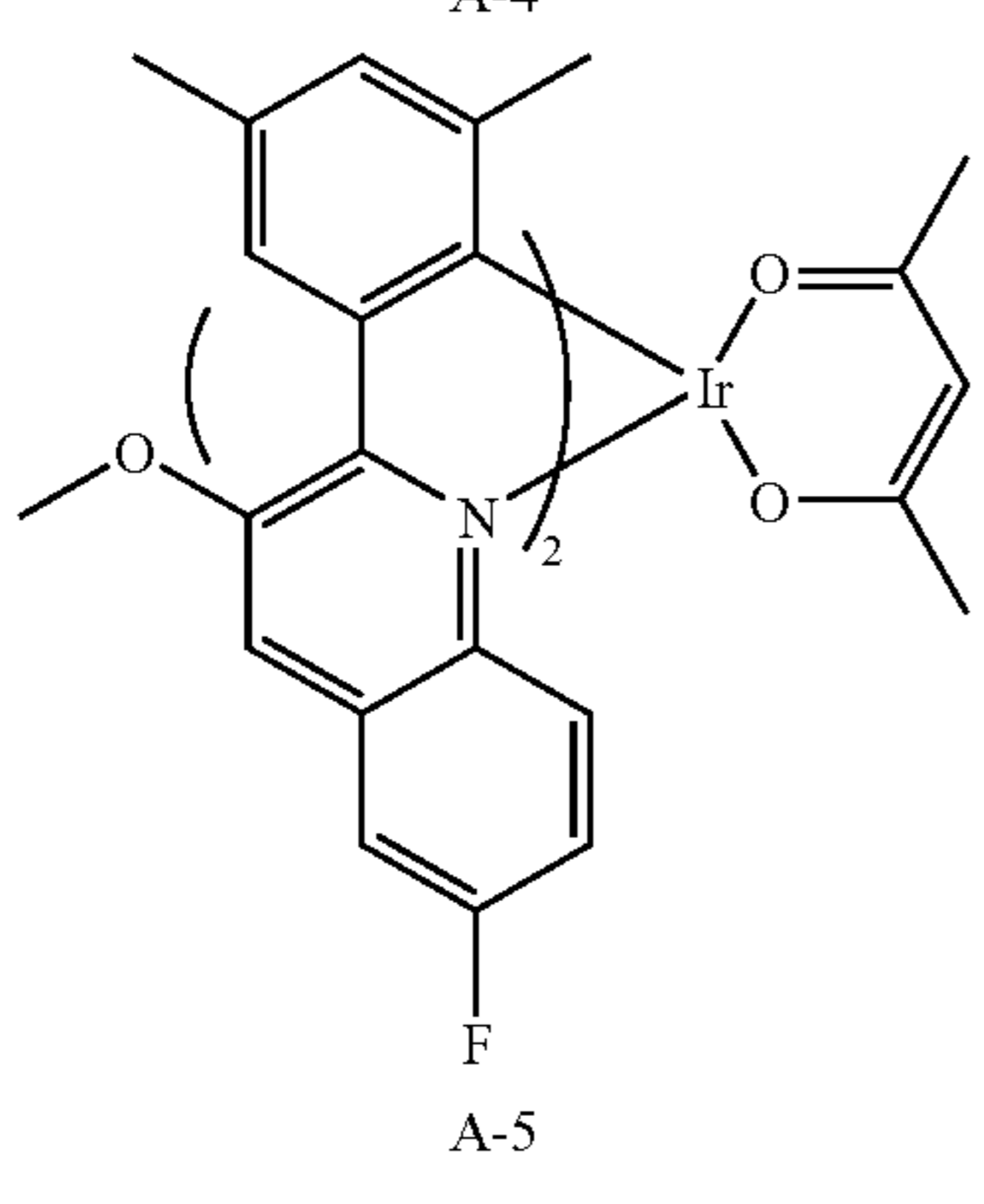
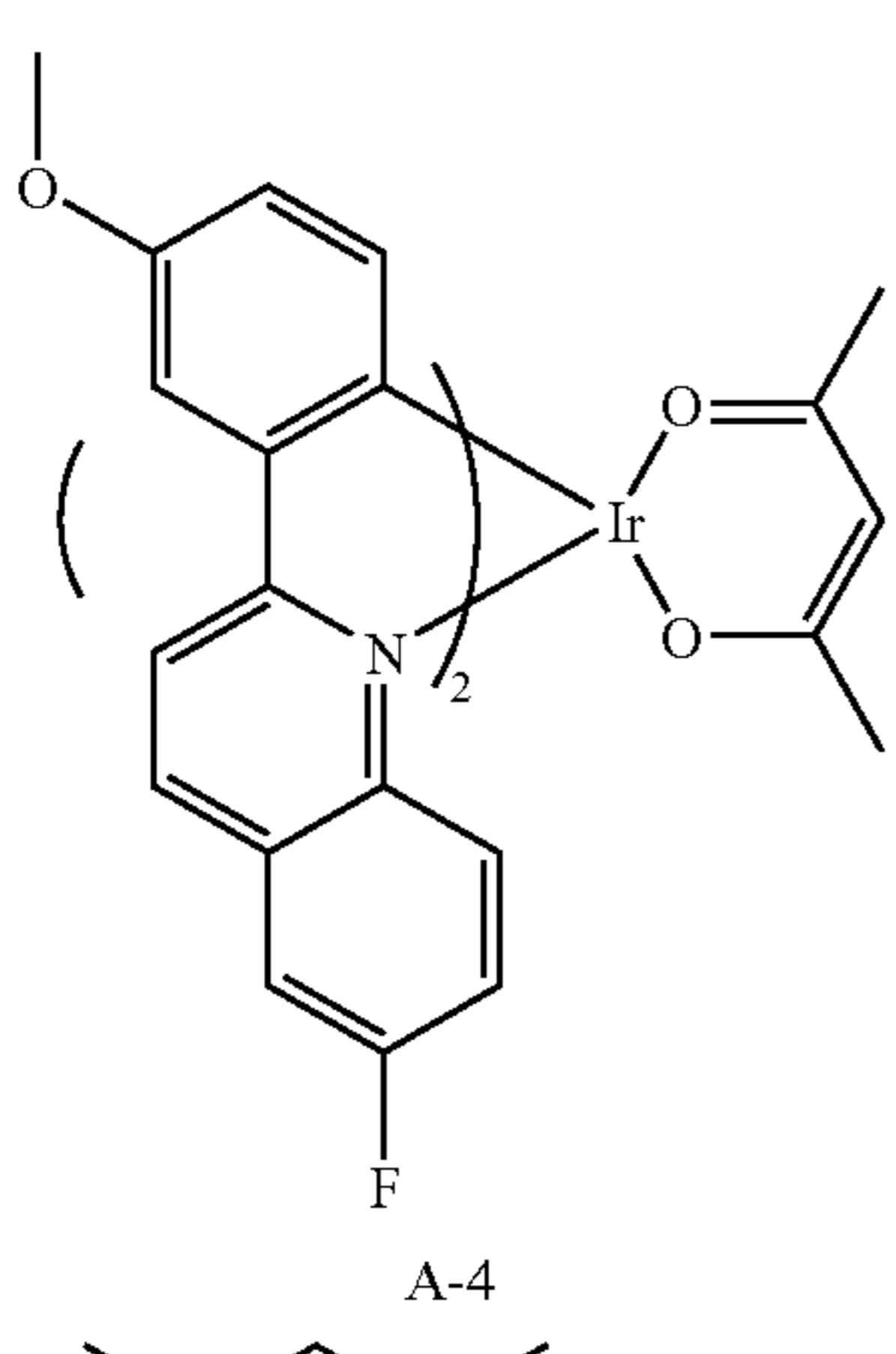
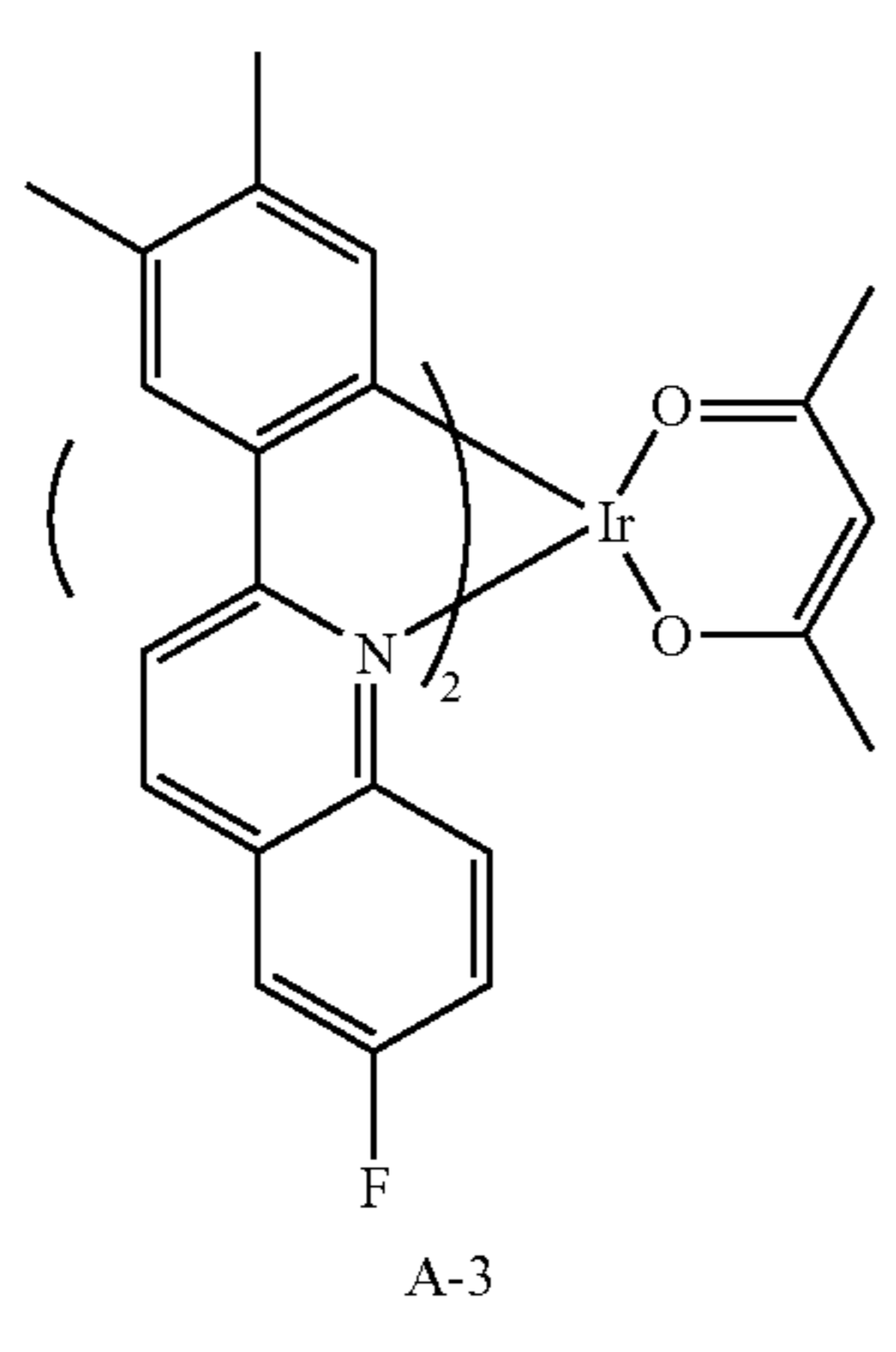
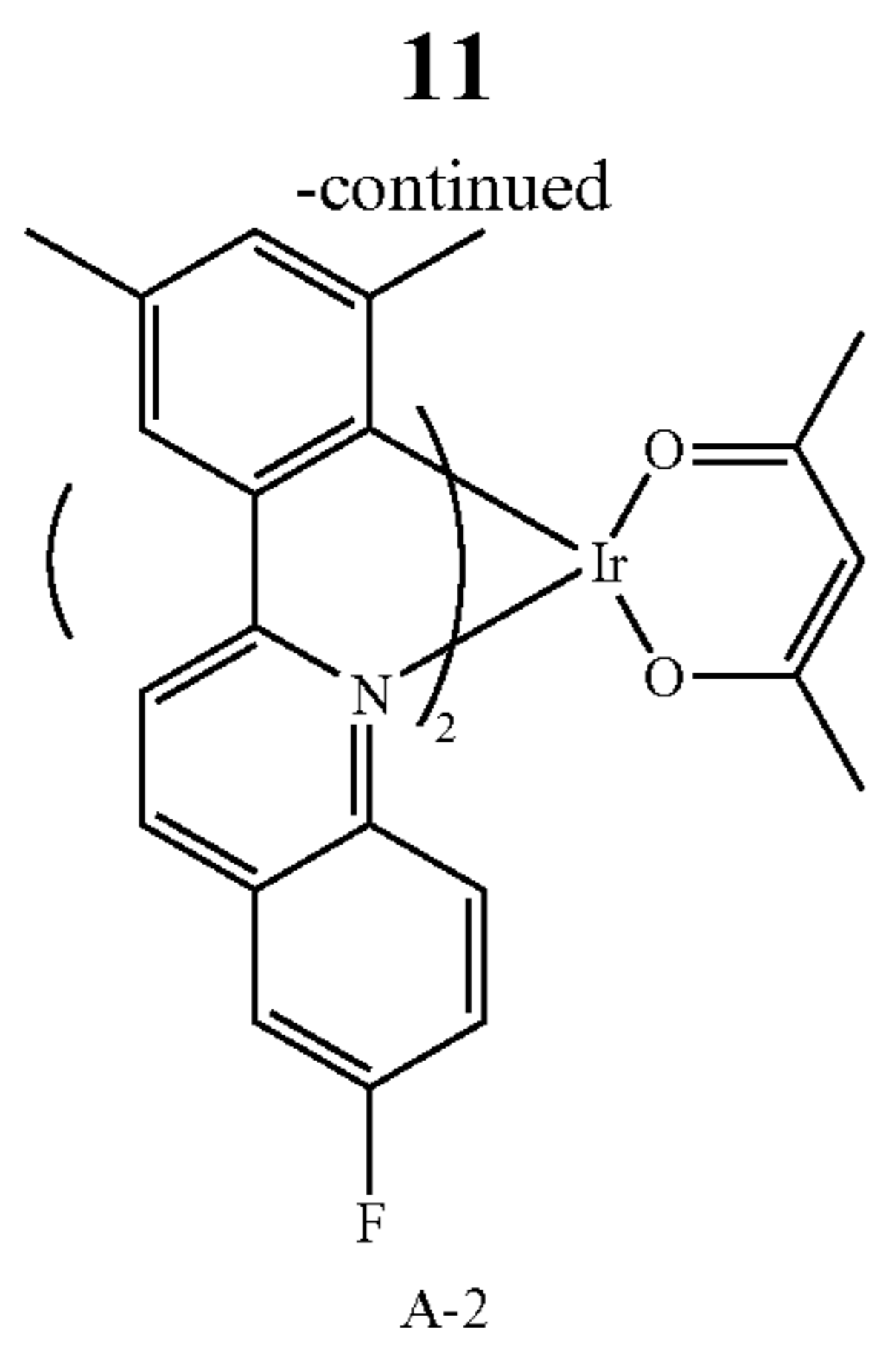
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[Formula 5]



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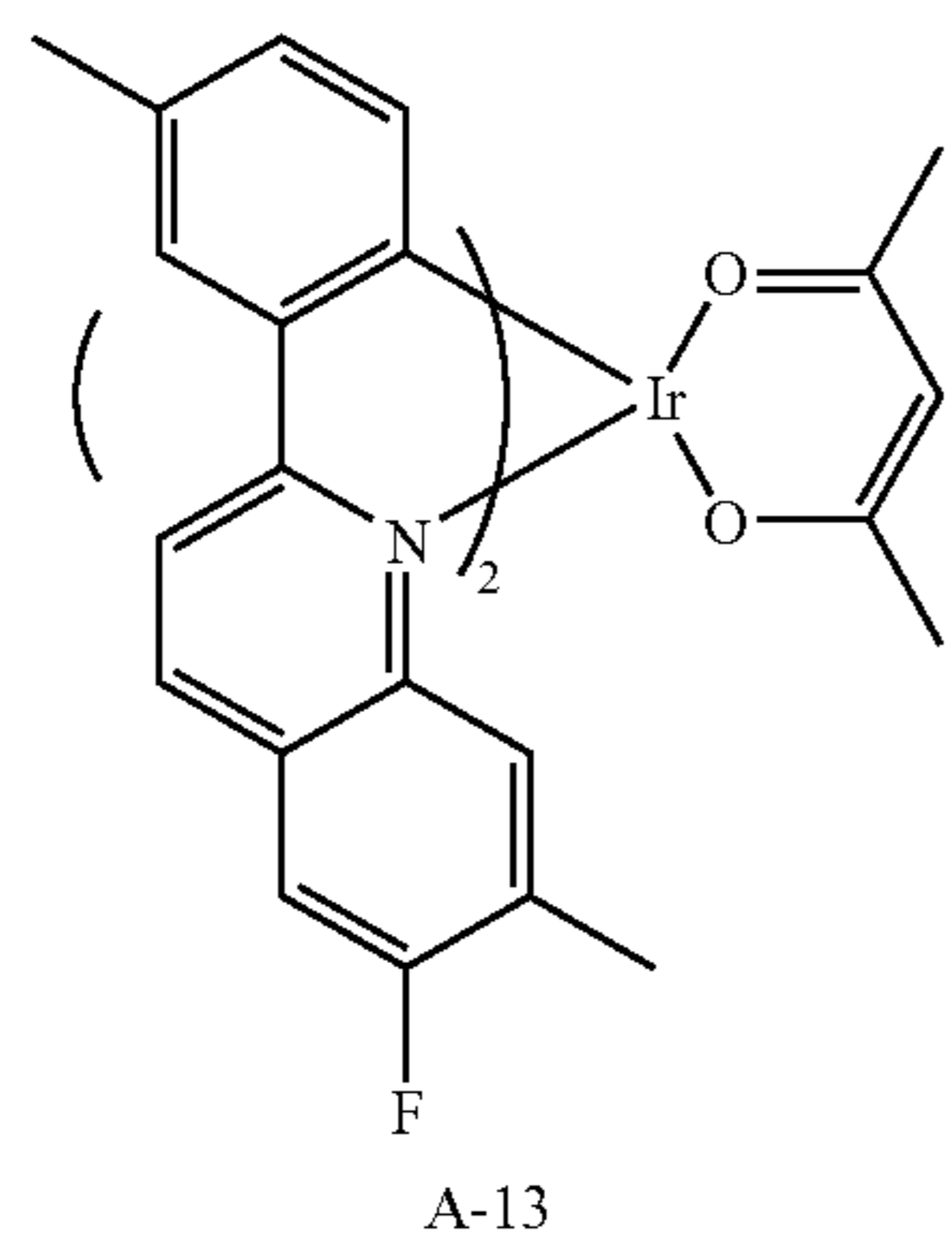
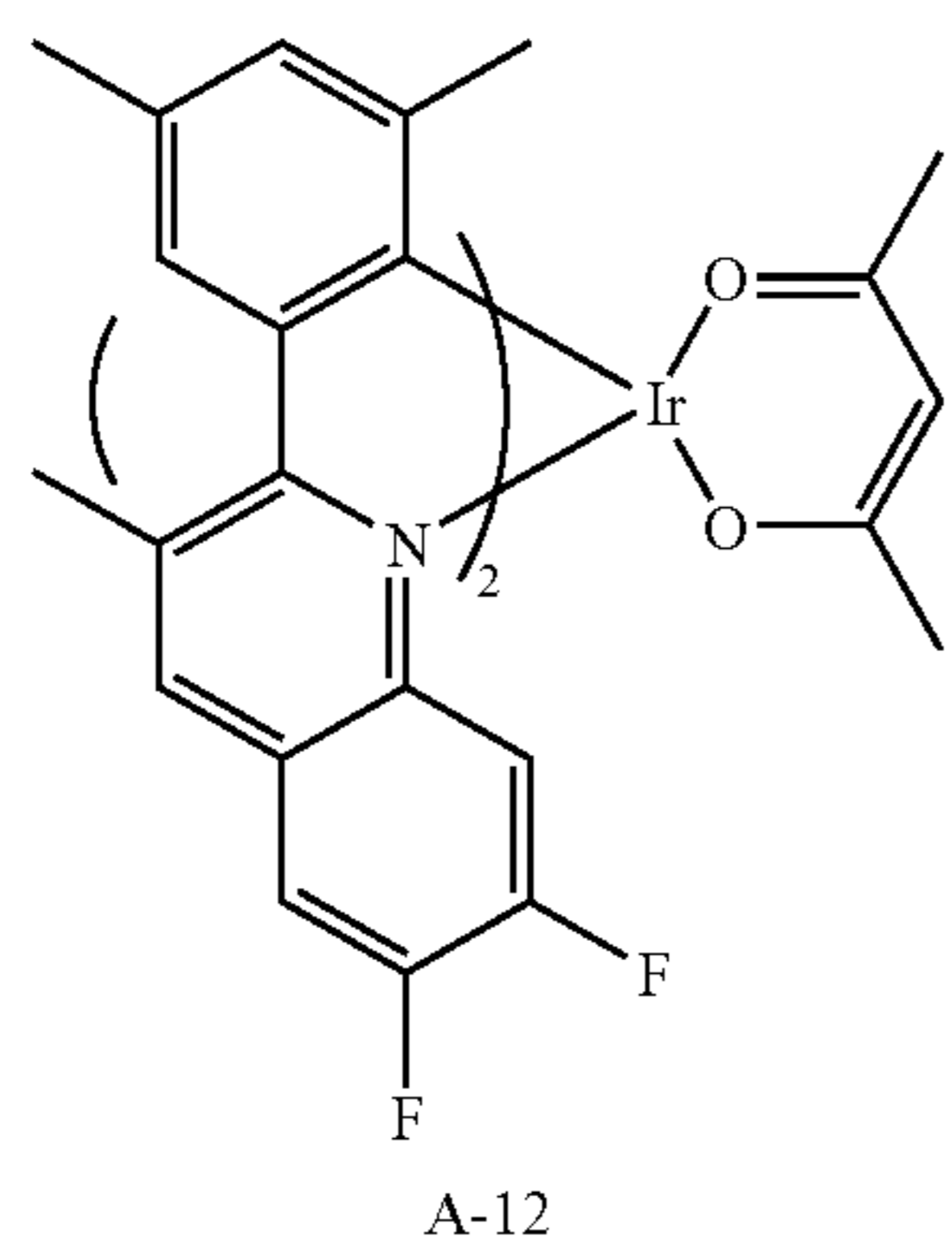
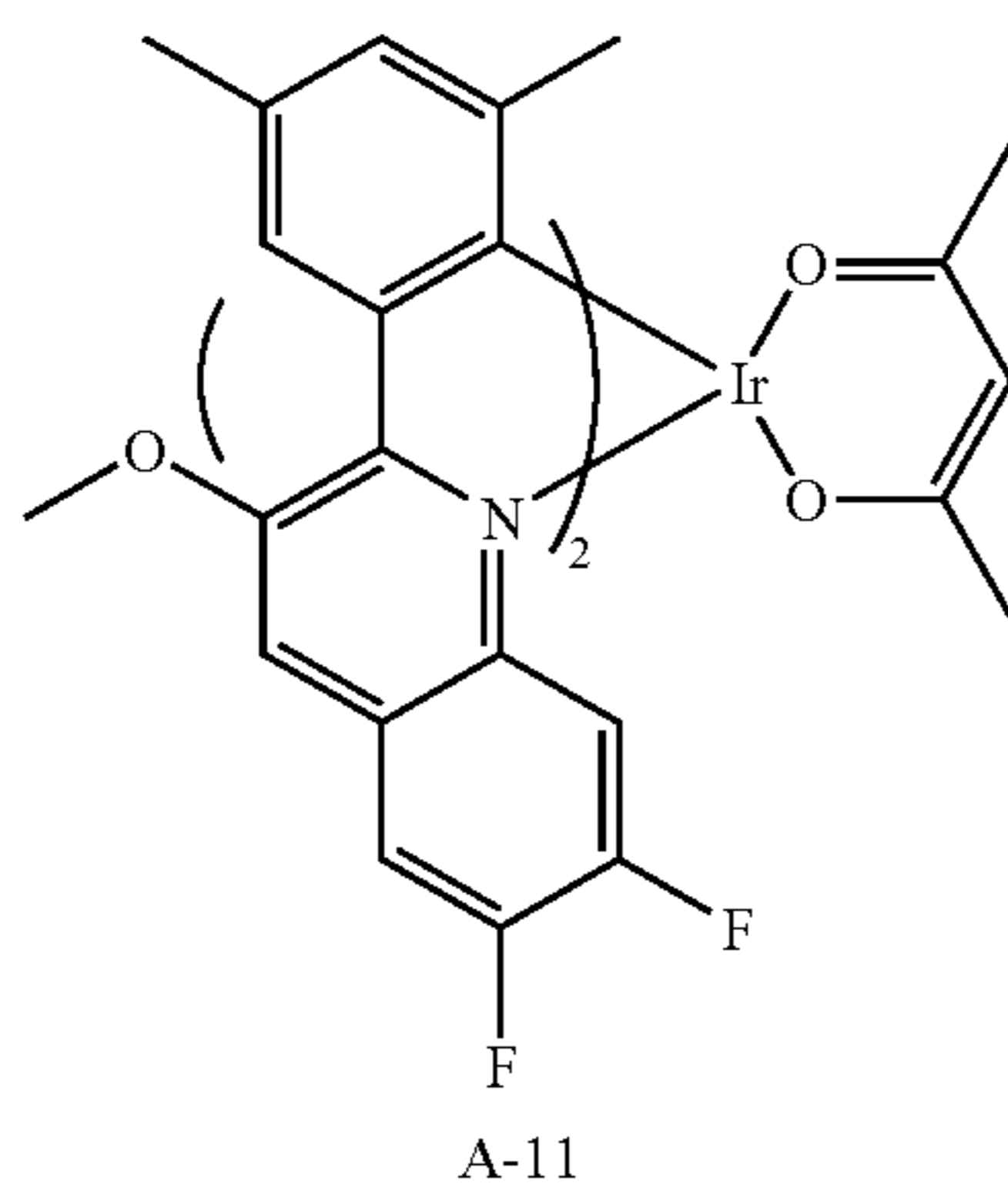
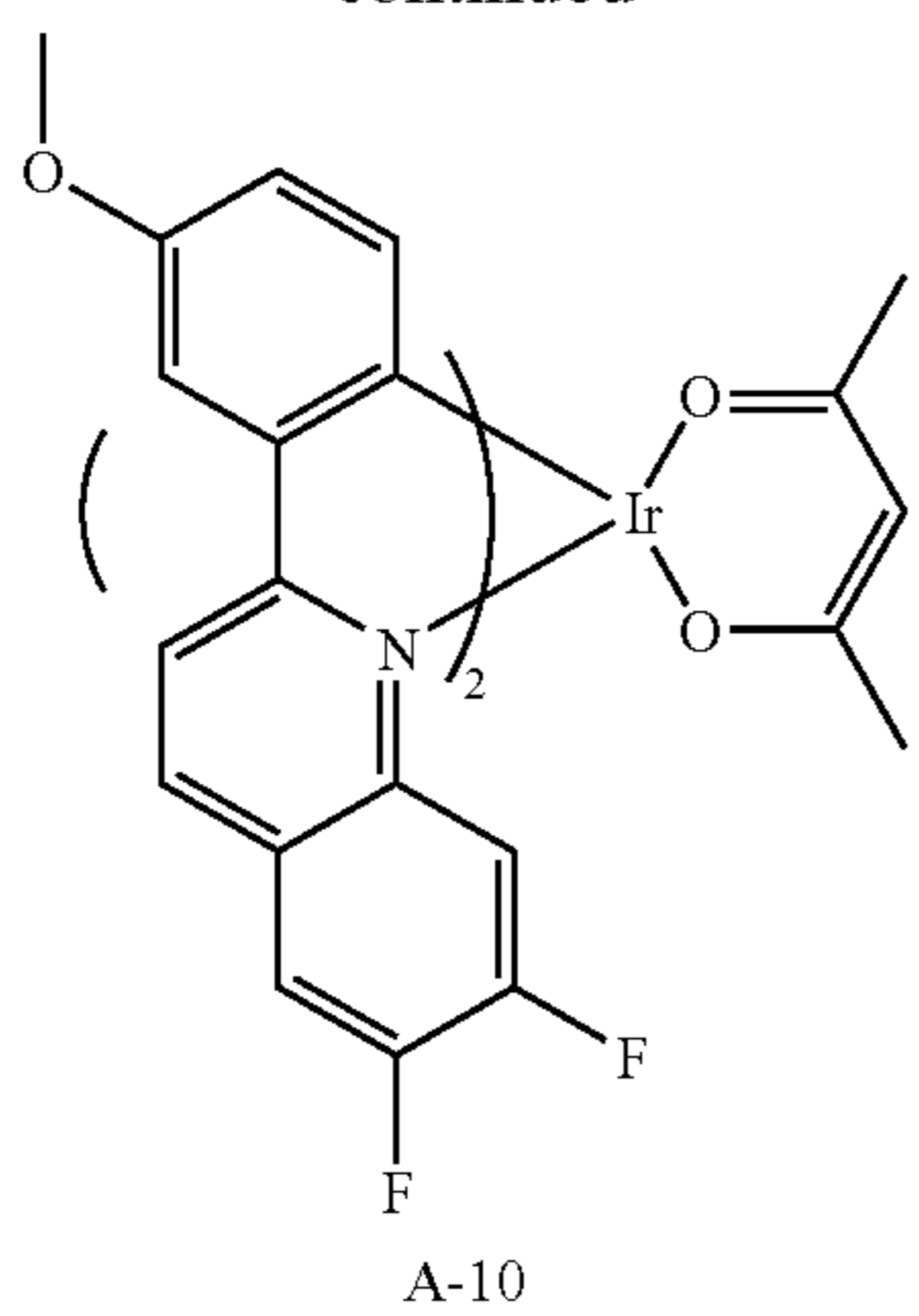
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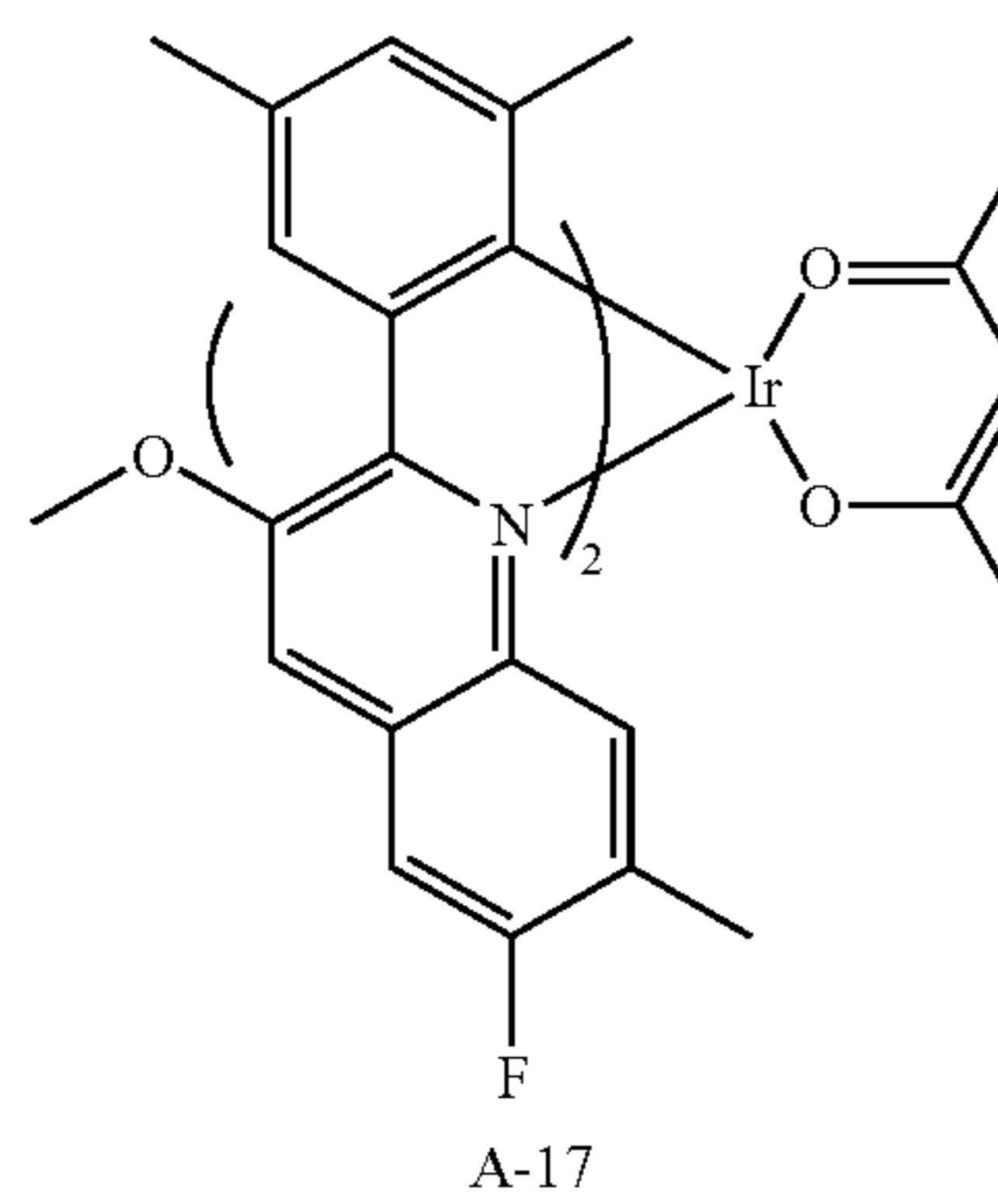
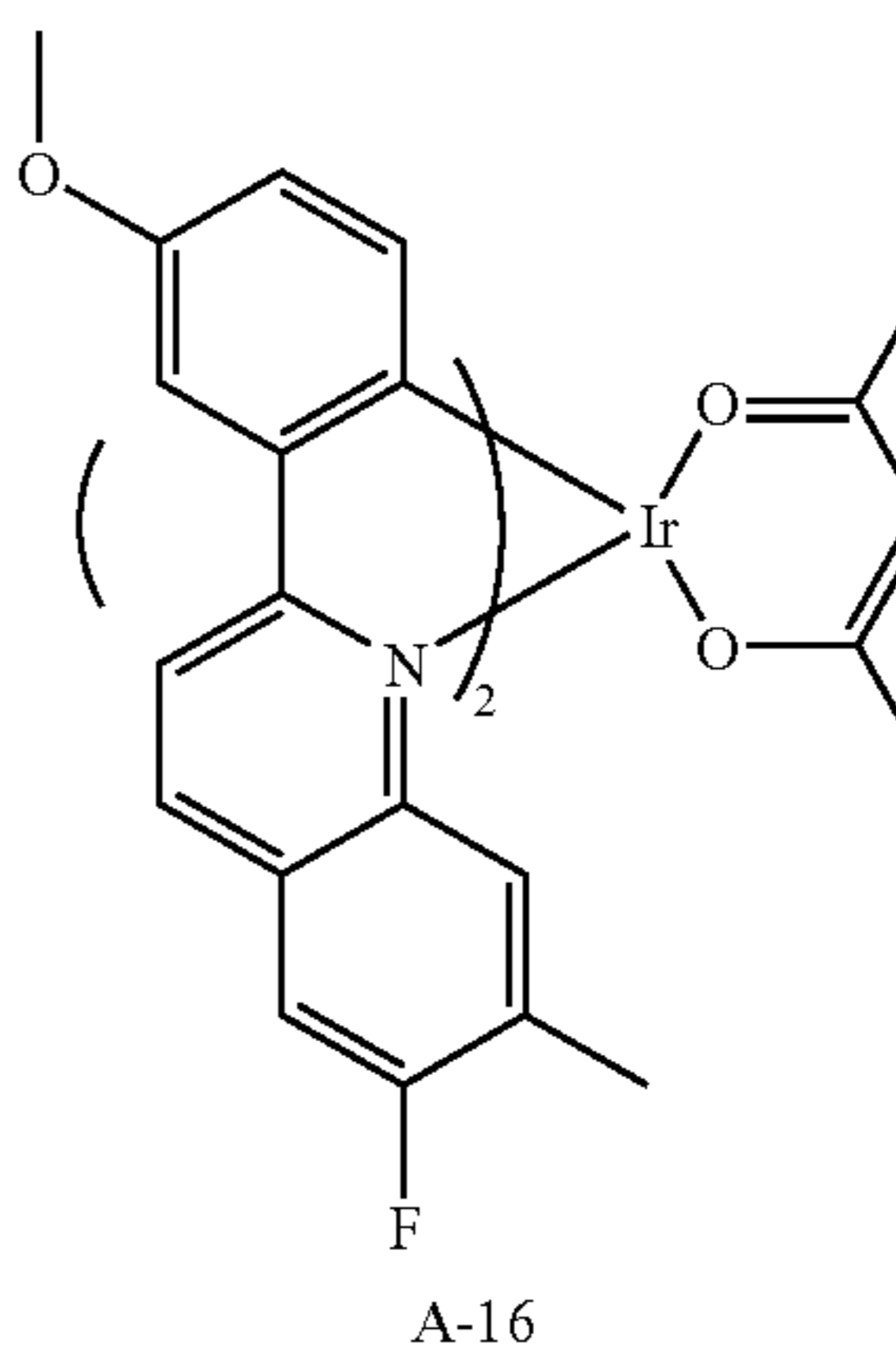
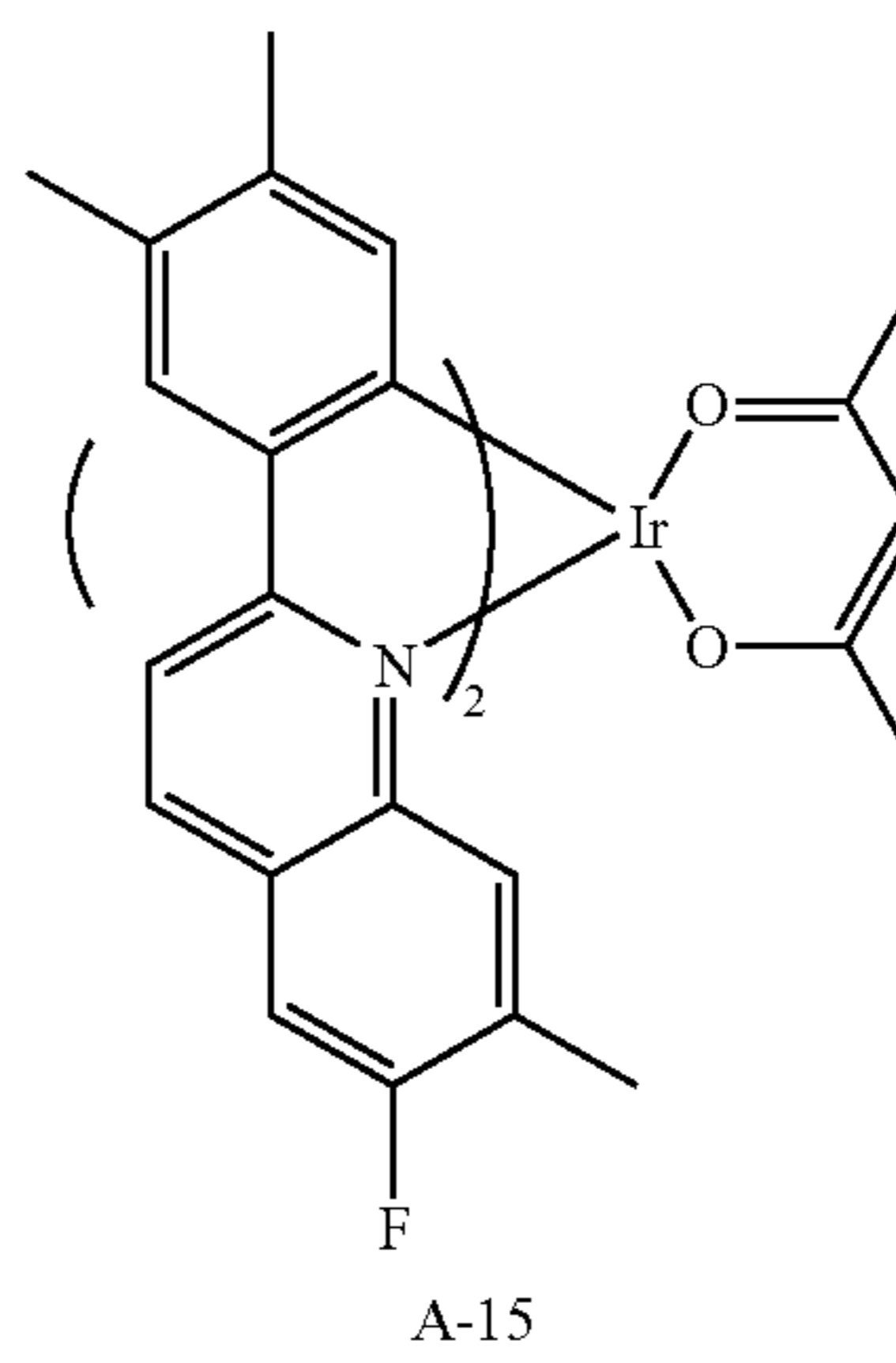
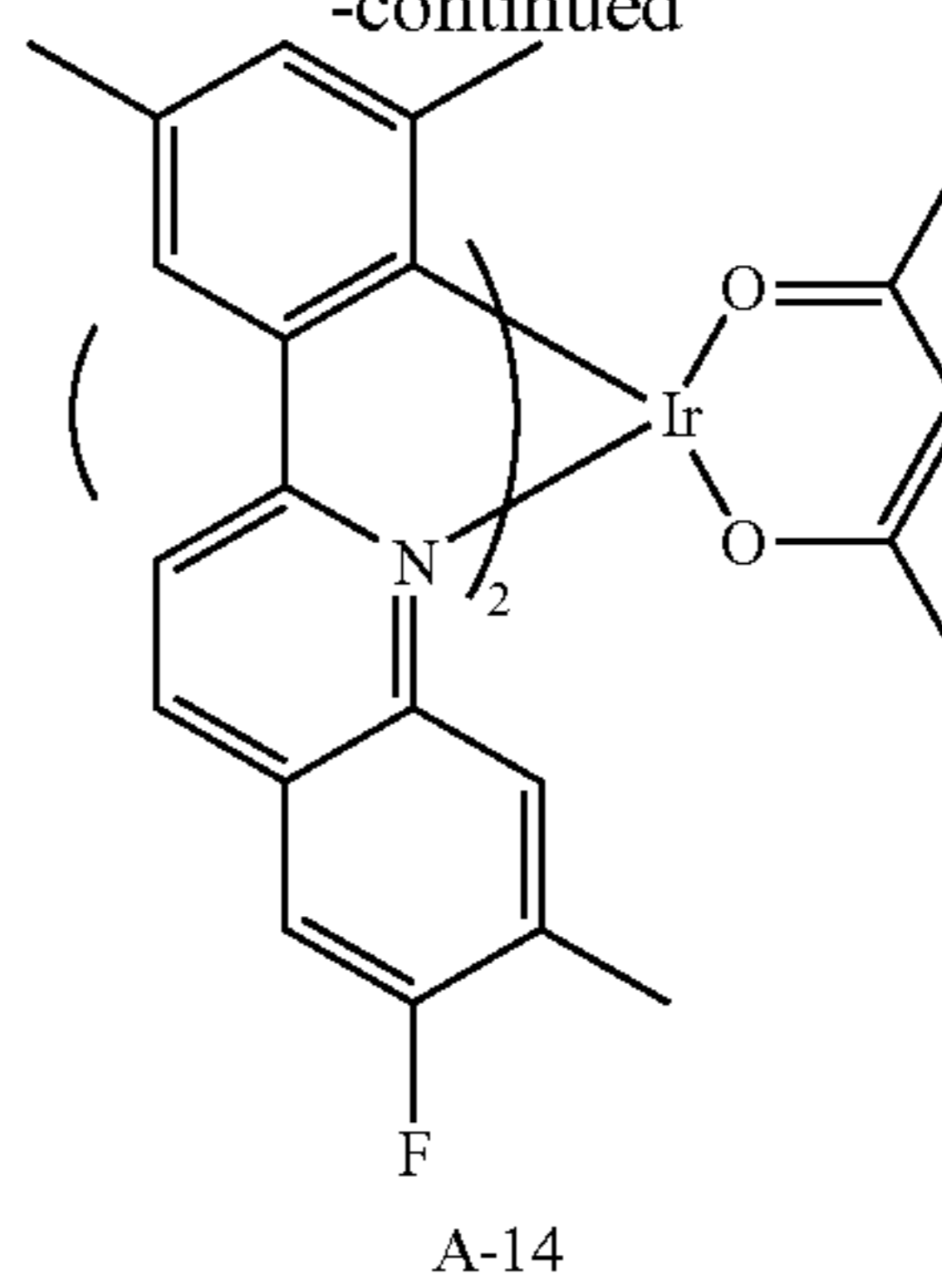
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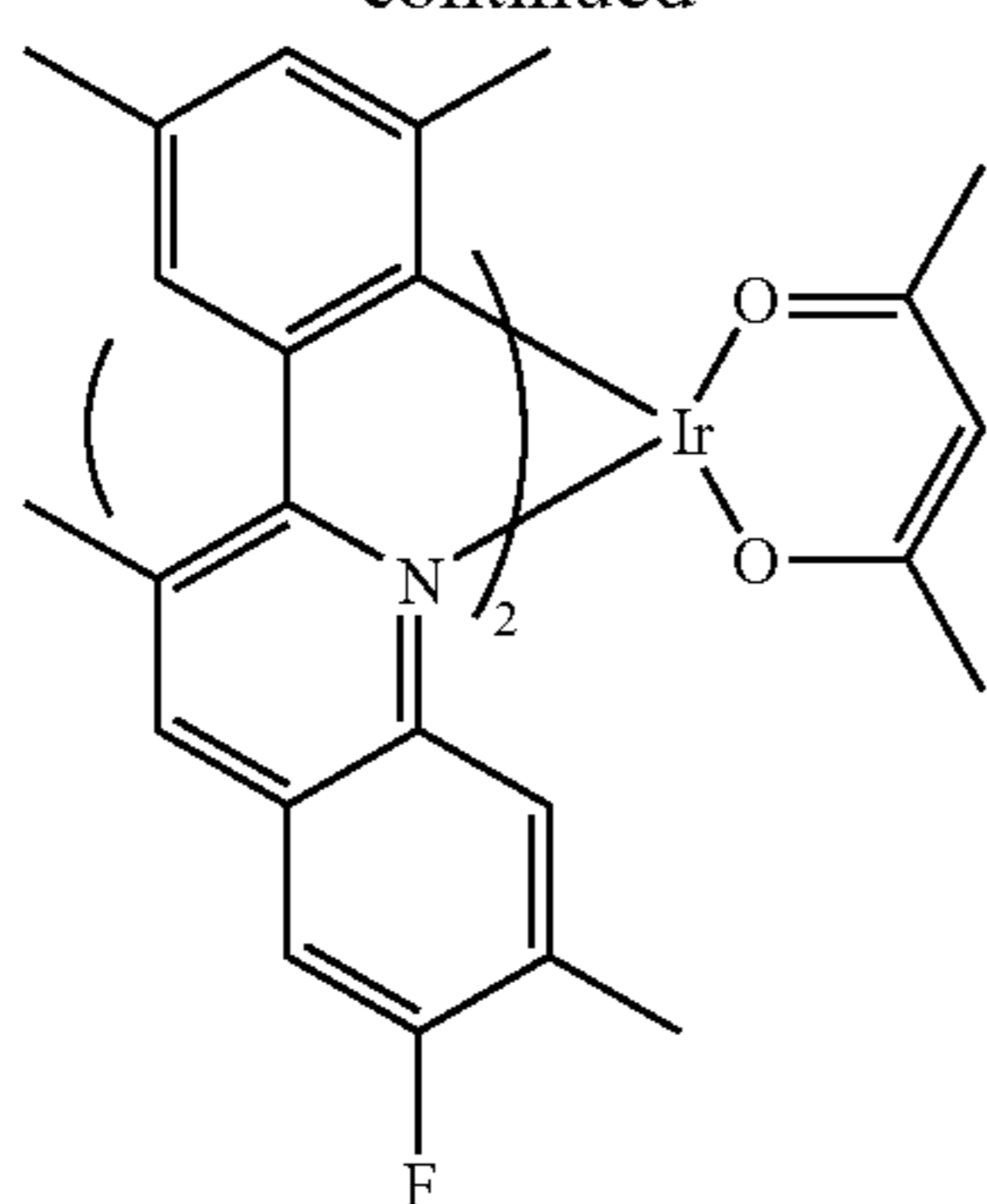
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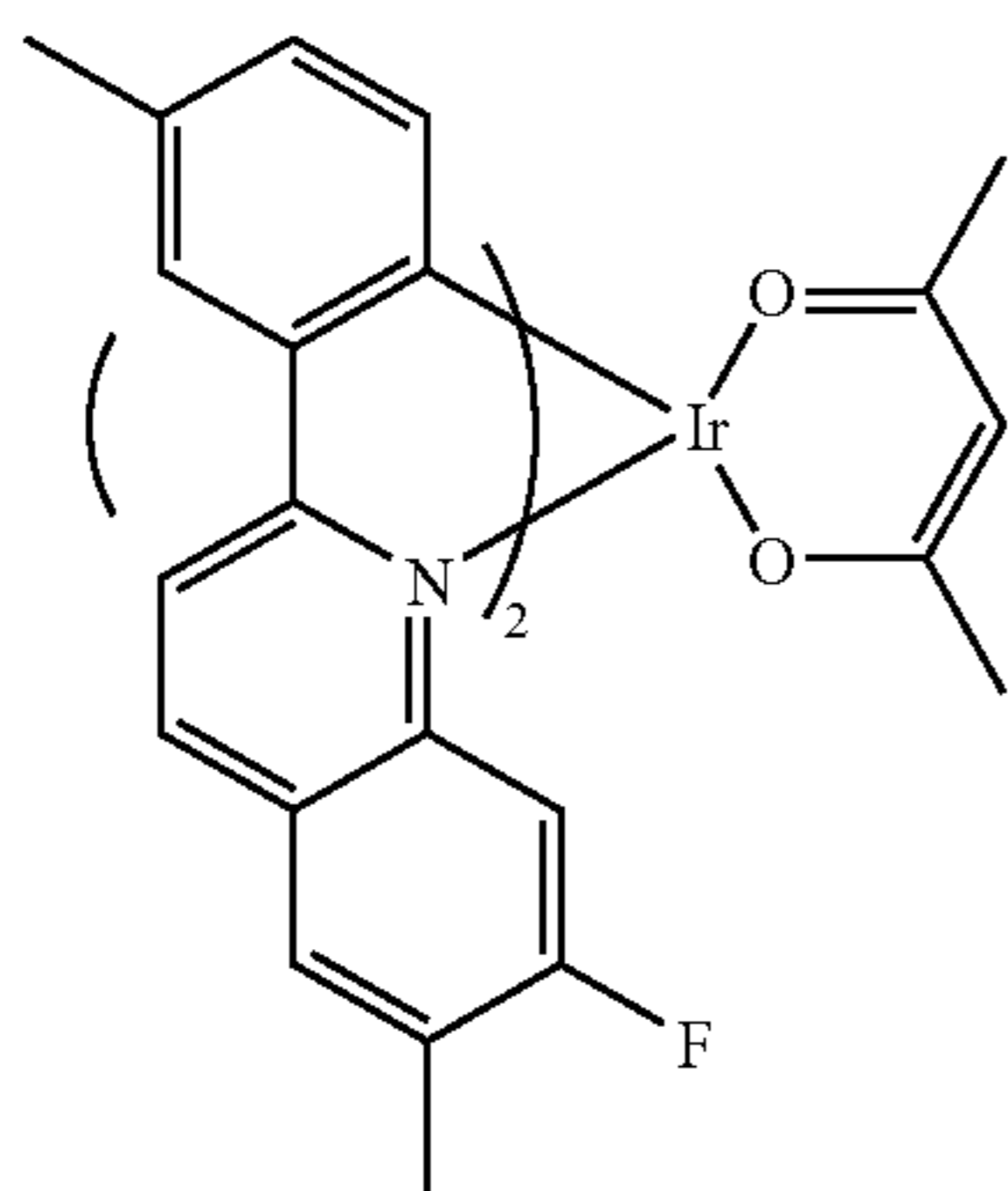


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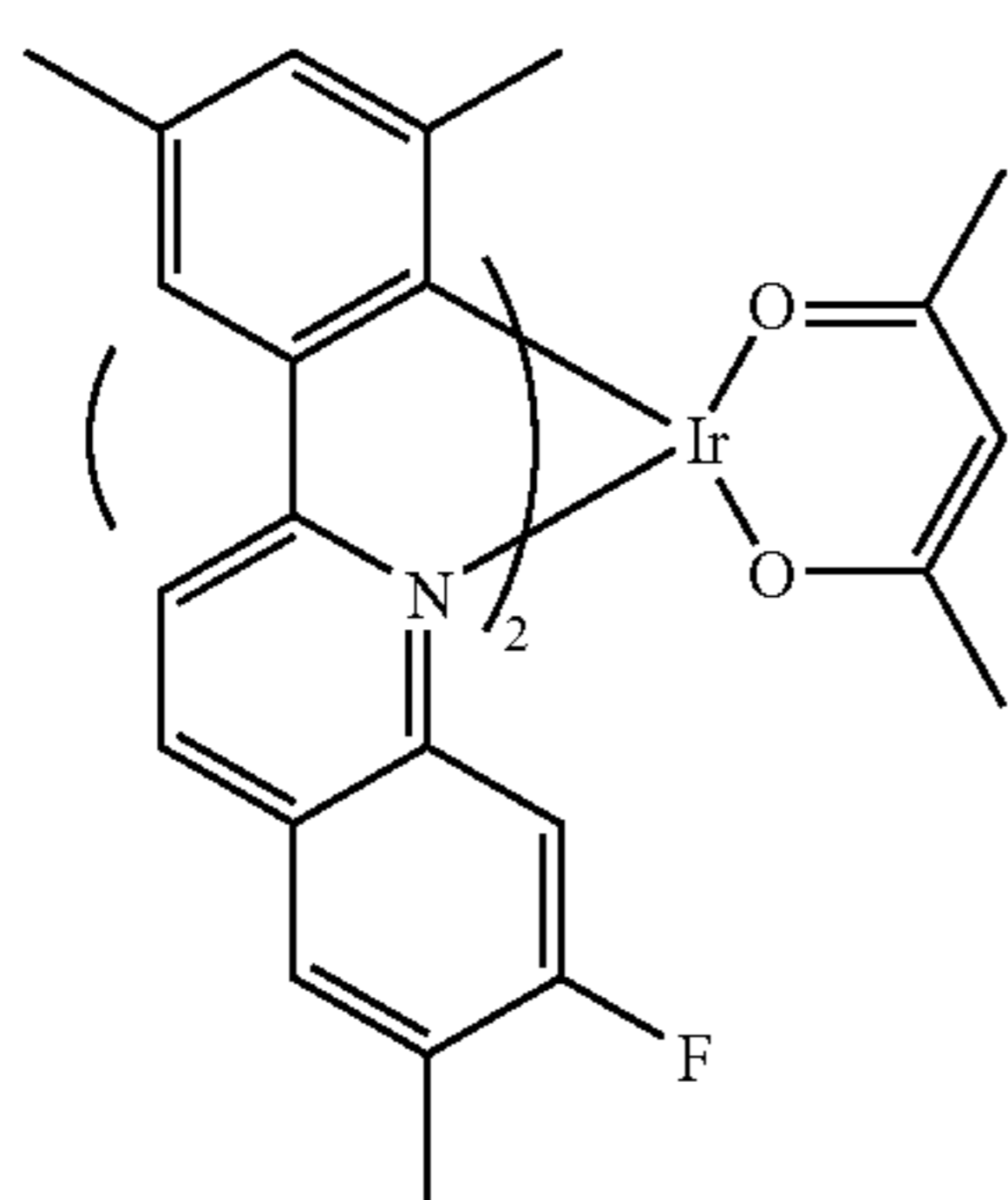
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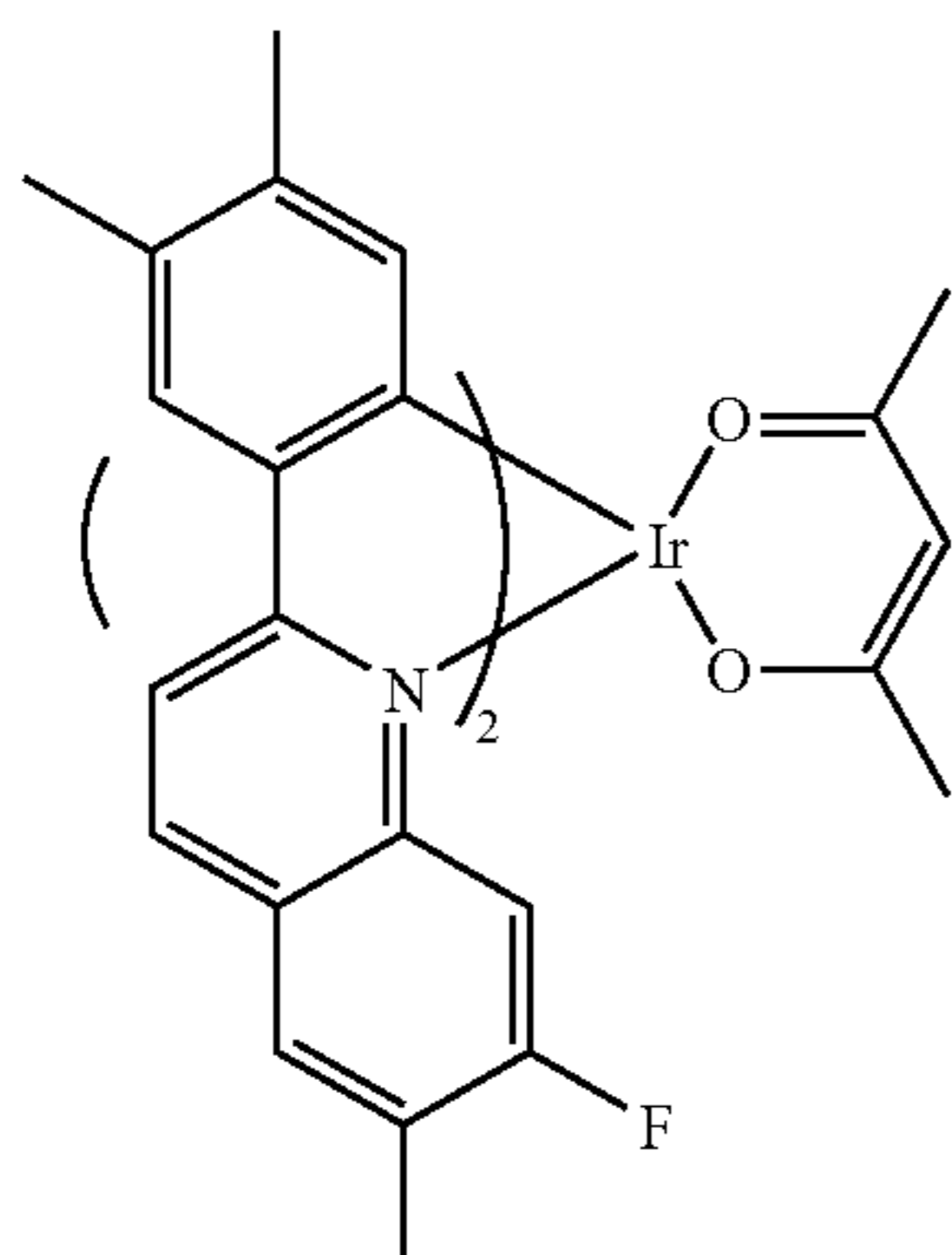
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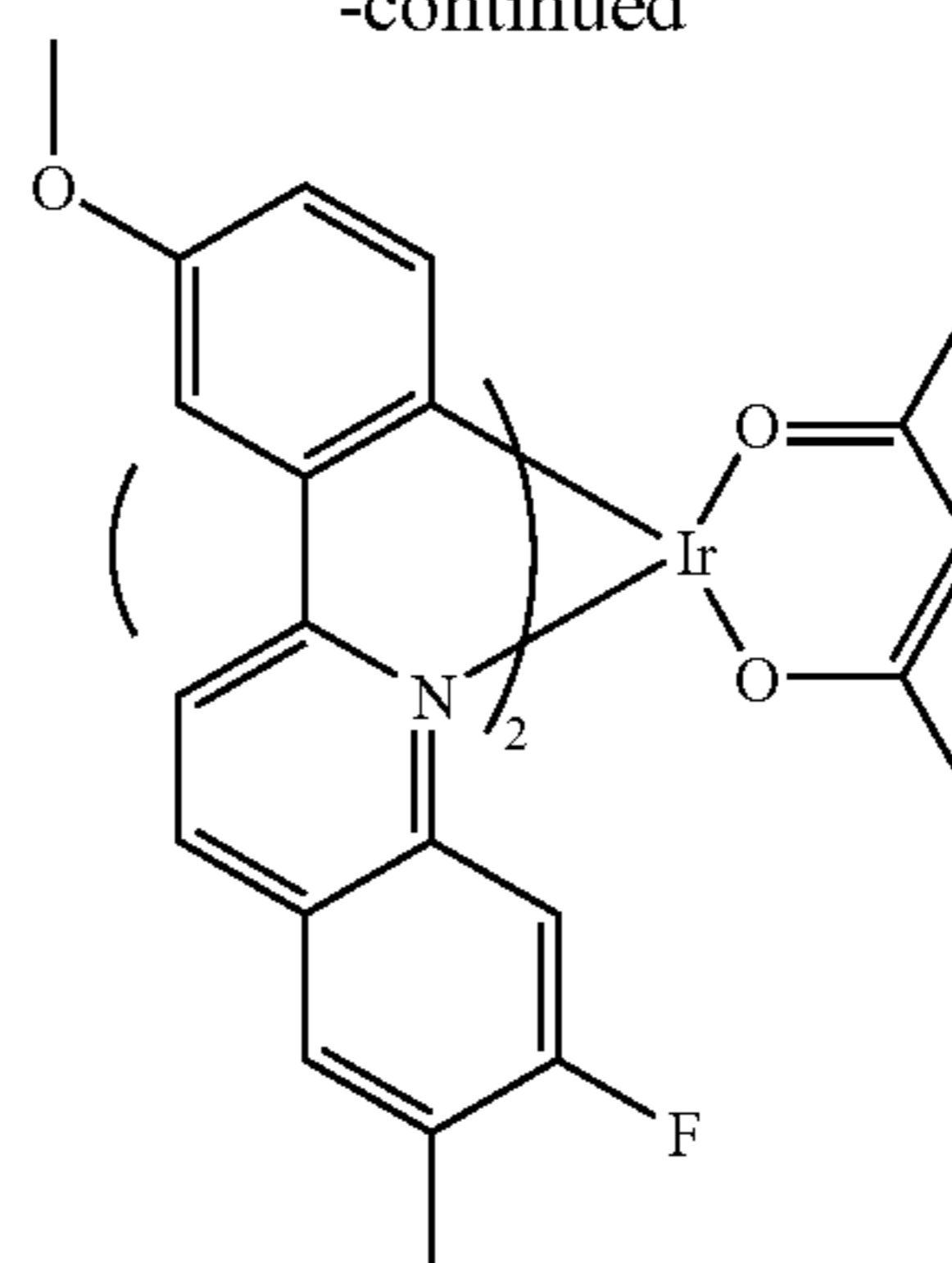
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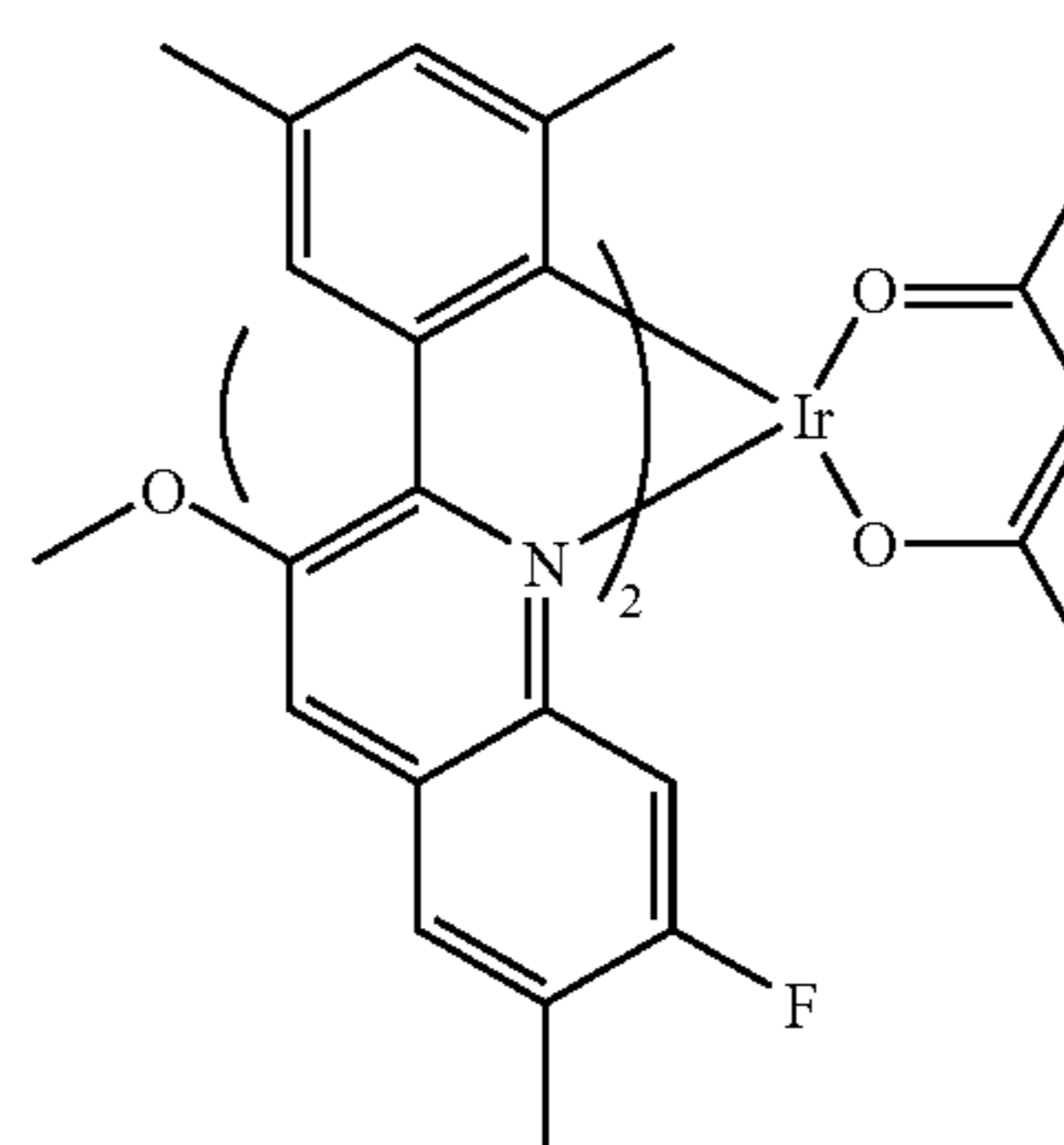
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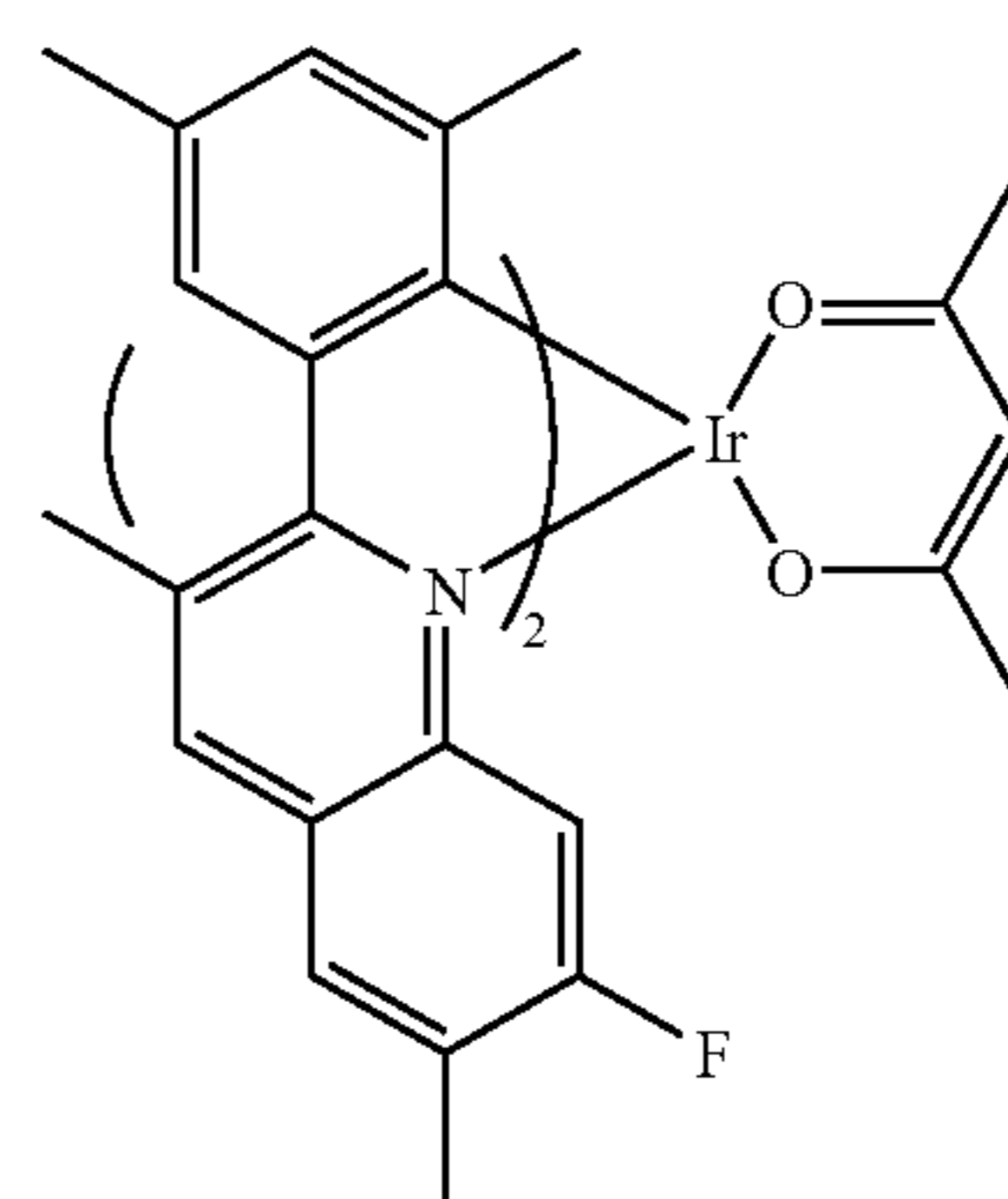
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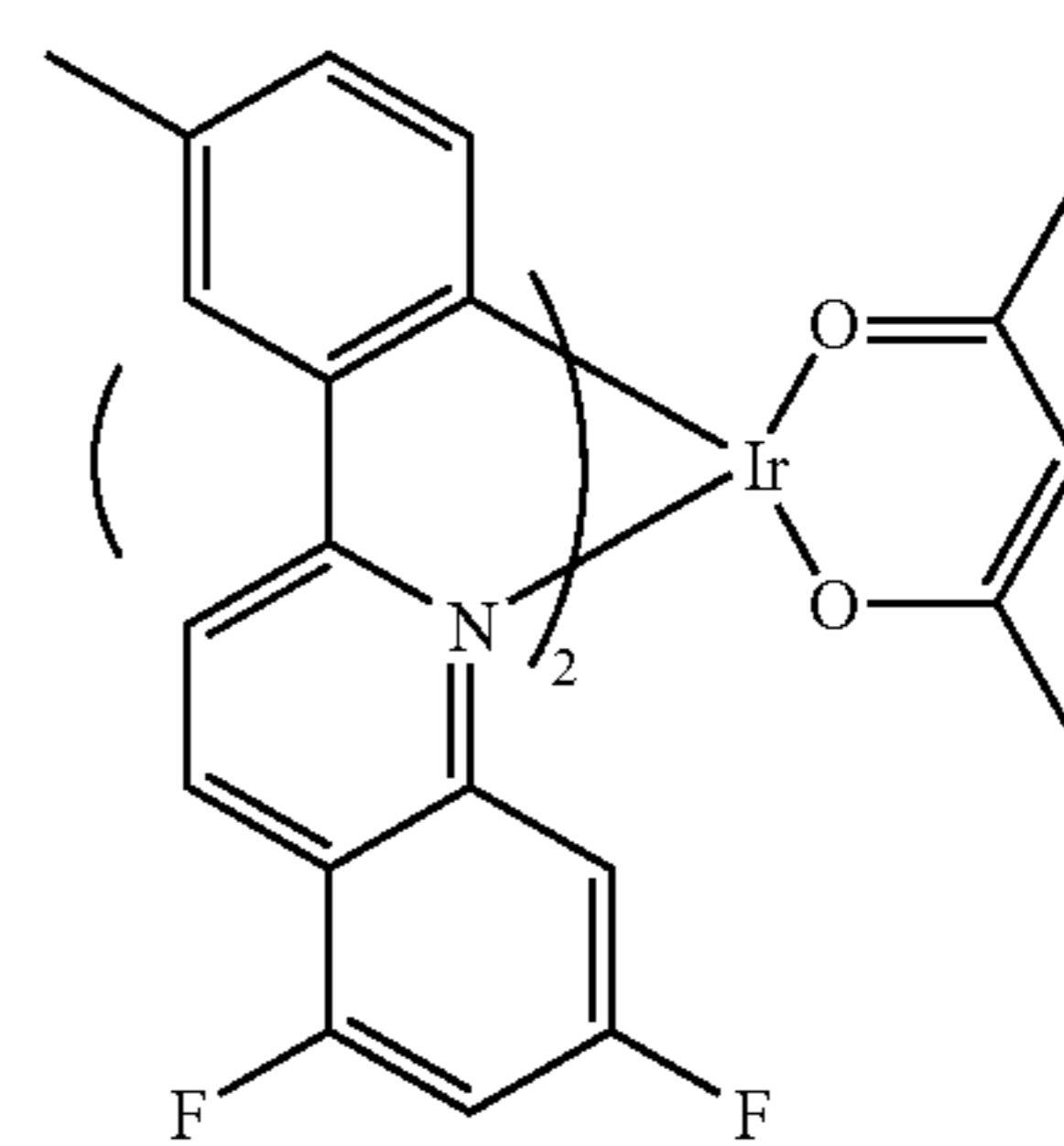
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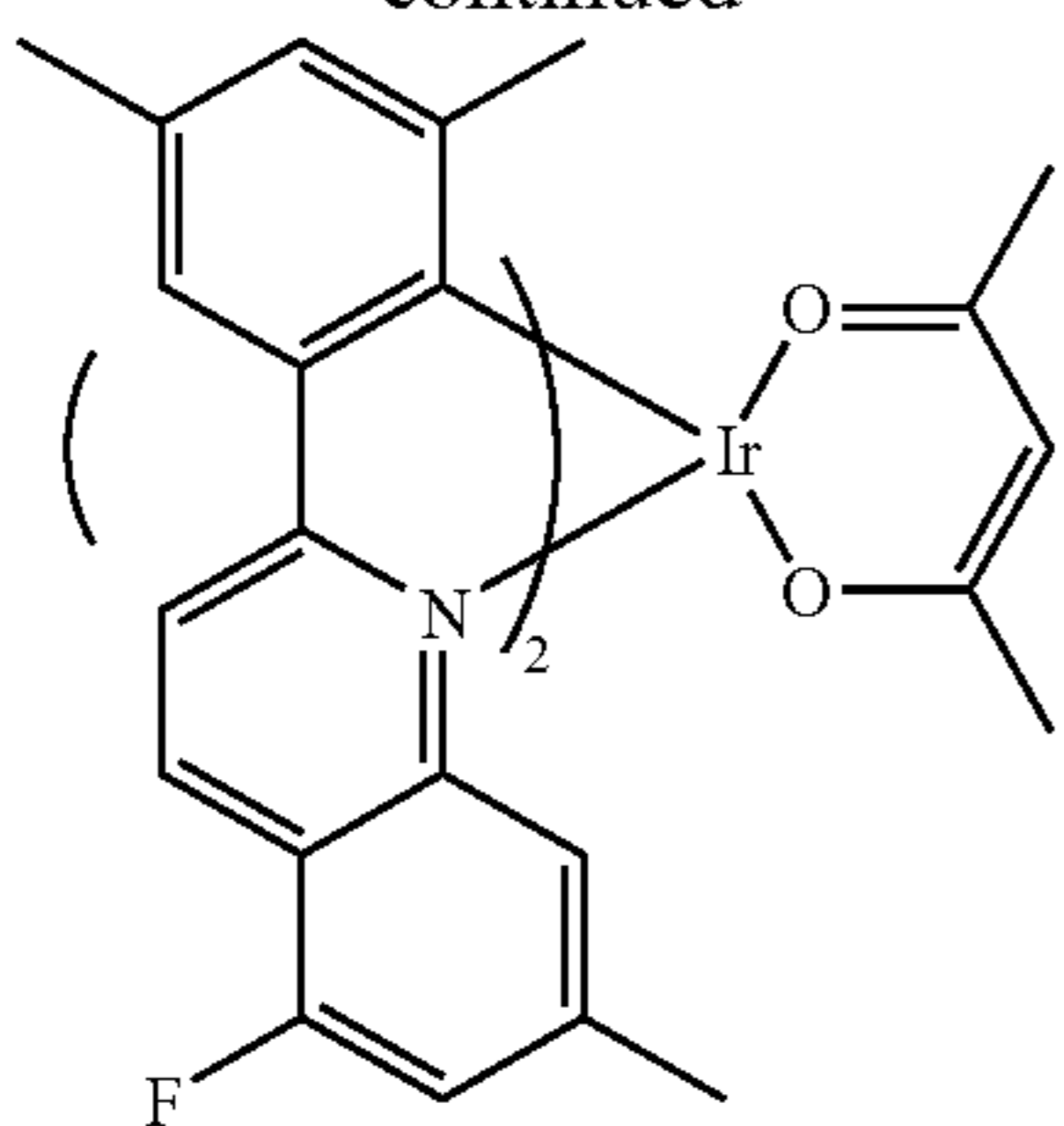
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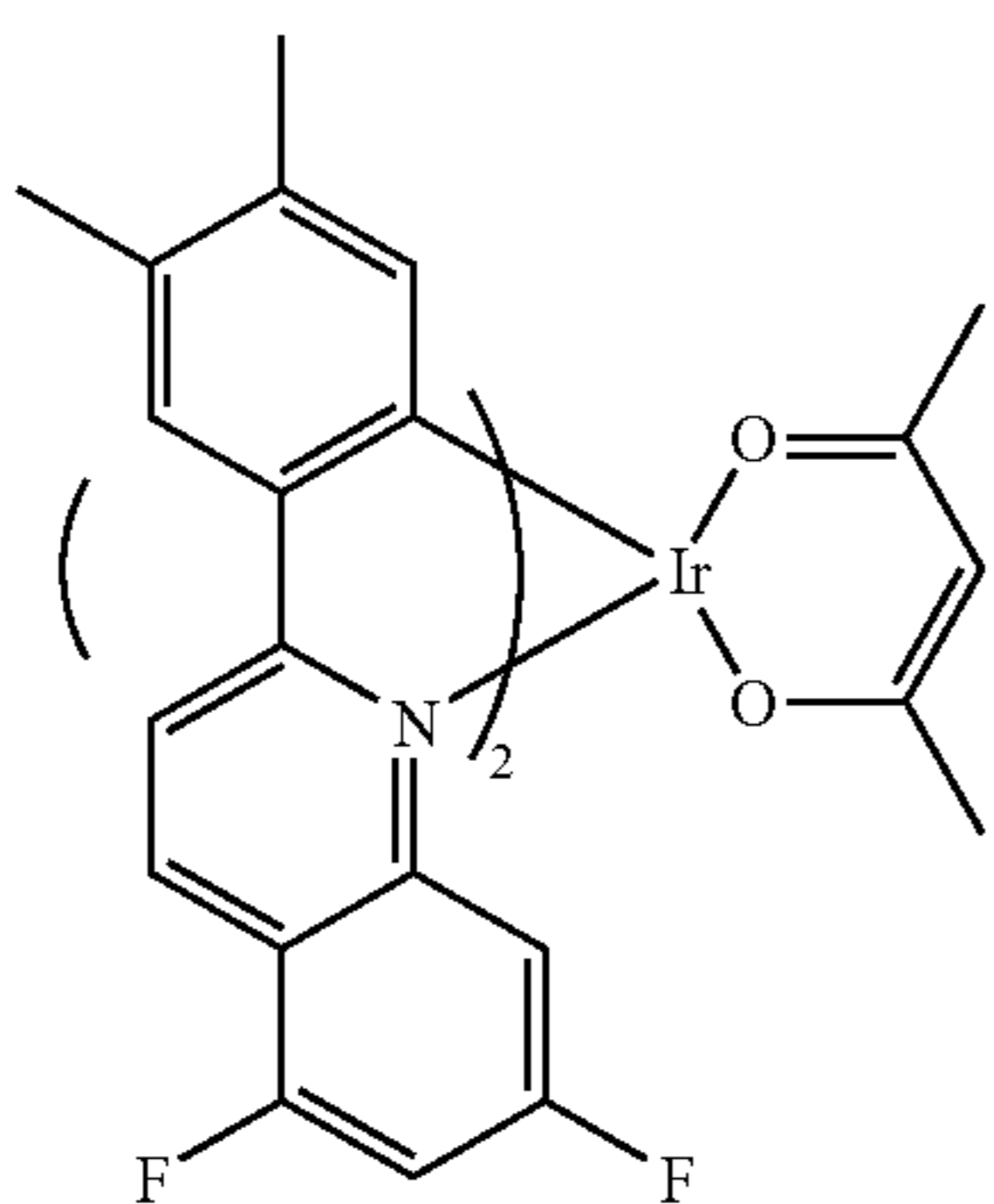


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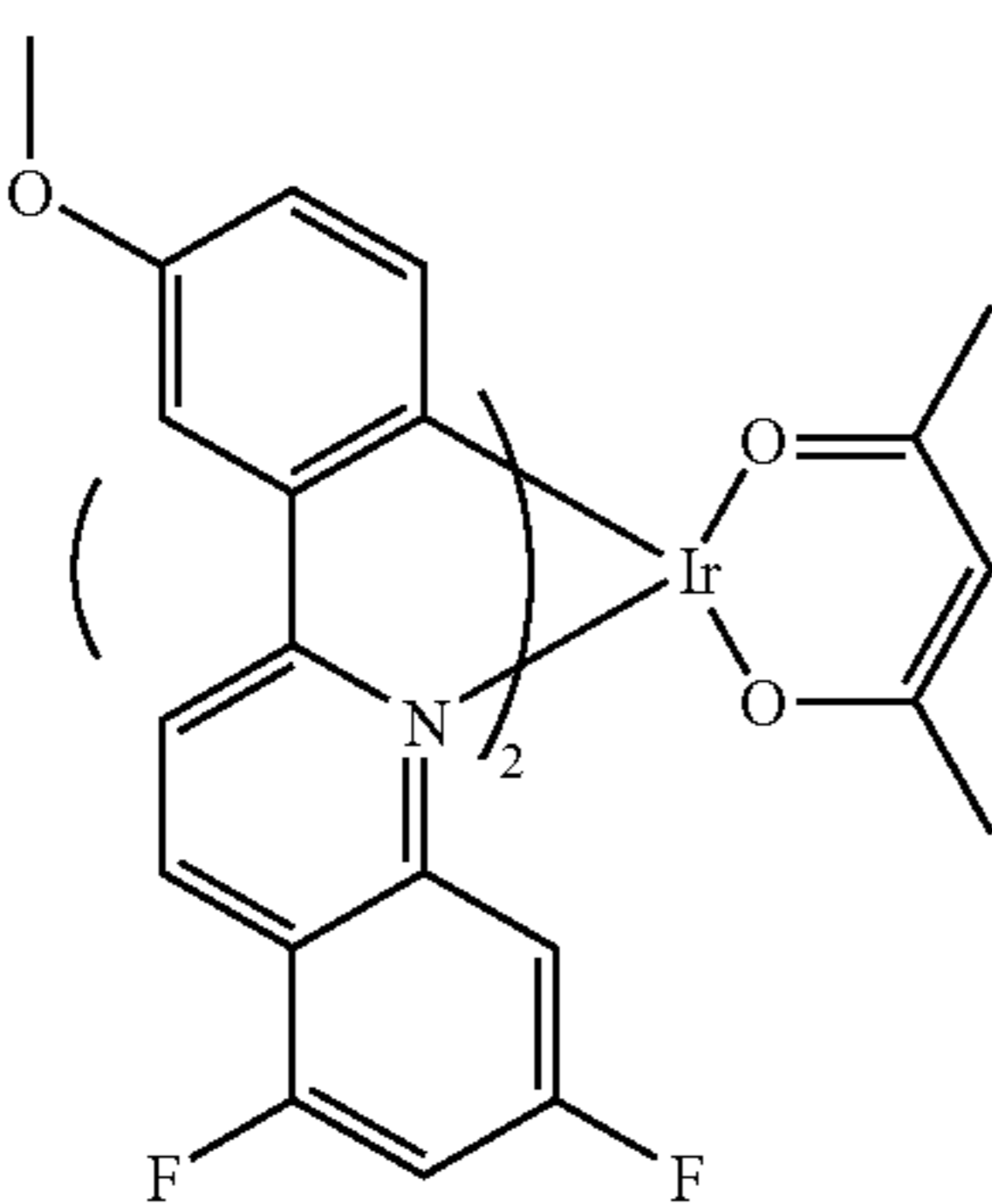
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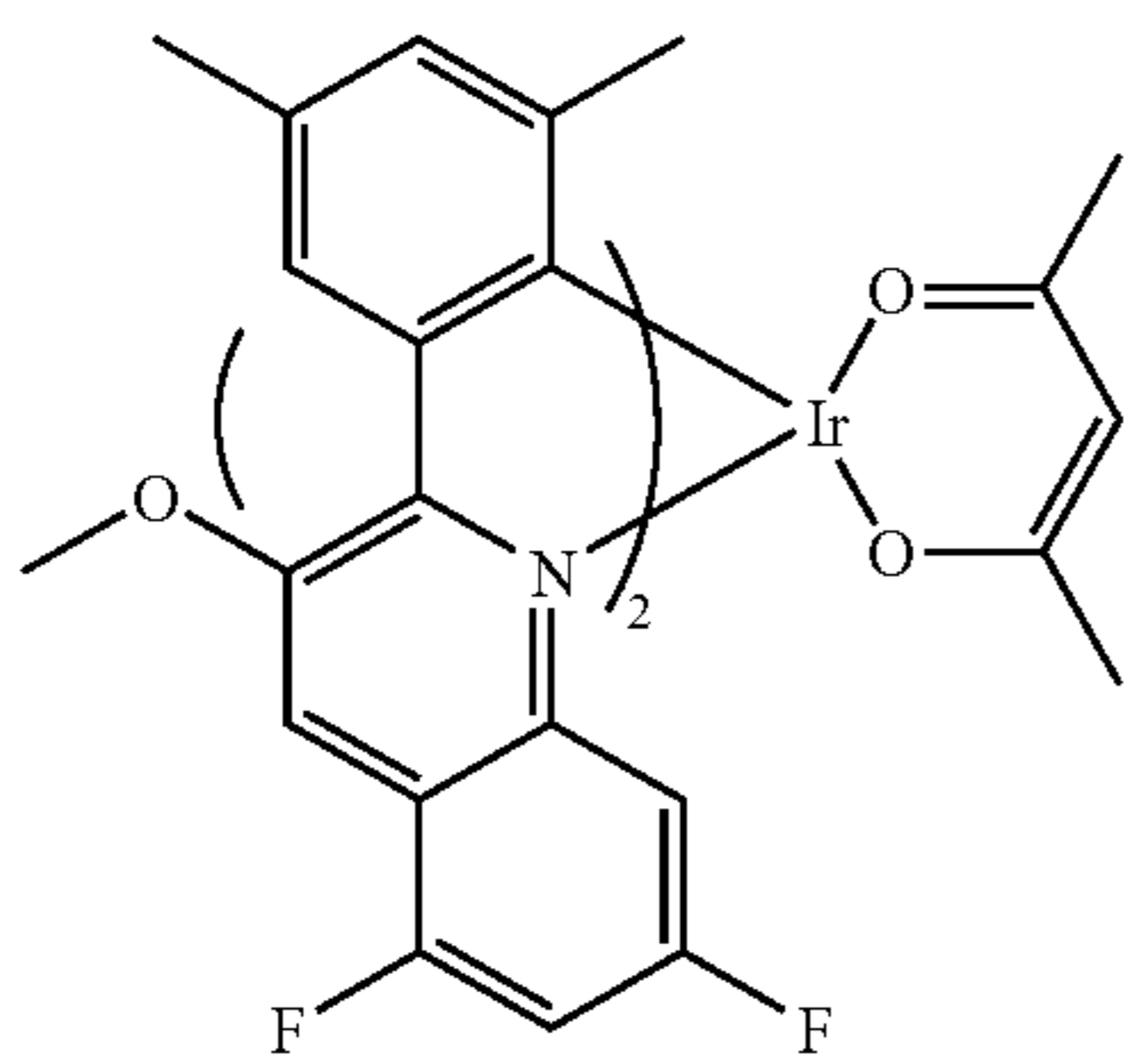
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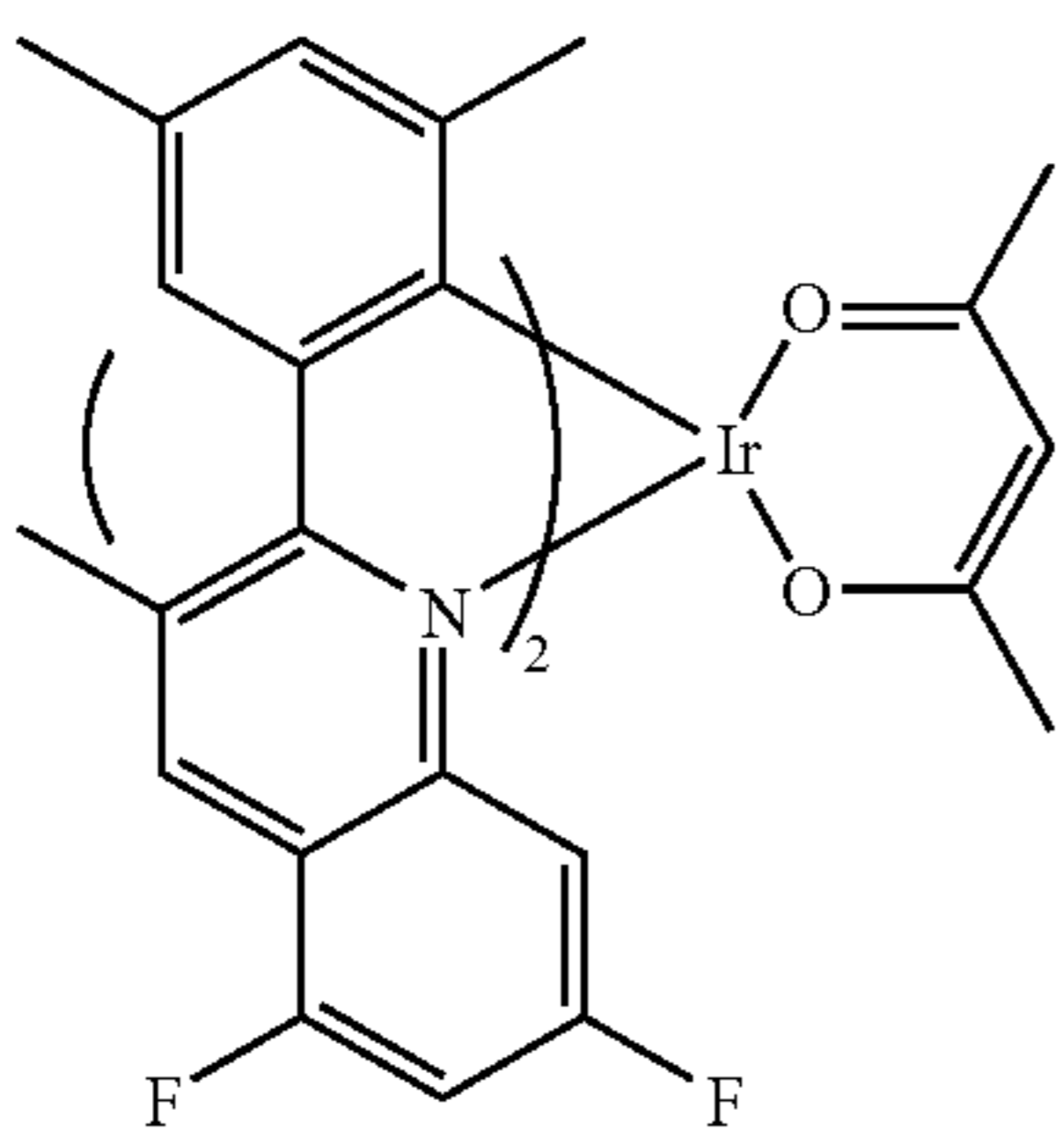
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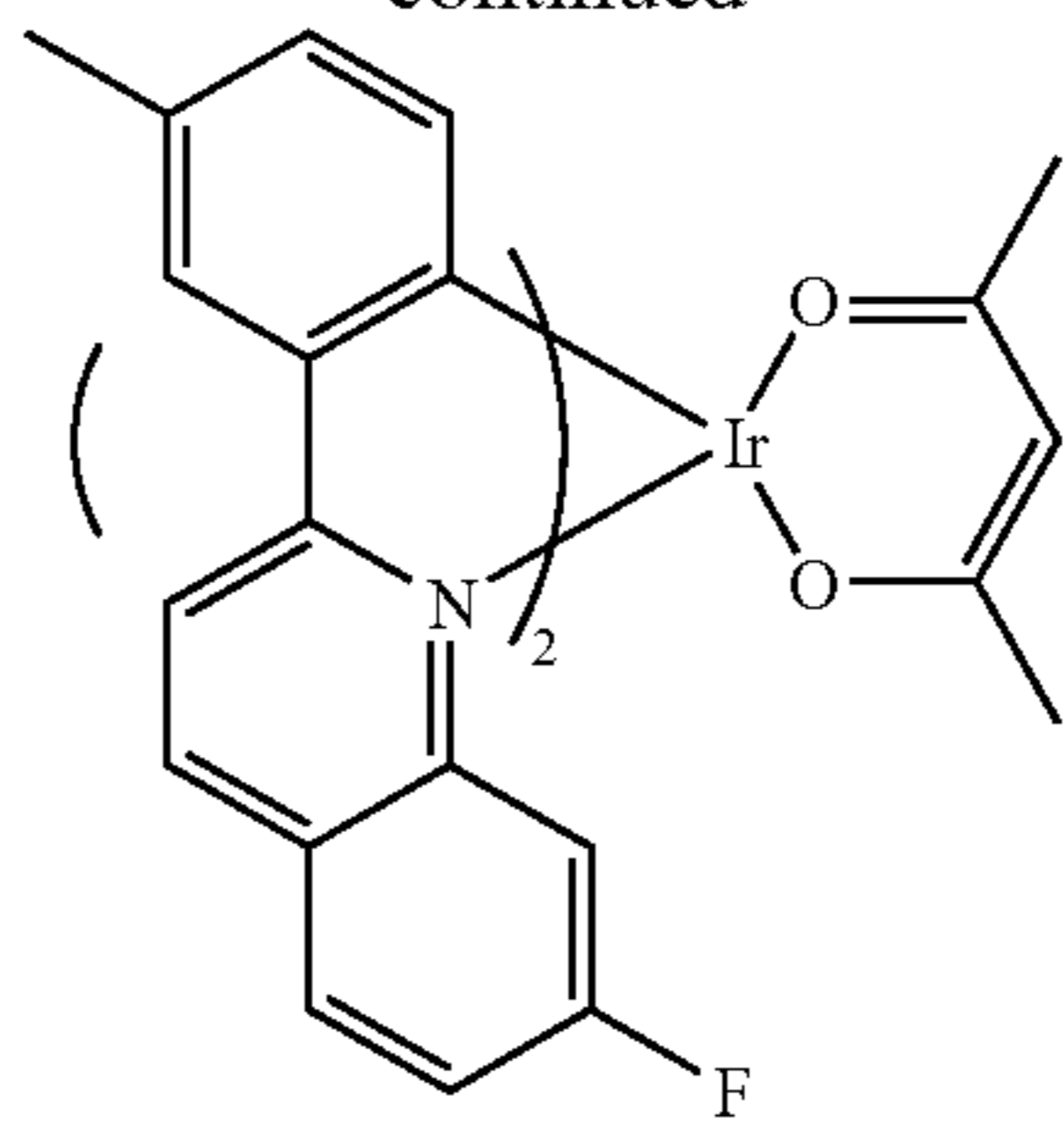
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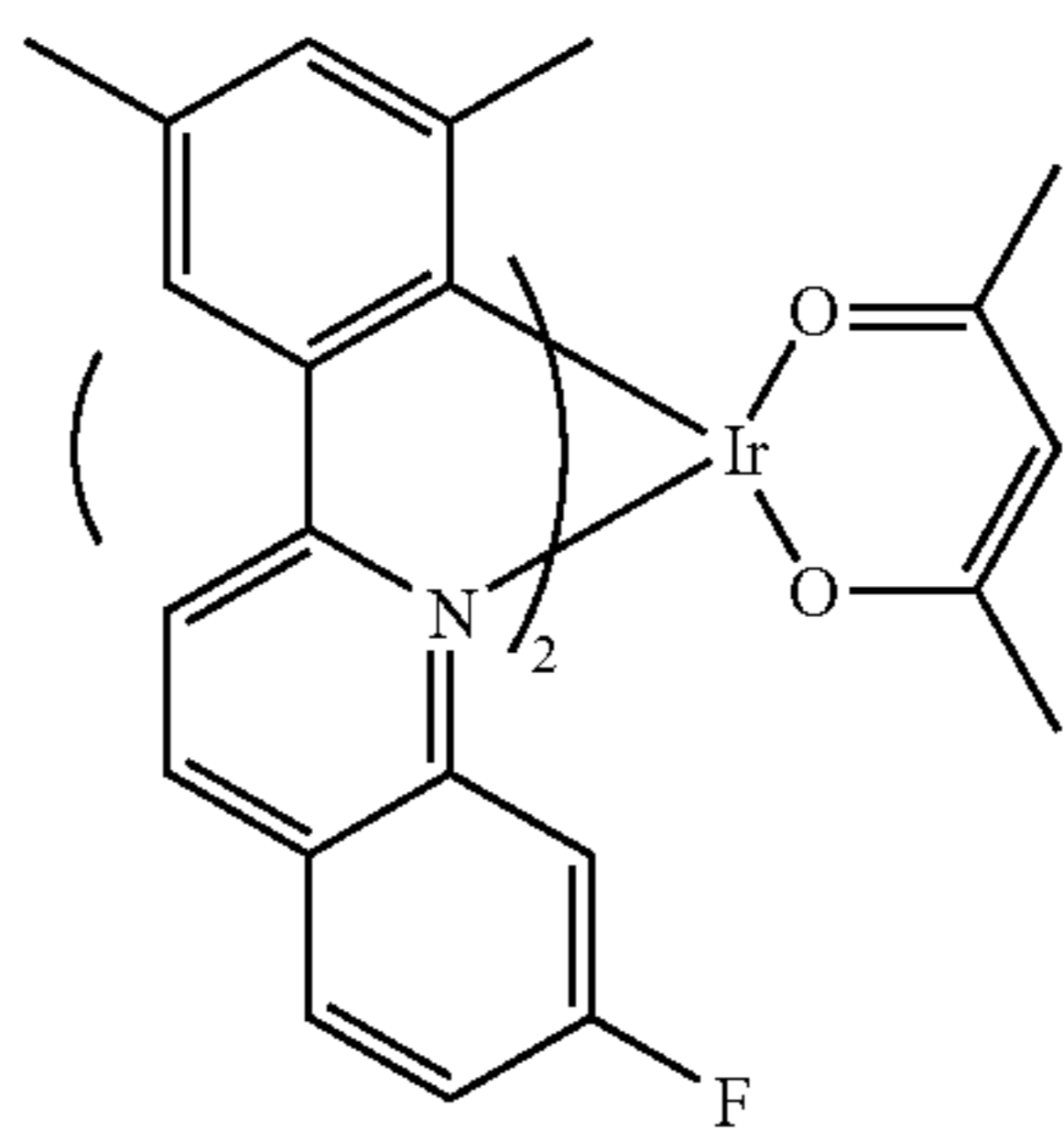
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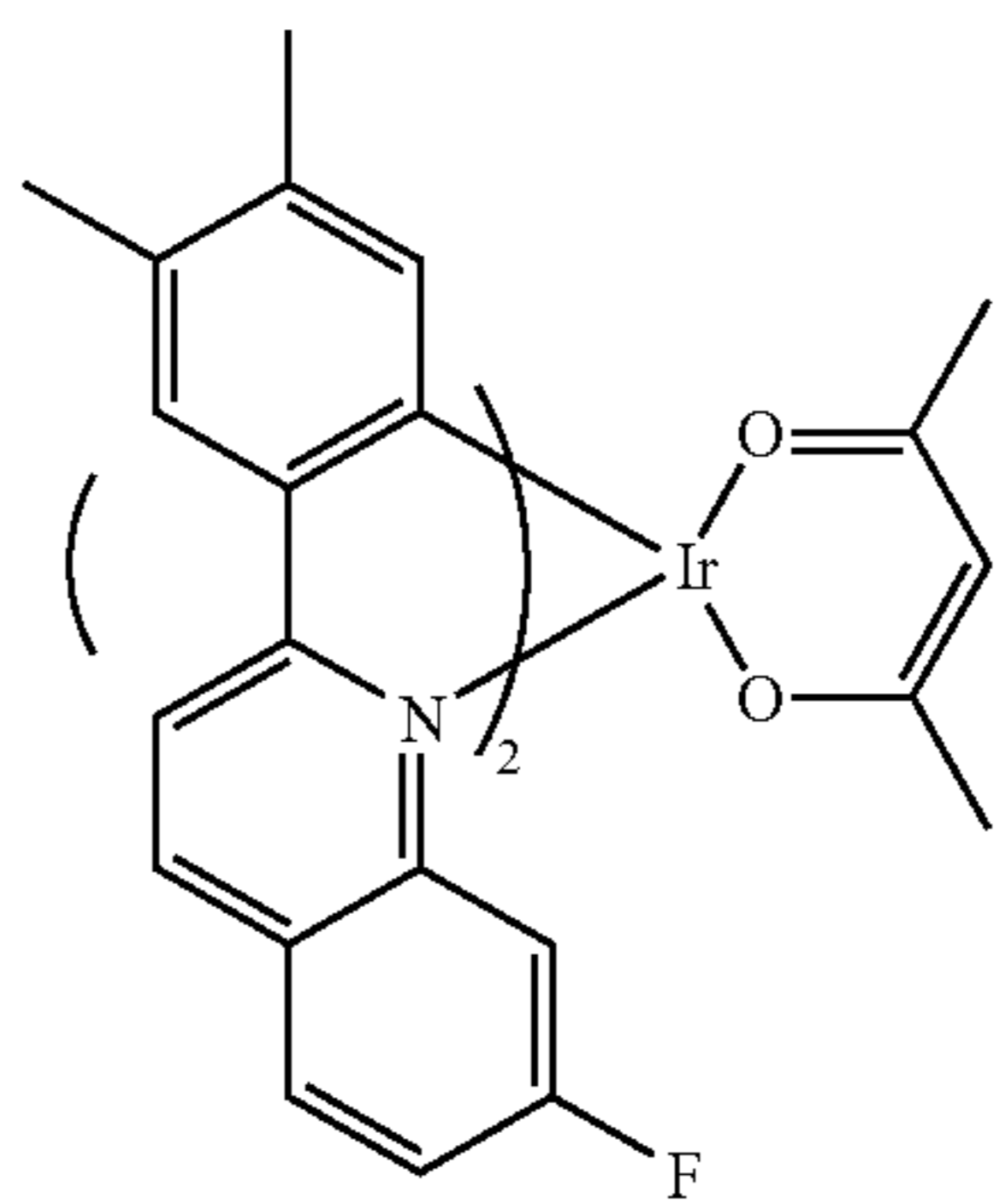
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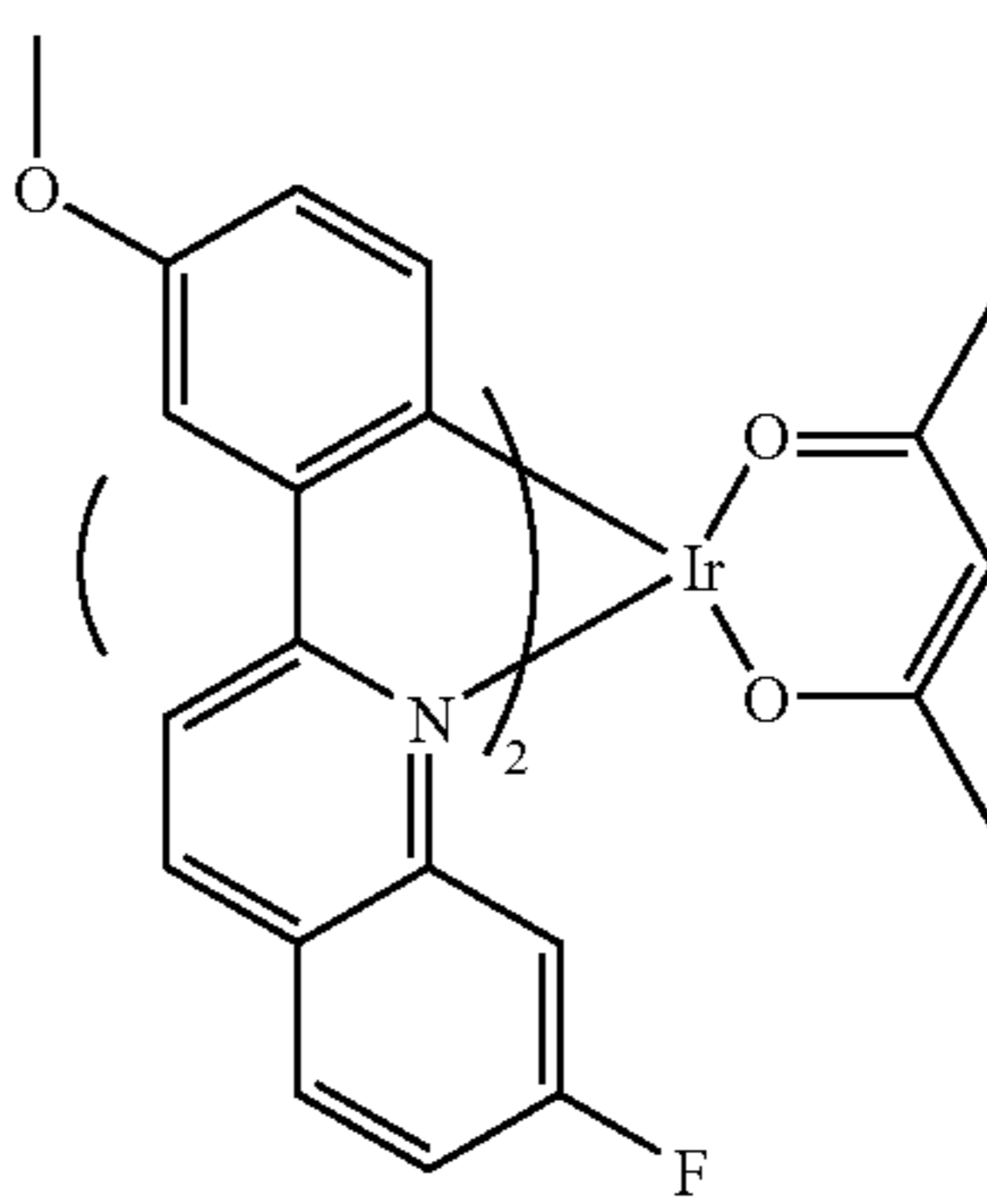
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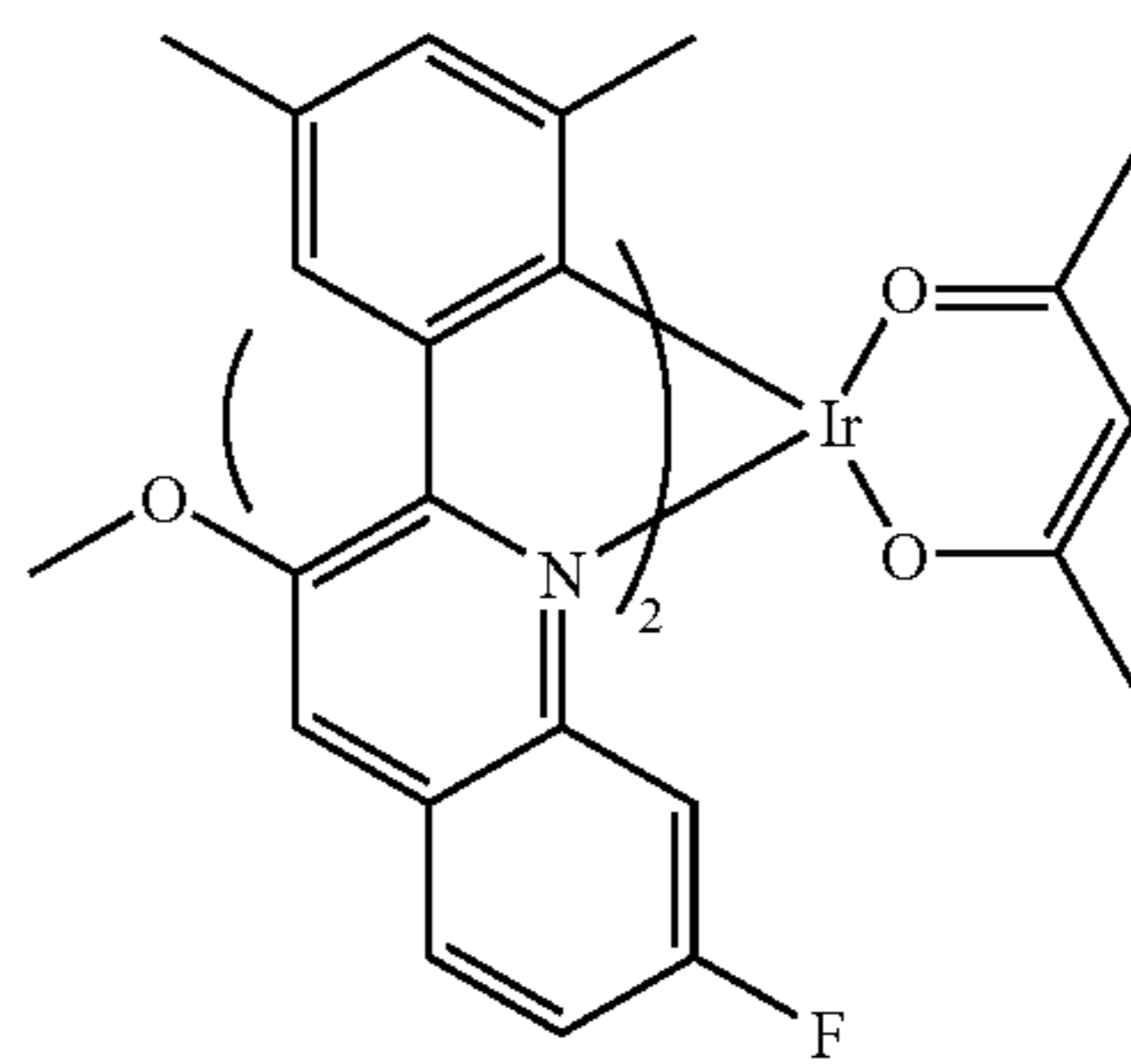
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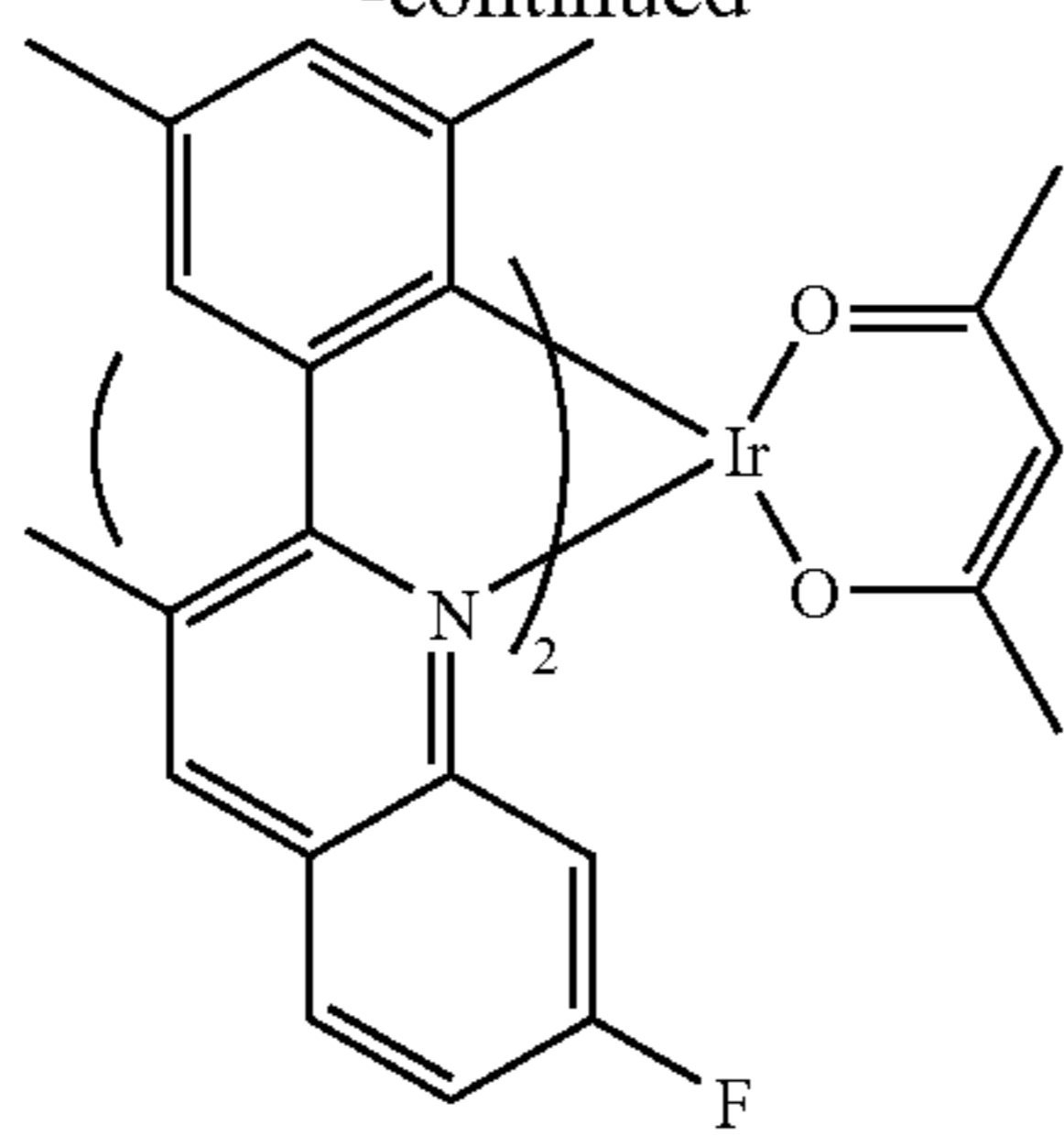
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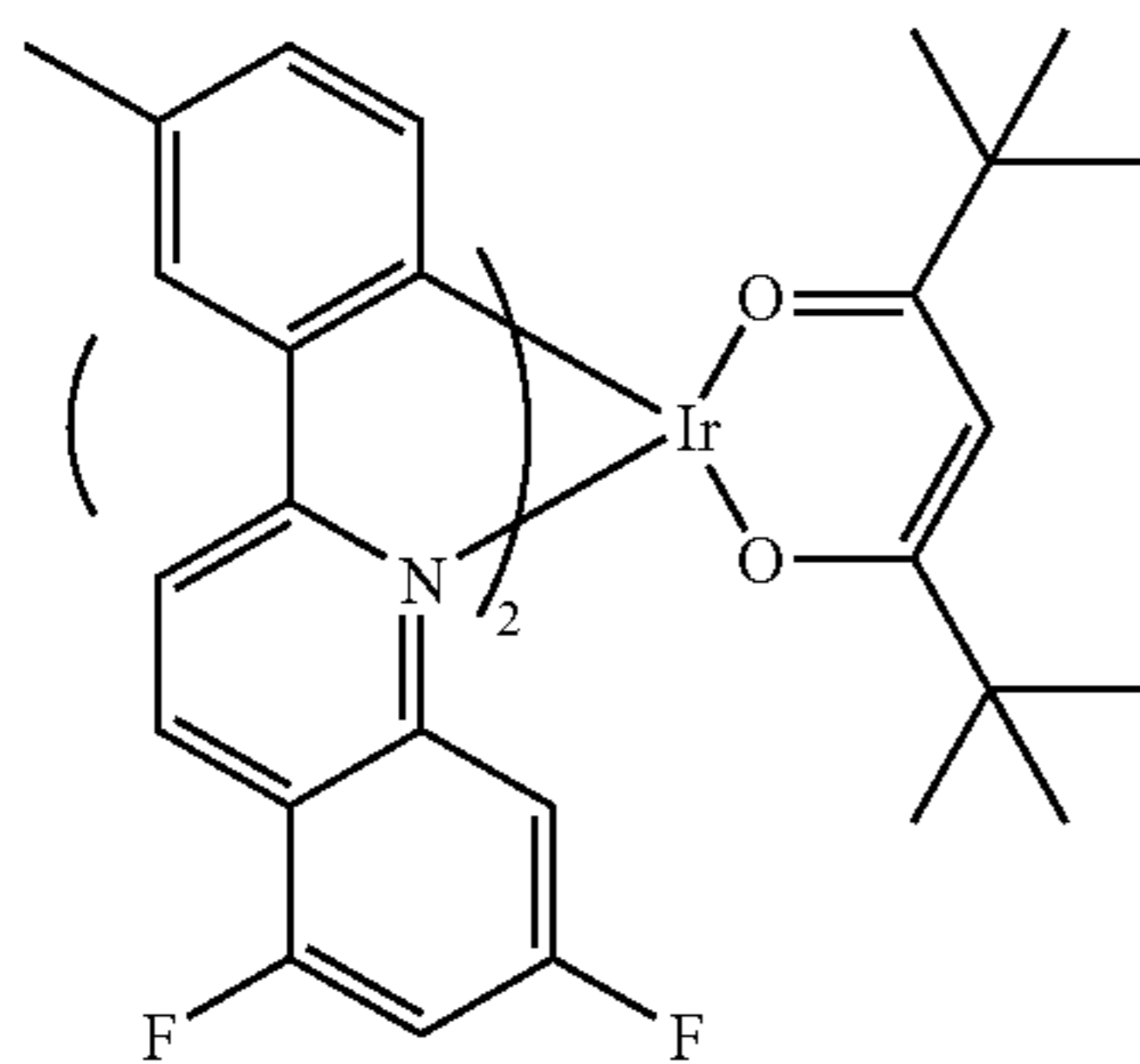
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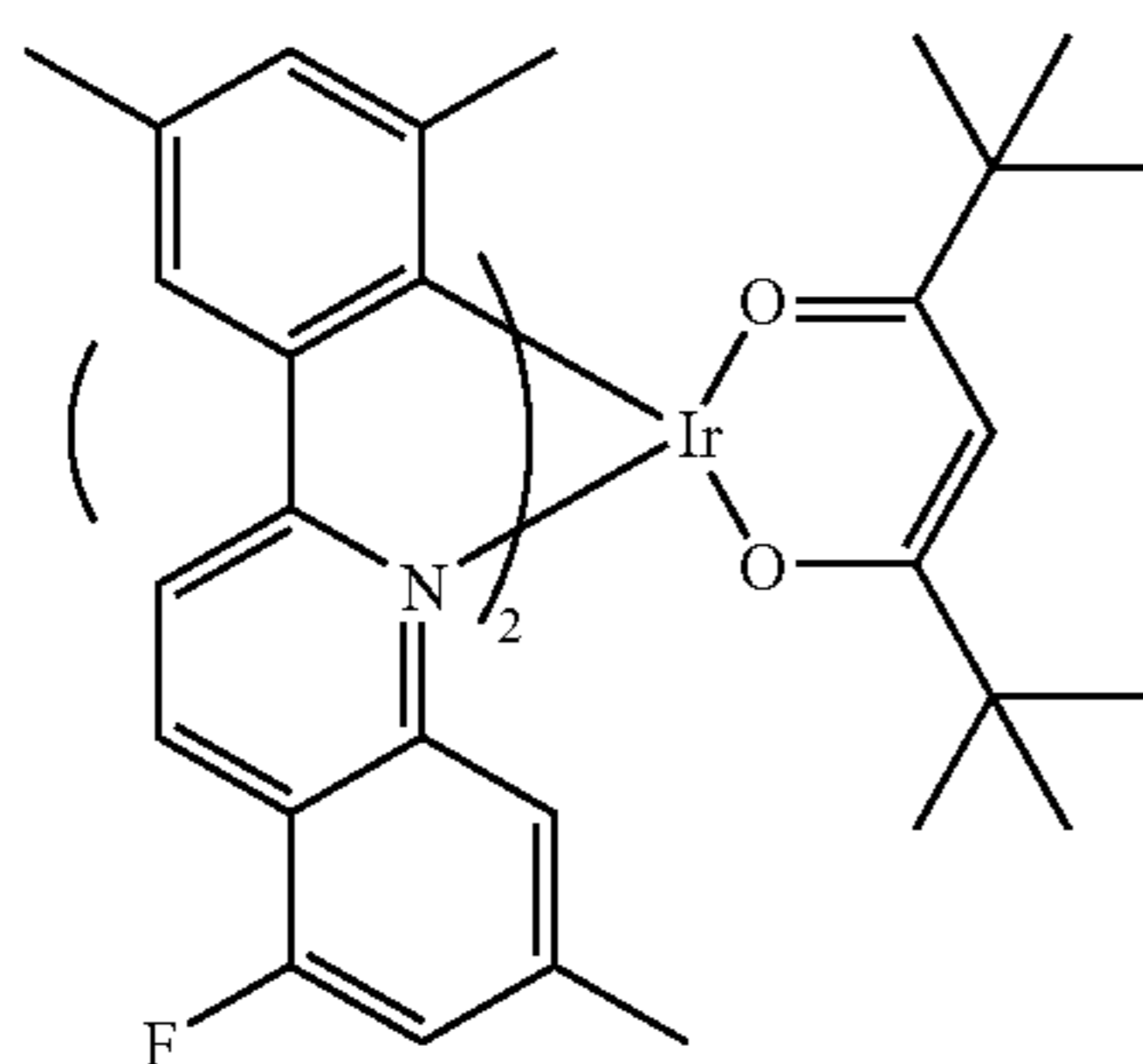
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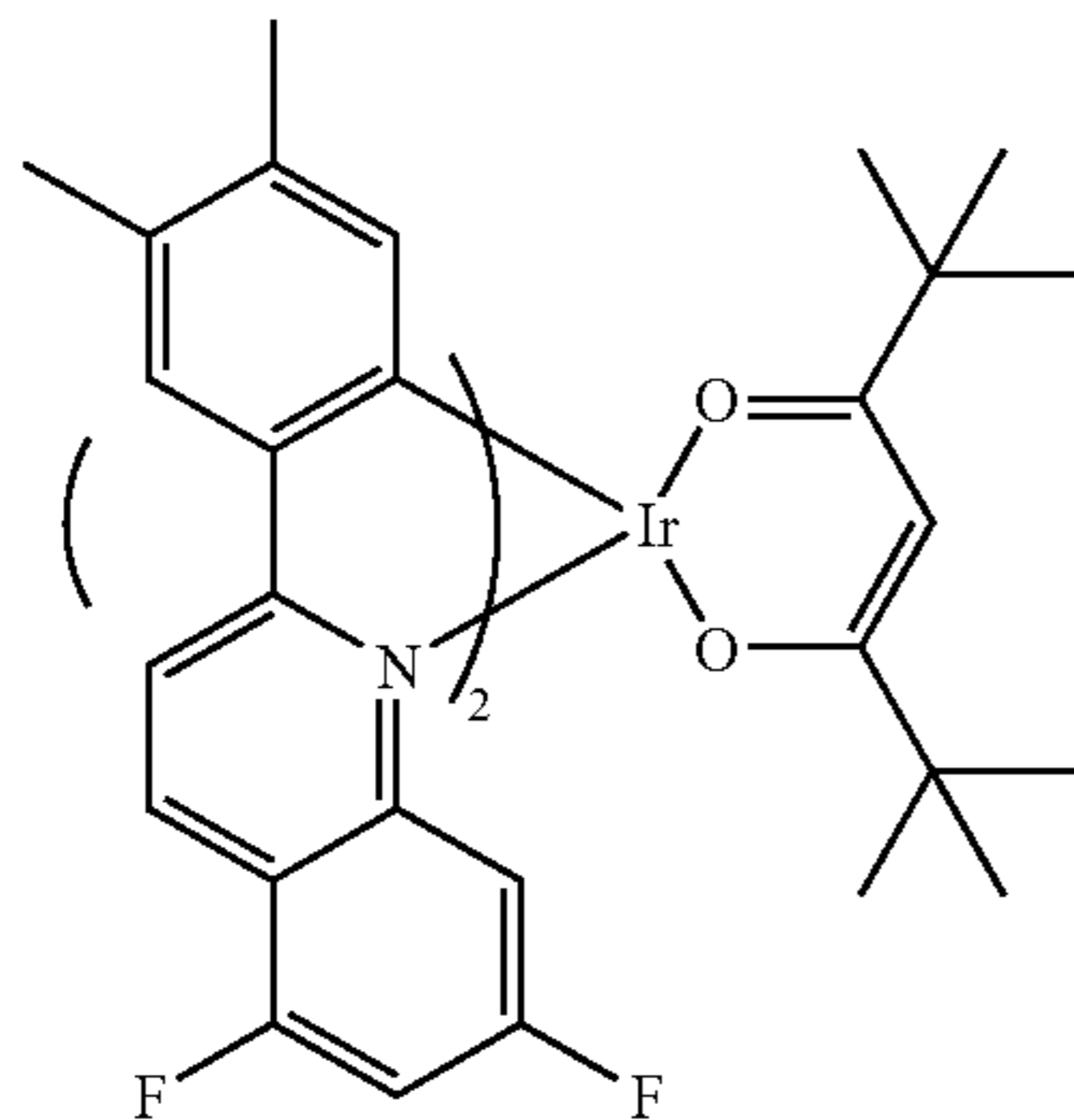
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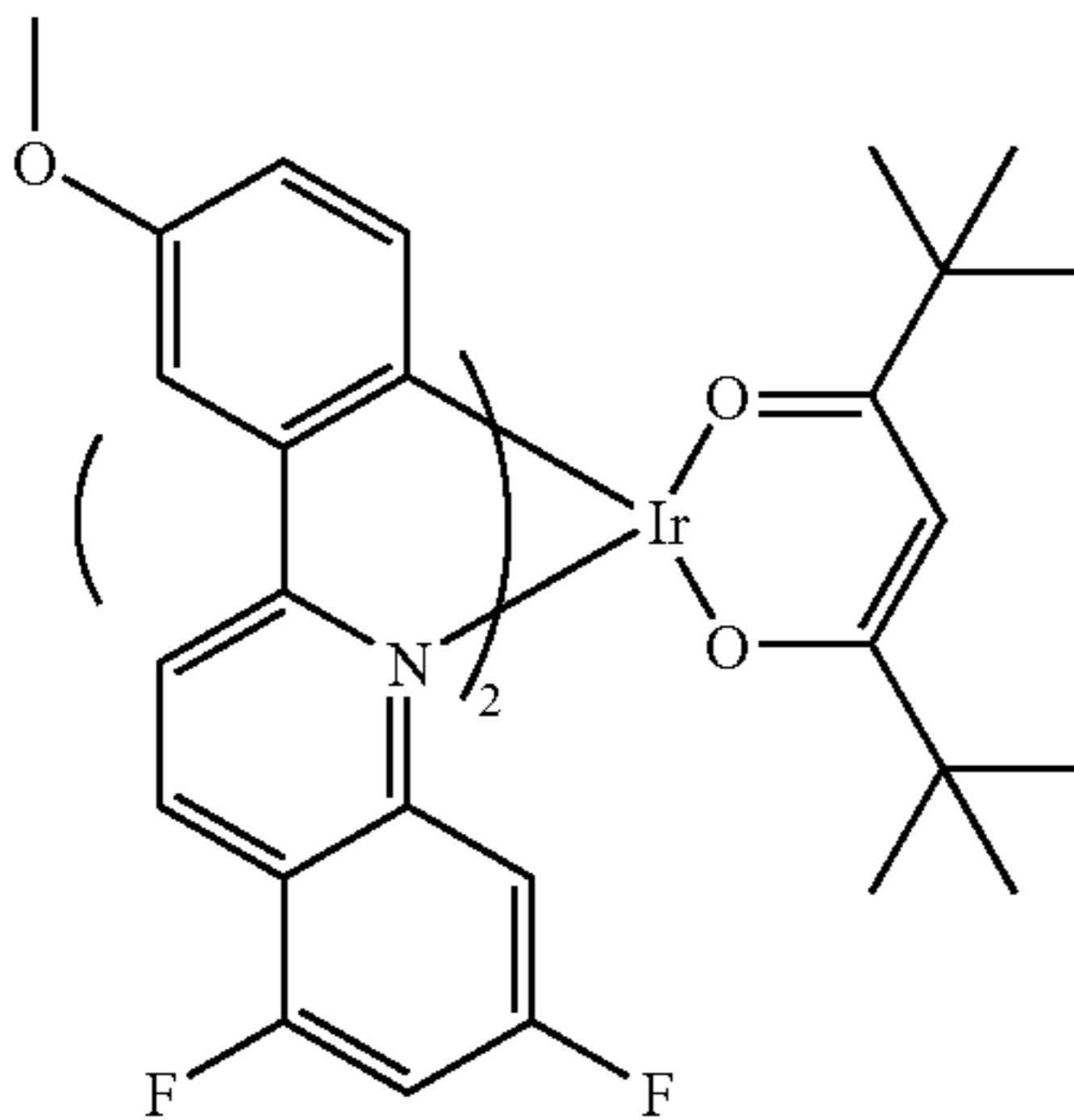
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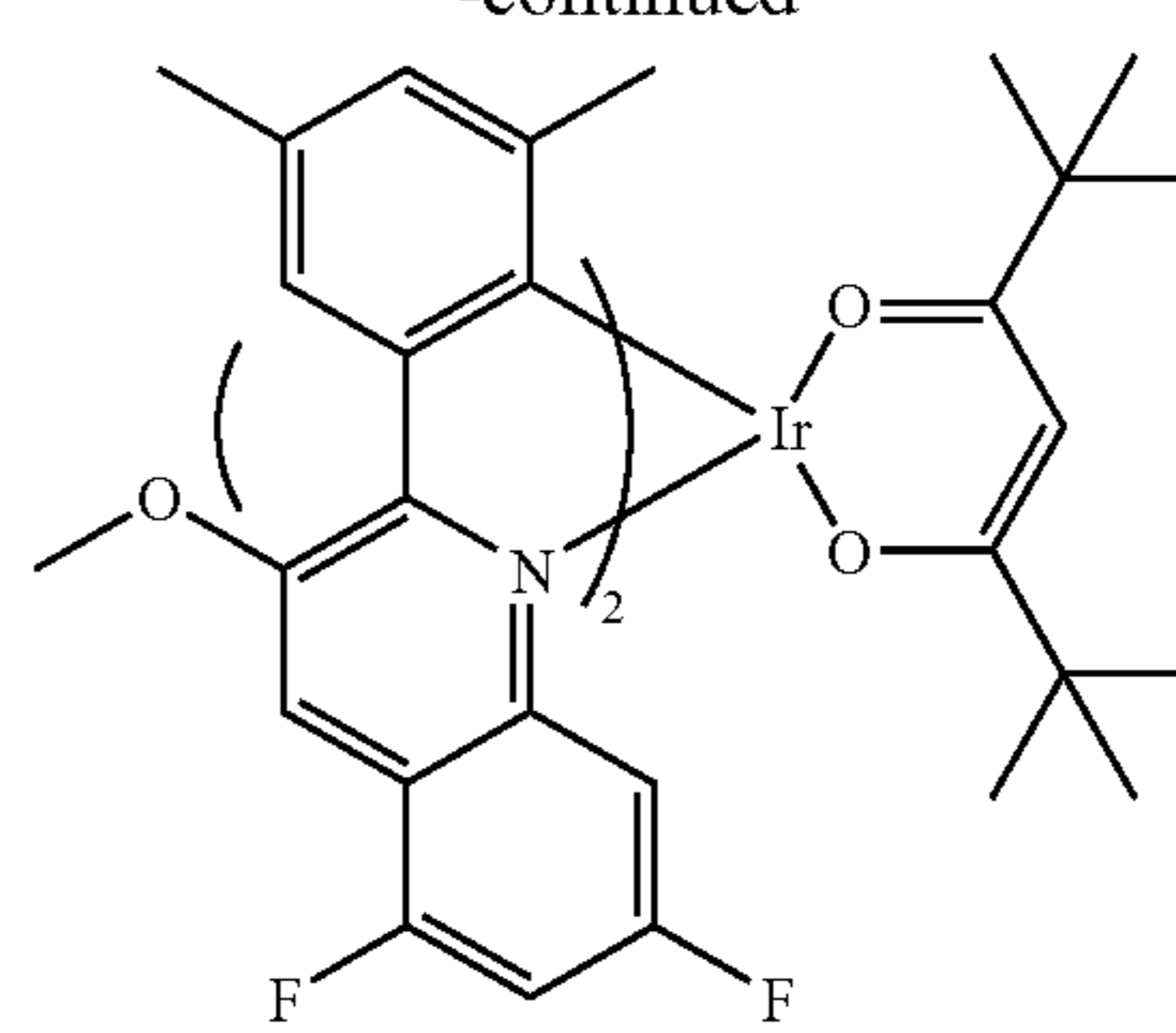
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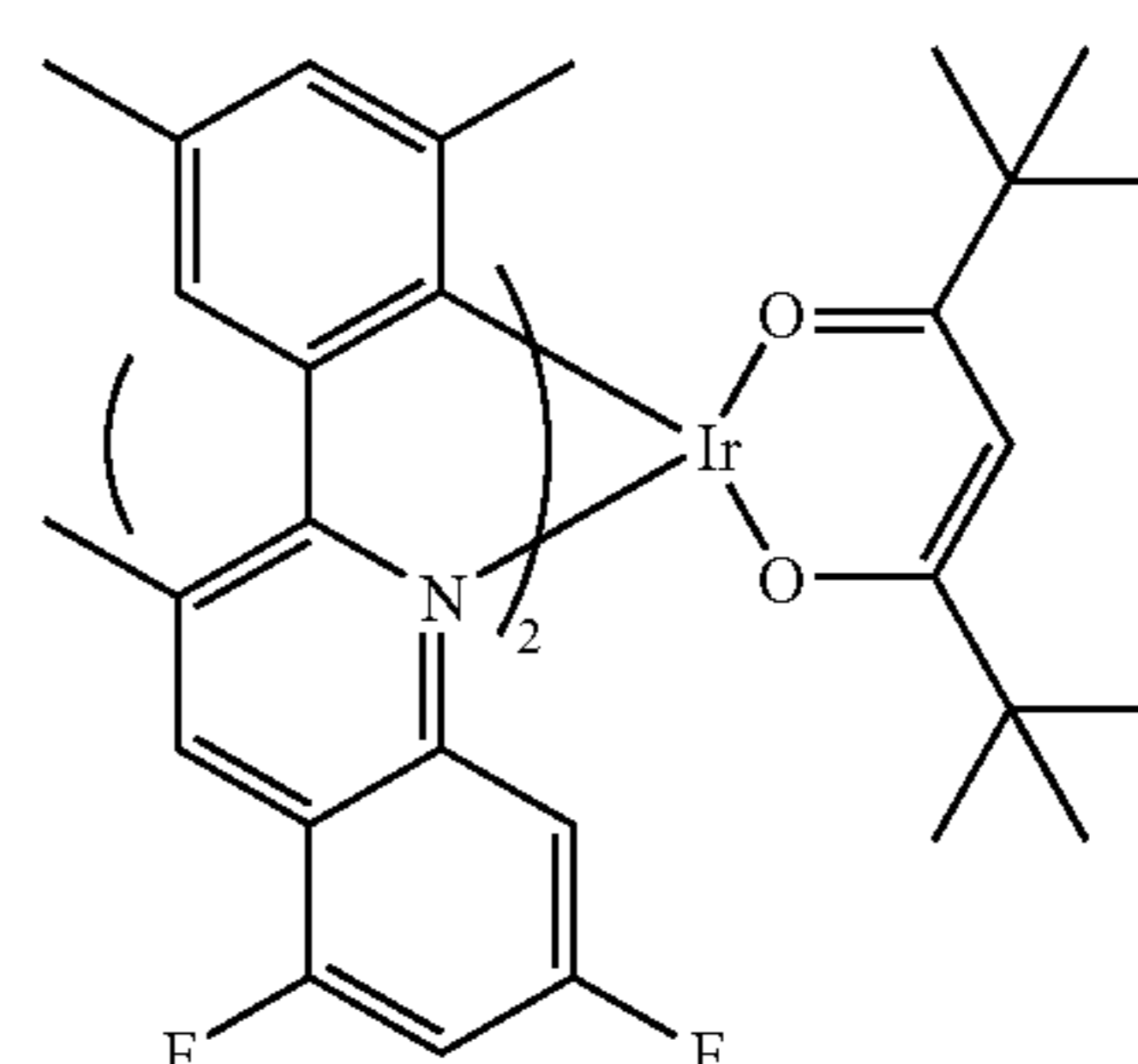
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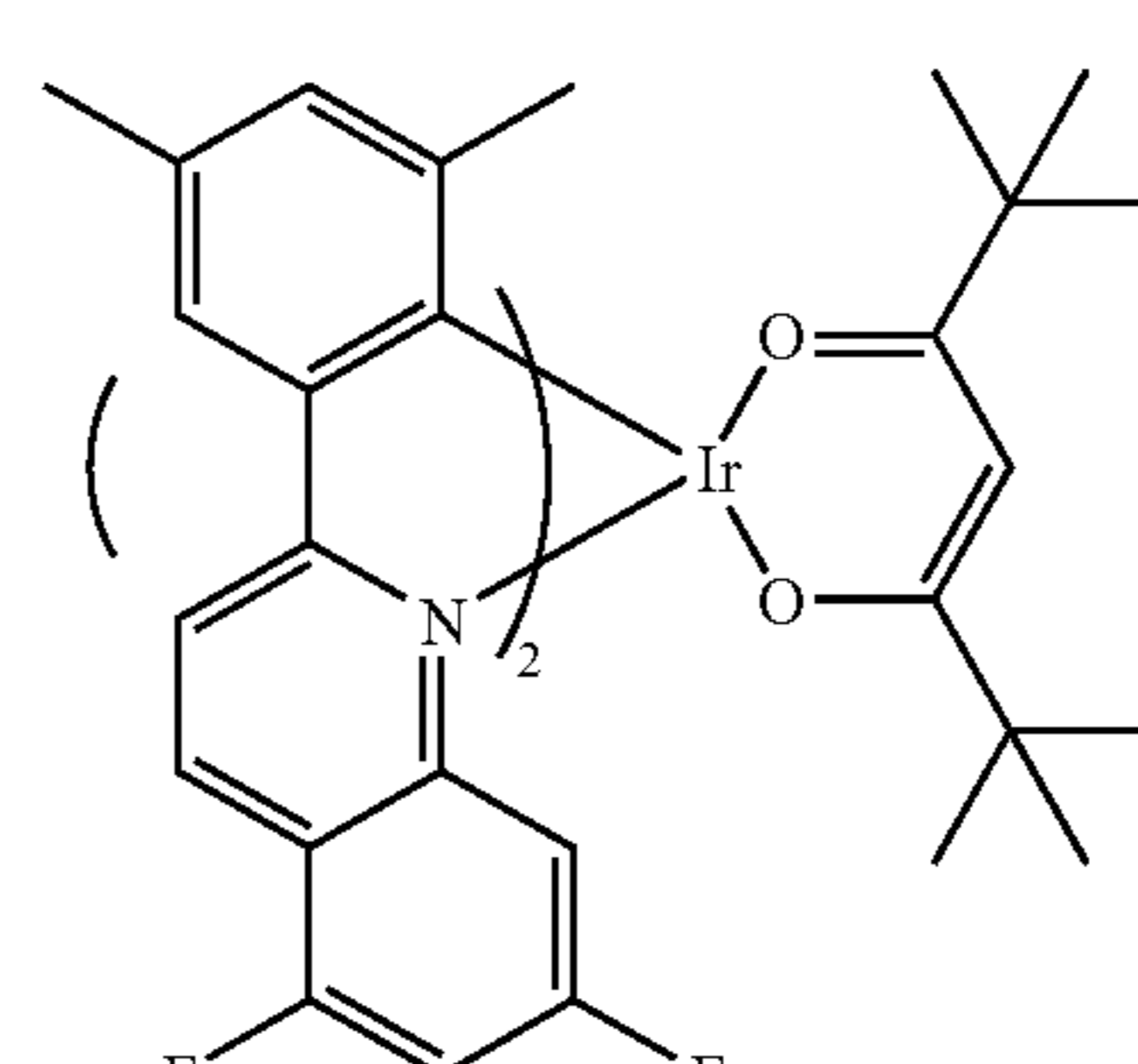
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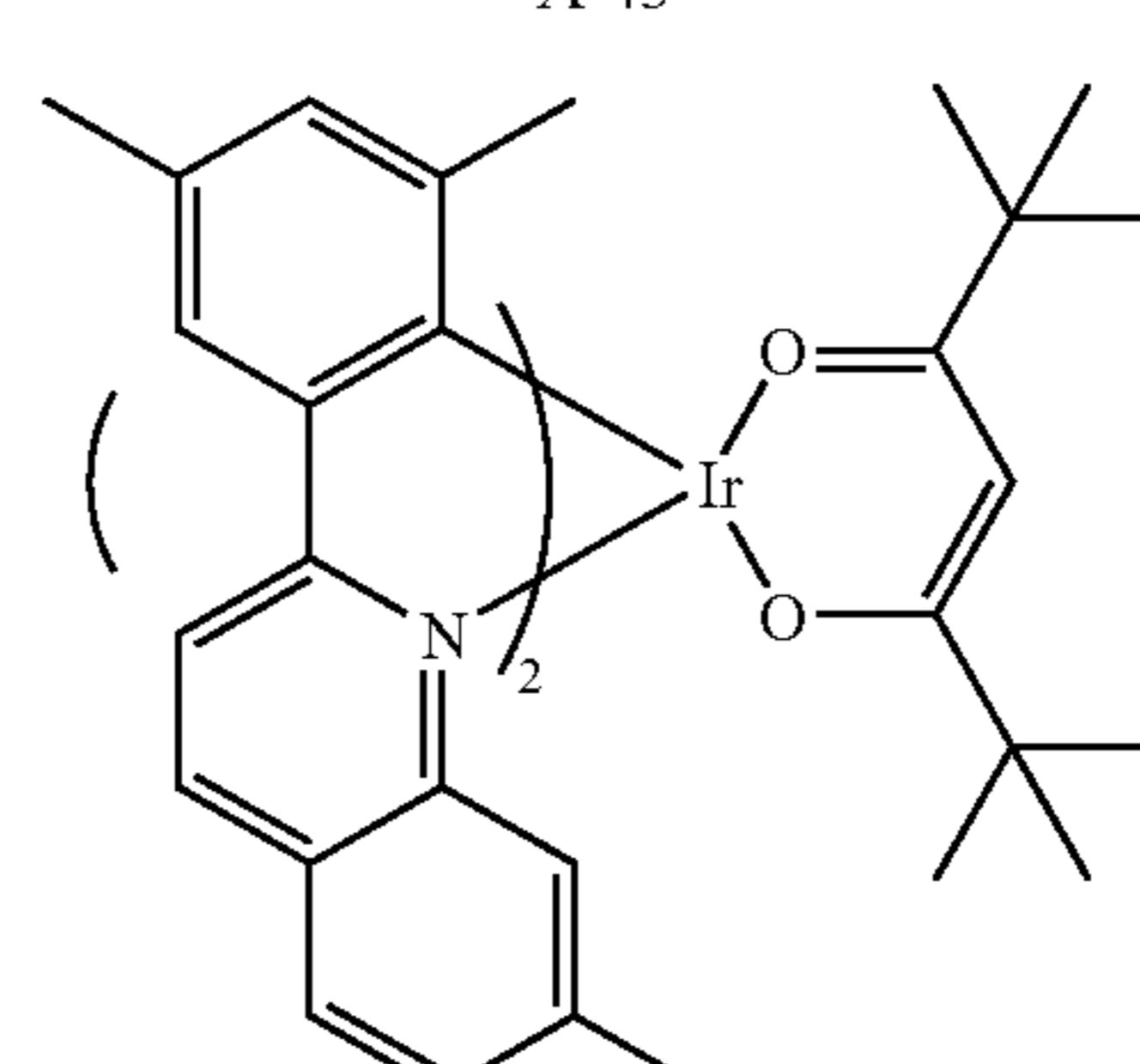
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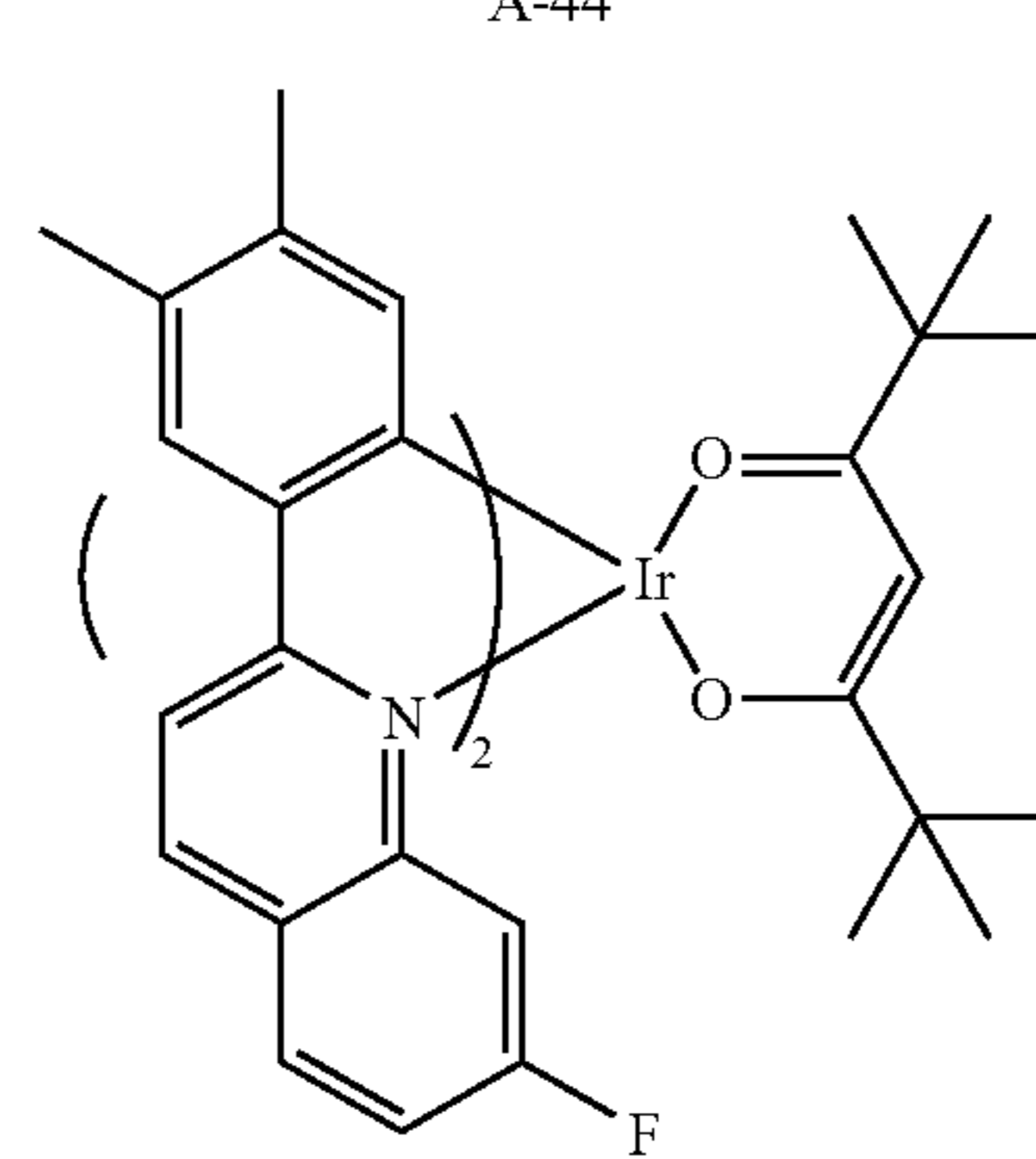
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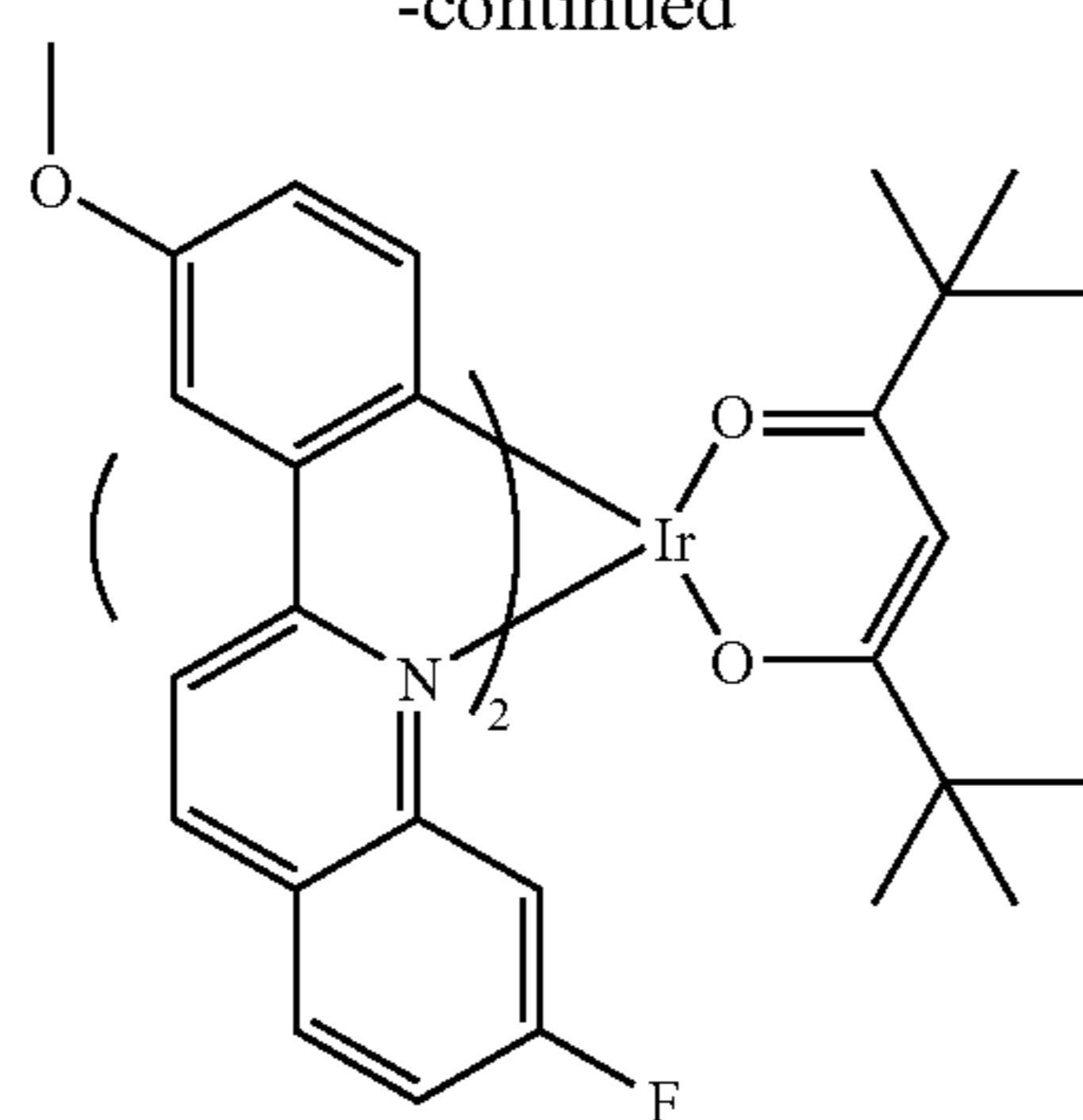
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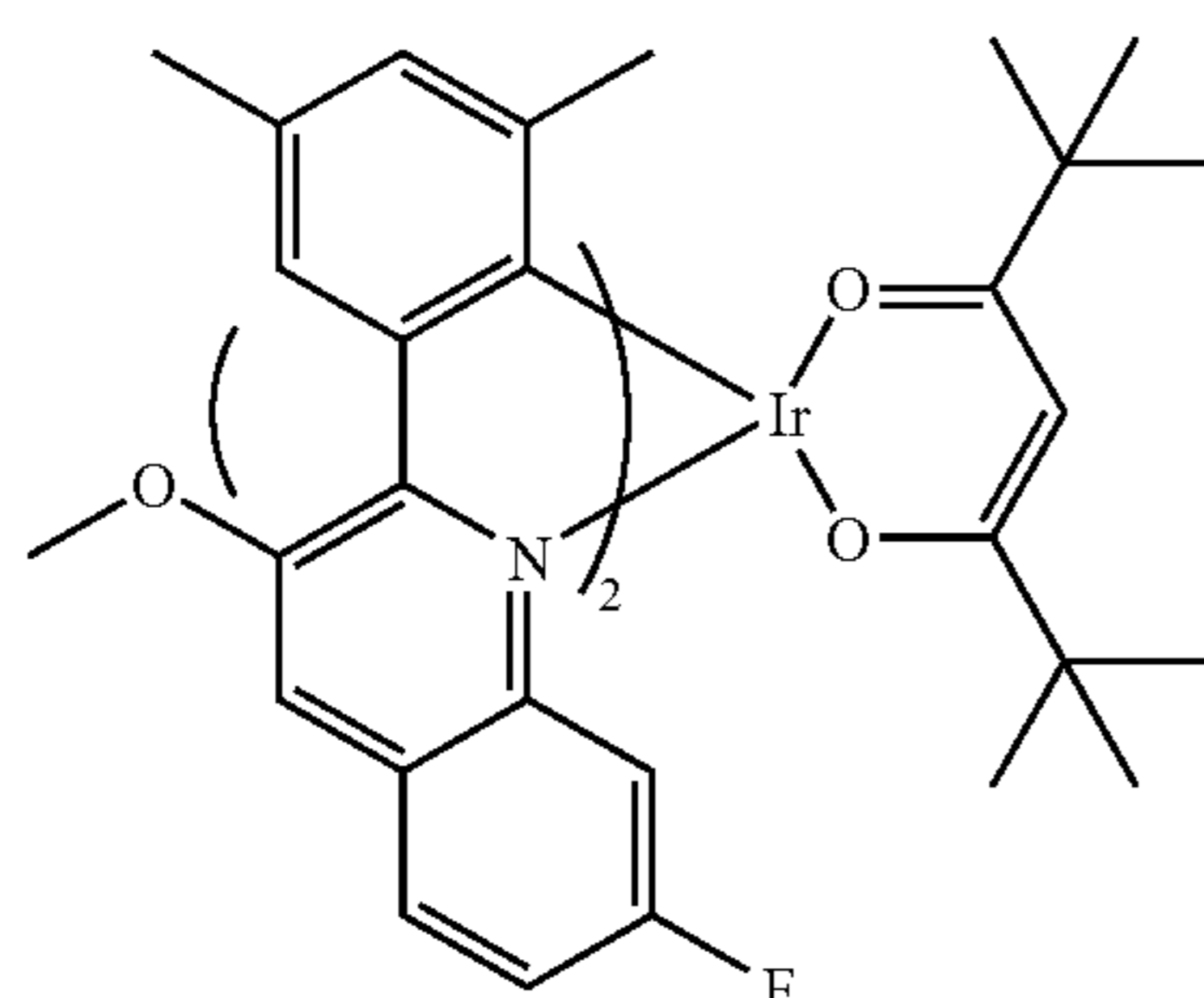
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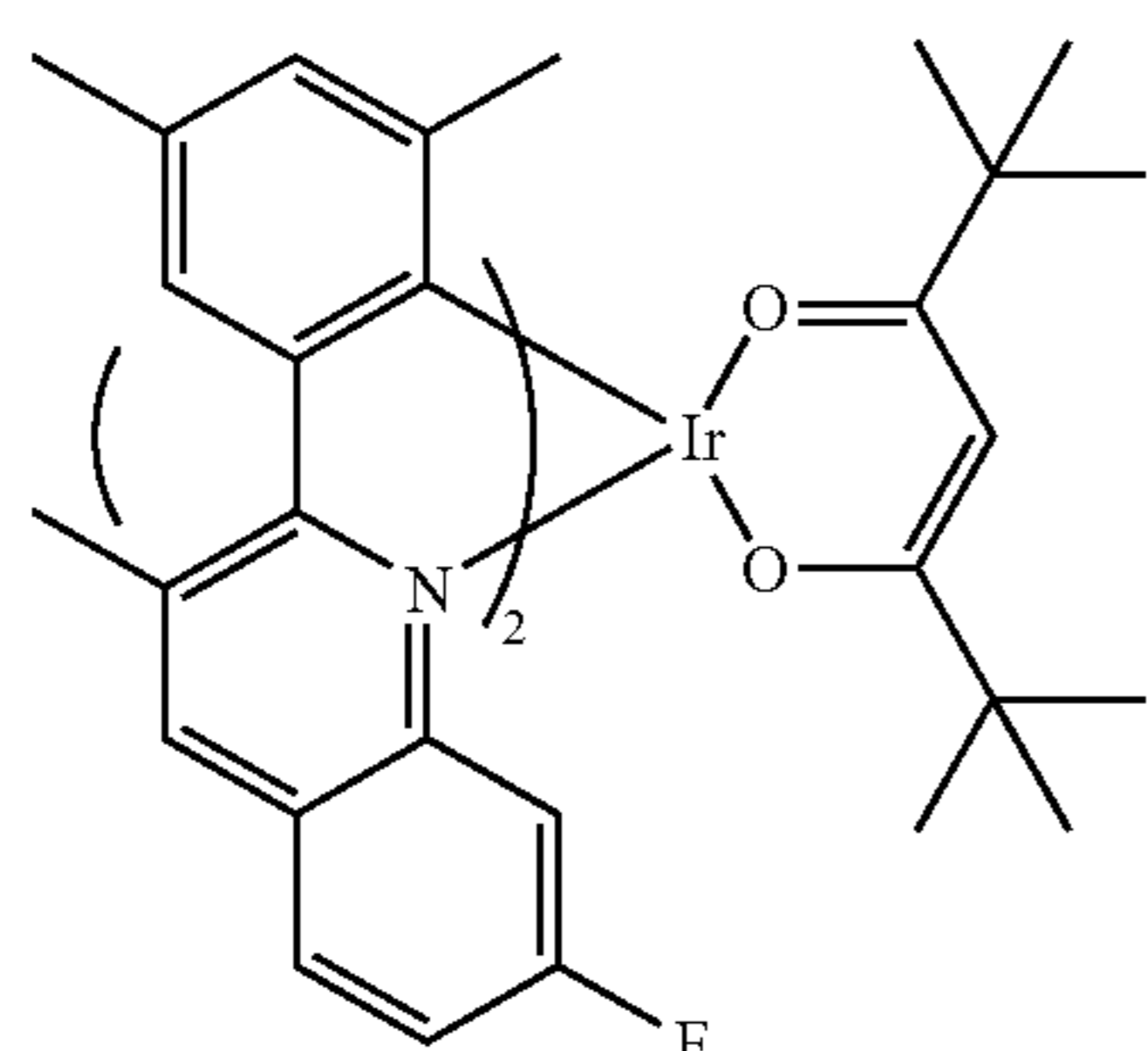
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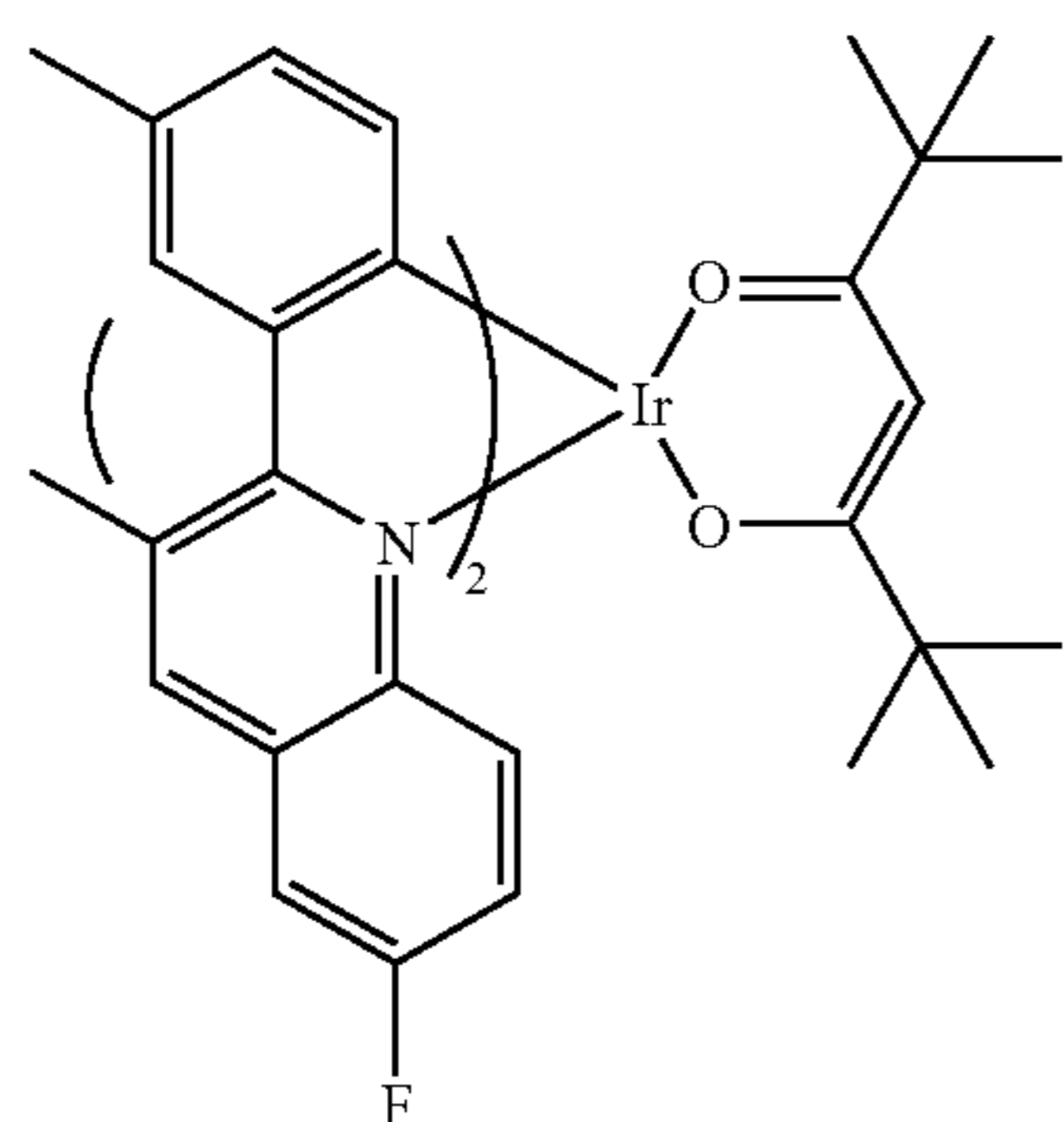
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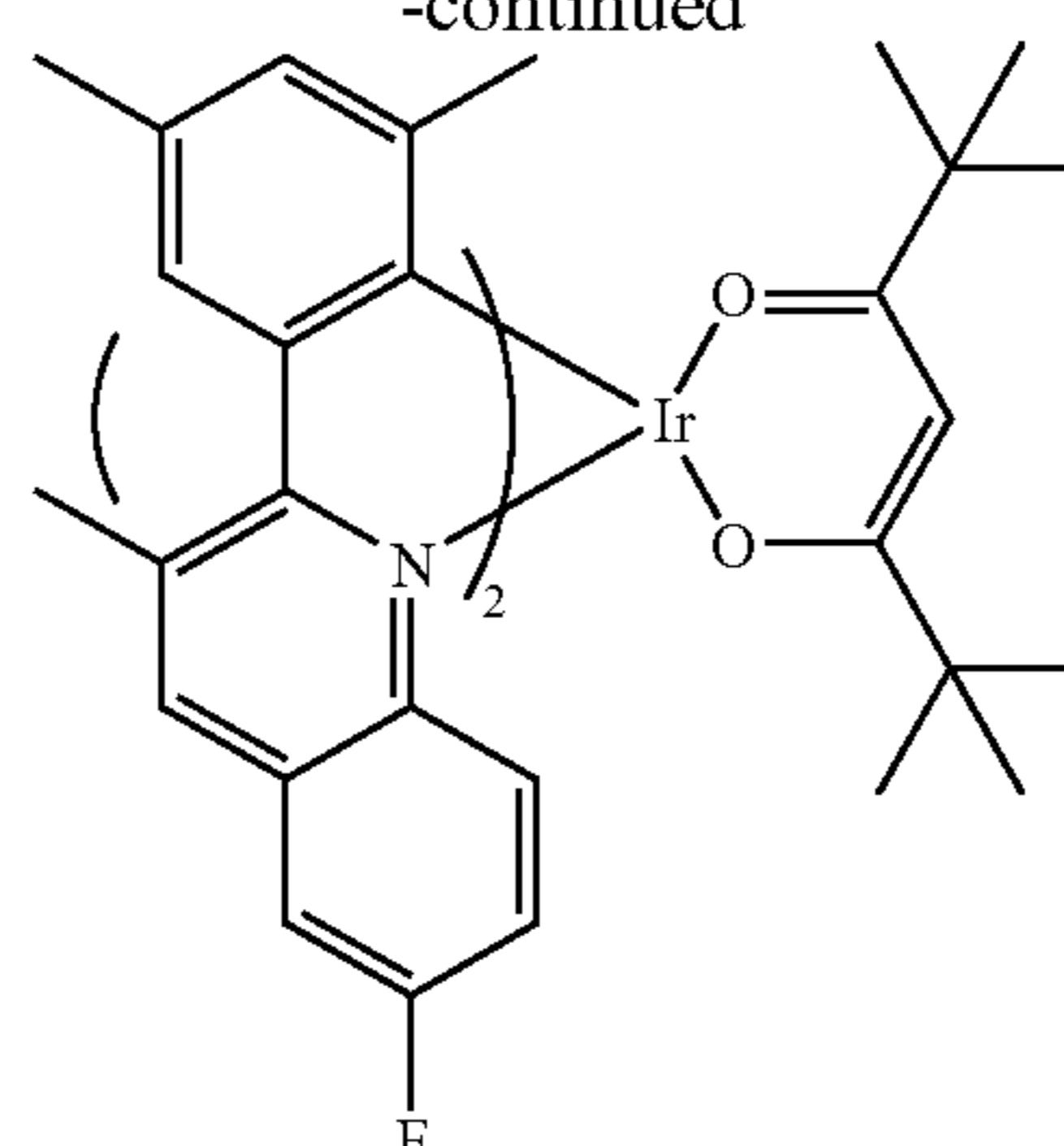
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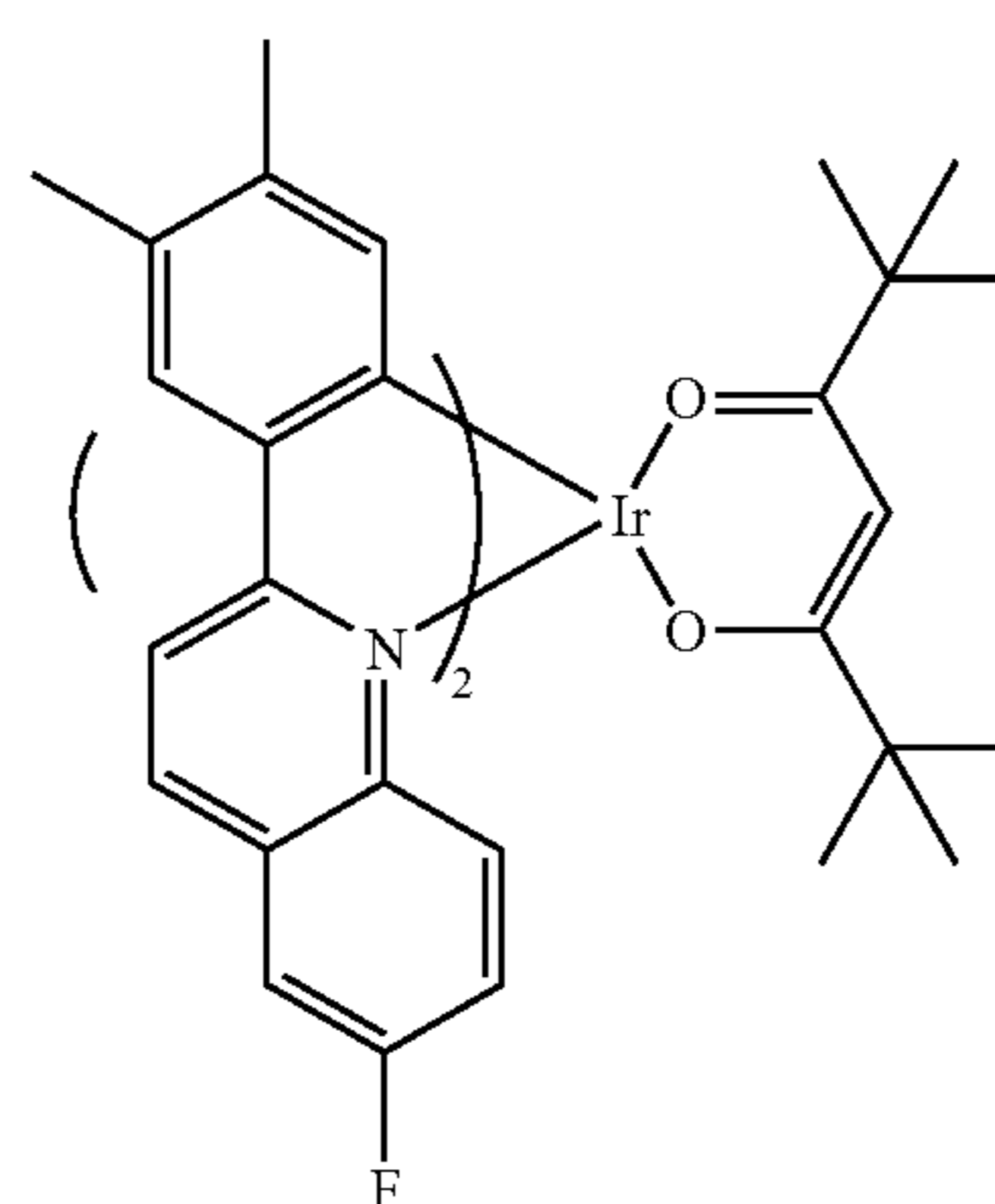
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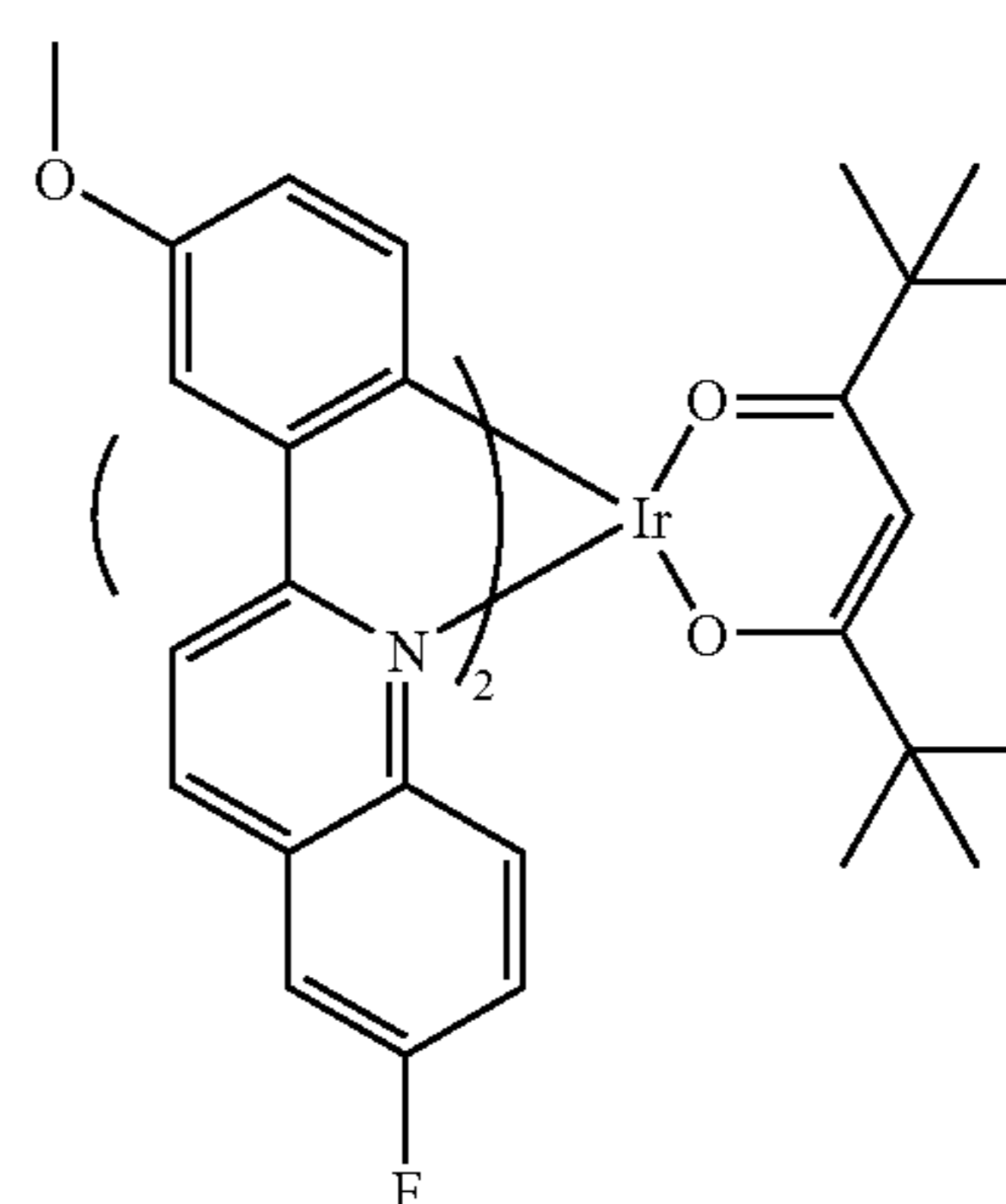
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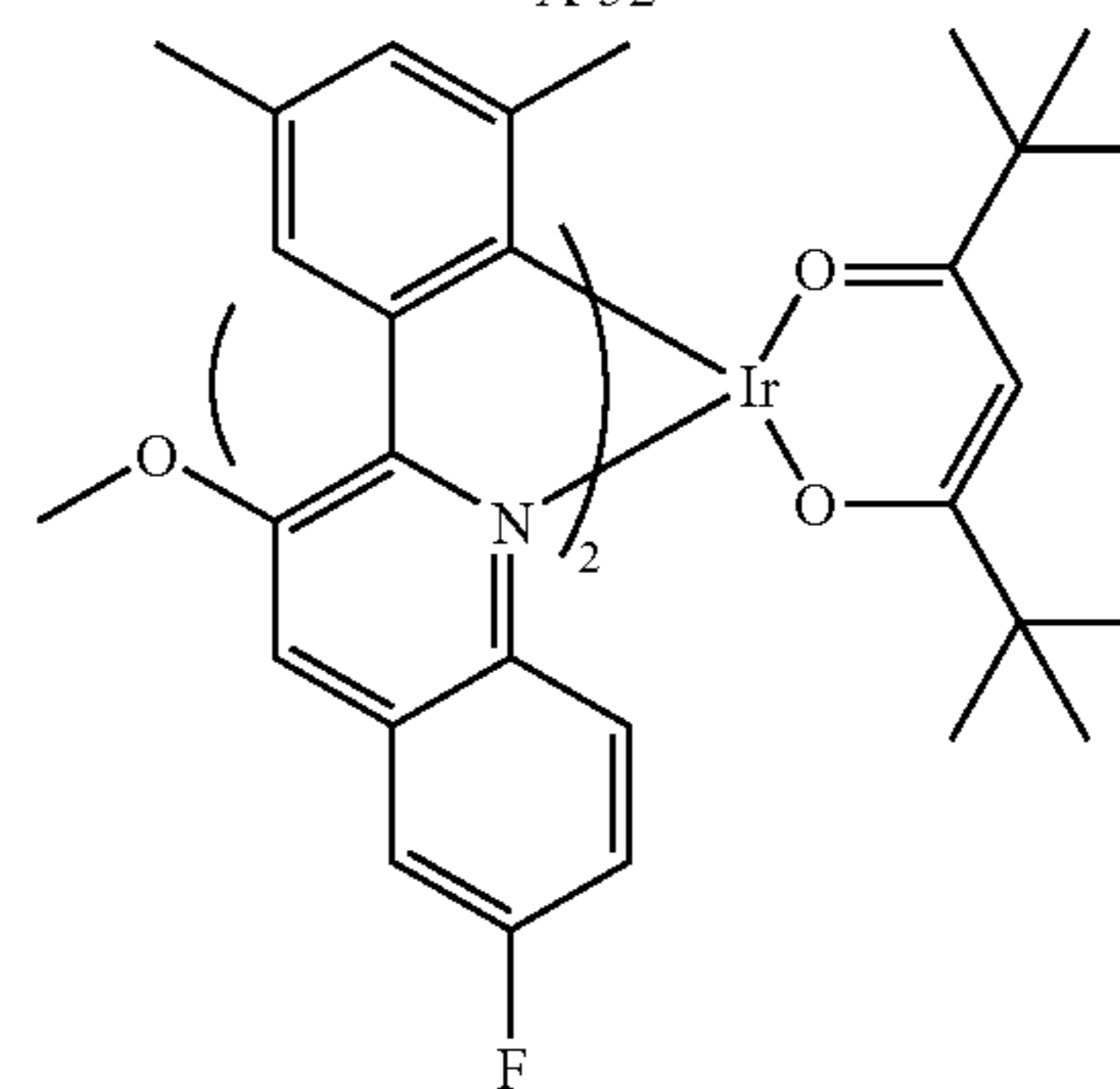
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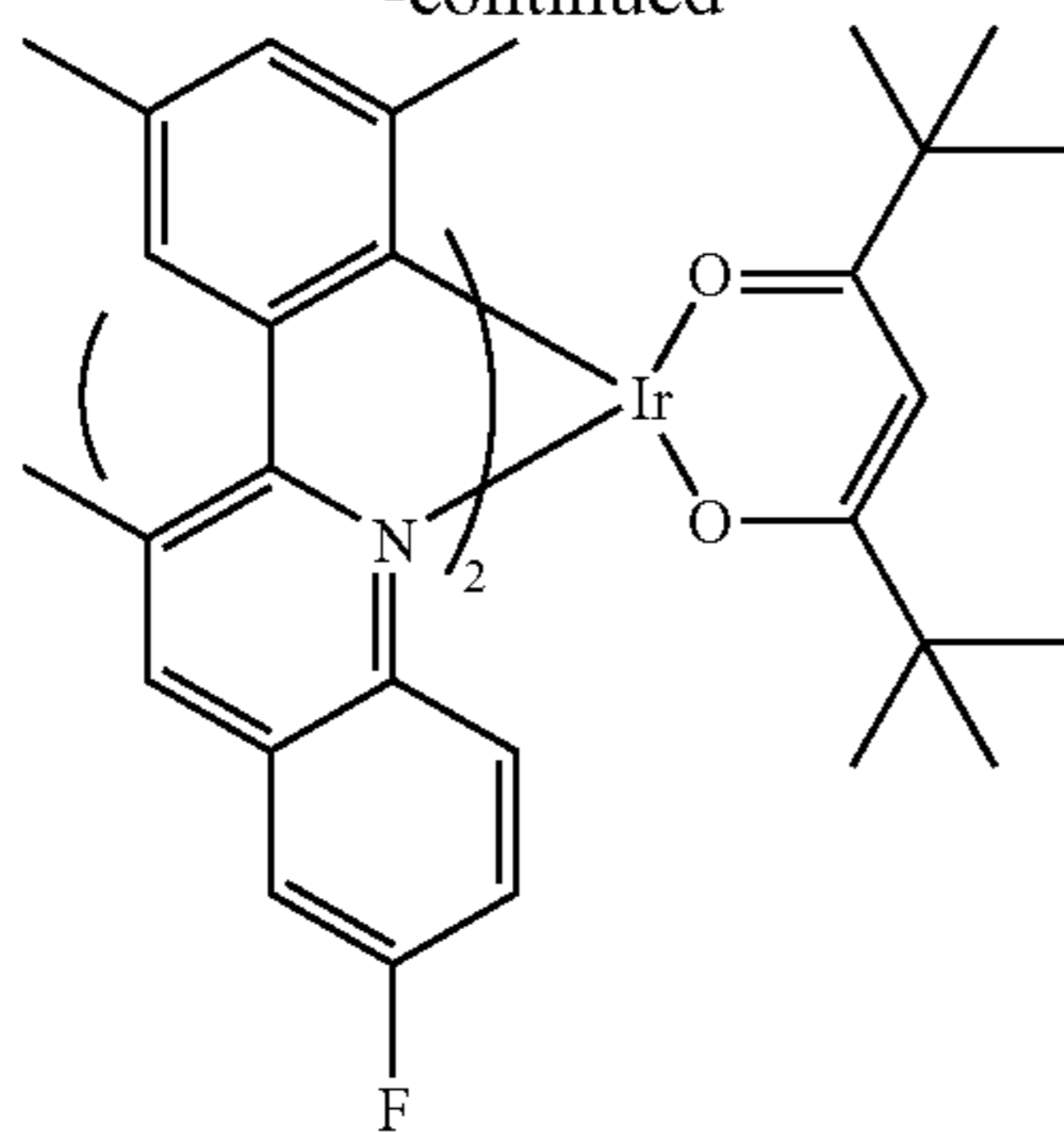
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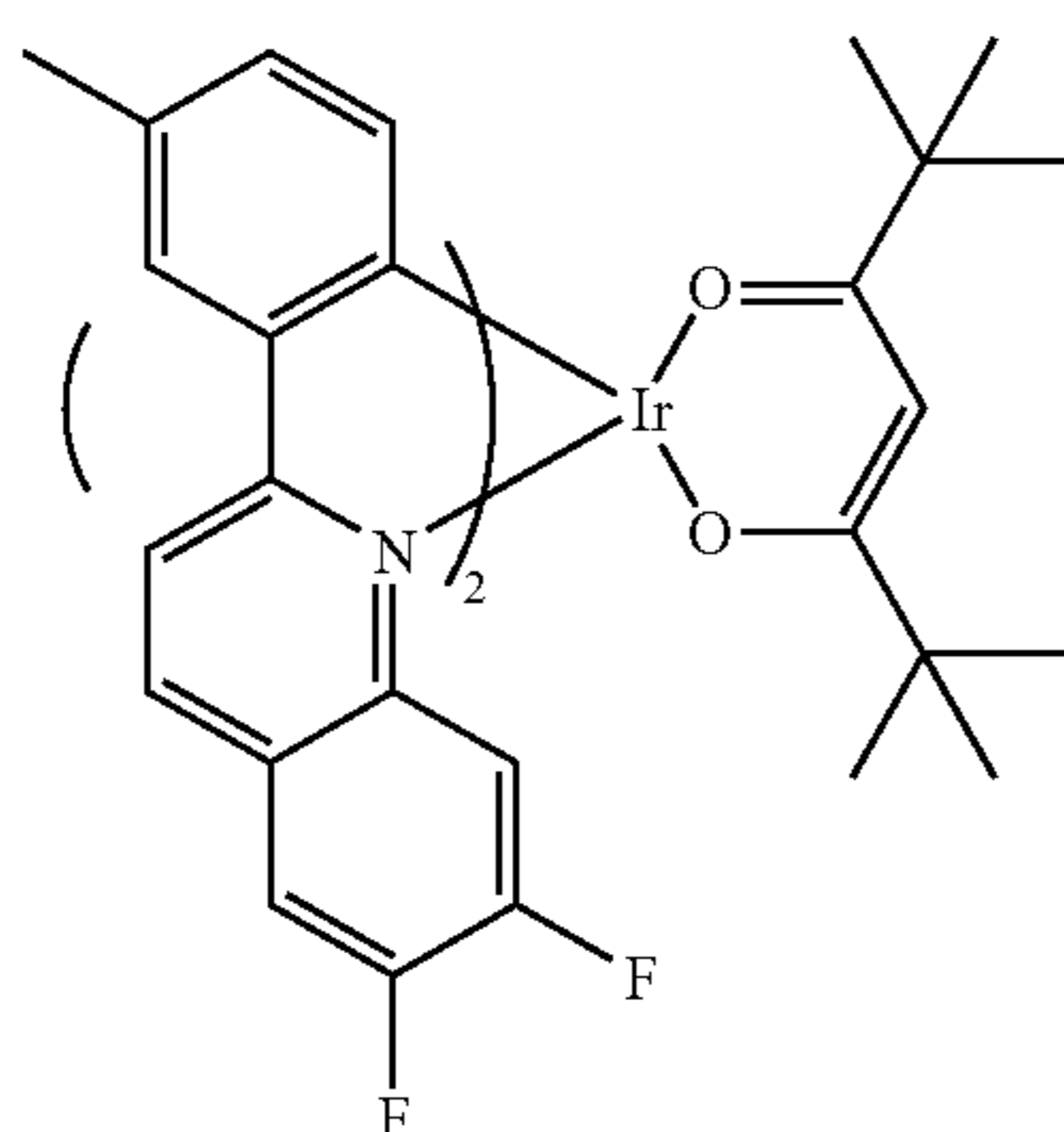


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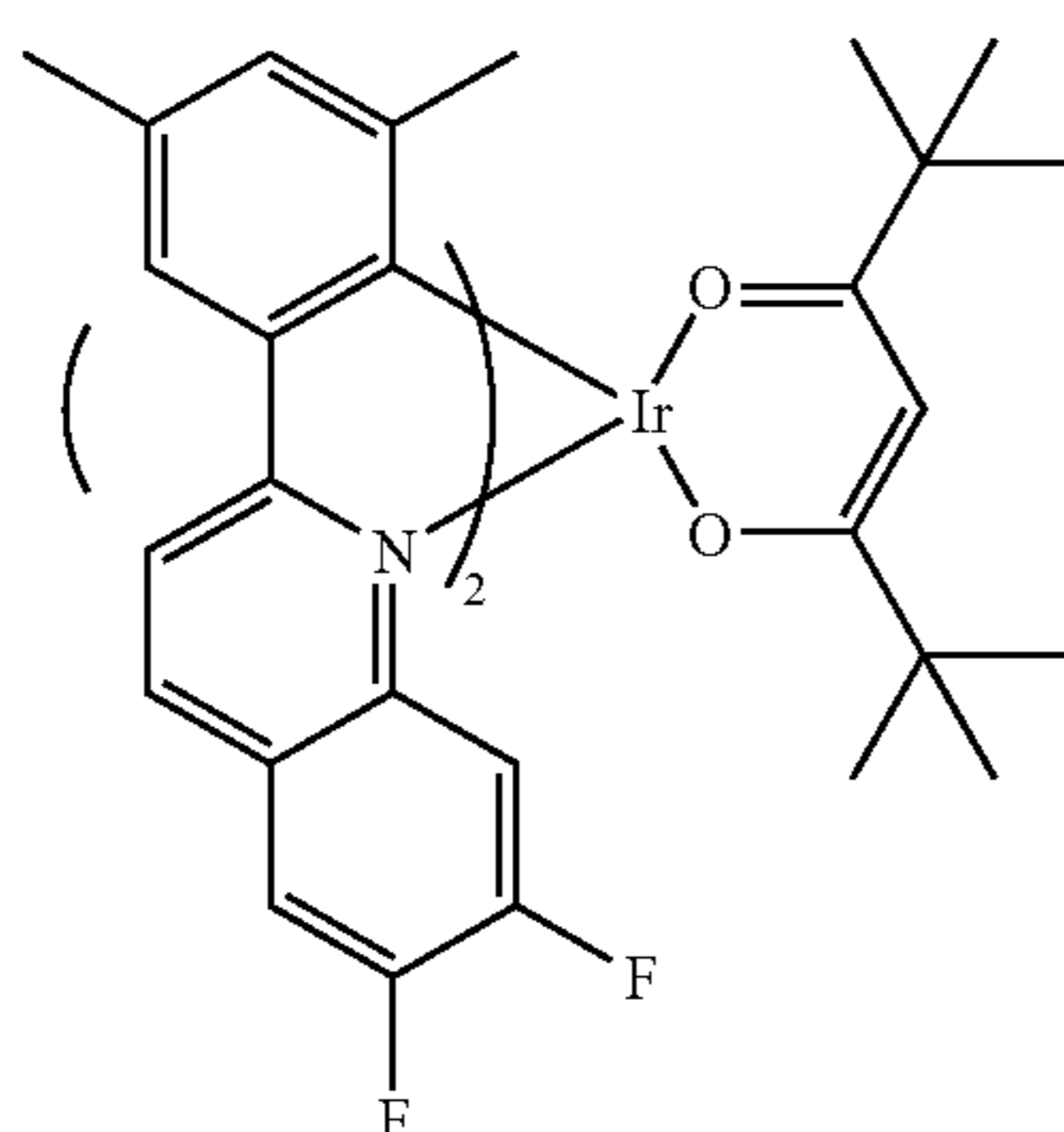
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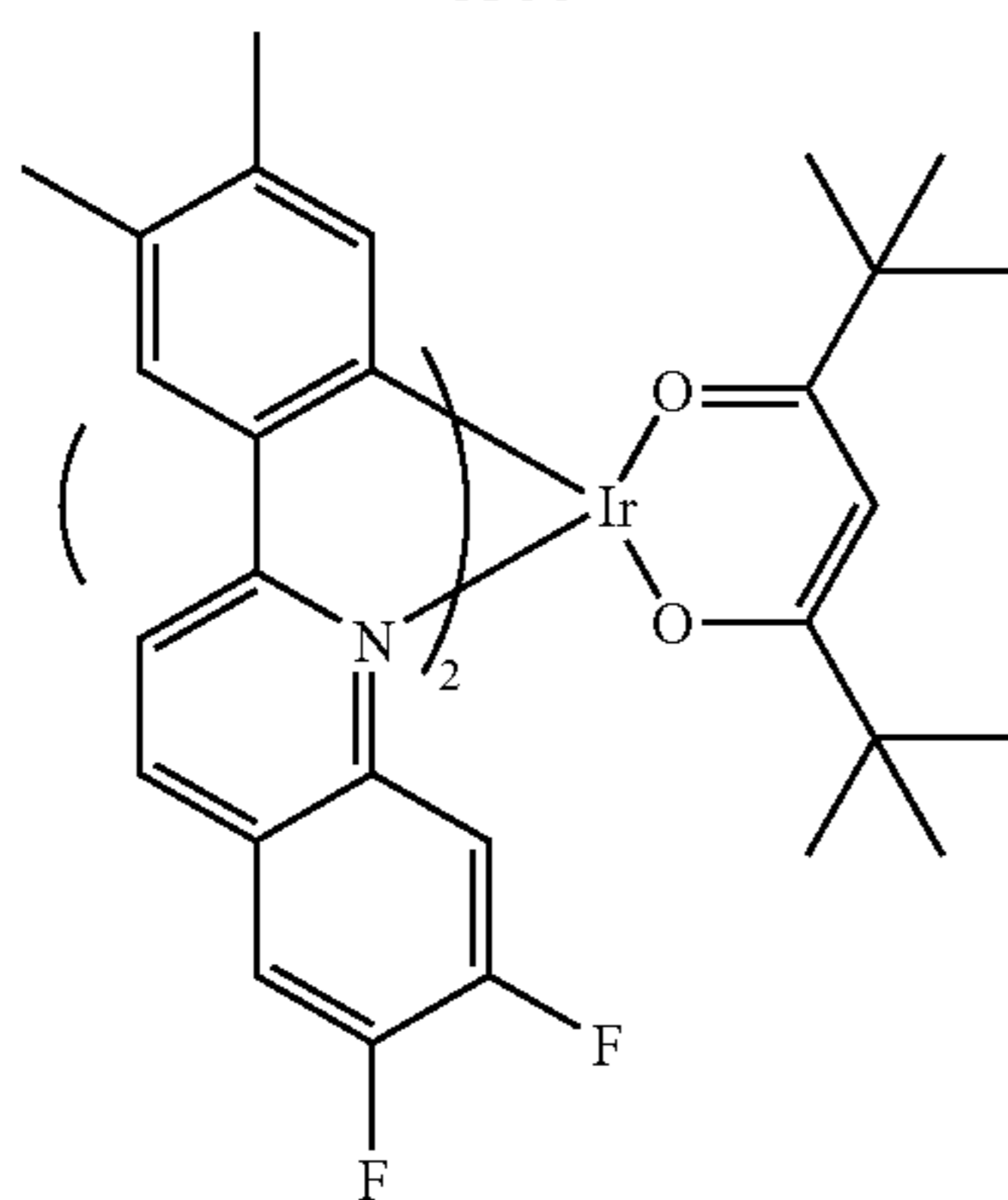
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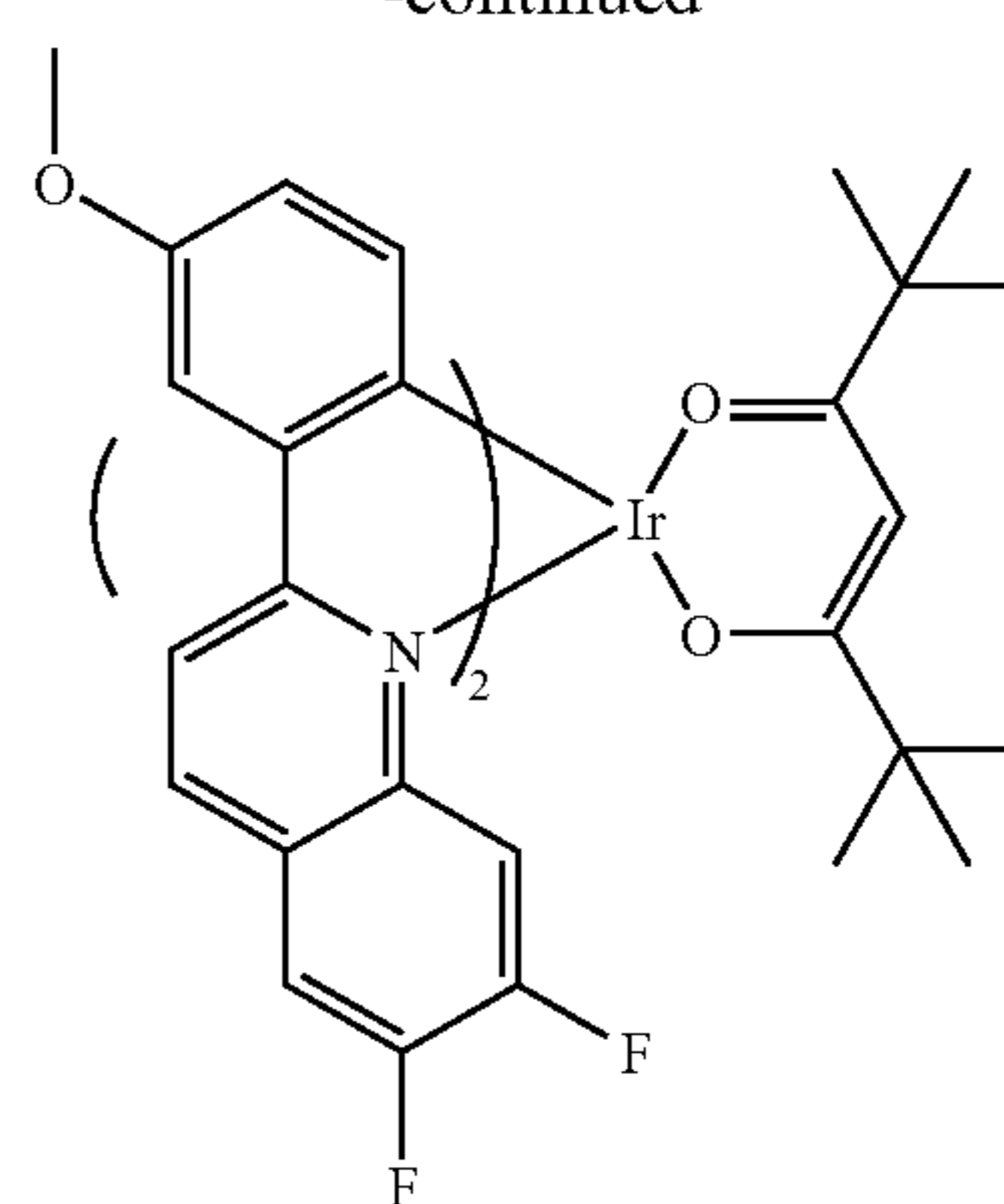
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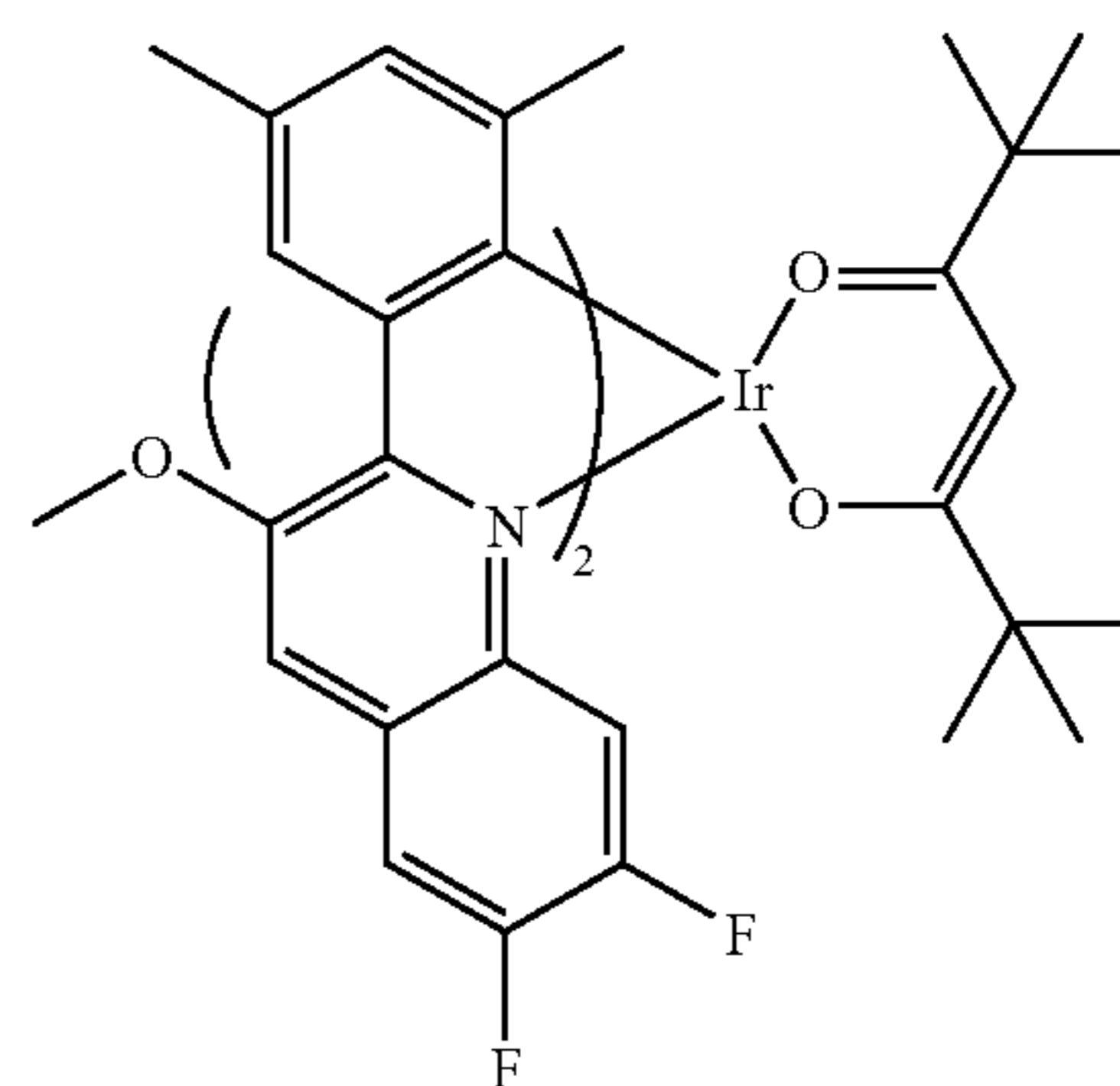
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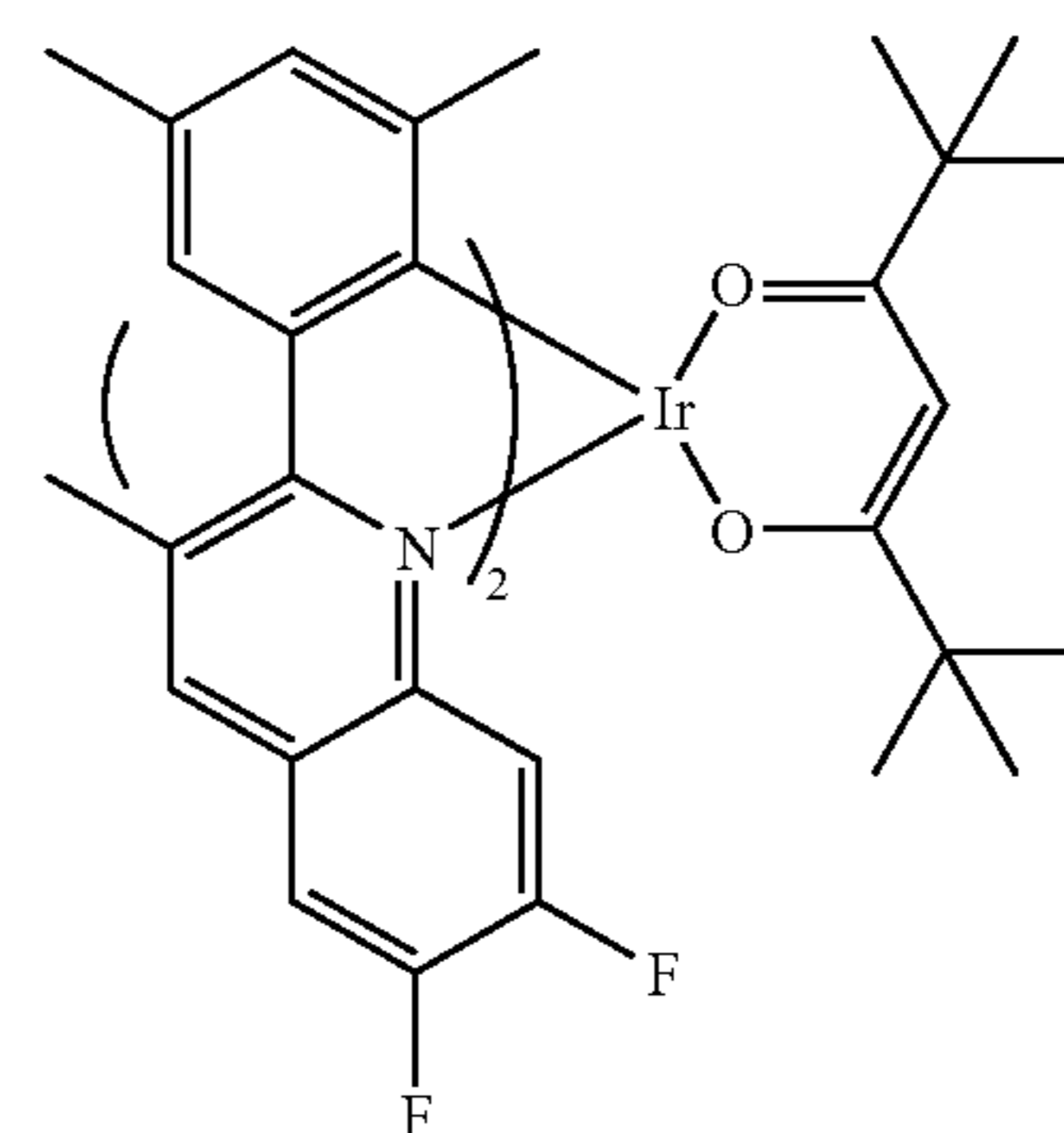
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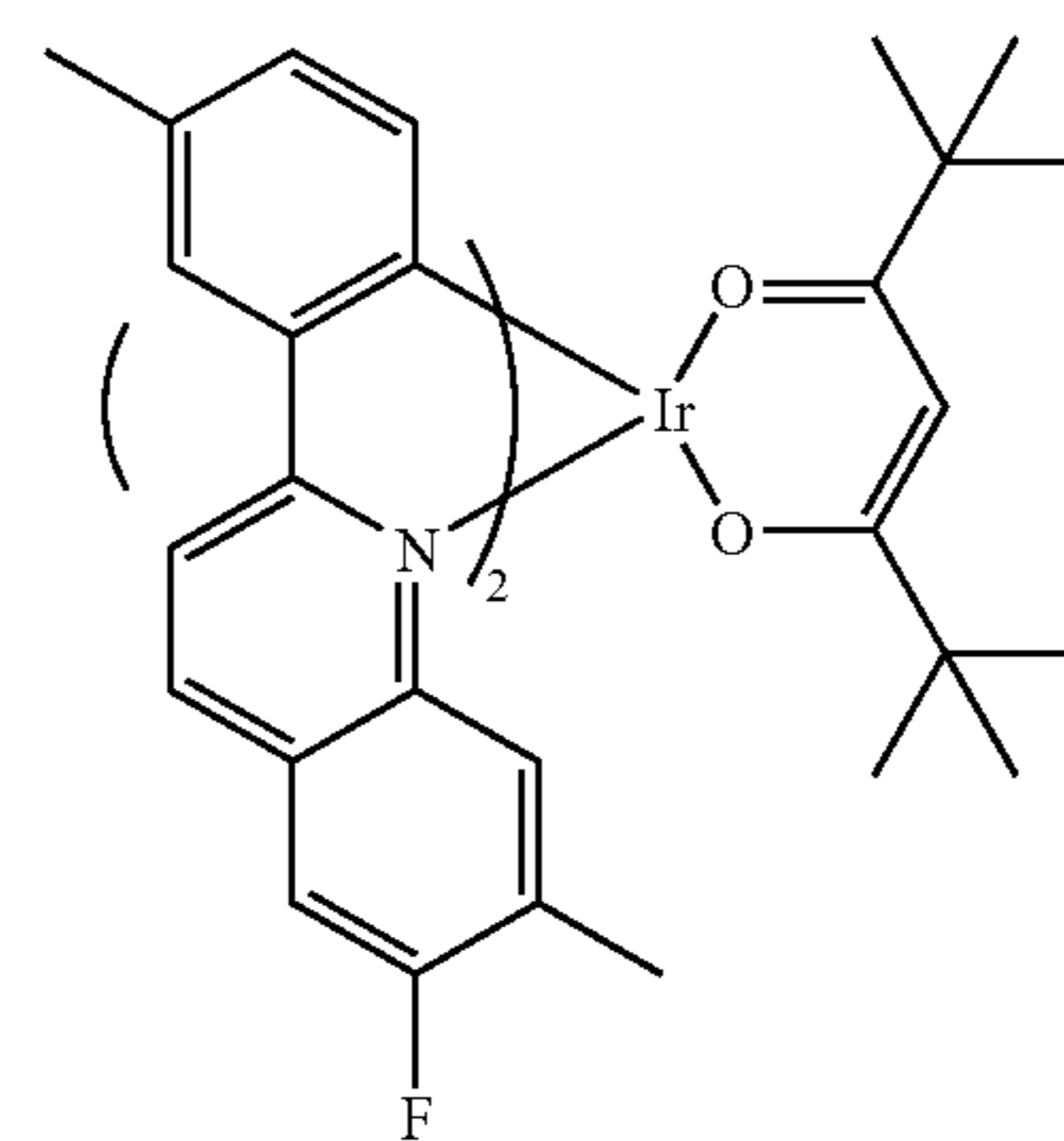
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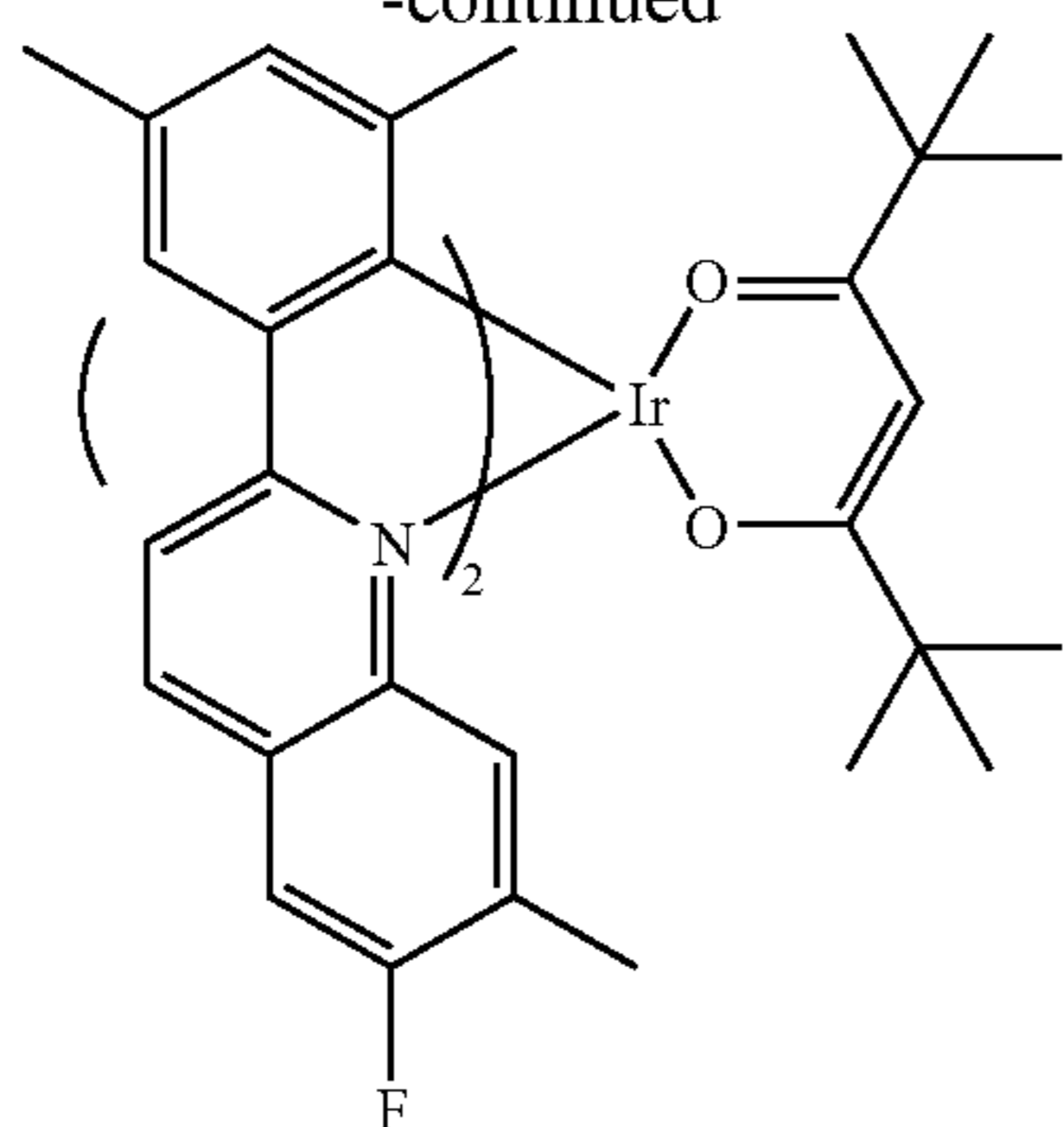
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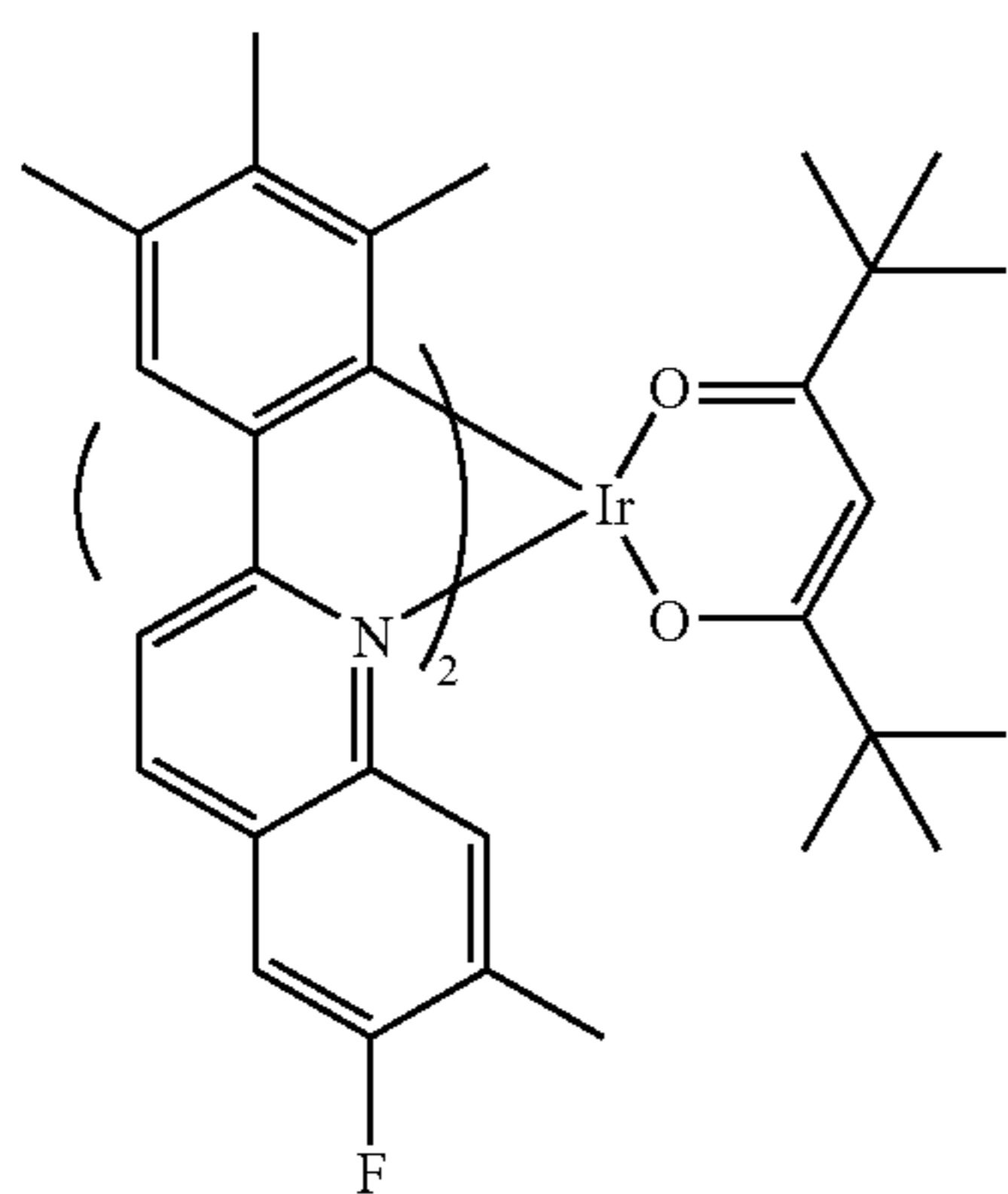
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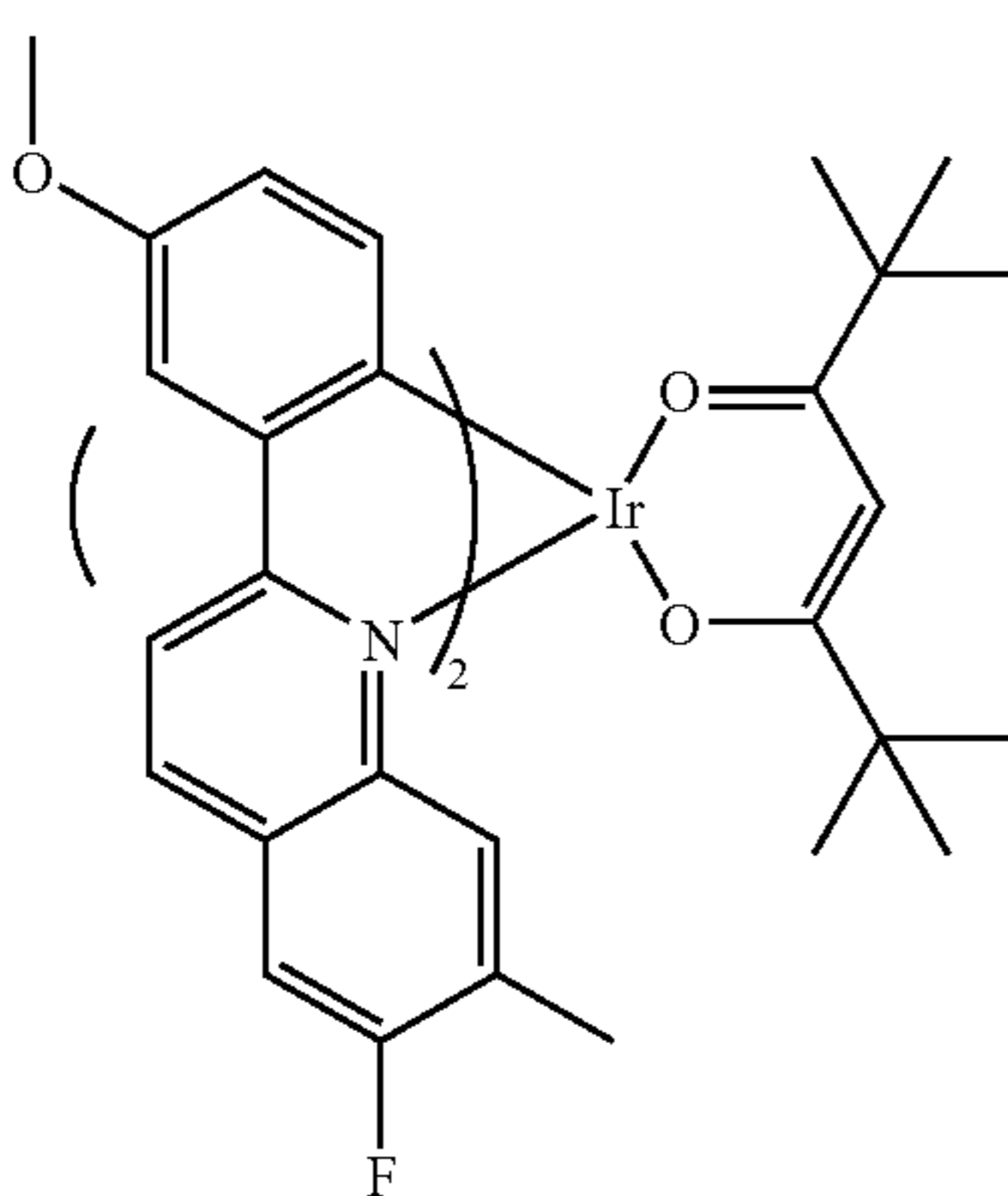
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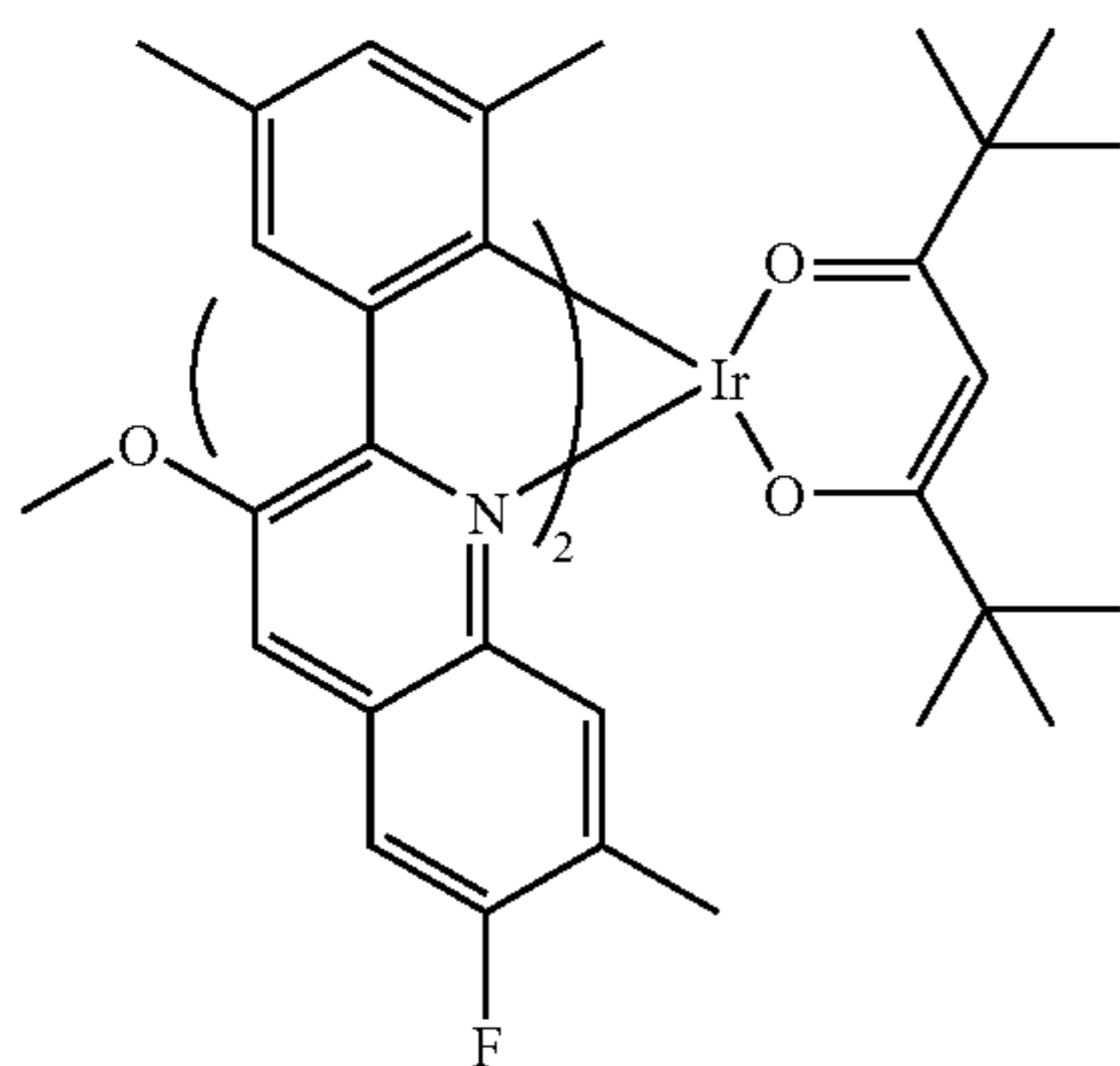
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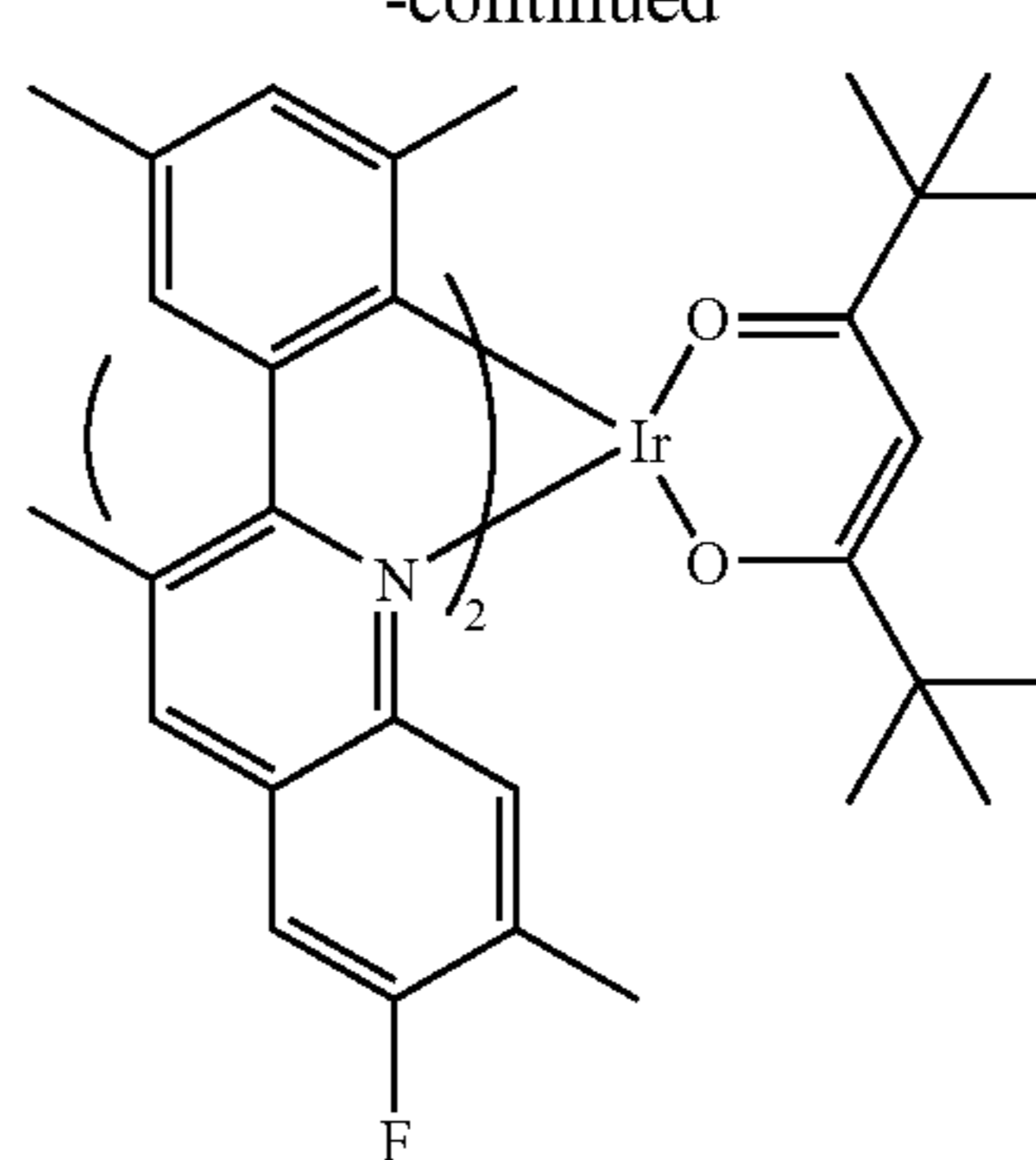
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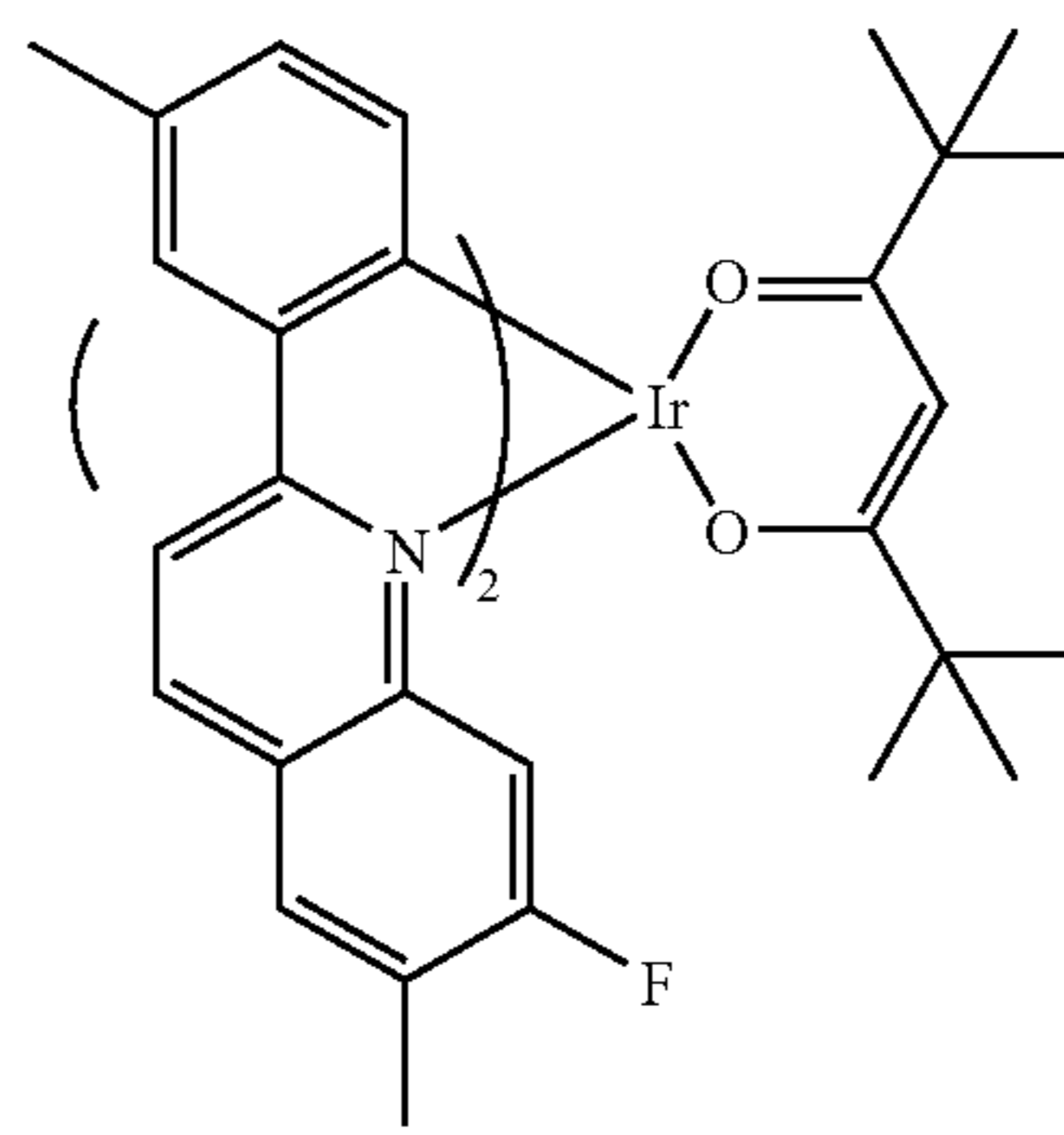
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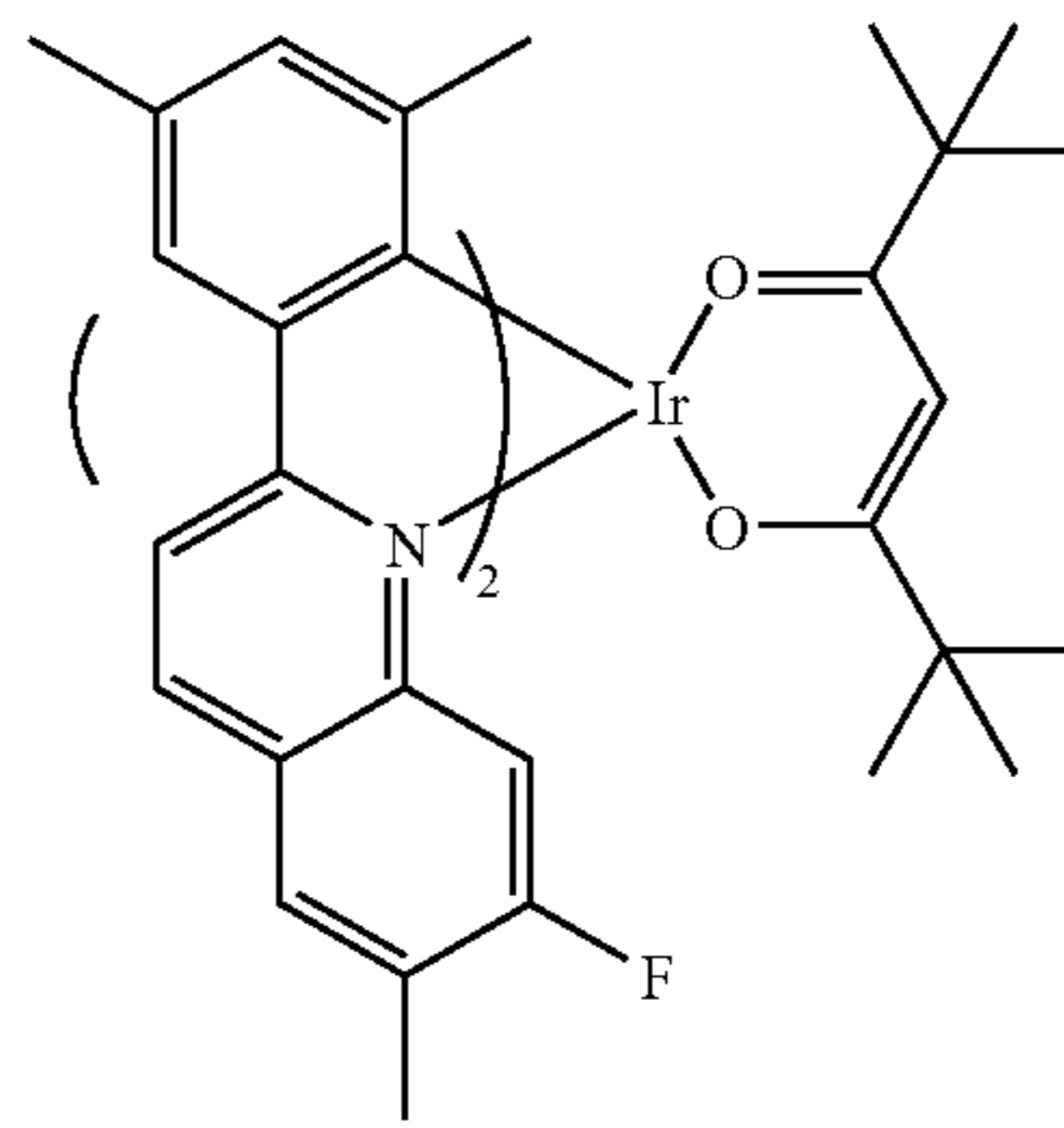
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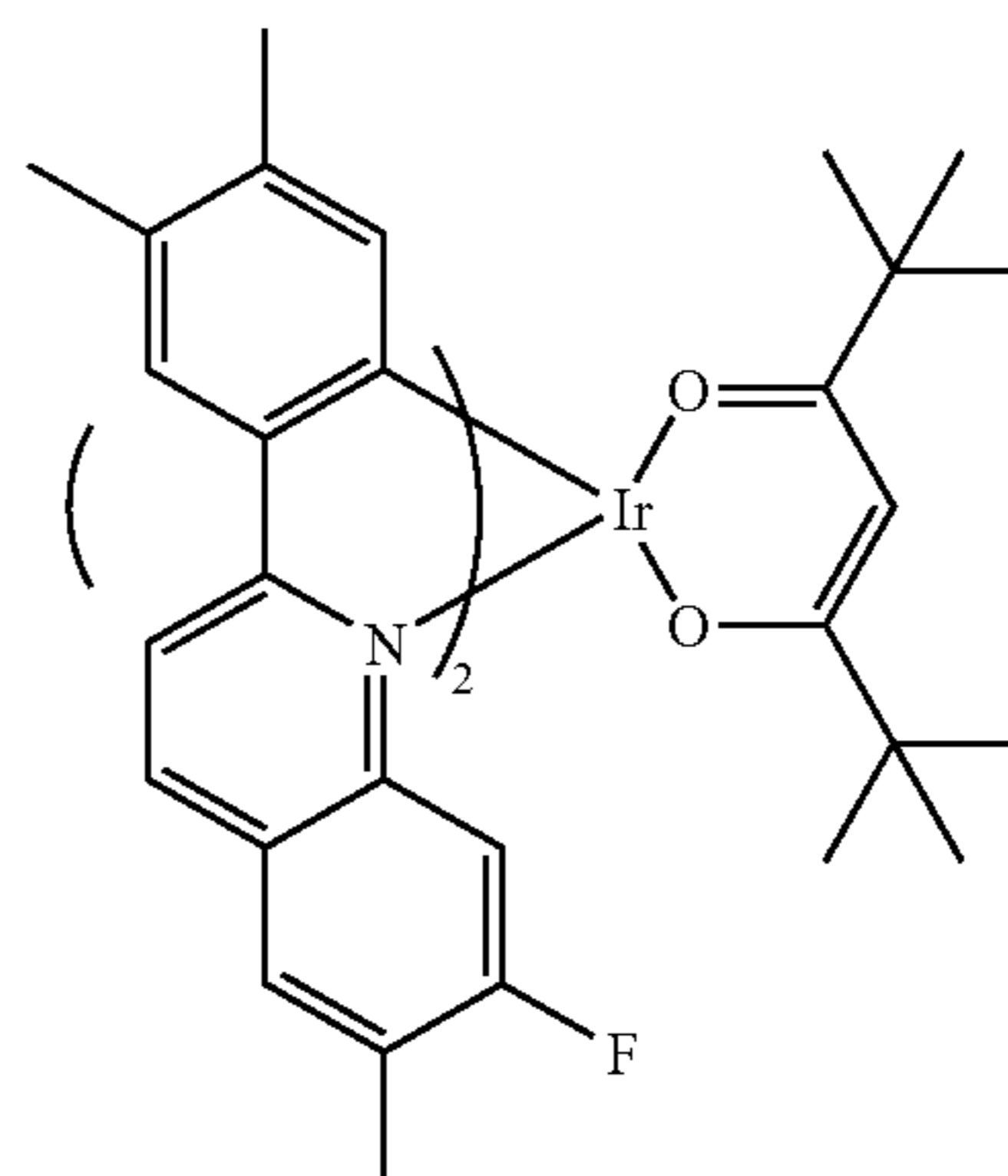
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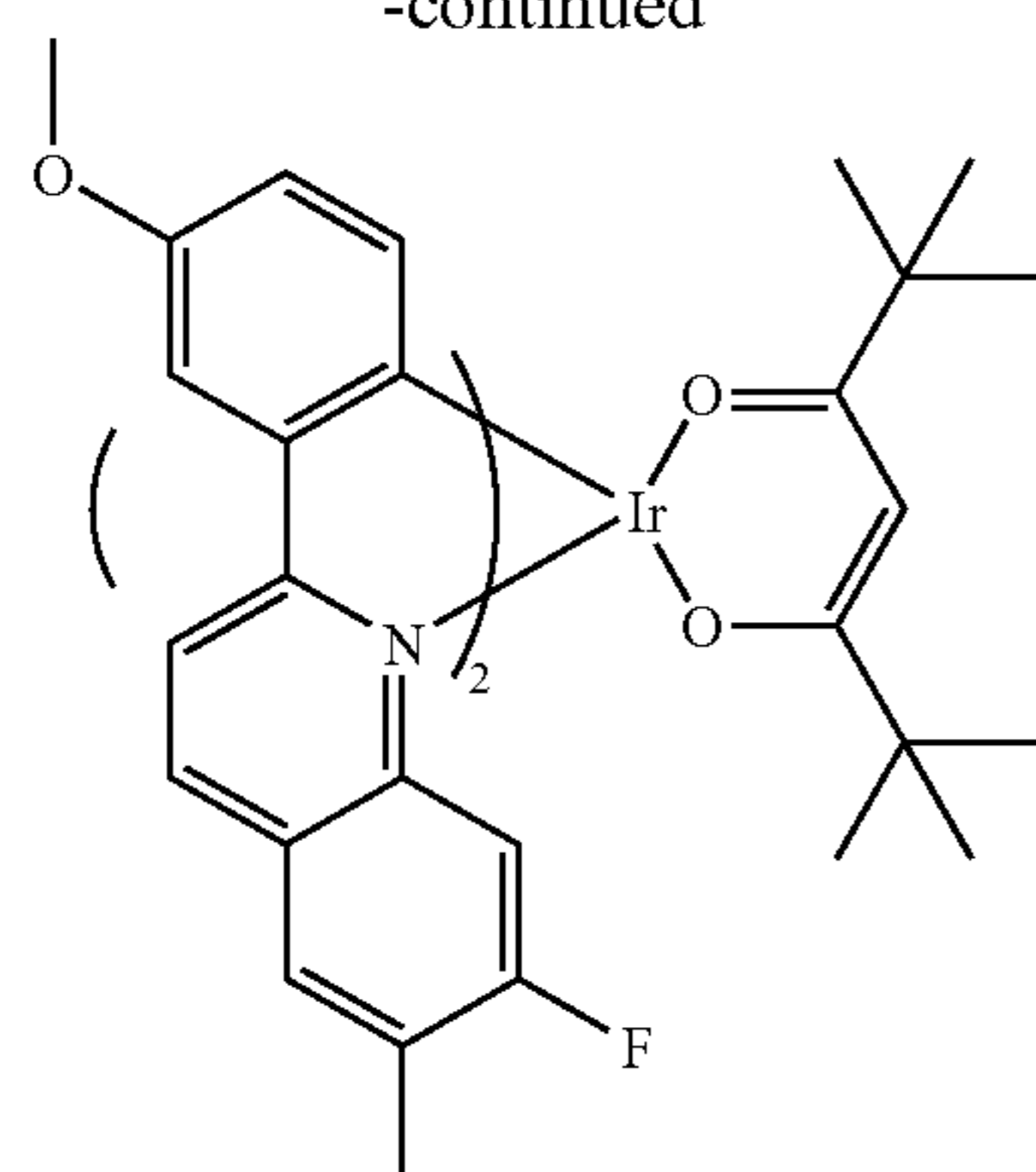
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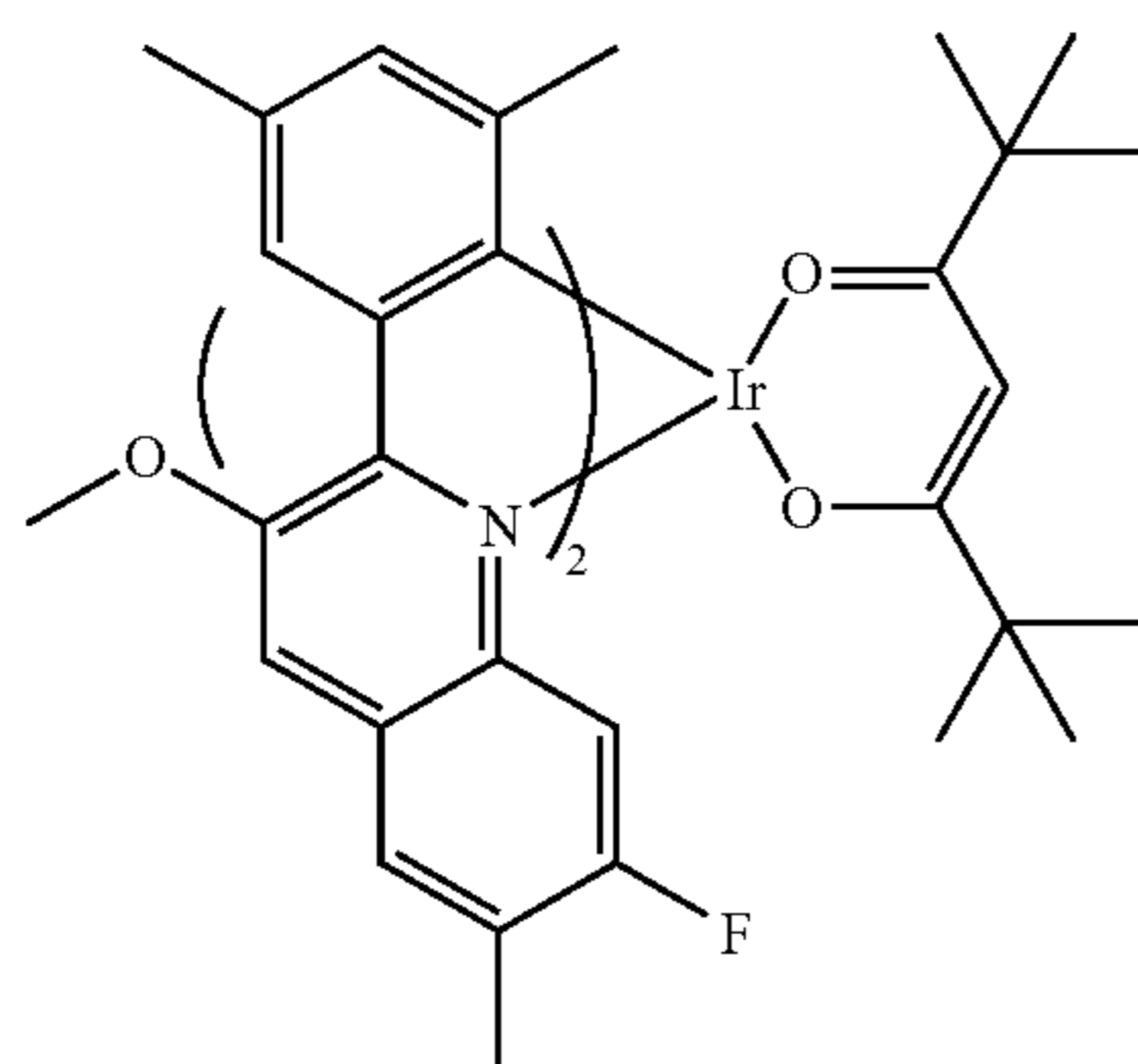
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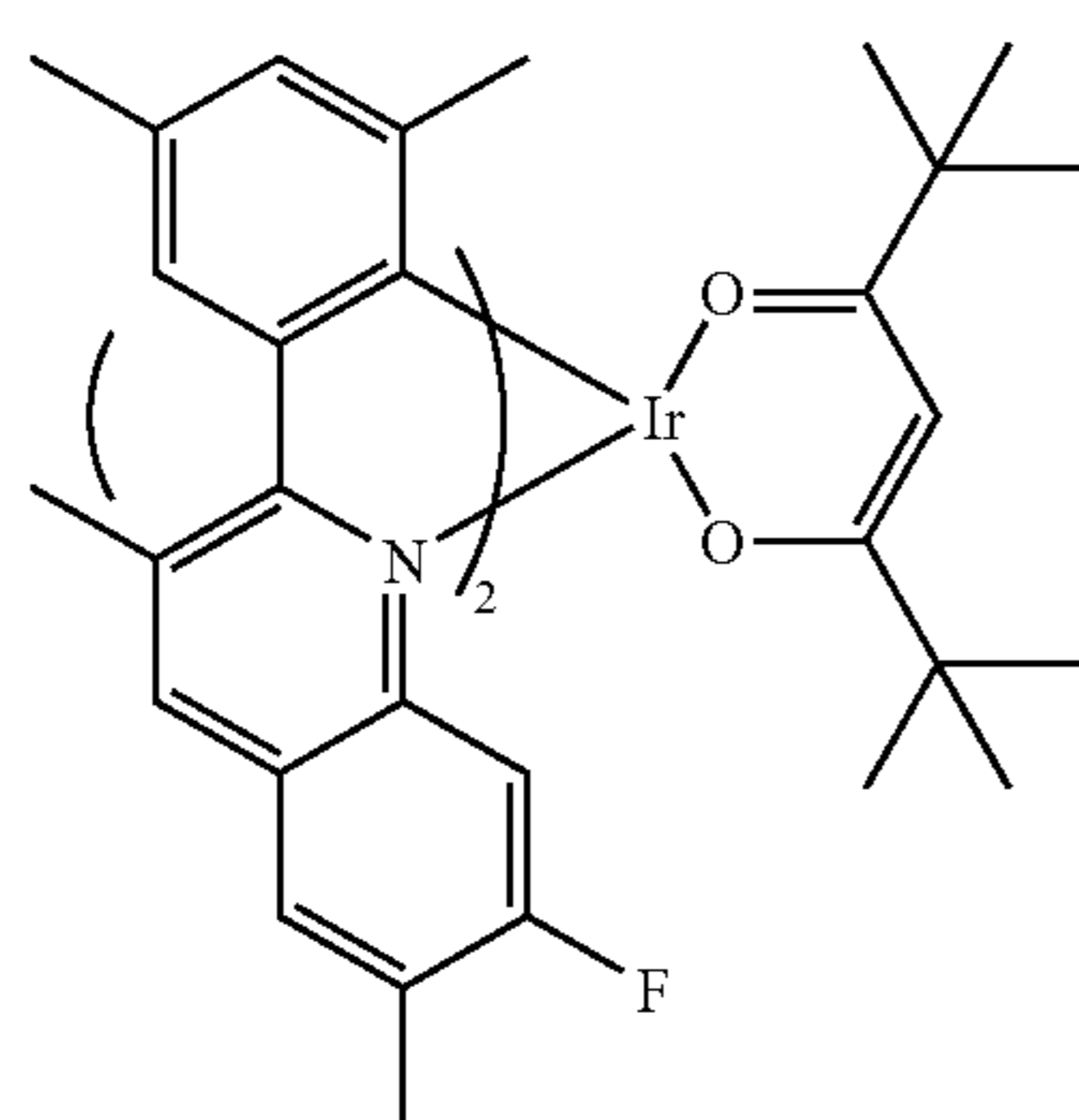
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## SYNTHESIS EXAMPLE

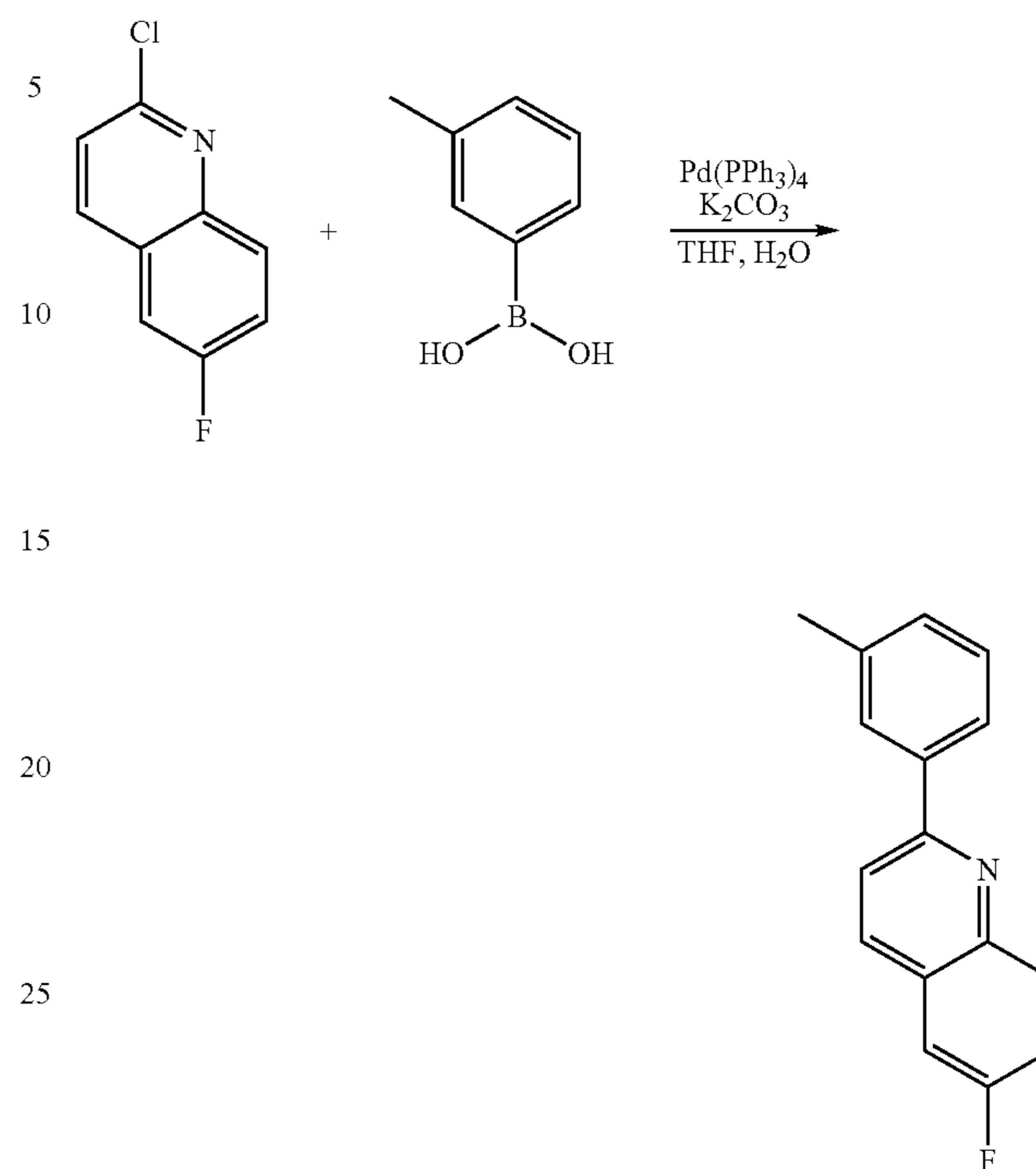
A synthesis example of the red phosphorescent compound represented by A-1 in the Formula 5 is explained. The red phosphorescent compound of A-1 is iridium(III){2-(3-methylphenyl)-6-fluoroquinoline-N,C<sup>2'</sup>}(2,4-pentanedionate)-0,0).

## 1. Synthesis of 2-(3-methylphenyl)-6-fluoroquinoline

2-(3-methylphenyl)-6-fluoroquinoline is synthesized by following Reaction Formula 1.

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[Reaction Formula 1]

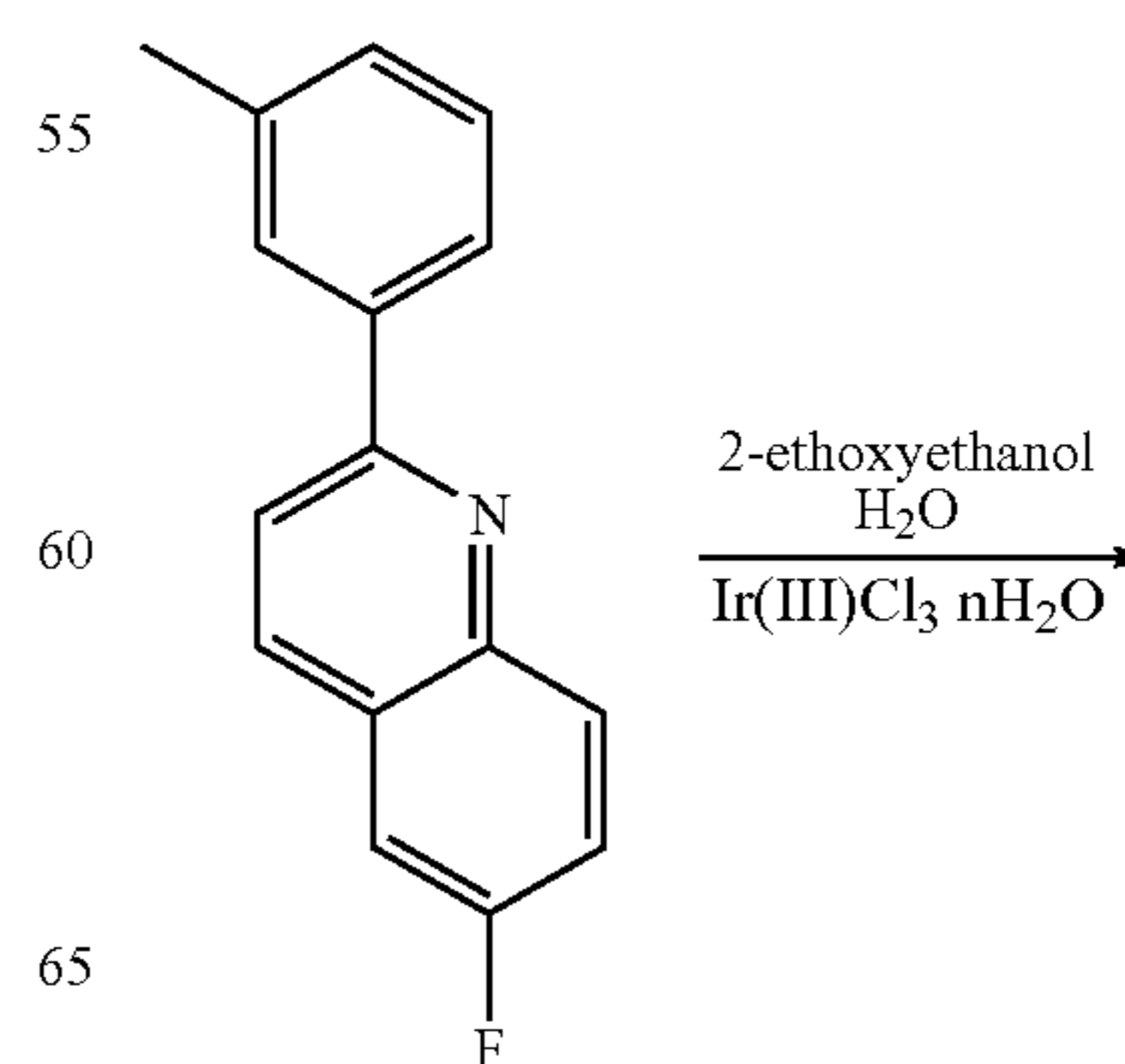


3-methylphenyl boronic acid (13 mmol), 2-chloro-6-fluoroquinoline (10 mmol), tetrakis(triphenylphosphine)palladium(0) (0.5 mmol) and potassium carbonate (15 g) are put in a two-neck round-bottom flask and dissolved in tetrahydrofuran (THF) (30 mL) and H<sub>2</sub>O (10 mL). Subsequently, the resulting solution is stirred in a bath under a temperature of about 100° C. for 24 hours. After completion of the reaction, THF and toluene are removed. The reaction mixture is extracted with dichloromethane and water, and then being distilled under reduced pressure. The resulting residue is filtered by silica gel column and distilled under reduced pressure again. Next, by re-crystallizing and filtering, 2-(3-methylphenyl)-6-fluoroquinoline (1.9 g) is yielded.

## 2. Synthesis of Chloro-Bridged Dimer Complex

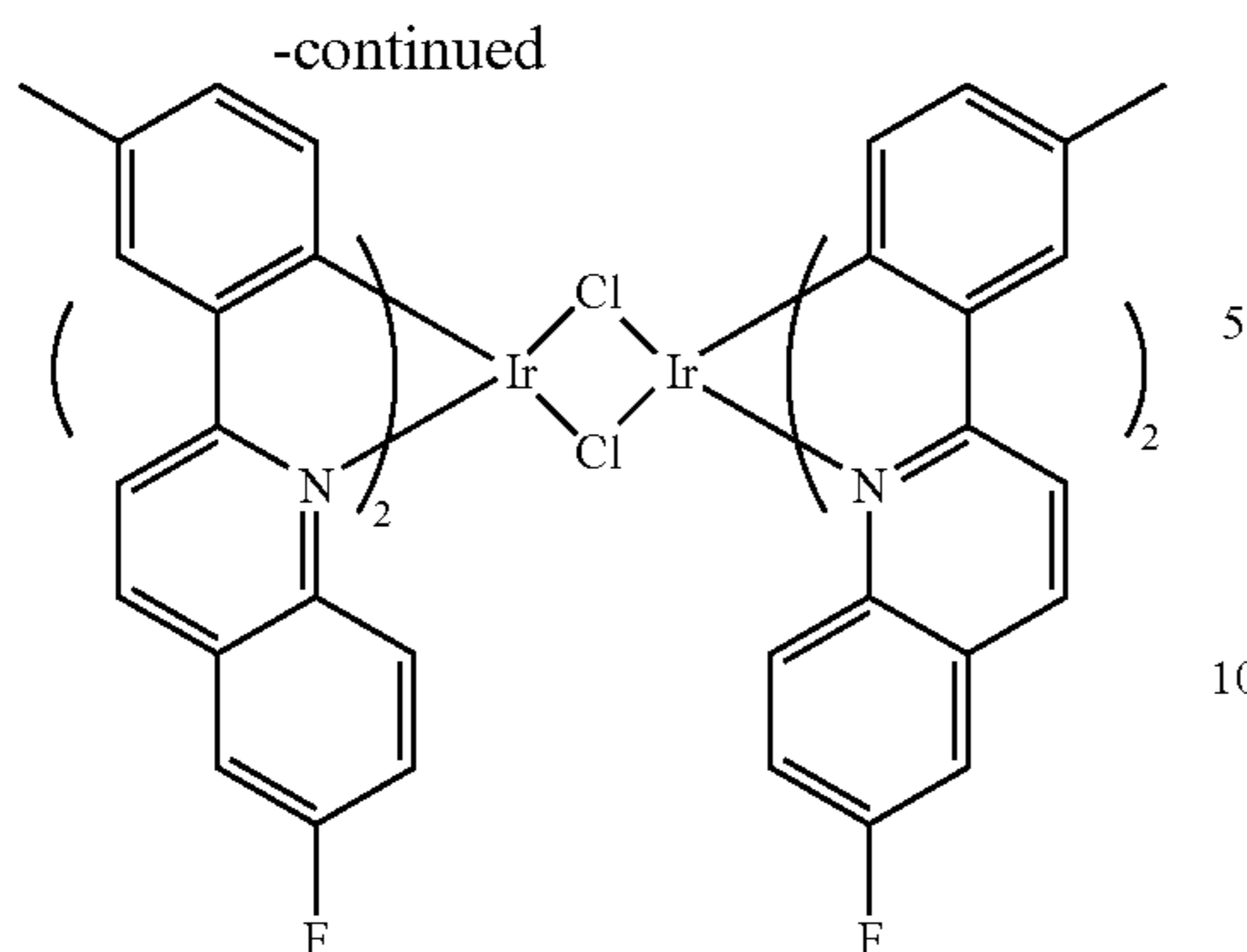
Chloro-bridged dimer complex is synthesized by following Reaction Formula 2.

[Reaction Formula 2]





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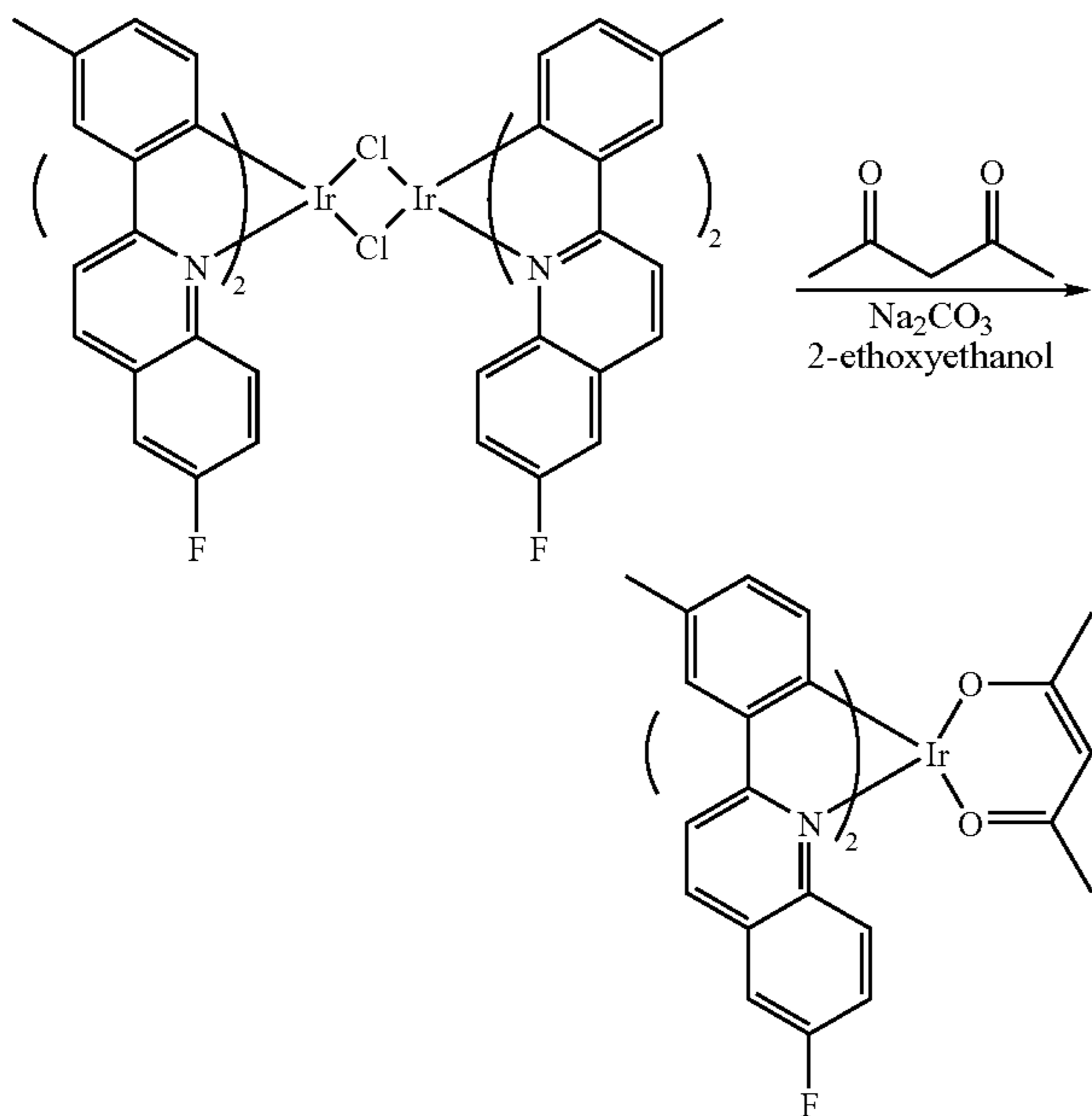


Iridium chloride (5 mmol) and 2-(3-methylphenyl)-6-fluoroquinoline (10 mmol) is put in a mixed solvent (30 mL), where a ratio of 2-ethoxyethanol to distilled water is 3:1. The mixture is refluxed for 24 hours, and water is added thereto. The resulting solid is filtered and washed by distilled water to yield chloro-bridged dimer complex.

### 3. Synthesis of iridium(III){2-(3-methylphenyl)-6-fluoroquinoline-N,C2'}(2,4-pentanedionate-0,0)

Iridium(III){2-(3-methylphenyl)-6-fluoroquinoline-N,C2'}(2,4-pentanedionate-0,0) is synthesized by following Reaction Formula 3.

[Reaction Formula 3]



Chloro-bridged dimer complex (1 mmol), 2,4-pentanedione (3 mmol) and sodium carbonate ( $\text{Na}_2\text{CO}_3$ ) (6 mmol) is put in 2-ethoxyethanol (30 mL), and is refluxed. The resulted mixture is cooled to a room temperature, and then distilled water is added thereto. The mixture is filtered. The resulted solid is dissolved in dichloromethane, and then is filtered by silica gel column. By re-crystallizing the resulted solution using dichloromethane and methanol to yield iridium(III){2-(3-methylphenyl)-6-fluoroquinoline-N,C2'}(2,4-pentanedionate-0,0).

Hereinafter, a detailed description will be made of preferred examples associated with the OLED according to the

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present invention. More specifically, the examples relate to an OLED including an emission material layer which uses the red phosphorescent compound of formula 2 as a dopant.

### Example 1

An indium-tin-oxide (ITO) layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), 4,4'-bis[N-(1-naphthyl-N-phenylamino)]-biphenyl (NPD) (about 400 angstroms), aluminum(III)bis(2-methyl-8-quinolino)4-phenylphenolate (BALq)+A-1 compound (about 5 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), fluorolithium (LiF) (about 5 angstroms) and aluminum (Al) (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the A-1 red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of 1257  $\text{cd}/\text{m}^2$  at an electric current of 0.9 mA and a voltage of 5.3 V. At this time, the X index and Y index of CIE color coordinates are 0.670 and 0.324, respectively. In addition, the OLED has a lifetime of 5500 hours at 2000  $\text{cd}/\text{m}^2$ . The lifetime is defined as the time taken before the luminance of the OLED decreases to half its initial value.

### Example 2

An ITO layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), NPD (about 400 angstroms), BALq+A-7 compound (about 5 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), LiF (about 5 angstroms) and Al (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the A-7 red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of 1213  $\text{cd}/\text{m}^2$  at an electric current of 0.9 mA and a voltage of 5.3 V. At this time, the X index and Y index of CIE color coordinates are 0.674 and 0.322, respectively. In addition, the OLED has a lifetime of 4500 hours at 2000  $\text{cd}/\text{m}^2$ .

### Example 3

An ITO layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), NPD (about 400 angstroms), BALq+A-19 compound (about 5 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), LiF (about 5 angstroms) and Al (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the A-19 red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of 1512  $\text{cd}/\text{m}^2$  at an electric current of 0.9 mA and a voltage of 5.7 V. At this time, the X index and Y index of CIE color coordinates are 0.664 and 0.332, respectively. In addition, the OLED has a lifetime of 6500 hours at 2000  $\text{cd}/\text{m}^2$ .



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## Example 4

An ITO layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), NPD (about 400 angstroms), BA1q+A-24 compound (about 5 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), LiF (about 5 angstroms) and Al (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the A-24 red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of  $1023 \text{ cd/m}^2$  at an electric current of 0.9 mA and a voltage of 5.0 V. At this time, the X index and Y index of CIE color coordinates are 0.685 and 0.311, respectively. In addition, the OLED has a lifetime of 6500 hours at  $2000 \text{ cd/m}^2$ .

## Comparative Example 1

An ITO layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), NPD (about 400 angstroms), BA1q+[formula 1-1] compound (about 7 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), LiF (about 5 angstroms) and Al (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the [formula 1-1] red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of  $1173 \text{ cd/m}^2$  at an electric current of 0.9 mA and a voltage of 6.0 V. At this time, the X index and Y index of CIE color coordinates are 0.606 and 0.375, respectively. In addition, the OLED has a lifetime of 4000 hours at  $2000 \text{ cd/m}^2$ .

## Comparative Example 2

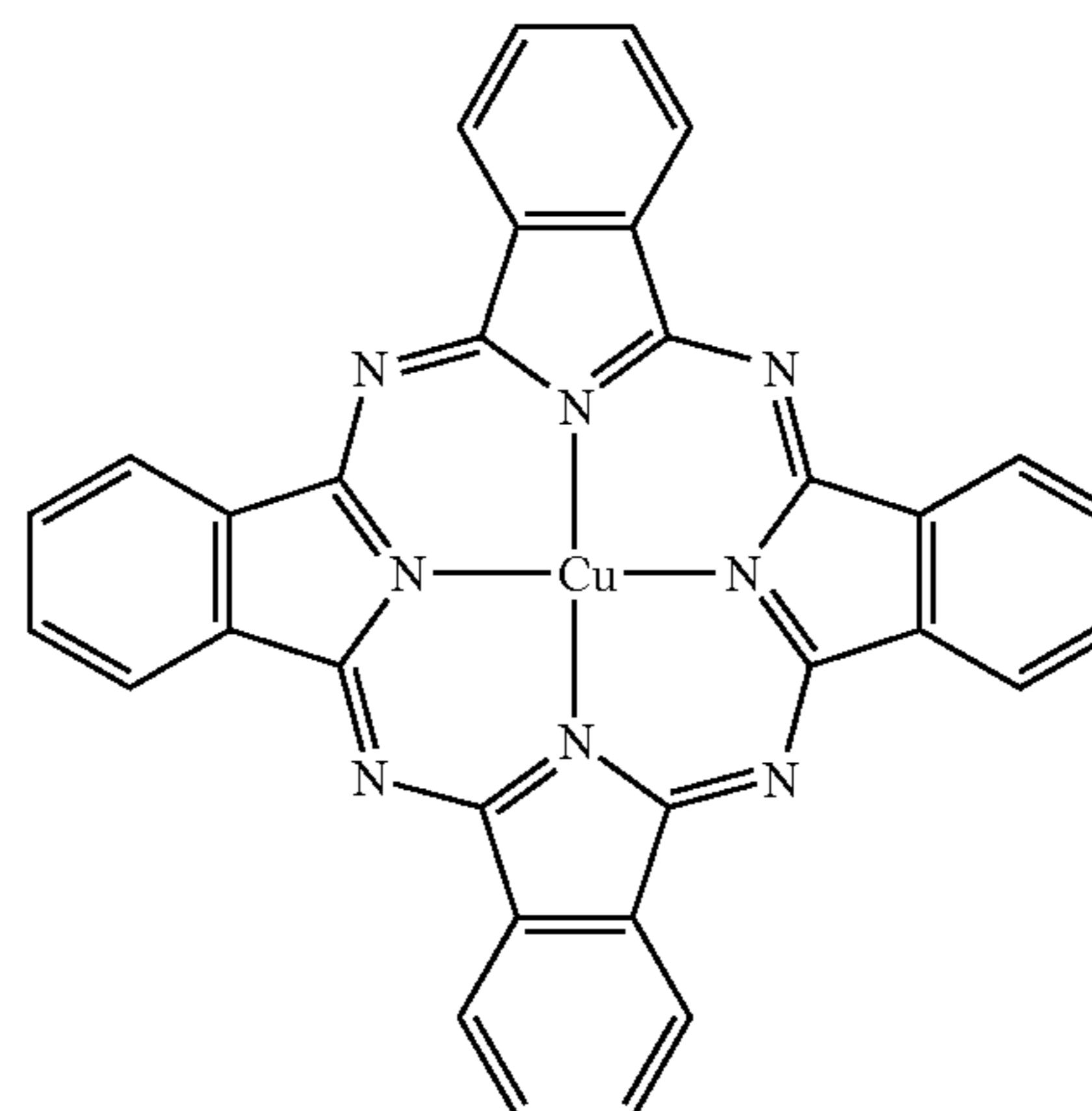
An ITO layer is patterned on a substrate and washed such that an emission area of the ITO layer is 3 mm\*3 mm. The substrate is loaded in a vacuum chamber, and the process pressure is adjusted to  $1 \times 10^{-6}$  torr. CuPC (about 200 angstroms), NPD (about 400 angstroms), BA1q+[formula 1-2] compound (about 7 weight %) (about 200 angstroms), Alq3 (about 300 angstroms), LiF (about 5 angstroms) and Al (about 1000 angstroms) are sequentially formed on the ITO layer such that an OLED is fabricated.

When the [formula 1-2] red phosphorescent compound is used as a dopant for an emission layer, the OLED produce a brightness of  $780 \text{ cd/m}^2$  at an electric current of 0.9 mA and a voltage of 7.5 V. At this time, the X index and Y index of CIE color coordinates are 0.659 and 0.329, respectively. In addition, the OLED has a lifetime of 2500 hours at  $2000 \text{ cd/m}^2$ .

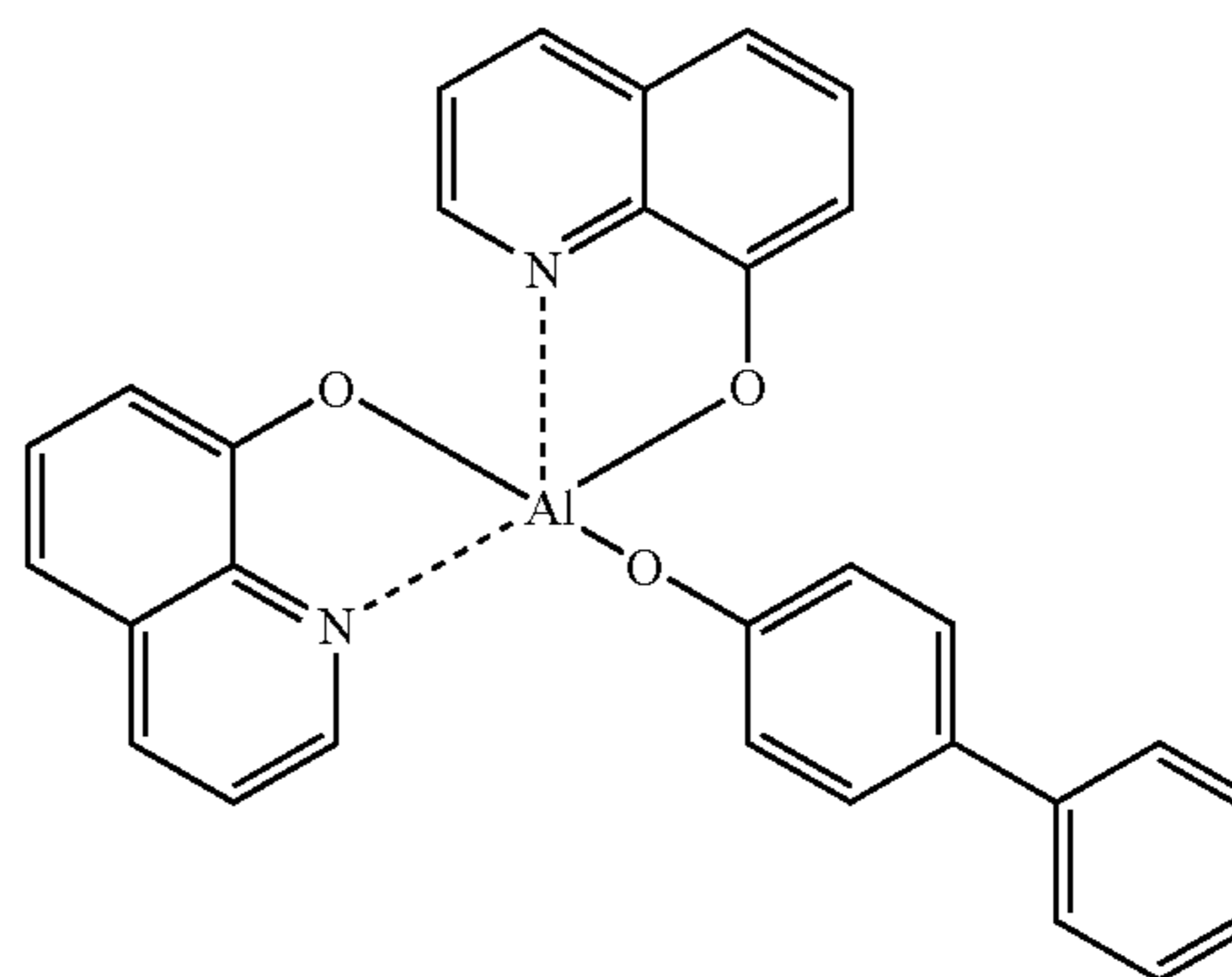
Herein, CuPC, BA1q, Alq3 are represented by following Formulas 6 to 8, respectively. BA1q is used for an emission material layer. However, the emission material layer may be formed of other materials. For example, Al metallic complex, zinc (Zn) metallic complex or CBP may be used for the emission material layer. CBP is a carbazole derivatives and represented by following Formula 9.

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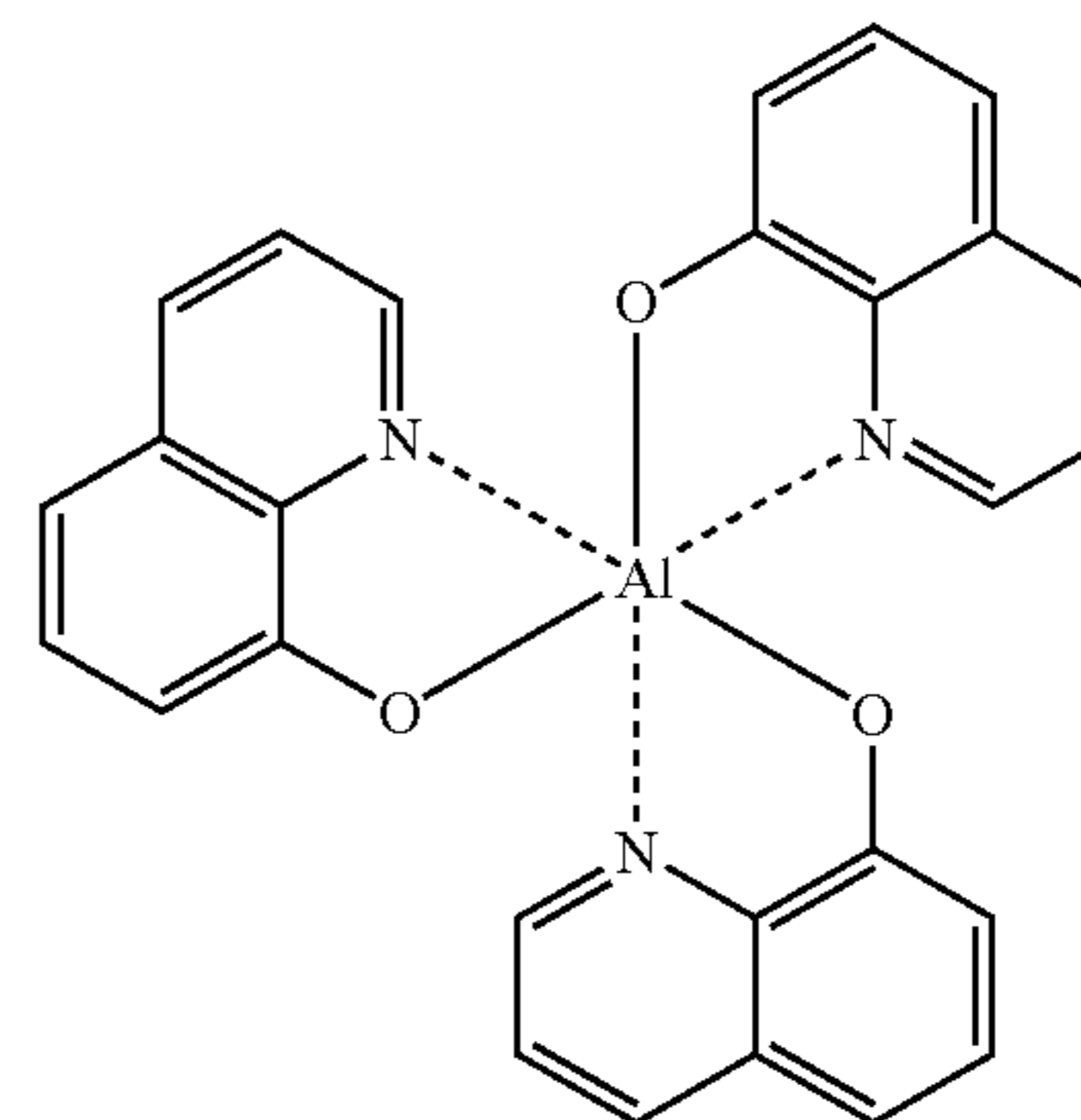
[Formula 6]



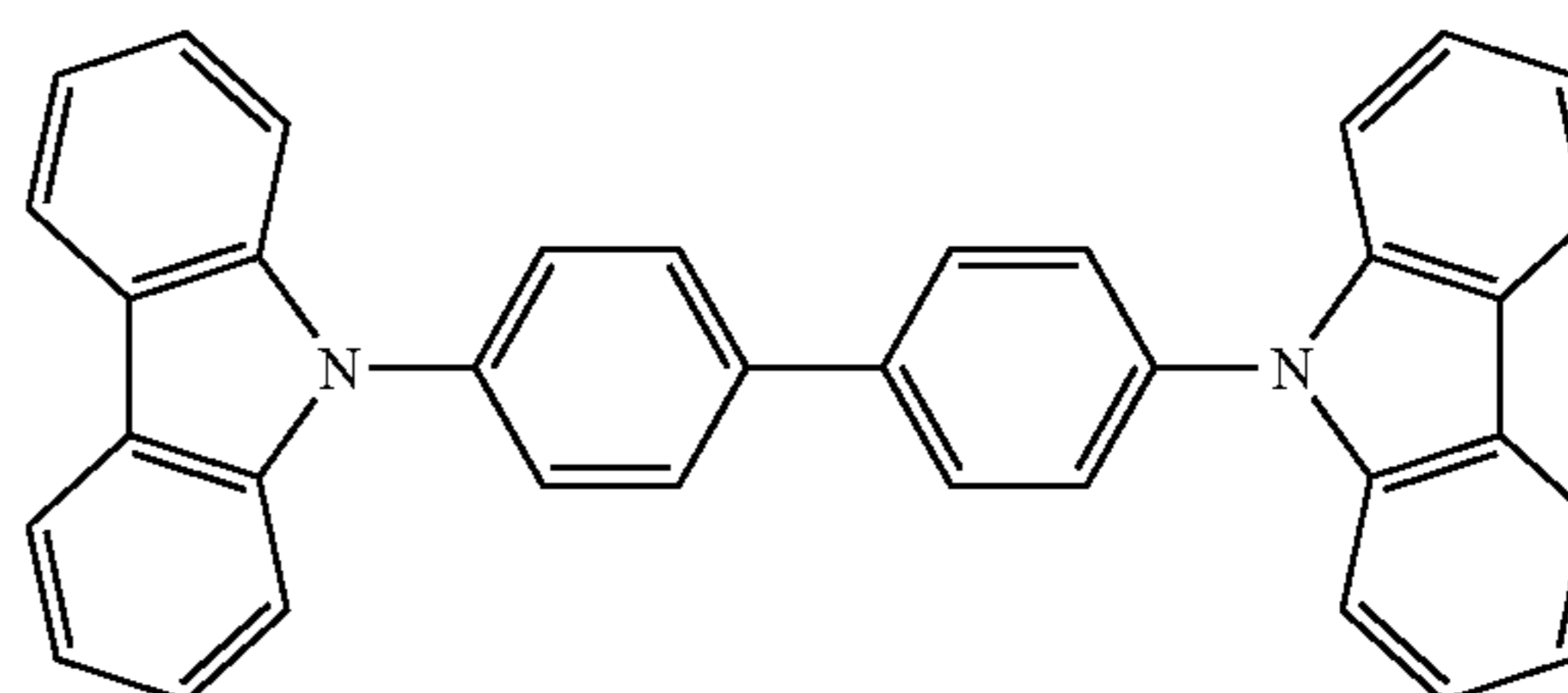
[Formula 7]



[Formula 8]



[Formula 9]



The OLED fabricated in Examples 1 to 4 and Comparative Examples 1 and 2 are evaluated for efficiency, brightness, lifetime, and so on. A voltage has a dimension of [V], an electric current has a dimension of [mA], a brightness has a dimension of [ $\text{cd/m}^2$ ], a current efficiency has a dimension of [ $\text{cd/A}$ ], a power efficiency has a dimension of [ $\text{lm/W}$ ], an internal quantum efficiency has a dimension of [%], and a lifetime has a dimension of [hour]. The evaluated results are shown in Table 1.



TABLE 1

	Volts	Electric current	Brightness	Current efficiency	Power efficiency	Internal quantum efficiency	CIE (X)	CIE (Y)	lifetime
Ex. 1	5.3	0.9	1257	12.6	7.5	18.0	0.670	0.324	5500
Ex. 2	5.3	0.9	1213	12.1	7.2	18.5	0.674	0.322	4500
Ex. 3	5.7	0.9	1512	15.1	8.3	18.9	0.664	0.332	6500
Ex. 4	5.0	0.9	1023	10.2	6.4	19.3	0.685	0.311	5000
Com.	6.0	0.9	1173	11.73	6.2	12.0	0.606	0.375	4000
Ex. 1									
Com.	7.5	0.9	780	7.8	3.3	10.4	0.659	0.329	2500
Ex. 2									

As shown in TABLE 1, the OLED in Examples 1 to 4 has high color purity (e.g., CIE(X)>0.65) and high internal quantum efficiency. Accordingly, the OLED according to the present invention has improved luminescence efficiency. As a result, when the red phosphorescent compound of the present invention as a dopant for an emission material layer of an OLED, the OLED has high color purity, high brightness and high luminescence efficiency. In addition, the OLED has elongated lifetime.

FIG. 2 is a schematic cross-sectional view of an OLED according to the present invention. In FIG. 2, an OLED 100 includes a first substrate 101, where a switching element (not shown) and a driving element DTr are formed, and a second substrate 150 where an organic light emitting diode E is formed. Each of the switching element and the driving element DTr may be a thin film transistor.

Although not shown, the first and second substrates 101 and 151 are attached by a seal pattern formed in their boundary. An absorbent is formed inner side of the seal pattern. A gate line and a data line cross each other to define a pixel region P on the first substrate 101. The switching element is formed at a crossing portion of the gate and data lines, and the driving element DTr is connected to the switching element. The driving element DTr includes a gate electrode 103, a gate insulating layer 106, a semiconductor layer 110, a source electrode 117 and a drain electrode 119. For example, the semiconductor layer 110 includes an active layer 110a of intrinsic amorphous silicon and an ohmic contact layer 110b of impurity-doped amorphous silicon. The driving element DTr having a bottom gate type shown in FIG. 2. However, the driving element has a top gate type wherein polycrystalline silicon may be used for the semiconductor layer.

A passivation layer 122 having a drain contact hole 125, which exposes a portion of the drain electrode 119 of the driving element DTr, is formed over the switching element and the driving element DTr. A connection electrode 130 is formed on the passivation layer and contacts the drain electrode 119 of the driving element DTr through the drain contact hole 125.

A first electrode 155 is formed on an entire surface of the second substrate 151. The first electrode 155 is formed of a material having a large work function and serves as an anode. For example, the first electrode 155 may be formed of ITO. A column spacer 158 corresponding to the connection electrode 158 on the first substrate 151 is formed.

An organic emission layer 176 including red, green and blue emission patterns is formed on the first electrode 155. The red, green and blue emission patterns correspond to the pixel region P. A second electrode 180 is formed on the organic emission layer 176 in each pixel region P. The second electrode 180 is formed of a material having a small work function and serves as a cathode. For example, the second electrode 180 may be formed of one of Al and Al alloy

(AlNd). The second electrode 180 on the column spacer 158 contacts the connection pattern 130 on the first substrate 101.

In addition, a wall 173 is formed on the first electrode 155. The wall 173 corresponds to boundaries of the pixel region P. Namely, the wall 173 corresponds to the gate and data lines on the first substrate 101. The wall 173 has a reverse taper shape. In more detail, a cross-sectional view of the wall 173 taken along a vertical line to the second substrate 151 has a wide side adjacent to the second substrate 151 and a wide side far to the second substrate 151. Due to the wall 173, the organic emission layer 176 and the second electrode 180 are separated in each pixel region P. A buffer layer 168 may be further formed between the wall 173 and the first electrode 155, and an auxiliary electrode 165 may be further formed between the buffer layer 168 and the first electrode 155. The auxiliary electrode 165 is formed of a low resistance metallic material such that a voltage can be efficiently applied to the first electrode 165. The buffer layer 168 and the auxiliary electrode 165 may be omitted.

Although not shown, to maximize luminescence efficiency, the organic emission layer 176 has a multiple-layered structure. For example, a hole injection layer (HIL), a hole transporting layer (HTL), an emitting material layer (EML), an electron transporting layer (ETL) and an electron injection layer (EIL) are stacked on the first electrode 155. In this case, the red emission pattern of the EML includes a host material, which is capable of transporting an electron and a hole, and the red phosphorescent compound as a dopant. The red phosphorescent compound according to the present invention is represented by the above [formula 2]. The red phosphorescent compound as a dopant is added with a range of about 0.1 weight % to about 50 weight % with respect to a total weight of a material in the red emission pattern. The host material may be formed of one of BAQ, Al metal complex, Zn metal complex and carbazole derivatives, for example, CBP. A ligand of Al metal complex and Zn metal complex may be one of quinolnyl, biphenyl, isoquinolnyl, phenyl, methylquinolnyl, dimethylquinolnyl and dimethyl-iso-quinolnyl. Each of the green and blue emission patterns also includes a phosphorescent compound.

On the other hand, in FIG. 2, the driving element DTr is disposed on the first substrate 101, while the organic luminescent diode E is disposed on the second substrate 151. In addition, since the first electrode 155 is formed of transparent ITO, light from the organic luminescent diode E passes through the second substrate 151. It is called as a top emission type. However, both the driving element DTr and the organic luminescent diode E may be disposed on the same substrate. The second electrode may be formed of a transparent material, while the first electrode may be formed of an opaque material. In this case, light from the organic luminescent diode passes through the first substrate. It is called as a bottom



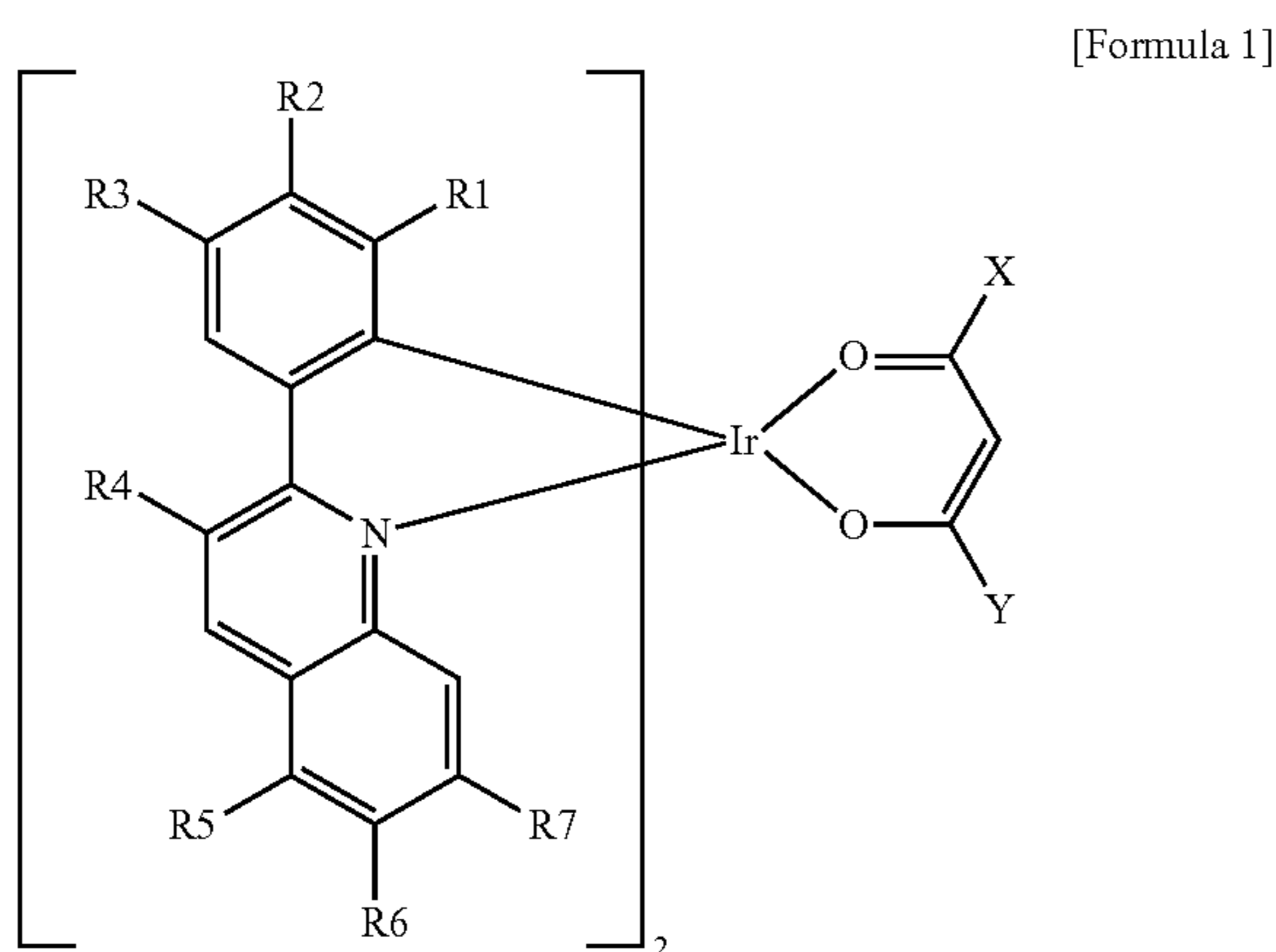
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emission type. The OLED of the present invention can be applied to any of the top and bottom emission types.

It will be apparent to those skilled in the art that various modifications and variations can be made in the present invention without departing from the spirit or scope of the invention. Thus, it is intended that the present invention cover the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A red phosphorescent composition comprising:  
a host material being capable of transporting an electrode or a hole; and  
a dopant material represented by Formula 1:



wherein each of R1 to R4 is selected from the group consisting of hydrogen atom (H) and non-substituted C1 to C6 alkyl, and at least one of R1 to R3 is non-substituted C1 to C6 alkyl,

wherein two of R5 to R7 are selected from the group consisting of halogen atom and non-substituted C1 to C6 alkyl, provided at least one is halogen, and one of R5 to R7 is hydrogen atom, and

wherein each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

2. The composition according to claim 1, wherein the non-substituted C1 to C6 alkyl is selected from the group consisting of methyl, ethyl, n-propyl, i-propyl, n-butyl, i-butyl, and t-butyl.

3. The composition according to claim 1, wherein the dopant material has a weight % of about 0.1 to about 50 with respect to a total weight of the composition.

4. The composition according to claim 1, wherein the host material is selected from the group consisting of aluminum(III)bis(2-methyl-8-quinolinato)4-phenylphenolate (BAIq), Al metal complex, Zn metal complex, and carbazole derivatives.

5. The composition according to claim 4, wherein the carbazole derivatives are 4,4'-N,N'-dicarbazole-biphenyl (CBP).

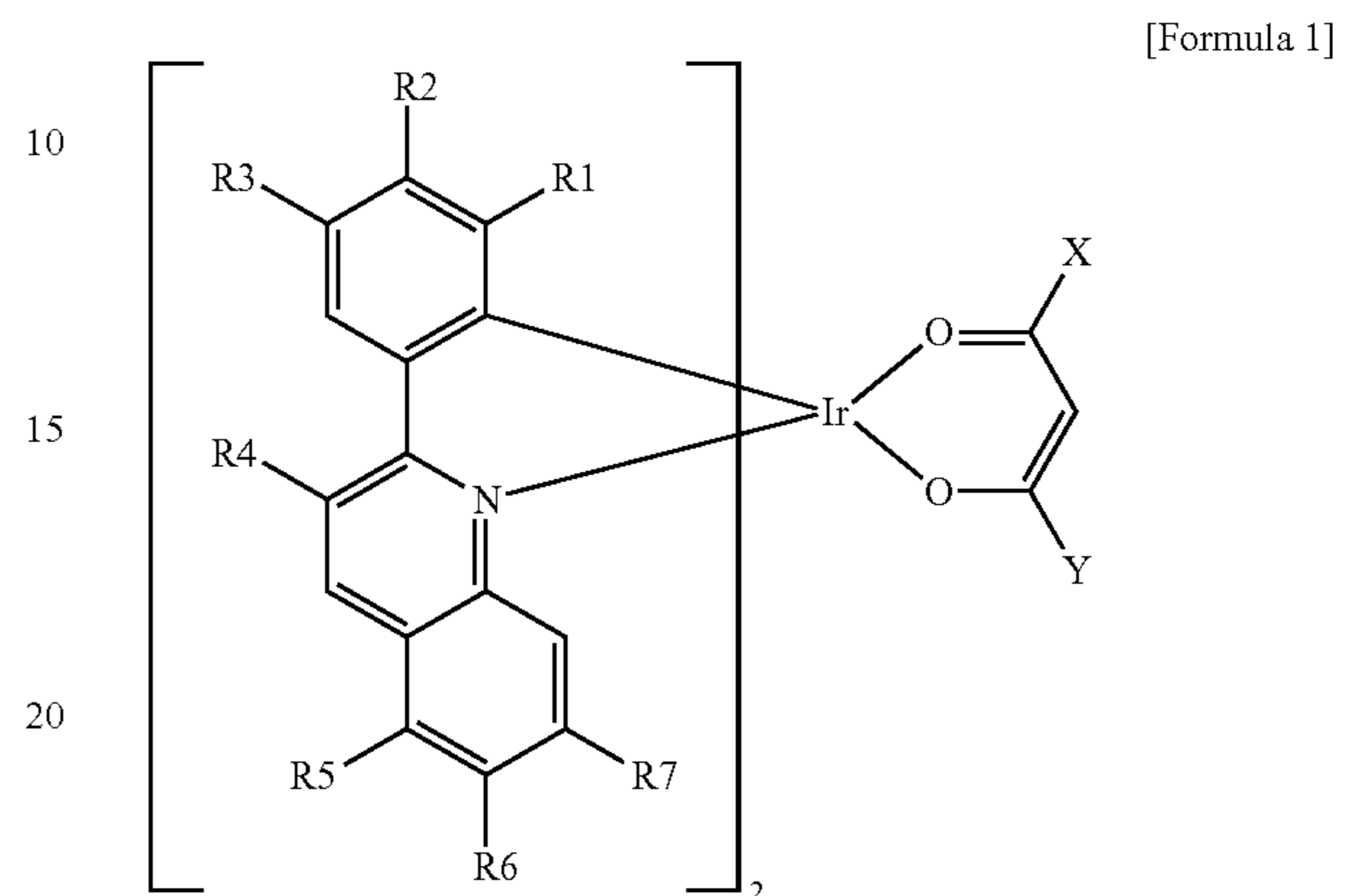
6. An organic electroluminescent device, comprising:  
a first substrate;  
a thin film transistor on the first substrate;  
a second substrate facing the first substrate; and  
an organic luminescent diode electrically connected to the thin film transistor and including a first electrode, a second electrode facing the first electrode and an organic emission layer disposed between the first and second

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electrodes, a red phosphorescent composition of the organic emission layer including:

a host material being capable of transporting an electrode or a hole; and

a dopant material represented by Formula 1:



wherein each of R1 to R4 is selected from the group consisting of hydrogen atom (H) and non-substituted C1 to C6 alkyl, and at least one of R1 to R3 is non-substituted C1 to C6 alkyl,

wherein two of R5 to R7 are selected from the group consisting of halogen atom and non-substituted C1 to C6 alkyl, provided at least one is halogen, and one of R5 to R7 is hydrogen atom, and

wherein each of X and Y is selected from the group consisting of H, non-substituted C1 to C6 alkyl and C1 to C6 alkyl substituted by fluorine.

7. The device according to claim 6, wherein the non-substituted C1 to C6 alkyl is selected from the group consisting of methyl, ethyl, n-propyl, i-propyl, n-butyl, i-butyl, and t-butyl.

8. The device according to claim 6, wherein the dopant material has a weight % of about 0.1 to about 50 with respect to a total weight of the composition.

9. The device according to claim 6, wherein the host material is selected from the group consisting of aluminum(III)bis(2-methyl-8-quinolinato)4-phenylphenolate (BAIq), Al metal complex, Zn metal complex, and carbazole derivatives.

10. The device according to claim 9, wherein the carbazole derivatives are 4,4'-N,N'-dicarbazole-biphenyl (CBP).

11. The device according to claim 6, wherein the organic emission layer has a stacked structure of a hole injection layer, a hole transporting layer, an emission material layer, an electron transporting layer and an electron injection layer.

12. The device according to claim 6, wherein the organic luminescent diode is formed on the first substrate.

13. The device according to claim 6, wherein the organic luminescent diode is formed on the second substrate.

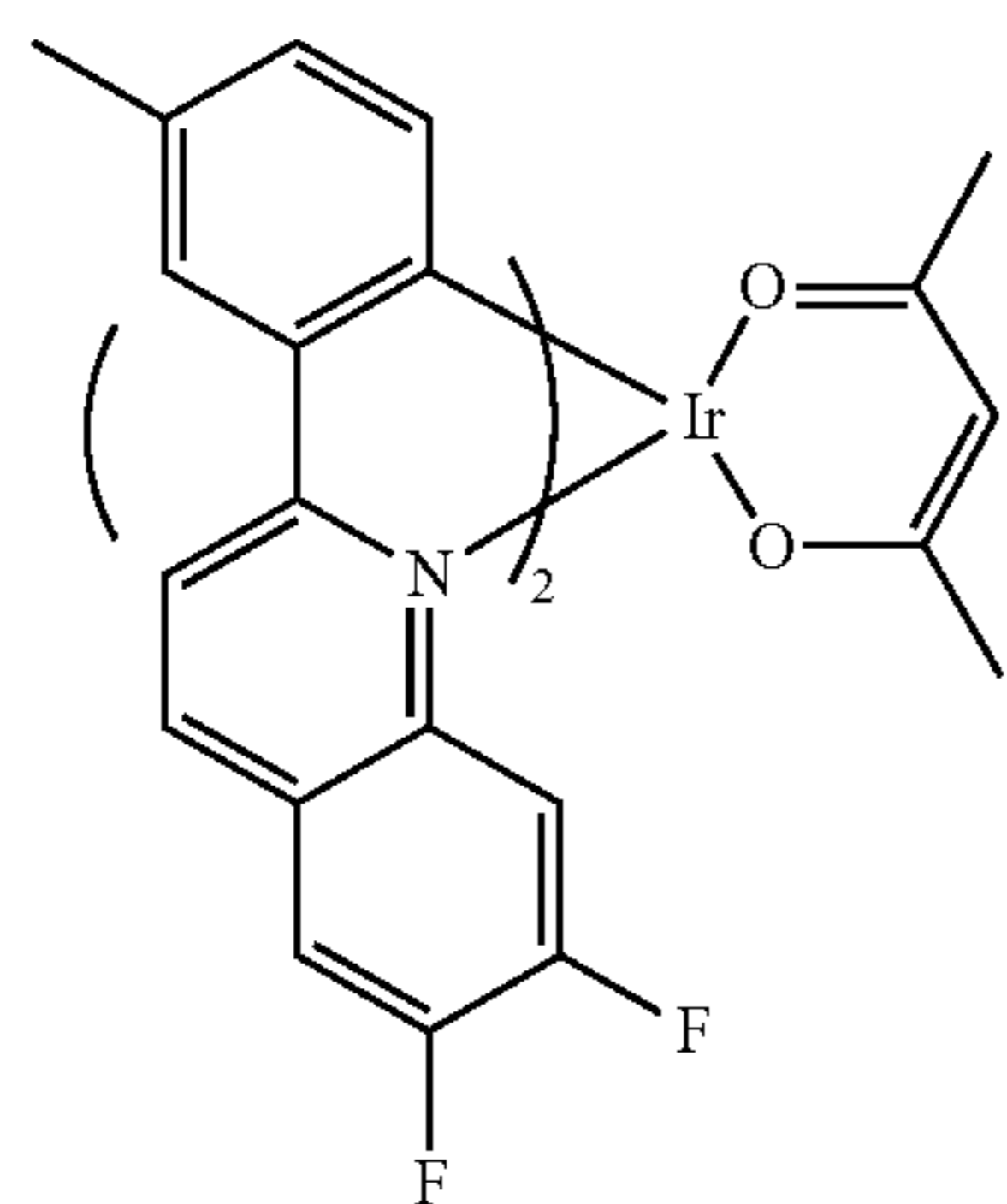
14. The device according to claim 6, wherein the first electrode is disposed between the second substrate and the second electrode and formed of a transparent conductive material.

15. The device according to claim 6, wherein the second electrode is disposed between the first substrate and the first electrode and formed of a transparent conductive material.

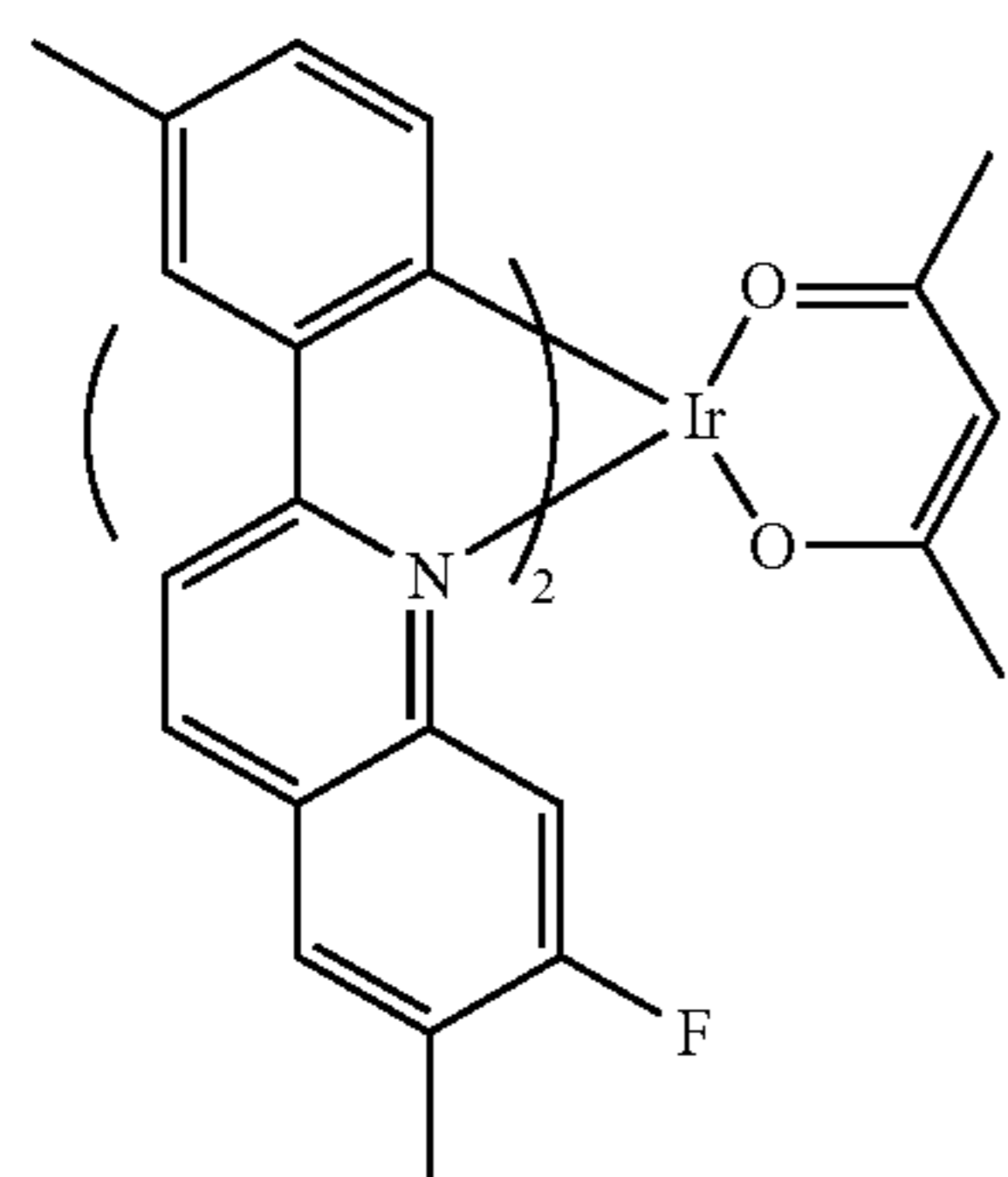
16. The composition according to claim 1, wherein the dopant material is represented by one of following Formulas 3 to 5:



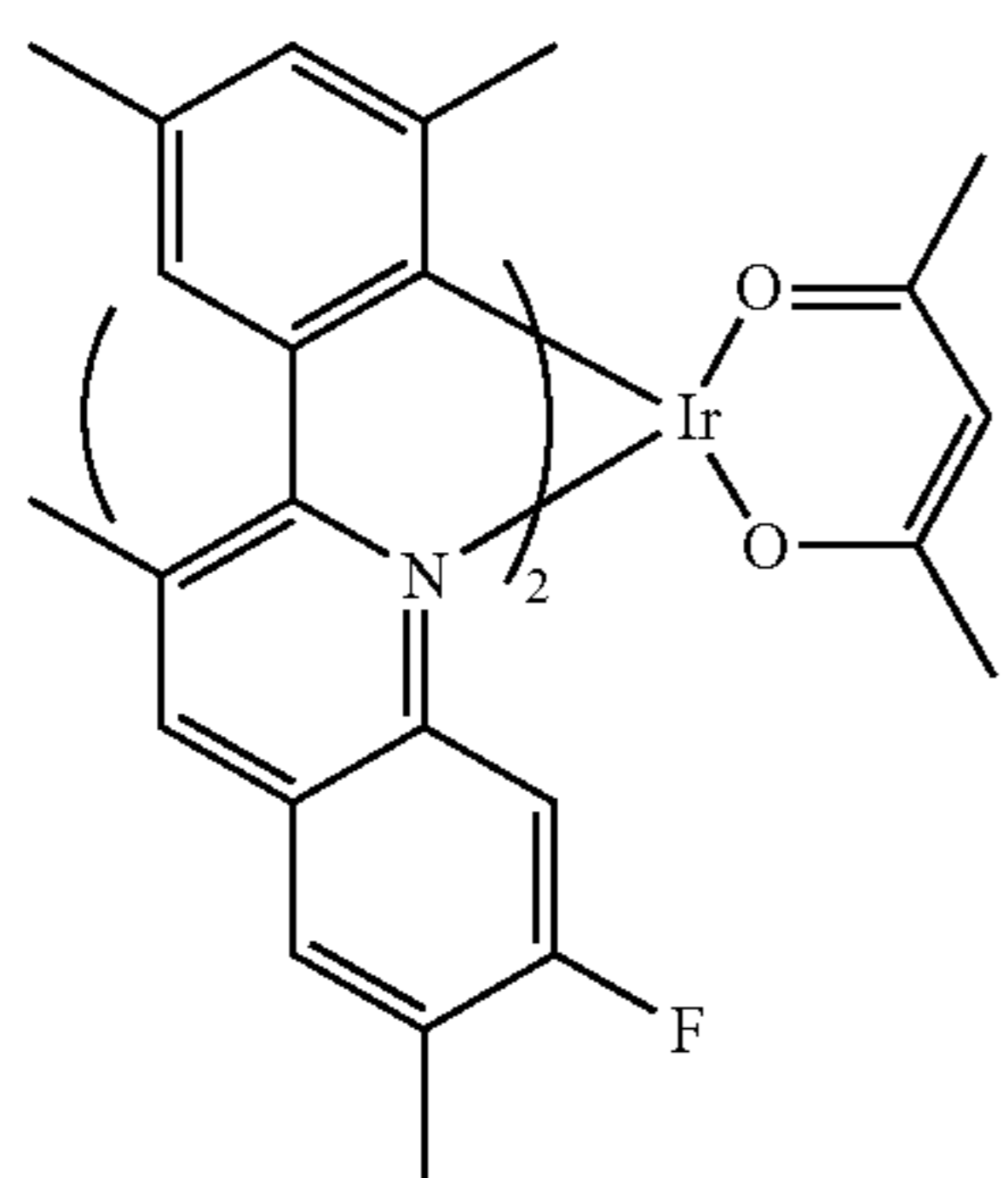
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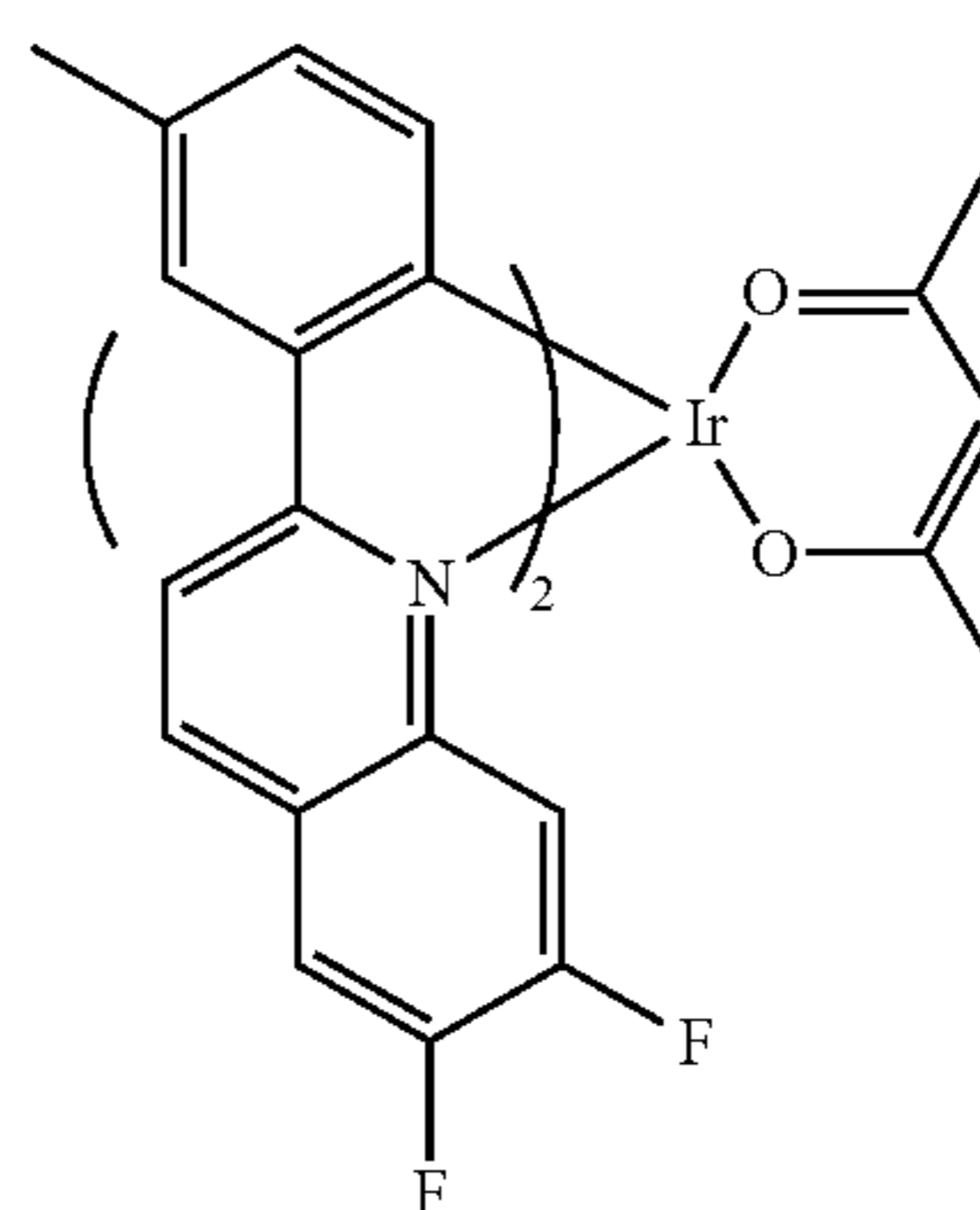


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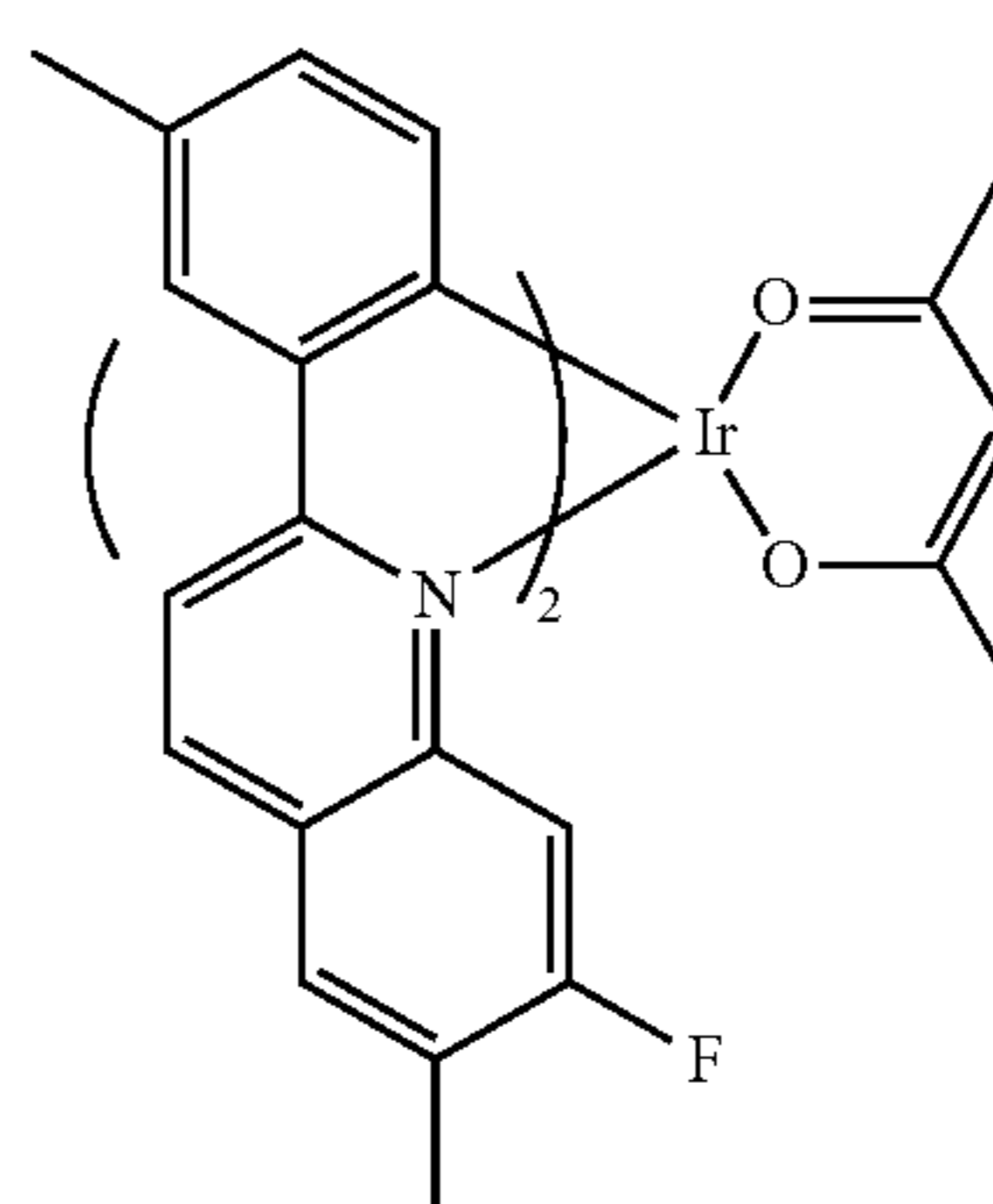


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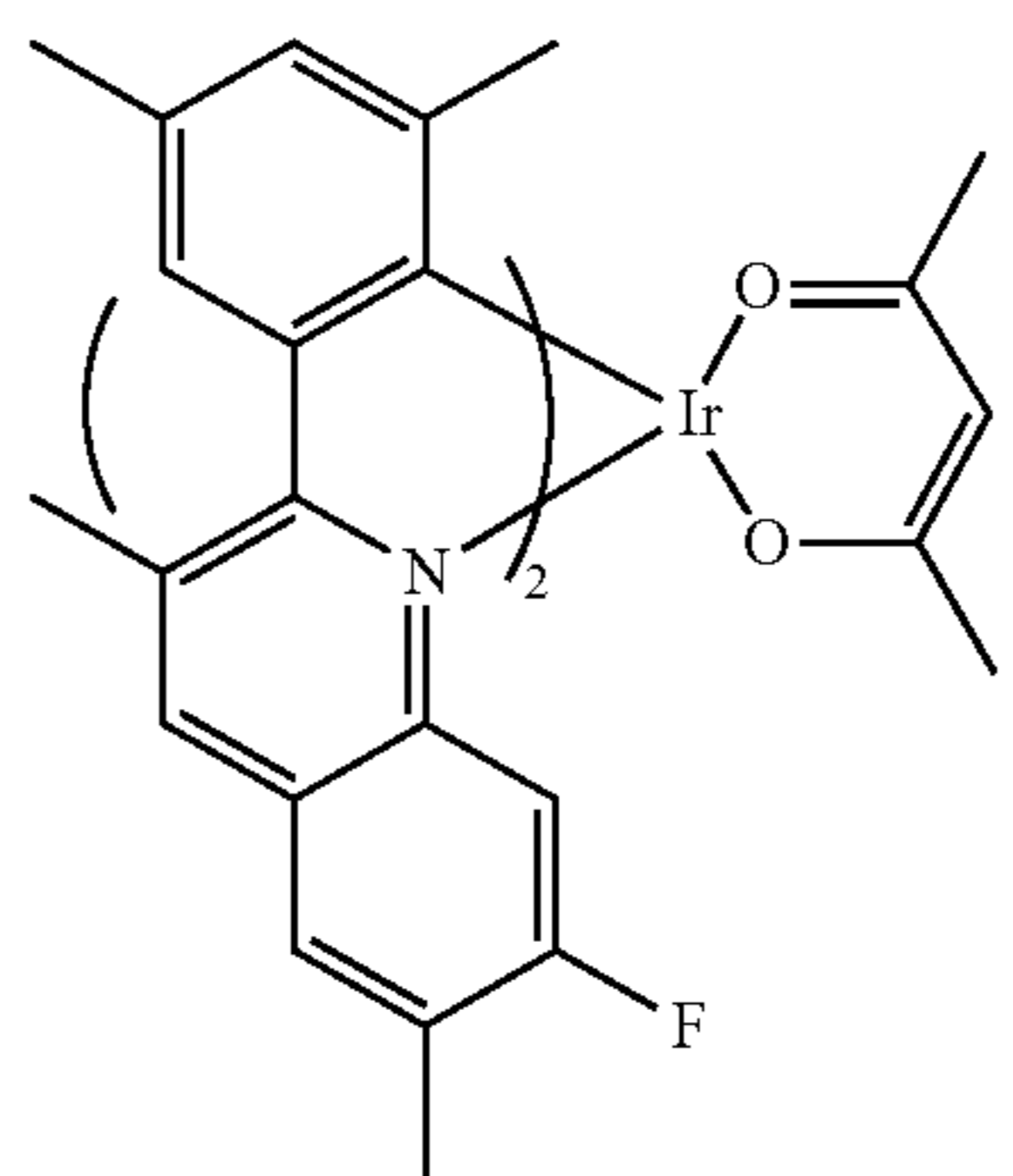
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A-24

[Formula 3]

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[Formula 4]

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[Formula 5]

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[Formula 3]

[Formula 4]

[Formula 5]

17. The organic electroluminescent device according to claim 6, wherein the dopant material is represented by one of following Formulas 3 to 5:

\* \* \* \* \*